

External Memory Interface Handbook Volume 3: Reference Material

For UniPHY-based Device Families

Updated for Intel® Quartus® Prime Design Suite: 17.0





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1. Functional Description—UniPHY

Note:

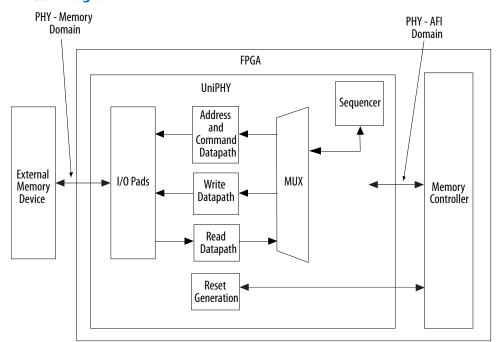
The External Memory Interface Handbook describes the UniPHY-based external memory interface IP available for use with Intel®'s V-series and earlier devices using UniPHY-based IP.

UniPHY is the physical layer of the external memory interface. The major functional units of the UniPHY layer include the following:

- · Reset and clock generation
- · Address and command datapath
- Write datapath
- Read datapath
- Sequencer

The following figure shows the PHY block diagram.

Figure 1. PHY Block Diagram



Related Information

• UniPHY Interfaces on page 23

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1.1. I/O Pads

The I/O pads contain all the I/O instantiations.

1.2. Reset and Clock Generation

At a high level, clocks in the PHY can be classified into two domains: the PHY-memory domain and the PHY-AFI domain.

The PHY-memory domain interfaces with the external memory device and always operate at full-rate. The PHY-AFI domain interfaces with the memory controller and can be a full-rate, half-rate, or quarter-rate clock, based on the controller in use.

The number of clock domains in a memory interface can vary depending on its configuration; for example:

- At the PHY-memory boundary, separate clocks may exist to generate the memory clock signal, the output strobe, and to output write data, as well as address and command signals. These clocks include pll_dq_write_clk, pll_write_clk, pll_mem_clk, and pll_addr_cmd_clk. These clocks are phase-shifted as required to achieve the desired timing relationships between memory clock, address and command signals, output data, and output strobe.
- For quarter-rate interfaces, additional clock domains such as pll_hr_clock are required to convert signals between half-rate and quarter-rate.
- For high-performance memory interfaces using Arria V, Cyclone V, or Stratix V devices, additional clocks may be required to handle transfers between the device core and the I/O periphery for timing closure. For core-to-periphery transfers, the latch clock is pll_c2p_write_clock; for periphery-to-core transfers, it is pll_p2c_read_clock. These clocks are automatically phase-adjusted for timing closure during IP generation, but can be further adjusted in the parameter editor. If the phases of these clocks are zero, the Fitter may remove these clocks during optimization.Also, high-performance interfaces using a Nios II-based sequencer require two additional clocks, pll_avl_clock for the Nios II processor, and pll_config_clock for clocking the I/O scan chains during calibration.

For a complete list of clocks in your memory interface, compile your design and run the **Report Clocks** command in the Timing Analyzer.

1.3. Dedicated Clock Networks

The UniPHY layer employs three types of dedicated clock networks:



- Global clock network
- Dual-regional clock network
- PHY clock network (applicable to Arria V, Cyclone V, and Stratix V devices, and later)

The PHY clock network is a dedicated high-speed, low-skew, balanced clock tree designed for high-performance external memory interface. For device families that support the PHY clock network, UniPHY always uses the PHY clock network for all clocks at the PHY-memory boundary.

For families that do not support the PHY clock network, UniPHY uses either dual-regional or global clock networks for clocks at the PHY-memory boundary. During generation, the system selects dual-regional or global clocks automatically, depending on whether a given interface spans more than one quadrant. UniPHY does not mix the usage of dual-regional and global clock networks for clocks at the PHY-memory boundary; this ensures that timing characteristics of the various output paths are as similar as possible.

The <variation_name>_pin_assignments.tcl script creates the appropriate clock network type assignment. The use of the PHY clock network is specified directly in the RTL code, and does not require an assignment.

The UniPHY uses an active-low, asychronous assert and synchronous de-assert reset scheme. The global reset signal resets the PLL in the PHY and the rest of the system is held in reset until after the PLL is locked.

1.4. Address and Command Datapath

The memory controller controls the read and write addresses and commands to meet the memory specifications.

The PHY is indifferent to address or command—that is, it performs no decoding or other operations—and the circuitry is the same for both. In full-rate and half-rate interfaces, address and command is full rate, while in quarter-rate interfaces, address and command is half rate.

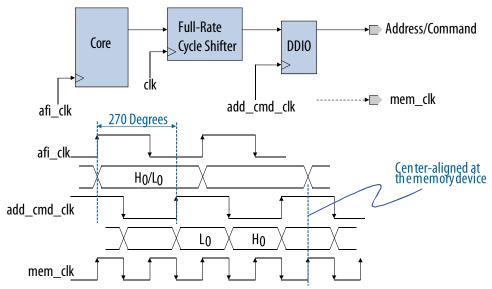
Address and command signals are generated in the Altera PHY interface (AFI) clock domain and sent to the memory device in the address and command clock domain. The double-data rate input/output (DDIO) stage converts the half-rate signals into full-rate signals, when the AFI clock runs at half-rate. For quarter-rate interfaces, additional DDIO stages exist to convert the address and command signals in the quarter-rate AFI clock domain to half-rate.

The address and command clock is offset with respect to the memory clock to balance the nominal setup and hold margins at the memory device (center-alignment). In the example below, this offset is 270 degrees. The Fitter can further optimize margins based on the actual delays and clock skews. In half-rate and quarter-rate designs, the full-rate cycle shifter blocks can perform a shift measured in full-rate cycles to implement the correct write latency; without this logic, the controller would only be able to implement even write latencies as it operates at half the speed. The full-rate cycle shifter is clocked by either the AFI clock or the address and command clock, depending on the PHY configuration, to maximize timing margins on the path from the AFI clock to the address and command clock.





Figure 2. Address and Command Datapath (Half-rate example shown)



1.5. Write Datapath

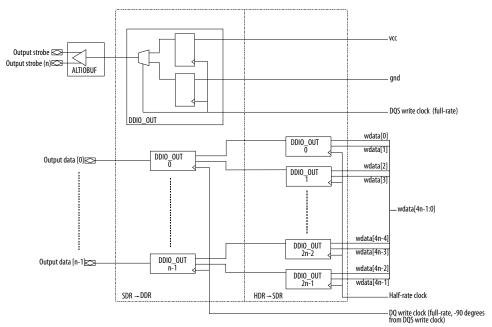
The write datapath passes write data from the memory controller to the I/O. The write data valid signal from the memory controller generates the output enable signal to control the output buffer. For memory protocols with a bidirectional data bus, it also generates the dynamic termination control signal, which selects between series (output mode) and parallel (input mode) termination.

The figure below illustrates a simplified write datapath of a typical half-rate interface. The full-rate DQS write clock is sent to a DDIO_OUT cell. The output of DDIO_OUT feeds an output buffer which creates a pair of pseudo differential clocks that connects to the memory. In full-rate mode, only the SDR-DDR portion of the path is used; in half-rate mode, the HDR-SDR circuitry is also required. The use of DDIO_OUT in both the output strobe and output data generation path ensures that their timing characteristics are as similar as possible. The

<variation_name>_pin_assignments.tcl script automatically specifies the logic
option that associates all data pins to the output strobe pin. The Fitter treats the pins
as a DQS/DQ pin group.



Figure 3. Write Datapath



1.5.1. Leveling Circuitry

Leveling circuitry is dedicated I/O circuitry to provide calibration support for fly-by address and command networks. For DDR3, leveling is always invoked, whether the interface targets a DIMM or a single component. For DDR3 implementations at higher frequencies, a fly-by topology is recommended for optimal performance. For DDR2, leveling circuitry is invoked automatically for frequencies above 240 MHz; no leveling is used for frequencies below 240 MHz.

For DDR2 at frequencies below 240 MHz, you should use a tree-style layout. For frequencies above 240 MHz, you can choose either a leveled or balanced-T or Y topology, as the leveled PHY calibrates to either implementation. Regardless of protocol, for devices without a levelling block—such as Arria II GZ, Arria V, and Cyclone V—a balanced-T PCB topology for address/command/clock must be used because fly-by topology is not supported.

For details about leveling delay chains, consult the memory interfaces hardware section of the device handbook for your FPGA.

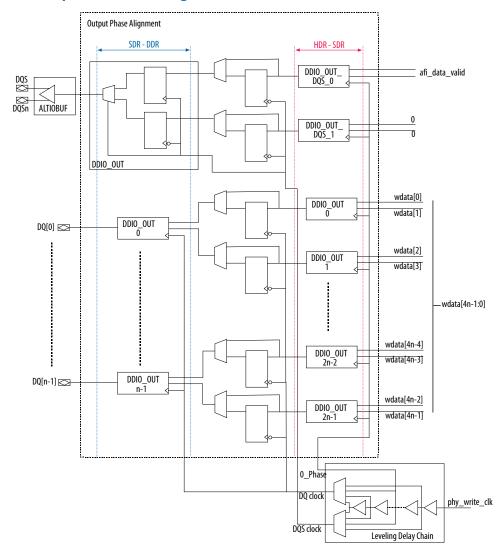
The following figure shows the write datapath for a leveling interface. The full-rate PLL output clock <code>phy_write_clk</code> goes to a leveling delay chain block which generates all other periphery clocks that are needed. The data signals that generate DQ and DQS signals pass to an output phase alignment block. The output phase alignment block feeds an output buffer which creates a pair of pseudo differential clocks that connect to the memory. In full-rate designs, only the SDR-DDR portion of the path is used; in half-rate mode, the HDR-SDR circuitry is also required. The use of DDIO_OUT in both the output strobe and output data generation paths ensures that their timing characteristics are as similar as possible. The

<variation_name>_pin_assignments.tcl script automatically specifies the logic
option that associates all data pins to the output strobe pin. The Quartus Prime Fitter
treats the pins as a DQS/DQ pin group.





Figure 4. Write Datapath for a Leveling Interface



1.6. Read Datapath

The read datapath passes read data from memory to the PHY. The following figure shows the blocks and flow in the read datapath.

For all protocols, the DQS logic block delays the strobe by 90 degrees to center-align the rising strobe edge within the data window. For DDR2, DDR3, and LPDDR2 protocols, the logic block also performs strobe gating, holding the DQS enable signal high for the entire period that data is received. One DQS logic block exists for each data group.



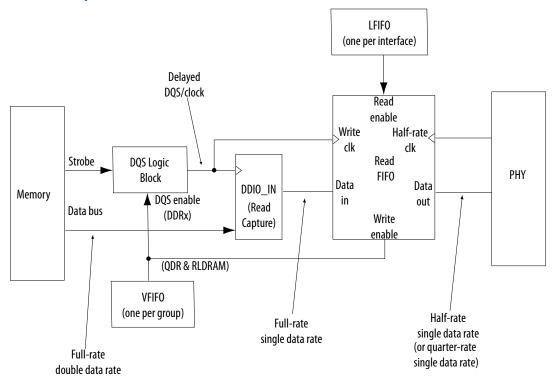
One VFIFO buffer exists for each data group. For DDR2, DDR3, and LPDDR2 protocols, the VFIFO buffer generates the DQS enable signal, which is delayed (by an amount determined during calibration) to align with the incoming DQS signal. For QDR and RLDRAM protocols, the output of the VFIFO buffer serves as the write enable signal for the Read FIFO buffer, signaling when to begin capturing data.

DDIO_IN receives data from memory at double-data rate and passes data on to the Read FIFO buffer at single-data rate.

The Read FIFO buffer temporarily holds data read from memory; one Read FIFO buffer exists for each data group. For half-rate interfaces, the Read FIFO buffer converts the full-rate, single data-rate input to a half-rate, single data-rate output which is then passed to the PHY core logic. In the case of a quarter-rate interface, soft logic in the PHY performs an additional conversion from half-rate single data rate to quarter-rate single data rate.

One LFIFO buffer exists for each memory interface; the LFIFO buffer generates the read enable signal for all Read FIFO blocks in an interface. The read enable signal is asserted when the Read FIFO blocks have buffered sufficient data from the memory to be read. The timing of the read enable signal is determined during calibration.

Figure 5. Read Datapath



1.7. Sequencer

The sequencer initializes and calibrates the external memory interface. Depending on the combination of protocol and IP architecture in your external memory interface, you may have either an RTL-based sequencer or a Nios[®] II-based sequencer.



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RTL-based sequencer implementations and Nios II-based sequencer implementations can have different pin requirements. You may not be able to migrate from an RTL-based sequencer to a Nios II-based sequencer and maintain the same pinout.

For information on sequencer support for different protocol-architecture combinations, refer to *Introduction to Intel FPGA Memory Solutions* in Volume 1 of this handbook. For information on pin planning, refer to *Planning Pin and FPGA Resources* in Volume 2 of this handbook.

Related Information

- Protocol Support Matrix
- Planning Pin and FPGA Resources

1.7.1. Nios II-Based Sequencer

The DDR2, DDR3, and LPDDR2 controllers with UniPHY employ a Nios II-based sequencer that is parameterizable and is dynamically generated at run time. The Nios II-based sequencer is also available with the QDR II and RLDRAM II controllers.

1.7.1.1. Nios II-based Sequencer Function

The sequencer enables high-frequency memory interface operation by calibrating the interface to compensate for variations in setup and hold requirements caused by transmission delays.

UniPHY converts the double-data rate interface of high-speed memory devices to a full-rate or half-rate interface for use within an FPGA. To compensate for slight variations in data transmission to and from the memory device, double-data rate is usually center-aligned with its strobe signal; nonetheless, at high speeds, slight variations in delay can result in setup or hold time violations. The sequencer implements a calibration algorithm to determine the combination of delay and phase settings necessary to maintain center-alignment of data and clock signals, even in the presence of significant delay variations. Programmable delay chains in the FPGA I/Os then implement the calculated delays to ensure that data remains centered. Calibration also applies settings to the FIFO buffers within the PHY to minimize latency and ensures that the read valid signal is generated at the appropriate time.

When calibration is completed, the sequencer returns control to the memory controller.

For more information about calibration, refer to *UniPHY Calibration Stages*, in this chapter.

Related Information

UniPHY Calibration Stages on page 50

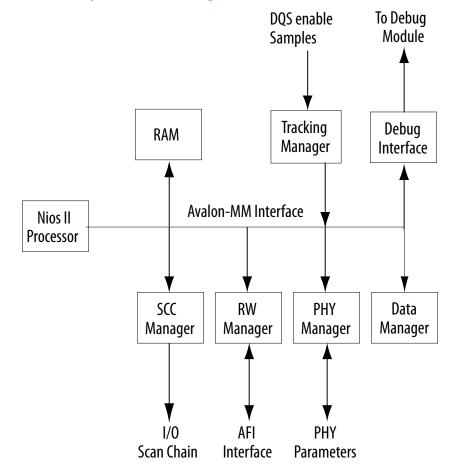
1.7.1.2. Nios II-based Sequencer Architecture

The sequencer is composed of a Nios II processor and a series of hardware-based component managers, connected together by an Avalon® bus. The Nios II processor performs the high-level algorithmic operations of calibration, while the component managers handle the lower-level timing, memory protocol, and bit-manipulation operations.



The high-level calibration algorithms are specified in C code, which is compiled into Nios II code that resides in the FPGA RAM blocks. The debug interface provides a mechanism for interacting with the various managers and for tracking the progress of the calibration algorithm, and can be useful for debugging problems that arise within the PHY. The various managers are specified in RTL and implement operations that would be slow or inefficient if implemented in software.

Figure 6. NIOS II-based Sequencer Block Diagram



The C code that defines the calibration routines is available for your reference in the \c name>_s0_software subdirectory. Intel recommends that you do not modify this C code.

1.7.1.3. Nios II-based Sequencer SCC Manager

The scan chain control (SCC) manager allows the sequencer to set various delays and phases on the I/Os that make up the memory interface. The latest Intel device families provide dynamic delay chains on input, output, and output enable paths which can be reconfigured at runtime. The SCC manager provides the calibration routines access to these chains to add delay on incoming and outgoing signals. A master on the Avalon-MM interface may require the maximum allowed delay setting on input and output paths, and may set a particular delay value in this range to apply to the paths.





The SCC manager implements the Avalon-MM interface and the storage mechanism for all input, output, and phase settings. It contains circuitry that configures a DQ- or DQS-configuration block. The Nios II processor may set delay, phases, or register settings; the sequencer scans the settings serially to the appropriate DQ or DQS configuration block.

1.7.1.4. Nios II-based Sequencer RW Manager

The read-write (RW) manager encapsulates the protocol to read and write to the memory device through the Altera PHY Interface (AFI). It provides a buffer that stores the data to be sent to and read from memory, and provides the following commands:

- Write configuration—configures the memory for use. Sets up burst lengths, read and write latencies, and other device specific parameters.
- Refresh—initiates a refresh operation at the DRAM. The command does not exist
 on SRAM devices. The sequencer also provides a register that determines whether
 the RW manager automatically generates refresh signals.
- Enable or disable multi-purpose register (MPR)—for memory devices with a special register that contains calibration specific patterns that you can read, this command enables or disables access to the register.
- Activate row—for memory devices that have both rows and columns, this
 command activates a specific row. Subsequent reads and writes operate on this
 specific row.
- Precharge—closes a row before you can access a new row.
- Write or read burst—writes or reads a burst length of data.
- Write guaranteed—writes with a special mode where the memory holds address
 and data lines constant. Intel guarantees this type of write to work in the presence
 of skew, but constrains to write the same data across the entire burst length.
- Write and read back-to-back—performs back-to-back writes or reads to adjacent banks. Most memory devices have strict timing constraints on subsequent accesses to the same bank, thus back-to-back writes and reads have to reference different banks.
- Protocol-specific initialization—a protocol-specific command required by the initialization sequence.

1.7.1.5. Nios II-based Sequencer PHY Manager

The PHY Manager provides access to the PHY for calibration, and passes relevant calibration results to the PHY. For example, the PHY Manager sets the VFIFO and LFIFO buffer parameters resulting from calibration, signals the PHY when the memory initialization sequence finishes, and reports the pass/fail status of calibration.

1.7.1.6. Nios II-based Sequencer Data Manager

The Data Manager stores parameterization-specific data in RAM, for the software to query.

1.7.1.7. Nios II-based Sequencer Tracking Manager

The Tracking Manager detects the effects of voltage and temperature variations that can occur on the memory device over time resulting in reduced margins, and adjusts the DQS enable delay as necessary to maintain adequate operating margins.

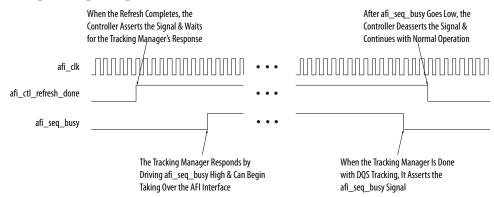


The Tracking Manager briefly assumes control of the AFI interface after each memory refresh cycle, issuing a read routine to the RW Manager, and then sampling the DQS tracking. Ideally, the falling edge of the DQS enable signal would align to the last rising edge of the raw DQS signal from the memory device. The Tracking Manager determines whether the DQS enable signal is leading or trailing the raw DQS signal.

Each time a refresh occurs, the Tracking Manager takes a sample of the raw DQS signal; any adjustments of the DQS enable signal occur only after sufficient samples of raw DQS have been taken. When the Tracking Manager determines that the DQS enable signal is either leading or lagging the raw DQS signal, it adjusts the DQS enable appropriately.

The following figure shows the Tracking manager signals.

Figure 7. Tracking Manager Signals



Some notes on Tracking Manager operation:

- The time taken by the Tracking Manager is arbitrary; if the period taken exceeds the refresh period, the Tracking Manager handles memory refresh.
- afi_seq_busy should go high fewer than 10 clock cycles after afi_ctl_refresh_done or afi_ctl_long_idle is asserted.
- afi_refresh_done should deassert fewer than 10 clock cycles after afi seq busy deasserts.





- afi_ctl_long_idle causes the Tracking Manager to execute an algorithm different than periodic refresh; use afi_ctl_long_idle when a long session has elapsed without a periodic refresh.
- The Tracking Manager is instantiated into the sequencer system when DQS Tracking is turned on.

Table 1. Configurations Supporting DQS Tracking

Device Family	Protocol	Memory Clock Frequency
Arria V (GX/GT/SX/ST) , Cyclone V	LPDDR2 (single rank)	All frequencies.
Arria V (GX/GT/SX/ST)	DDR3 (single rank)	450 MHz or higher for speed grade 5, or higher than 534 MHz.
Arria V GZ, Stratix V (E/GS/GT/GX)		750 MHz or higher.

• If you do not want to use DQS tracking, you can disable it (at your own risk), by opening the Verilog file <variant_name</pre>>_if0_c0.v in an editor, and changing the value of the USE_DQS_TRACKING parameter from 1 to 0.

1.7.1.8. Nios II-based Sequencer Processor

The Nios II processor manages the calibration algorithm; the Nios II processor is unavailable after calibration is completed.

The same calibration algorithm supports all device families, with some differences. The following sections describe the calibration algorithm for DDR3 SDRAM on Stratix III devices. Calibration algorithms for other protocols and families are a subset and significant differences are pointed out when necessary. As the algorithm is fully contained in the software of the sequencer (in the C code) enabling and disabling specific steps involves turning flags on and off.

Calibration consists of the following stages:

- Initialize memory.
- Calibrate read datapath.
- Calibrate write datapath.
- Run diagnostics.

1.7.1.9. Nios II-based Sequencer Calibration and Diagnostics

Calibration must initialize all memory devices before they can operate properly. The sequencer performs this memory initialization stage when it takes control of the PHY at startup.

Calibrating the read datapath comprises the following steps:

- Calibrate DQS enable cycle and phase.
- Perform read per-bit deskew to center the strobe signal within data valid window.
- Reduce LFIFO latency.

Calibrating the write datapath involves the following steps:

- Center align DQS with respect to DQ.
- Align DQS with mem_clk.





The sequencer estimates the read and write margins under noisy conditions, by sweeping input and output DQ and DQS delays to determine the size of the data valid windows on the input and output sides. The sequencer stores this diagnostic information in the local memory and you can access it through the debugging interface.

When the diagnostic test finishes, control of the PHY interface passes back to the controller and the sequencer issues a pass or fail signal.

Related Information

External Memory Interface Debug Toolkit on page 272

1.7.2. RTL-based Sequencer

The RTL-based sequencer is available for QDR II and RLDRAM II interfaces, on supported device families other than Arria V. The RTL sequencer is a state machine that processes the calibration algorithm.

The sequencer assumes control of the interface at reset (whether at initial startup or when the IP is reset) and maintains control throughout the calibration process. The sequencer relinquishes control to the memory controller only after successful calibration. The following tables list the major states in the RTL-based sequencer.

Table 2. Sequencer States

RTL-based Sequencer State	Description
RESET	Remain in this state until reset is released.
LOAD_INIT	Load any initialization values for simulation purposes.
STABLE	Wait until the memory device is stable.
WRITE_ZERO	Issue write command to address 0.
WAIT_WRITE_ZERO	Write all 0xAs to address 0.
WRITE_ONE	Issue write command to address 1.
WAIT_WRITE_ONE	Write all 0x5s to address 1.
Valid Calibration States	
V_READ_ZERO	Issue read command to address 0 (expected data is all 0xAs).
V_READ_NOP	This state represents the minimum number of cycles required between 2 back-to-back read commands. The number of NOP states depends on the burst length.
V_READ_ONE	Issue read command to address 1 (expected data is all 0x5s).
V_WAIT_READ	Wait for read valid signal.
V_COMPARE_READ_ZERO_READ_ONE	Parameterizable number of cycles to wait before making the read data comparisons.
V_CHECK_READ_FAIL	When a read fails, the write pointer (in the AFI clock domain) of the valid FIFO buffer is incremented. The read pointer of the valid FIFO buffer is in the DQS clock domain. The gap between the read and write pointers is effectively the latency between the time when the PHY receives the read command and the time valid data is returned to the PHY.
V_ADD_FULL_RATE	Advance the read valid FIFO buffer write pointer by an extra full rate cycle.
V_ADD_HALF_RATE	Advance the read valid FIFO buffer write pointer by an extra half rate cycle. In full-rate designs, equivalent to V_ADD_FULL_RATE.
	continued





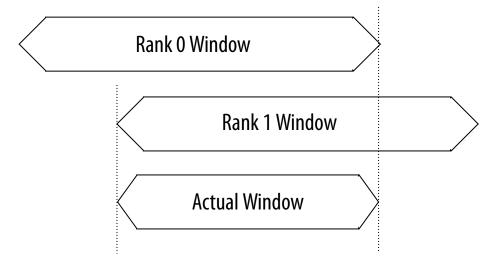
RTL-based Sequencer State	Description	
V_READ_FIFO_RESET	Reset the read and write pointers of the read data synchronization FIFO buffer.	
V_CALIB_DONE	Valid calibration is successful.	
Latency Calibration States		
L_READ_ONE	Issue read command to address 1 (expected data is all 0x5s).	
L_WAIT_READ	Wait for read valid signal from read datapath. Initial read latency is set to a predefined maximum value.	
L_COMPARE_READ_ONE	Check returned read data against expected data. If data is correct, go to L_REDUCE_LATENCY; otherwise go to L_ADD_MARGIN.	
L_REDUCE_LATENCY	Reduce the latency counter by 1.	
L_READ_FLUSH	Read from address 0, to flush the contents of the read data resynchronization FIFO buffer.	
L_WAIT_READ_FLUSH	Wait until the whole FIFO buffer is flushed, then go back to L_READ and try again.	
L_ADD_MARGIN	Increment latency counter by 3 (1 cycle to get the correct data, 2 more cycles of margin for run time variations). If latency counter value is smaller than predefined ideal condition minimum, then go to CALIB_FAIL.	
CALIB_DONE	Calibration is successful.	
CALIB_FAIL	Calibration is not successful.	

1.8. Shadow Registers

Shadow registers are a hardware feature of Arria V GZ and Stratix V devices that enables high-speed multi-rank calibration for DDR3 quarter-rate and half-rate memory interfaces, up to 800MHz for dual-rank interfaces and 667MHz for quad-rank interfaces.

Prior to the introduction of shadow registers, the data valid window of a multi-rank interface was calibrated to the overlapping portion of the data valid windows of the individual ranks. The resulting data valid window for the interface would be smaller than the individual data valid windows, limiting overall performance.

Figure 8. Calibration of Overlapping Data Valid Windows, without Shadow Registers



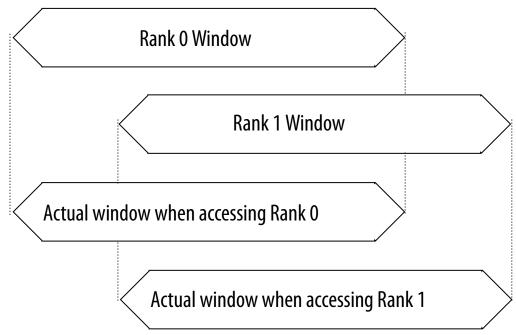




Shadow registers allow the sequencer to calibrate each rank separately and fully, and then to save the calibrated settings for each rank in its own set of shadow registers, which are part of the IP scan chains. During a rank-to-rank switch, the rank-specific set of calibration settings is restored just-in-time to optimize the data valid window for each rank.

The following figure illustrates how the use of rank-specific calibration settings results in a data valid window appropriate for the current rank.

Figure 9. Rank-specific Calibration Settings, with Shadow Registers



The shadow registers and their associated rank-switching circuitry are part of the device I/O periphery hardware.

1.8.1. Shadow Registers Operation

The sequencer calibrates each rank individually and stores the resulting configuration in shadow registers, which are part of the IP scan chains. UniPHY then selects the appropriate configuration for the rank in use, switching between configurations as necessary. Calibration results for deskew delay chains are stored in the shadow registers. For DQS enable/disable, delay chain configurations come directly from the FPGA core.

Signals

The afi_wrank signal indicates the rank to which the controller is writing, so that the PHY can switch to the appropriate setting. Signal timing is identical to afi_dqs_burst; that is, afi_wrank must be asserted at the same time as afi_dqs_burst, and must be of the same duration.



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The afi_rrank signal indicates the rank from which the controller is reading, so that the PHY can switch to the appropriate setting. This signal must be asserted at the same time as afi_rdata_en when issuing a read command, and once asserted, must remain unchanged until the controller issues a new read command to another rank.

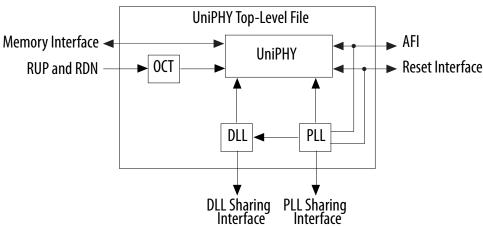
1.9. UniPHY Interfaces

The following figure shows the major blocks of the UniPHY and how it interfaces with the external memory device and the controller.

Note:

Instantiating the delay-locked loop (DLL) and the phase-locked loop (PLL) on the same level as the UniPHY eases DLL and PLL sharing.

Figure 10. UniPHY Interfaces with the Controller and the External Memory



The following interfaces are on the UniPHY top-level file:

- AFI
- Memory interface
- · DLL sharing interface
- PLL sharing interface
- OCT interface

AFI

The UniPHY datapath uses the Altera PHY interface (AFI). The AFI is in a simple connection between the PHY and controller. The AFI is based on the DDR PHY interface (DFI) specification, with some calibration-related signals not used and some additional Intel-specific sideband signals added.

For more information about the AFI, refer to AFI 3.0 Specification, in this chapter.

The Memory Interface

For information on the memory interface, refer to *UniPHY Signals*, in this chapter.

Related Information

AFI 3.0 Specification on page 35





UniPHY Signals on page 27

1.9.1. The DLL and PLL Sharing Interface

You can generate the UniPHY memory interface and configure it to share its PLL, DLL, or both interfaces.

By default, a UniPHY memory interface variant contains a PLL and DLL; the PLL produces a variety of required clock signals derived from the reference clock, and the DLL produces a delay codeword. In this case the PLL sharing mode is "No sharing". A UniPHY variant can be configured as a PLL Master and/or DLL Master, in which case the corresponding interfaces are exported to the UniPHY top-level and can be connected to an identically configured UniPHY variant PLL Slave and/or DLL Slave. The UniPHY slave variant is instantiated without a PLL and/or DLL, which saves device resources.

Note:

- 1. For Arria II GX, Arria II GZ, Stratix III, and Stratix IV devices, the PLL and DLL must both be shared at the same time—their sharing modes must match. This restriction does not apply to Arria V, Arria V GZ, Cyclone V, or Stratix V devices.
- 2. For devices with hard memory interface components onboard, you cannot share PLL or DLL resources between soft and hard interfaces.

1.9.1.1. Sharing PLLs or DLLs

To share PLLs or DLLs, follow these steps:

- To create a PLL or DLL master, create a UniPHY memory interface IP core. To make the PLL and/or DLL interface appear at the top-level in the core, on the PHY Settings tab in the parameter editor, set the PLL Sharing Mode and/or DLL Sharing Mode to Master.
- To create a PLL or DLL slave, create a second UniPHY memory interface IP core. To make the PLL and/or DLL interface appear at the top-level in the core, on the PHY Settings tab set the PLL Sharing Mode and/or DLL Sharing Mode to Slave.
- Connect the PLL and/or DLL sharing interfaces by following the appropriate step, below:
 - For cores generated with IP Catalog: connect the PLL and/or DLL interface ports between the master and slave cores in your wrapper RTL. When using PLL sharing, connect the afi_clk, afi_half_clk, and afi_reset_export_n outputs from the UniPHY PLL master to the afi_clk, afi_half_clk, and afi_reset_in inputs on the UniPHY PLL slave.
 - For cores generated with Platform Designer, connect the PLL and/or DLL interface in the Platform Designer GUI. When using PLL sharing, connect the afi_clk, afi_half_clk, and afi_reset_export_n outputs from the UniPHY PLL master to the afi_clk, afi_half_clk, and afi_reset_in inputs on the UniPHY PLL slave.

Platform Designer supports only one-to-one conduit connections in the patch panel. To share a PLL from a UniPHY PLL master with multiple slaves, you should replicate the number of PLL sharing conduit interfaces in the Platform Designer patch panel by choosing **Number of PLL sharing interfaces** in the parameter editor.



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Note:

You may connect a slave UniPHY instance to the clocks from a user-defined PLL instead of from a UniPHY master. The general procedure for doing so is as follows:

- 1. Make a template, by generating your IP with **PLL Sharing Mode** set to No Sharing, and then compiling the example project to determine the frequency and phases of the clock outputs from the PLL.
- Generate an external PLL using the IP Catalog flow, with the equivalent output clocks.
- 3. Generate your IP with **PLL Sharing Mode** set to Slave, and connect the external PLL to the PLL sharing interface.

You must be very careful when connecting clock signals to the slave. Connecting to clocks with frequency or phase different than what the core expects may result in hardware failure.

Note:

The signal dll_pll_locked is an internal signal from the PLL to the DLL which ensures that the DLL remains in reset mode until the PLL becomes locked. This signal is not available for use by customer logic.

1.9.1.2. About PLL Simulation

PLL frequencies may differ between the synthesis and simulation file sets. In either case the achieved PLL frequencies and phases are calculated and reported in real time in the parameter editor.

For the simulation file set, clocks are specified in the RTL, not in units of frequency but by the period in picoseconds, thus avoiding clock drift due to picosecond rounding error.

For the synthesis file set, there are two mechanisms by which clock frequencies are specified in the RTL, based on the target device family:

- For Arria V, Arria V GZ, Cyclone V, and Stratix V, clock frequencies are specified in MHz
- For Arria II GX, Arria II GZ, Stratix III, and Stratix IV, clock frequencies are specified by integer multipliers and divisors. For these families, the real simulation model—as opposed to the default abstract simulation model—also uses clock frequencies specified by integer ratios.

1.9.2. The OCT Sharing Interface

By default, the UniPHY IP generates the required on-chip termination (OCT) control block at the top-level RTL file for the PHY.

If you want, you can instantiate this block elsewhere in your code and feed the required termination control signals into the IP core by turning off **Master for OCT Control Block** on the **PHY Settings** tab. If you turn off **Master for OCT Control Block**, you must instantiate the OCT control block or use another UniPHY instance as a master, and ensure that the parallel and series termination control bus signals are connected to the PHY.

The following figures show the PHY architecture with and without Master for OCT Control Block.



Figure 11. PHY Architecture with Master for OCT Control Block

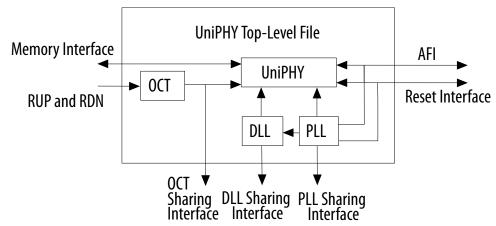
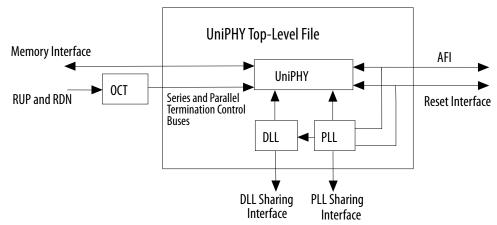


Figure 12. PHY Architecture without Master for OCT Control Block



1.9.2.1. Modifying the Pin Assignment Script for QDR II and RLDRAM II

If you generate a QDR II or RLDRAM II slave IP core, you must modify the pin assignment script to allow the fitter to correctly resolve the OCT termination block name in the OCT master core.

To modify the pin assignment script for QDR II or RLDRAM II slaves, follow these steps:

- 1. In a text editor, open your system's Tcl pin assignments script file, as follows:
 - For systems generated with the IP Catalog: Open the <IP core name>/ <slave core name>_p0_pin_assignments.tcl file.
 - For systems generated with Platform Designer: Open the <hDL Path>/ <submodules>/<slave core name>_p0_pin_assignments.tcl file.
- 2. Search for the following line:

```
set ::master_corename "_MASTER_CORE_"
```





- 3. Replace _MASTER_CORE_ with the instance name of the UniPHY master to which the slave is connected. The instance name is determined from the pin assignments file name, as follows:
 - For systems generated with Platform Designer, the instance name is the <master core name> component of the pins assignments file name: <HDL path>/<submodules>/<master core name>_p0_pin_assignments.tcl.
 - For systems generated with the IP Catalog, the instance name is the <master core name > component of the pins assignments file name: <IP core name > /<master core name > _p0_pin_assignments.tcl.

1.10. UniPHY Signals

The following tables list the UniPHY signals.

Table 3. Clock and Reset Signals

Name	Direction	Width	Description
pll_ref_clk	Input	1	PLL reference clock input.
global_reset_n	Input	1	Active low global reset for PLL and all logic in the PHY, which causes a complete reset of the whole system. Minimum recommended pulse width is 100ns.
soft_reset_n	Input	1	Holding soft_reset_n low holds the PHY in a reset state. However it does not reset the PLL, which keeps running. It also holds the afi_reset_n output low.

Table 4. DDR2 and DDR3 SDRAM Interface Signals

Name	Direction	Width	Description
mem_ck, mem_ck_n	Output	MEM_CK_WIDTH	Memory clock.
mem_cke	Output	MEM_CLK_EN_WIDTH	Clock enable.
mem_cs_n	Output	MEM_CHIP_SELECT_WIDTH	Chip select
mem_cas_n	Output	MEM_CONTROL_WIDTH	Column address strobe.
mem_ras_n	Output	MEM_CONTROL_WIDTH	Row address strobe.
mem_we_n	Output	MEM_CONTROL_WIDTH	Write enable.
mem_a	Output	MEM_ADDRESS_WIDTH	Address.
mem_ba	Output	MEM_BANK_ADDRESS_WIDTH	Bank address.
mem_dqs, mem_dqs_n	Bidirectional	MEM_DQS_WIDTH	Data strobe.
mem_dq	Bidirectional	MEM_DQ_WIDTH	Data.
			continued





Name	Direction	Width	Description
mem_dm	Output	MEM_DM_WIDTH	Data mask.
mem_odt	Output	MEM_ODT_WIDTH	On-die termination.
mem_reset_n (DDR3 only)	Output	1	Reset
mem_ac_parity (DDR3 only, RDIMM/ LRDIMM only)	Output	MEM_CONTROL_WIDTH	Address/command parity bit. (Even parity, per the RDIMM spec, JESD82-29A.)
mem_err_out_n (DDR3 only, RDIMM/ LRDIMM only)	Input	MEM_CONTROL_WIDTH	Address/command parity error.

Table 5. UniPHY Parameters

Parameter Name	Description
AFI_RATIO	AFI_RATIO is 1 in full-rate designs. AFI_RATIO is 2 for half-rate designs.
	AFI_RATIO is 4 for quarter-rate designs.
MEM_IF_DQS_WIDTH	The number of DQS pins in the interface.
MEM_ADDRESS_WIDTH	The address width of the specified memory device.
MEM_BANK_WIDTH	The bank width of the specified memory device.
MEM_CHIP_SELECT_WIDTH	The chip select width of the specified memory device.
MEM_CONTROL_WIDTH	The control width of the specified memory device.
MEM_DM_WIDTH	The DM width of the specified memory device.
MEM_DQ_WIDTH	The DQ width of the specified memory device.
MEM_READ_DQS_WIDTH	The READ DQS width of the specified memory device.
MEM_WRITE_DQS_WIDTH	The WRITE DQS width of the specified memory device.
OCT_SERIES_TERM_CONTROL_WIDTH	-
OCT_PARALLEL_TERM_CONTROL_WIDTH	-
AFI_ADDRESS_WIDTH	The AFI address width, derived from the corresponding memory interface width.
AFI_BANK_WIDTH	The AFI bank width, derived from the corresponding memory interface width.
AFI_CHIP_SELECT_WIDTH	The AFI chip select width, derived from the corresponding memory interface width.
AFI_DATA_MASK_WIDTH	The AFI data mask width.
AFI_CONTROL_WIDTH	The AFI control width, derived from the corresponding memory interface width.
	continued





Parameter Name	Description
AFI_DATA_WIDTH	The AFI data width.
AFI_DQS_WIDTH	The AFI DQS width.
DLL_DELAY_CTRL_WIDTH	The DLL delay output control width.
NUM_SUBGROUP_PER_READ_DQS	A read datapath parameter for timing purposes.
QVLD_EXTRA_FLOP_STAGES	A read datapath parameter for timing purposes.
READ_VALID_TIMEOUT_WIDTH	A read datapath parameter; calibration fails when the timeout counter expires.
READ_VALID_FIFO_WRITE_ADDR_WIDTH	A read datapath parameter; the write address width for half-rate clocks.
READ_VALID_FIFO_READ_ADDR_WIDTH	A read datapath parameter; the read address width for full-rate clocks.
MAX_LATENCY_COUNT_WIDTH	A latency calibration parameter; the maximum latency count width.
MAX_READ_LATENCY	A latency calibration parameter; the maximum read latency.
READ_FIFO_READ_ADDR_WIDTH	_
READ_FIFO_WRITE_ADDR_WIDTH	_
MAX_WRITE_LATENCY_COUNT_WIDTH	A write datapath parameter; the maximum write latency count width.
INIT_COUNT_WIDTH	An initallization sequence.
MRSC_COUNT_WIDTH	A memory-specific initialization parameter.
INIT_NOP_COUNT_WIDTH	A memory-specific initialization parameter.
MRS_CONFIGURATION	A memory-specific initialization parameter.
MRS_BURST_LENGTH	A memory-specific initialization parameter.
MRS_ADDRESS_MODE	A memory-specific initialization parameter.
MRS_DLL_RESET	A memory-specific initialization parameter.
MRS_IMP_MATCHING	A memory-specific initialization parameter.
MRS_ODT_EN	A memory-specific initialization parameter.
MRS_BURST_LENGTH	A memory-specific initialization parameter.
MEM_T_WL	A memory-specific initialization parameter.
MEM_T_RL	A memory-specific initialization parameter.
SEQ_BURST_COUNT_WIDTH	The burst count width for the sequencer.
	continued







Parameter Name	Description
VCALIB_COUNT_WIDTH	The width of a counter that the sequencer uses.
DOUBLE_MEM_DQ_WIDTH	
HALF_AFI_DATA_WIDTH	
CALIB_REG_WIDTH	The width of the calibration status register.
NUM_AFI_RESET	The number of AFI resets to generate.

Note:

For information about the AFI signals, refer to AFI 3.0 Specification in this chapter.

Related Information

AFI 3.0 Specification on page 35

1.11. PHY-to-Controller Interfaces

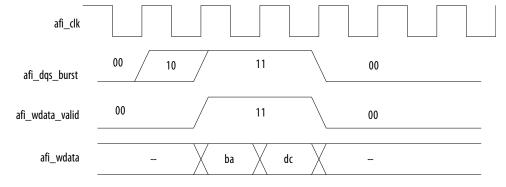
Various modules connect to UniPHY through specific ports.

The AFI standardizes and simplifies the interface between controller and PHY for all Intel memory designs, thus allowing you to easily interchange your own controller code with Intel's high-performance controllers. The AFI PHY interface includes an administration block that configures the memory for calibration and performs necessary accesses to mode registers that configure the memory as required.

For half-rate designs, the address and command signals in the UniPHY are asserted for one mem_clk cycle (1T addressing), such that there are two input bits per address and command pin in half-rate designs. If you require a more conservative 2T addressing (where signals are asserted for two mem_clk cycles), drive both input bits (of the address and command signal) identically in half-rate designs.

The following figure shows the half-rate write operation.

Figure 13. Half-Rate Write with Word-Aligned Data

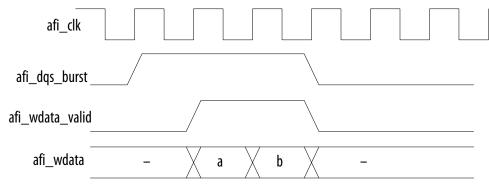


The following figure shows a full-rate write.





Figure 14. Full-Rate Write



For quarter-rate designs, the address and command signals in the UniPHY are asserted for one mem_clk cycle (1T addressing), such that there are four input bits per address and command pin in quarter-rate designs. If you require a more conservative 2T addressing (where signals are asserted for two mem_clk cycles), drive either the two lower input bits or the two upper input bits (of the address and command signal) identically.

After calibration is completed, the sequencer sends the write latency in number of clock cycles to the controller.

The AFI has the following conventions:

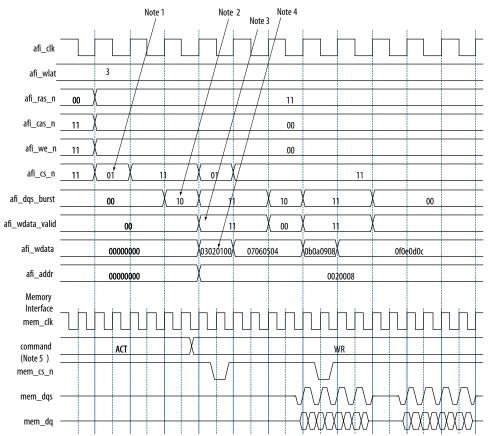
- With the AFI, high and low signals are combined in one signal, so for a single chip select (afi_cs_n) interface, afi_cs_n[1:0], location 0 appears on the memory bus on one mem_clk cycle and location 1 on the next mem_clk cycle.
 - Note: This convention is maintained for all signals so for an 8 bit memory interface, the write data (afi_wdata) signal is afi_wdata[31:0], where the first data on the DQ pins is afi_wdata[7:0], then afi wdata[15:8], then afi wdata[23:16], then afi wdata[31:24].
- Spaced reads and writes have the following definitions:
 - Spaced writes—write commands separated by a gap of one controller clock (afi_clk) cycle.
 - Spaced reads—read commands separated by a gap of one controller clock (afi_clk) cycle.

The following figures show writes and reads, where the IP core writes data to and reads from the same address. In each example, afi_rdata and afi_wdata are aligned with controller clock (afi_clk) cycles. All the data in the bit vector is valid at once. These figures assume the following general points:

- The burst length is four.
- An 8-bit interface with one chip select.
- The data for one controller clock (afi_clk) cycle represents data for two memory clock (mem_clk) cycles (half-rate interface).







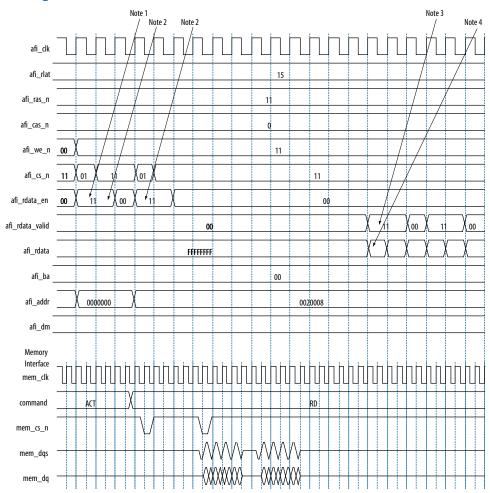
Notes to Figure:

- 1. To show the even alignment of afi_cs_n, expand the signal (this convention applies for all other signals).
- 2. The afi_dqs_burst must go high one memory clock cycle before afi_wdata_valid. Compare with the word-unaligned case.
- 3. The afi_wdata_valid is asserted afi_wlat + 1 controller clock (afi_clk) cycles after chip select (afi_cs_n) is asserted. The afi_wlat indicates the required write latency in the system. The value is determined during calibration and is dependant upon the relative delays in the address and command path and the write datapath in both the PHY and the external DDR SDRAM subsystem. The controller must drive afi_cs_n and then wait afi_wlat (two in this example) afi clks before driving afi wdata valid.
- 4. Observe the ordering of write data (afi_wdata). Compare this to data on the mem dq signal.
- 5. In all waveforms a command record is added that combines the memory pins ras_n, cas_n and we_n into the current command that is issued. This command is registered by the memory when chip select (mem_cs_n) is low. The important commands in the presented waveforms are WR= write, ACT = activate.





Figure 16. Word-Aligned Reads



Notes to Figure:

- For AFI, afi_rdata_en is required to be asserted one memory clock cycle before chip select (afi_cs_n) is asserted. In the half-rate afi_clk domain, this requirement manifests as the controller driving 11 (as opposed to the 01) on afi rdata en.
- 2. AFI requires that afi_rdata_en is driven for the duration of the read. In this example, it is driven to 11 for two half-rate afi_clks, which equates to driving to 1, for the four memory clock cycles of this four-beat burst.
- 3. The afi_rdata_valid returns 15 (afi_rlat) controller clock (afi_clk) cycles after afi_rdata_en is asserted. Returned is when the afi_rdata_valid signal is observed at the output of a register within the controller. A controller can use the afi_rlat value to determine when to register to returned data, but this is unnecessary as the afi_rdata_valid is provided for the controller to use as an enable when registering read data.
- 4. Observe the alignment of returned read data with respect to data on the bus.



Related Information

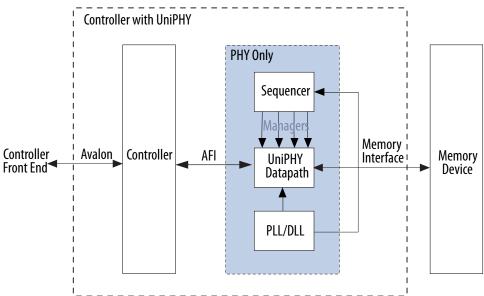
- AFI 3.0 Specification on page 35
- Timing Diagrams for UniPHY IP on page 236

1.12. Using a Custom Controller

By default, the UniPHY-based external memory interface IP cores are delivered with both the PHY and the memory controller integrated, as depicted in the following figure.

If you want to use your own custom controller with the UniPHY PHY, check the **Generate PHY only** box on the **PHY Settings** tab of the parameter editor and generate the IP. The resulting top-level IP consists of only the sequencer, UniPHY datapath, and PLL/DLL — the shaded area in the figure below.

Figure 17. Memory Controller with UniPHY



The AFI interface is exposed at the top-level of the generated IP core; you can connect the AFI interface to your custom controller.

When you enable **Generate PHY only**, the generated example designs include the memory controller appropriately instantiated to mediate read/write commands from the traffic generator to the PHY-only IP.

For information on the AFI protocol, refer to the AFI 3.0 Specification, in this chapter. For information on the example designs, refer to Chapter 9, Example Designs, in this volume.

Related Information

- AFI 3.0 Specification on page 35
- Traffic Generator and BIST Engine on page 210



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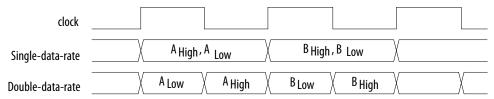
1.13. AFI 3.0 Specification

The Altera PHY interface (AFI) 3.0 defines communication between the controller and physical layer (PHY) in the external memory interface IP.

The AFI is a single-data-rate interface, meaning that data is transferred on the rising edge of each clock cycle. Most memory interfaces, however, operate at double-data-rate, transferring data on both the rising and falling edges of the clock signal. If the AFI interface is to directly control a double-data-rate signal, two single-data-rate bits must be transmitted on each clock cycle; the PHY then sends out one bit on the rising edge of the clock and one bit on the falling edge.

The AFI convention is to send the low part of the data first and the high part second, as shown in the following figure.

Figure 18. Single Versus Double Data Rate Transfer



1.13.1. Bus Width and AFI Ratio

In cases where the AFI clock frequency is one-half or one-quarter of the memory clock frequency, the AFI data must be twice or four times as wide, respectively, as the corresponding memory data. The ratio between AFI clock and memory clock frequencies is referred to as the AFI ratio. (A half-rate AFI interface has an AFI ratio of 2, while a quarter-rate interface has an AFI ratio of 4.)

In general, the width of the AFI signal depends on the following three factors:

- The size of the equivalent signal on the memory interface. For example, if a[15:0] is a DDR3 address input and the AFI clock runs at the same speed as the memory interface, the equivalent afi addr bus will be 16-bits wide.
- The data rate of the equivalent signal on the memory interface. For example, if d[7:0] is a double-data-rate QDR II input data bus and the AFI clock runs at the same speed as the memory interface, the equivalent afi_write_data bus will be 16-bits wide.
- The AFI ratio. For example, if cs_n is a single-bit DDR3 chip select input and the AFI clock runs at half the speed of the memory interface, the equivalent afi_cs_n bus will be 2-bits wide.

The following formula summarizes the three factors described above:

```
AFI_width = memory_width * signal_rate * AFI_RATE_RATIO
```

Note:

The above formula is a general rule, but not all signals obey it. For definite signal-size information, refer to the specific table.



1.13.2. AFI Parameters

The following tables list Altera PHY interface (AFI) parameters for AFI 3.0.

The parameters described in the following tables affect the width of AFI signal buses. Parameters prefixed by MEM_IF_ refer to the signal size at the interface between the PHY and memory device.

Table 6. Ratio Parameters

Parameter Name	Description
AFI_RATE_RATIO	The ratio between the AFI clock frequency and the memory clock frequency. For full-rate interfaces this value is 1, for half-rate interfaces the value is 2, and for quarter-rate interfaces the value is 4.
DATA_RATE_RATIO	The number of data bits transmitted per clock cycle. For single-date rate protocols this value is 1, and for double-data rate protocols this value is 2.
ADDR_RATE_RATIO	The number of address bits transmitted per clock cycle. For single-date rate address protocols this value is 1, and for double-data rate address protocols this value is 2.

Table 7. Memory Interface Parameters

Parameter Name	Description
MEM_IF_ADDR_WIDTH	The width of the address bus on the memory device(s).
MEM_IF_BANKADDR_WIDTH	The width of the bank address bus on the interface to the memory device(s). Typically, the $\log 2$ of the number of banks.
MEM_IF_CS_WIDTH	The number of chip selects on the interface to the memory device(s).
MEM_IF_WRITE_DQS_WIDTH	The number of DQS (or write clock) signals on the write interface. For example, the number of DQS groups.
MEM_IF_CLK_PAIR_COUNT	The number of CK/CK# pairs.
MEM_IF_DQ_WIDTH	The number of DQ signals on the interface to the memory device(s). For single-ended interfaces such as QDR II, this value is the number of D or Q signals.
MEM_IF_DM_WIDTH	The number of data mask pins on the interface to the memory device(s).
MEM_IF_READ_DQS_WIDTH	The number of DQS signals on the read interface. For example, the number of DQS groups.

Table 8. Derived AFI Parameters

Parameter Name	Derivation Equation
AFI_ADDR_WIDTH	MEM_IF_ADDR_WIDTH * AFI_RATE_RATIO * ADDR_RATE_RATIO
AFI_BANKADDR_WIDTH	MEM_IF_BANKADDR_WIDTH * AFI_RATE_RATIO * ADDR_RATE_RATIO
AFI_CONTROL_WIDTH	AFI_RATE_RATIO * ADDR_RATE_RATIO
AFI_CS_WIDTH	MEM_IF_CS_WIDTH * AFI_RATE_RATIO
AFI_DM_WIDTH	MEM_IF_DM_WIDTH * AFI_RATE_RATIO * DATA_RATE_RATIO
AFI_DQ_WIDTH	MEM_IF_DQ_WIDTH * AFI_RATE_RATIO * DATA_RATE_RATIO
AFI_WRITE_DQS_WIDTH	MEM_IF_WRITE_DQS_WIDTH * AFI_RATE_RATIO
AFI_LAT_WIDTH	6
	continued





Parameter Name	Derivation Equation
AFI_RLAT_WIDTH	AFI_LAT_WIDTH
AFI_WLAT_WIDTH	AFI_LAT_WIDTH * MEM_IF_WRITE_DQS_WIDTH
AFI_CLK_PAIR_COUNT	MEM_IF_CLK_PAIR_COUNT
AFI_WRANK_WIDTH	Number of ranks * MEM_IF_WRITE_DQS_WIDTH *AFI_RATE_RATIO
AFI_RRANK_WIDTH	Number of ranks * MEM_IF_READ_DQS_WIDTH *AFI_RATE_RATIO

1.13.3. AFI Signals

The following tables list Altera PHY interface (AFI) signals grouped according to their functions.

In each table, the **Direction** column denotes the direction of the signal relative to the PHY. For example, a signal defined as an output passes out of the PHY to the controller. The AFI specification does not include any bidirectional signals.

Note: Not all signals listed apply to every device family or every memory protocol.

1.13.3.1. AFI Clock and Reset Signals

The AFI interface provides up to two clock signals and an asynchronous reset signal.

Table 9. Clock and Reset Signals

Signal Name	Direction	Width	Description
afi_clk	Output	1	Clock with which all data exchanged on the AFI bus is synchronized. In general, this clock is referred to as full-rate, half-rate, or quarter-rate, depending on the ratio between the frequency of this clock and the frequency of the memory device clock.
afi_half_clk	Output	1	Clock signal that runs at half the speed of the afi_clk. The controller uses this signal when the half-rate bridge feature is in use. This signal is optional.
afi_reset_n	Output	1	Asynchronous reset output signal. You must synchronize this signal to the clock domain in which you use it.

1.13.3.2. AFI Address and Command Signals

The address and command signals for AFI 3.0 encode read/write/configuration commands to send to the memory device. The address and command signals are single-data rate signals.

Table 10. Address and Command Signals

Signal Name	Direction	Width	Description
afi_ba	Input	AFI_BANKADDR_WIDTH	Bank address.
afi_cke	Input	AFI_CLK_EN_WIDTH	Clock enable.
			continued



Signal Name	Direction	Width	Description
afi_cs_n	Input	AFI_CS_WIDTH	Chip select signal. (The number of chip selects may not match the number of ranks; for example, RDIMMs and LRDIMMs require a minimum of 2 chip select signals for both single-rank and dual-rank configurations. Consult your memory device data sheet for information about chip select signal width.)
afi_ras_n	Input	AFI_CONTROL_WIDTH	RAS# (for DDR2 and DDR3 memory devices.)
afi_we_n	Input	AFI_CONTROL_WIDTH	WE# (for DDR2, DDR3, and RLDRAM II memory devices.)
afi_cas_n	Input	AFI_CONTROL_WIDTH	CAS# (for DDR2 and DDR3 memory devices.)
afi_ref_n	Input	AFI_CONTROL_WIDTH	REF# (for RLDRAM II memory devices.)
afi_rst_n	Input	AFI_CONTROL_WIDTH	RESET# (for DDR3 memory devices.)
afi_odt	Input	AFI_CLK_EN_WIDTH	On-die termination signal for DDR2 and DDR3 memory devices. (Do not confuse this memory device signal with the FPGA's internal onchip termination signal.)
afi_mem_clk_disable	Input	AFI_CLK_PAIR_COUNT	When this signal is asserted, mem_clk and mem_clk_n are disabled. This signal is used in low-power mode.
afi_wps_n	Output	AFI_CS_WIDTH	WPS (for QDR II/II+ memory devices.)
afi_rps_n	Output	AFI_CS_WIDTH	RPS (for QDR II/II+ memory devices.)

1.13.3.3. AFI Write Data Signals

Write Data Signals for AFI 3.0 control the data, data mask, and strobe signals passed to the memory device during write operations.

Table 11. Write Data Signals

Signal Name	Direction	Width	Description
afi_dqs_burst	Input	AFI_WRITE_DQS_WIDTH	Controls the enable on the strobe (DQS) pins for DDR2, DDR3, and LPDDR2 memory devices. When this signal is asserted, mem_dqs and mem_dqsn are driven.
			continued





Signal Name	Direction	Width	Description
			This signal must be asserted before afi_ wdata_valid to implement the write preamble, and must be driven for the correct duration to generate a correctly timed mem_dqs signal.
afi_wdata_valid	Input	AFI_WRITE_DQS_WIDTH	Write data valid signal. This signal controls the output enable on the data and data mask pins.
afi_wdata	Input	AFI_DQ_WIDTH	Write data signal to send to the memory device at double-data rate. This signal controls the PHY's mem_dq output.
afi_dm	Input	AFI_DM_WIDTH	Data mask. This signal controls the PHY's mem_dm signal for DDR2, DDR3, LPDDR2 and RLDRAM II memory devices.)
afi_bws_n	Input	AFI_DM_WIDTH	Data mask. This signal controls the PHY's mem_bws_n signal for QDR II/II+ memory devices.
afi_wrank	Input	AFI_WRANK_WIDTH	Shadow register signal. Signal indicating the rank to which the controller is writing, so that the PHY can switch to the appropriate setting. Signal timing is identical to afi_dqs_burst; that is, afi_ wrank must be asserted at the same time as afi_dqs_burst, and must be of the same duration.

1.13.3.4. AFI Read Data Signals

Read Data Signals for AFI 3.0 control the data sent from the memory device during read operations.

Table 12. Read Data Signals

Signal Name	Direction	Width	Description
afi_rdata_en	Input	AFI_RATE_RATIO	Read data enable. Indicates that the memory controller is currently performing a read operation. This signal is held high only for cycles of relevant data (read data masking). If this signal is aligned to even clock cycles, it is possible to use 1-bit even in half-rate mode (i.e., AFI_RATE=2).
afi_rdata_en_full	Input	AFI_RATE_RATIO	Read data enable full. Indicates that the memory controller is currently performing a read operation. This signal is held high for the entire read burst. If this signal is aligned to even clock cycles, it is possible to use 1-bit even in half-rate mode (i.e., AFI_RATE=2).
continued			





Signal Name	Direction	Width	Description
afi_rdata	Output	AFI_DQ_WIDTH	Read data from the memory device. This data is considered valid only when afi_rdata_valid is asserted by the PHY.
afi_rdata_valid	Output	AFI_RATE_RATIO	Read data valid. When asserted, this signal indicates that the afi_rdata bus is valid. If this signal is aligned to even clock cycles, it is possible to use 1-bit even in half-rate mode (i.e., AFI_RATE=2).
afi_rrank	Input	AFI_RRANK_WIDTH	Shadow register signal. Signal indicating the rank from which the controller is reading, so that the PHY can switch to the appropriate setting. Must be asserted at the same time as afi_rdata_en when issuing a read command, and once asserted, must remain unchanged until the controller issues a new read command to another rank.

1.13.3.5. AFI Calibration Status Signals

The PHY instantiates a sequencer which calibrates the memory interface with the memory device and some internal components such as read FIFOs and valid FIFOs. The sequencer reports the results of the calibration process to the controller through the Calibration Status Signals in the AFI interface.

Table 13. Calibration Status Signals

Signal Name	Direction	Width	Description
afi_cal_success	Output	1	Asserted to indicate that calibration has completed successfully.
afi_cal_fail	Output	1	Asserted to indicate that calibration has failed.
afi_cal_req	Input	1	Effectively a synchronous reset for the sequencer. When this signal is asserted, the sequencer returns to the reset state; when this signal is released, a new calibration sequence begins.
afi_wlat	Output	AFI_WLAT_WIDTH	The required write latency in afi_clk cycles, between address/command and write data being issued at the PHY/ controller interface. The afi_wlat value can be different for different groups; each group's write latency can range from 0 to 63. If write latency is the same for all groups, only the lowest 6 bits are required.
afi_rlat	Output	AFI_RLAT_WIDTH	The required read latency in afi_clk cycles between address/command and read data being returned to the PHY/controller interface. Values can range from 0 to 63.

Note to Table:

1. The afi_rlat signal is not supported for PHY-only designs. Instead, you can sample the afi_rdata_valid signal to determine when valid read data is available.





1.13.3.6. AFI Tracking Management Signals

When tracking management is enabled, the sequencer can take control over the AFI 3.0 interface at given intervals, and issue commands to the memory device to track the internal DQS Enable signal alignment to the DQS signal returning from the memory device. The tracking management portion of the AFI 3.0 interface provides a means for the sequencer and the controller to exchange handshake signals.

Table 14. Tracking Management Signals

Signal Name	Direction	Width	Description
afi_ctl_refresh_done	Input	MEM_IF_CS_WIDTH	Handshaking signal from controller to tracking manager, indicating that a refresh has occurred and waiting for a response.
afi_seq_busy	Output	MEM_IF_CS_WIDTH	Handshaking signal from sequencer to controller, indicating when DQS tracking is in progress.
afi_ctl_long_idle	Input	MEM_IF_CS_WIDTH	Handshaking signal from controller to tracking manager, indicating that it has exited low power state without a periodic refresh, and waiting for response.

1.14. Register Maps

The following table lists the overall register mapping for the DDR2, DDR3, and LPDDR2 SDRAM Controllers with UniPHY.

Note:

Addresses shown in the table are 32-bit word addresses. If a byte-addressed master such as a Nios II processor accesses the CSR, it is necessary to multiply the addresses by four.

Table 15. Register Map

Address	Description
UniPHY Registo	er Map
0x001	Reserved.
0x004	UniPHY status register 0.
0x005	UniPHY status register 1.
0x006	UniPHY status register 2.
0x007	UniPHY memory initialization parameters register 0.
Controller Regi	ster Map
0x100	Reserved.
0x110	Controller status and configuration register.
0x120	Memory address size register 0.
0x121	Memory address size register 1.
0x122	Memory address size register 2.
0x123	Memory timing parameters register 0.
	continued





Address	Description
0x124	Memory timing parameters register 1.
0x125	Memory timing parameters register 2.
0x126	Memory timing parameters register 3.
0x130	ECC control register.
0x131	ECC status register.
0x132	ECC error address register.

1.14.1. UniPHY Register Map

The UniPHY register map allows you to control the memory components' mode register settings. The following table lists the register map for UniPHY.

Note:

Addresses shown in the table are 32-bit word addresses. If a byte-addressed master such as a Nios II processor accesses the CSR, it is necessary to multiply the addresses by four.

Table 16. UniPHY Register Map

Address	Bit	Name	Default	Access	Description
0x001	15:0	Reserved.	0	_	Reserved for future use.
	31:16	Reserved.	0	_	Reserved for future use.
0x002	15:0	Reserved.	0	_	Reserved for future use.
	31:16	Reserved.	0	_	Reserved for future use.
0x004	0	SOFT_RESET	_	Write only	Initiate a soft reset of the interface. This bit is automatically deasserted after reset.
	23:1	Reserved.	0	_	Reserved for future use.
	24	AFI_CAL_SUCCESS	_	Read only	Reports the value of the UniPHY afi_cal_success. Writing to this bit has no effect.
	25	AFI_CAL_FAIL	_	Read only	Reports the value of the UniPHY afi_cal_fail. Writing to this bit has no effect.
	26	PLL_LOCKED	_	Read only	Reports the PLL lock status.
	31:27	Reserved.	0	_	Reserved for future use.
0x005	7:0	Reserved.	0	_	Reserved for future use.
	15:8	Reserved.	0	_	Reserved for future use.
	23:16	Reserved.	0	_	Reserved for future use.
	31:24	Reserved.	0	_	Reserved for future use.
0x006	7:0	INIT_FAILING_STAGE	_	Read only	Initial failing error stage of calibration. Only applicable if AFI_CAL_FAIL=1. 0: None 1: Read Calibration - VFIFO 2: Write Calibration - Write Leveling
					continued





1	15:8				3: Read Calibration - LFIFO Calibration 4: Write Calibration - Write Deskew 5: Unused 6: Refresh 7: Calibration Skipped
	15:8				8: Calibration Skipped 8: Calibration Aborted 9: Read Calibration - VFIFO After Writes
		INIT_FAILING_SUBSTA GE		Read only	Initial failing error substage of calibration. Only applicable if AFI_CAL_FAIL=1. If INIT_FAILING_STAGE = 1 or 9: 1: Read Calibration - Guaranteed read failure 2: Read Calibration - No working DQSen phase found 3: Read Calibration - Per-bit read deskew failure If INIT_FAILING_STAGE = 2: 1: Write Calibration - No first working write leveling phase found 2: Write Calibration - No last working write leveling phase found 3: Write Calibration - Write leveling copy failure If INIT_FAILING_STAGE = other, substages do not apply.
2	23:16	INIT_FAILING_GROUP	_	Read only	Initial failing error group of calibration. Only applicable if AFI_CAL_FAIL=1. Returns failing DQ pin instead of failing group, if: INIT_FAILING_STAGE=1 and INIT_FAILING_SUBSTAGE=3. Or INIT_FAILING_STAGE=4 and INIT_FAILING_SUBSTAGE=1.
3	31:24	Reserved.	0	_	Reserved for future use.
0x007 3	31:0	DQS_DETECT	_	Read only	Identifies if DQS edges have been identified for each of the groups. Each bit corresponds to one DQS group.
0x008(DD 1 R2)	1:0	RTT_NOM	_	Read only	Rtt (nominal) setting of the DDR2 Extended Mode Register used during memory initialization.
3	31:2	Reserved.	0	_	Reserved for future use.
0x008(DD 2 R3)	2:0	RTT_NOM	_		Rtt (nominal) setting of the DDR3 MR1 mode register used during memory initialization.
4	4:3	Reserved.	0		Reserved for future use.
6	6:5	ODS	_		Output driver impedence control setting of the DDR3 MR1 mode register used during memory initialization.





Address	Bit	Name	Default	Access	Description
	8:7	Reserved.	0		Reserved for future use.
	10:9	RTT_WR	_		Rtt (writes) setting of the DDR3 MR2 mode register used during memory initialization.
	31:11	Reserved.	0		Reserved for future use.
0x008(LP DDR2)	3:0	DS			Driver impedence control for MR3 during initialization.
	31:4	Reserved.			Reserved for future use.

1.14.2. Controller Register Map

The controller register map allows you to control the memory controller settings.

Note: Dynamic reconfiguration is not currently supported.

For information on the controller register map, refer to *Controller Register Map*, in the *Functional Description—HPC II* chapter.

Related Information

- Soft Controller Register Map on page 183
- Hard Controller Register Map on page 187

1.15. Ping Pong PHY

Ping Pong PHY is an implementation of UniPHY that allows two memory interfaces to share address and command buses through time multiplexing. Compared to having two independent interfaces, Ping Pong PHY uses fewer pins and less logic, while maintaining equivalent throughput.

The Ping Pong PHY supports only quarter-rate configurations of the DDR3 protocol on Arria V GZ and Stratix V devices.

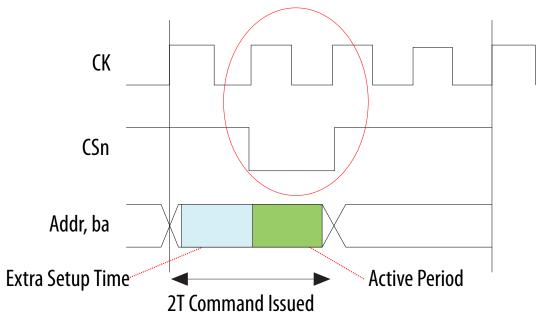
1.15.1. Ping Pong PHY Feature Description

In conventional UniPHY, the address and command buses of a DDR3 quarter-rate interface use 2T time—meaning that they are issued for two full-rate clock cycles, as illustrated below.



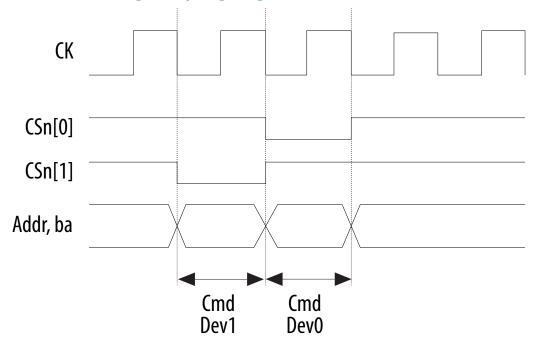


Figure 19. 2T Command Timing



With the Ping Pong PHY, address and command signals from two independent controllers are multiplexed onto shared buses by delaying one of the controller outputs by one full-rate clock cycle. The result is 1T timing, with a new command being issued on each full-rate clock cycle. The following figure shows address and command timing for the Ping Pong PHY.

Figure 20. 1T Command Timing Use by Ping Pong PHY



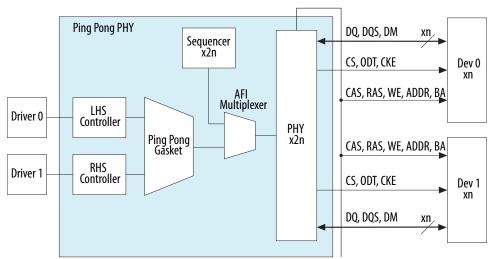




1.15.2. Ping Pong PHY Architecture

The following figure shows a top-level block diagram of the Ping Pong PHY. Functionally, the IP looks like two independent memory interfaces. The two controller blocks are referred to as right-hand side (RHS) and left-hand side (LHS), respectively. A gasket block located between the controllers and the PHY merges the AFI signals. The PHY is double data width and supports both memory devices. The sequencer is the same as with regular UniPHY, and calibrates the entire double-width PHY.

Figure 21. Ping Pong PHY Architecture

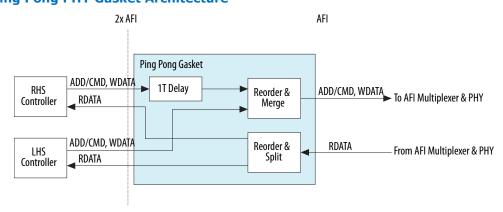


1.15.2.1. Ping Pong Gasket

The gasket delays and remaps quarter-rate signals so that they are correctly time-multiplexed at the full-rate PHY output. The gasket also merges address and command buses ahead of the PHY.

AFI interfaces at the input and output of the gasket provide compatibility with the PHY and with memory controllers.

Figure 22. Ping Pong PHY Gasket Architecture



The following table shows how the gasket processes key AFI signals.





Table 17. Key AFI Signals Processed by Ping Pong PHY Gasket

Signal	Direction(Width multiplier)	Description	Gasket Conversions
cas, ras, we, addr, ba	Controller (1x) to PHY (1x)	Address and command buses shared between devices.	Delay RHS by 1T; merge.
cs, odt, cke	Controller (1x) to PHY (2x)	Chip select, on-die termination, and clock enable, one per device.	Delay RHS by 1T; reorder, merge.
wdata, wdata_valid, dqs_burst, dm	Controller (1x) to PHY (2x)	Write datapath signals, one per device.	Delay RHS by 1T; reorder, merge.
rdata_en_rd, rdata_en_rd_full	Controller (1x) to PHY (2x)	Read datapath enable signals indicating controller performing a read operation, one per device.	Delay RHS by 1T.
rdata_rdata_valid	PHY (2x) to Controller (1x)	Read data, one per device.	Reorder; split.
cal_fail, cal_success, seq_busy, wlat, rlat	PHY (1x) to Controller (1x)	Calibration result, one per device.	Pass through.
rst_n, mem_clk_disable, ctl_refresh_done, ctl_long_idle	Controller (1x) to PHY (1x)	Reset and DQS tracking signals, one per PHY.	AND (&)
cal_req, init_req	Controller (1x) to PHY (1x)	Controller to sequencer requests.	OR ()
wrank, rrank	Controller (1x) to PHY (2x)	Shadow register support.	Delay RHS by 1T; reorder; merge.

1.15.2.2. Ping Pong PHY Calibration

The sequencer treats the Ping Pong PHY as a regular interface of double the width. For example, in the case of two x16 devices, the sequencer calibrates both devices together as a x32 interface. The sequencer chip select signal fans out to both devices so that they are treated as a single interface. The VFIFO calibration process is unchanged. For LFIFO calibration, the LFIFO buffer is duplicated for each interface and the worst-case read datapath delay of both interfaces is used.

1.15.3. Ping Pong PHY Operation

To use the Ping Pong PHY, proceed as described below.

- 1. Configure a single memory interface according to your requirements.
- 2. Select the **Enable Ping Pong PHY** option in the **Advanced PHY Options** section of the **PHY Settings** tab in the DDR3 parameter editor.

The Quartus Prime software then replicates the interface, resulting in two memory controllers and a shared PHY, with the gasket block inserted between the controllers and PHY. The system makes the necessary modifications to top-level component connections, as well as the PHY read and write datapaths, and the AFI mux, without further input from you.

1.16. Efficiency Monitor and Protocol Checker

The Efficiency Monitor and Protocol Checker allows measurement of traffic efficiency on the Avalon-MM bus between the controller and user logic, measures read latencies, and checks the legality of Avalon commands passed from the master. The Efficiency



Monitor and Protocol Checker is available with the DDR2, DDR3, and LPDDR2 SDRAM controllers with UniPHY Intel FPGA IP and the RLDRAM II Controller with UniPHY Intel FPGA IP. The Efficiency Monitor and Protocol Checker is is not available for QDR II and QDR II+ SRAM, or for the MAX 10 device family, or for Arria V or Cyclone V designs using the Hard Memory Controller.

1.16.1. Efficiency Monitor

The Efficiency Monitor reports read and write throughput on the controller input, by counting command transfers and wait times, and making that information available to the External Memory Interface Toolkit via an Avalon slave port. This information may be useful to you when experimenting with advanced controller settings, such as command look ahead depth and burst merging.

1.16.2. Protocol Checker

The Protocol Checker checks the legality of commands on the controller's input interface against the Intel Avalon interface specification, and sets a flag in a register on an Avalon slave port if an illegal command is detected.

1.16.3. Read Latency Counter

The Read Latency Counter measures the minimum and maximum wait times for read commands to be serviced on the Avalon bus. Each read command is time-stamped and placed into a FIFO buffer upon arrival, and latency is determined by comparing that timestamp to the current time when the first beat of the returned read data is provided back to the master.

1.16.4. Using the Efficiency Monitor and Protocol Checker

To include the Efficiency Monitor and Protocol Checker when you generate your IP core, proceed as described below.

- 1. On the **Diagnostics** tab in the parameter editor, turn on **Enable the Efficiency Monitor and Protocol Checker on the Controller Avalon Interface**.
- 2. To see the results of the data compiled by the Efficiency Monitor and Protocol Checker, use the External Memory Interface Toolkit.

For information on the External Memory Interface Toolkit, refer to *External Memory Interface Debug Toolkit*, in section 2 of this volume. For information about the Avalon interface, refer to *Avalon Interface Specifications*.

Related Information

- Avalon Interface Specifications
- External Memory Interface Debug Toolkit on page 272





1.16.5. Avalon CSR Slave and JTAG Memory Map

The following table lists the memory map of registers inside the Efficiency Monitor and Protocol Checker. This information is only of interest if you want to communicate directly with the Efficiency Monitor and Protocol Checker without using the External Memory Interface Toolkit. This CSR map is not part of the UniPHY CSR map.

Prior to reading the data in the CSR, you must issue a read command to address 0x01 to take a snapshot of the current data.

Table 18. Avaion CSR Slave and JTAG Memory Map

Address	Bit	Name	Default	Access	Description
0x01	31:0	Reserved	0	Read Only	Used internally by EMIF Toolkit to identify Efficiency Monitor type. This address must be read prior to reading the other CSR contents.
0x02	31:0	Reserved	0	_	Used internally by EMIF Toolkit to identify Efficiency Monitor version.
0x08	0	Efficiency Monitor reset	_	Write only	Write a 0 to reset.
	7:1	Reserved	_	_	Reserved for future use.
	8	Protocol Checker reset	_	Write only	Write a 0 to reset.
	15:9	Reserved	_	_	Reserved for future use.
	16	Start/stop Efficiency Monitor	_	Read/Write	Starting and stopping statistics gathering.
	23:17	Reserved	_	_	Reserved for future use.
	31:24	Efficiency Monitor status	_	Read Only	bit 0: Efficiency Monitor stopped bit 1: Waiting for start of pattern bit 2: Running bit 3: Counter saturation
0x10	15:0	Efficiency Monitor address width	_	Read Only	Address width of the Efficiency Monitor.
	31:16	Efficiency Monitor data width	_	Read Only	Data Width of the Efficiency Monitor.
0x11	15:0	Efficiency Monitor byte enable	_	Read Only	Byte enable width of the Efficiency Monitor.
	31:16	Efficiency Monitor burst count width	_	Read Only	Burst count width of the Efficiency Monitor.
0x14	31:0	Cycle counter	_	Read Only	Clock cycle counter for the Efficiency Monitor. Lists the number of clock cycles elapsed before the Efficiency Monitor stopped.
0x18	31:0	Transfer counter	_	Read Only	Counts any read or write data transfer cycle.
0x1C	31:0	Write counter	_	Read Only	Counts write requests, including those during bursts.
0x20	31:0	Read counter	_	Read Only	Counts read requests.
0x24	31:0	Readtotal counter	_	Read Only	Counts read requests (total burst requests).
	•	·			continued



Address	Bit	Name	Default	Access	Description
0x28	31:0	NTC waitrequest counter	_	Read Only	Counts Non Transfer Cycles (NTC) due to slave wait request high.
0x2C	31:0	NTC noreaddatavalid counter	_	Read Only	Counts Non Transfer Cycles (NTC) due to slave not having read data.
0x30	31:0	NTC master write idle counter	_	Read Only	Counts Non Transfer Cycles (NTC) due to master not issuing command, or pause in write burst.
0x34	31:0	NTC master idle counter	_	Read Only	Counts Non Transfer Cycles (NTC) due to master not issuing command anytime.
0x40	31:0	Read latency min	_	Read Only	The lowest read latency value.
0x44	31:0	Read latency max	_	Read Only	The highest read latency value.
0x48	31:0	Read latency total [31:0]	_	Read Only	The lower 32 bits of the total read latency.
0x49	31:0	Read latency total [63:32]	_	Read Only	The upper 32 bits of the total read latency.
0x50	7:0	Illegal command	_	Read Only	Bits used to indicate which illegal command has occurred. Each bit represents a unique error.
	31:8	Reserved	_	_	Reserved for future use.

1.17. UniPHY Calibration Stages

The DDR2, DDR3, and LPDDR2 SDRAM controllers with UniPHY Intel FPGA IP, the QDR II and QDR II+ SRAM Controller with UniPHY Intel FPGA IP, the RLDRAM II Controller with UniPHY Intel FPGA IP, and the RLDRAM 3 UniPHY Intel FPGA IP, go through several stages of calibration. Calibration information is useful in debugging calibration failures.

The section includes an overview of calibration, explanation of the calibration stages, and a list of generated calibration signals. The information in this section applies only to the Nios II-based sequencer used in the DDR2, DDR3, and LPDDR2 SDRAM Controllers with UniPHY versions 10.0 and later, and, optionally, in the QDR II and QDR II+ SRAM and RLDRAM II Controllers with UniPHY version 11.0 and later, and the RLDRAM 3 PHY-only IP. The information in this section applies to the Arria II GZ, Arria V, Arria V GZ, Cyclone V, Stratix III, Stratix IV, and Stratix V device families.

Note:

- 1. For QDR II and QDR II+ SRAM and RLDRAM II Controllers with UniPHY version 11.0 and later, you have the option to select either the RTL-based sequencer or the Nios II-based sequencer. Generally, choose the RTL-based sequencer when area is the major consideration, and choose the Nios II-based sequencer when performance is the major consideration.
- 2. For RLDRAM 3, write leveling is not performed. The sequencer does not attempt to optimize margin for the tCKDK timing requirement.

1.17.1. Calibration Overview

Calibration configures the memory interface (PHY and I/Os) so that data can pass reliably to and from memory.



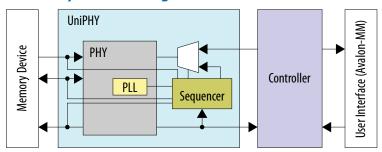
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The sequencer illustrated in the figure below calibrates the PHY and the I/Os. To correctly transmit data between a memory device and the FPGA at high speed, the data must be center-aligned with the data clock.

Calibration also determines the delay settings needed to center-align the various data signals with respect to their clocks. I/O delay chains implement the required delays in accordance with the computed alignments. The Nios II-based sequencer performs two major tasks: FIFO buffer calibration and I/O calibration. FIFO buffer calibration adjusts FIFO lengths and I/O calibration adjusts any delay chain and phase settings to centeralign data signals with respect to clock signals for both reads and writes. When the calibration process completes, the sequencer shuts off and passes control to the memory controller.

Figure 23. Sequencer in Memory Interface Logic



1.17.2. Calibration Stages

The calibration process begins when the PHY reset signal deasserts and the PLL and DLL lock.

The following stages of calibration take place:

- 1. Read calibration part one—DQS enable calibration (only for DDR2 and DDR3 SDRAM Controllers with UniPHY) and DQ/DQS centering
- 2. Write calibration part one-Leveling
- 3. Write calibration part two-DQ/DQS centering
- 4. Read calibration part two—Read latency minimization

Note:

For multirank calibration, the sequencer transmits every read and write command to each rank in sequence. Each read and write test is successful only if all ranks pass the test. The sequencer calibrates to the intersection of all ranks.

The calibration process assumes the following conditions; if either of these conditions is not true, calibration likely fails in its early stages:

- The address and command paths must be functional; calibration does not tune the address and command paths. (The Quartus Prime software fully analyzes the timing for the address and command paths, and the slack report is accurate, assuming the correct board timing parameters.)
- At least one bit per group must work before running per-bit-deskew calibration. (This assumption requires that DQ-to-DQS skews be within the recommended 20 ps.)



1.17.3. Memory Initialization

The memory is powered up according to protocol initialization specifications. All ranks power up simultaneously. Once powered, the device is ready to receive mode register load commands. This part of initialization occurs separately for each rank. The sequencer issues mode register set commands on a per-chip-select basis and initializes the memory to the user-specified settings.

1.17.4. Stage 1: Read Calibration Part One—DQS Enable Calibration and DQ/DQS Centering

Read calibration occurs in two parts. Part one is DQS enable calibration with DQ/DQS centering, which happens during stage 1 of the overall calibration process; part two is read latency minimization, which happens during stage 4 of the overall calibration process.

The objectives of DOS enable calibration and DO/DOS centering are as follows:

- To calculate when the read data is received after a read command is issued to setup the Data Valid Prediction FIFO (VFIFO) cycle
- To align the input data (DQ) with respect to the clock (DQS) to maximize the read margins (DDR2 and DDR3 only)

DQS enable calibration and DQ/DQS centering consists of the following actions:

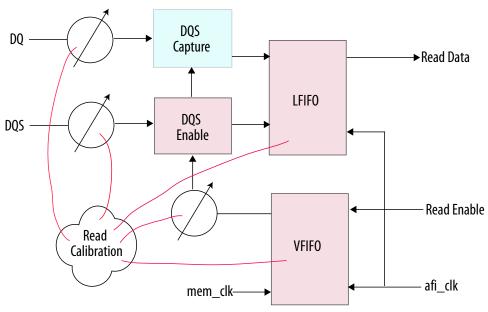
- Guaranteed Write
- DQS Enable Calibration
- DO/DOS Centering

The following figure illustrates the components in the read data path that the sequencer calibrates in this stage. (The round knobs in the figure represent configurable hardware over which the sequencer has control.)





Figure 24. Read Data Path Calibration Model

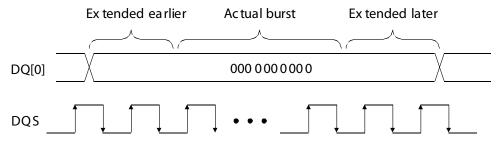


1.17.4.1. Guaranteed Write

Because initially no communication can be reliably performed with the memory device, the sequencer uses a guaranteed write mechanism to write data into the memory device. (For the QDR II protocol, guaranteed write is not necessary, a simple write mechanism is sufficient.)

The guaranteed write is a write command issued with all data pins, all address and bank pins, and all command pins (except chip select) held constant. The sequencer begins toggling DQS well before the expected latch time at memory and continues to toggle DQS well after the expected latch time at memory. DQ-to-DQS relationship is not a factor at this stage because DQ is held constant.

Figure 25. Guaranteed Write of Zeros







The guaranteed write consists of a series of back-to-back writes to alternating columns and banks. For example, for DQ[0] for the DDR3 protocol, the guaranteed write performs the following operations:

- Writes a full burst of zeros to bank 0, column 0
- Writes a full burst of zeros to bank 0, column 1
- Writes a full burst of ones to bank 3, column 0
- Writes a full burst of ones to bank 3, column 1

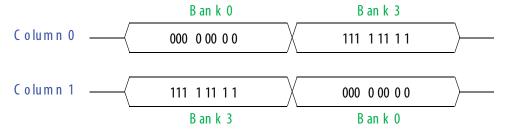
(Different protocols may use different combinations of banks and columns.)

The guaranteed write is followed by back-to-back read operations at alternating banks, effectively producing a stream of zeros followed by a stream of ones, or vice versa. The sequencer uses the zero-to-one and one-to-zero transitions in between the two bursts to identify a correct read operation, as shown in the figure below.

Although the approach described above for pin DQ[0] would work by writing the same pattern to all DQ pins, it is more effective and robust to write (and read) alternating ones and zeros to alternating DQ bits. The value of the DQ bit is still constant across the burst, and the back-to-back read mechanism works exactly as described above, except that odd DQ bits have ones instead of zeros, or vice versa.

The guaranteed write does not ensure a correct DQS-to-memory clock alignment at the memory device—DQS-to-memory clock alignment is performed later, in stage 2 of the calibration process. However, the process of guaranteed write followed by read calibration is repeated several times for different DQS-to-memory clock alignments, to ensure at least one correct alignment is found.

Figure 26. Back to Back Reads on Pin DQ[0]



1.17.4.2. DQS Enable Calibration

DQS enable calibration ensures reliable capture of the DQ signal without glitches on the DQS line. At this point LFIFO is set to its maximum value to guarantee a reliable read from read capture registers to the core. Read latency is minimized later.

Note:

- The full DQS enable calibration is applicable only for DDR2 and DDR3 protocols; QDR II and RLDRAM protocols use only the VFIFO-based cycle-level calibration, described below.
- 2. Delay and phase values used in this section are examples, for illustrative purposes. Your exact values may vary depending on device and configuration.

DQS enable calibration controls the timing of the enable signal using 3 independent controls: a cycle-based control (the VFIFO), a phase control, and a delay control. The VFIFO selects the cycle by shifting the controller-generated read data enable signal,



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rdata_en, by a number of full-rate clock cycles. The phase is controlled using the DLL, while the delays are adjusted using a sequence of individual delay taps. The resolution of the phase and delay controls varies with family and configuration, but is approximately 45° for the phase, and between 10 and 50 picoseconds for the delays.

The sequencer finds the two edges of the DQS enable window by searching the space of cycles, phases, and delays (an exhaustive search can usually be avoided by initially assuming the window is at least one phase wide). During the search, to test the current settings, the sequencer issues back-to-back reads from column 0 of bank 0 and bank 3, and column 1 of bank 0 and bank 3, as shown in the preceding figure. Two full bursts are read and compared with the reference data for each phase and delay setting.

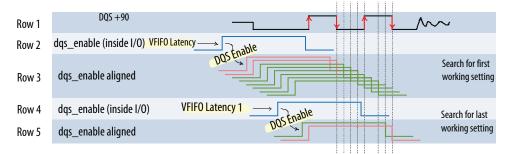
Once the sequencer identifies the two edges of the window, it center-aligns the falling edge of the DQS enable signal within the window. At this point, per-bit deskew has not yet been performed, therefore not all bits are expected to pass the read test; however, for read calibration to succeed, at least one bit per group must pass the read test.

The following figure shows the DQS and DQS enable signal relationship. The goal of DQS enable calibration is to find settings that satisfy the following conditions:

- The DQS enable signal rises before the first rising edge of DQS.
- The DQS enable signal is at one after the second-last falling edge of DQS.
- The DQS enable signal falls before the last falling edge of DQS.

The ideal position for the falling edge of the DQS enable signal is centered between the second-last and last falling edges of DQS.

Figure 27. DQS and DQS Enable Signal Relationships







The following points describe each row of the above figure:

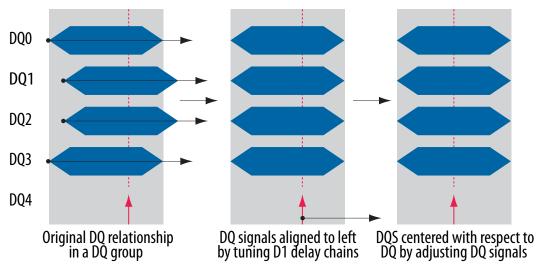
- Row 1 shows the DQS signal shifted by 90° to center-align it to the DQ data.
- Row 2 shows the raw DQS enable signal from the VFIFO.
- Row 3 shows the effect of sweeping DQS enable phases. The first two settings (shown in red) fail to properly gate the DQS signal because the enable signal turns off before the second-last falling edge of DQS. The next six settings (shown in green) gate the DQS signal successfully, with the DQS signal covering DQS from the first rising edge to the second-last falling edge.
- Row 4 shows the raw DQS enable signal from the VFIFO, increased by one clock cycle relative to Row 2.
- Row 5 shows the effect of sweeping DQS enable, beginning from the initial DQS enable of Row 4. The first setting (shown in green) successfully gates DQS, with the signal covering DQS from the first rising edge to the second-last falling edge. The second signal (shown in red), does not gate DQS successfully because the enable signal extends past the last falling edge of DQS. Any further adjustment would show the same failure.

1.17.4.3. Centering DQ/DQS

The centering DQ/DQS stage attempts to align DQ and DQS signals on reads within a group. Each DQ signal within a DQS group might be skewed and consequently arrive at the FPGA at a different time. At this point, the sequencer sweeps each DQ signal in a DQ group to align them, by adjusting DQ input delay chains (D1).

The following figure illustrates a four DQ/DQS group per-bit-deskew and centering.

Figure 28. Per-bit Deskew



To align and center DQ and DQS, the sequencer finds the right edge of DQ signals with respect to DQS by sweeping DQ signals within a DQ group to the right until a failure occurs. In the above figure, DQ0 and DQ3 fail after six taps to the right; DQ1 and DQ2 fail after 5 taps to the right. To align the DQ signals, DQ0 and DQ3 are shifted to the right by 1 tap.



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To find the center of DVW, the DQS signal is shifted to the right until a failure occurs. In the above figure, a failure occurs after 3 taps, meaning that there are 5 taps to the right edge and 3 taps to the left edge. To center-align DQ and DQS, the sequencer shifts the aligned DQ signal by 1 more tap to the right.

Note:

The sequencer does not adjust DQS directly; instead, the sequencer center-aligns DQS with respect to DQ by delaying the DQ signals.

1.17.5. Stage 2: Write Calibration Part One

The objectives of the write calibration stage are to align DQS to the memory clock at each memory device, and to compensate for address, command, and memory clock skew at each memory device. This stage is important because the address, command, and clock signals for each memory component arrive at different times.

Note:

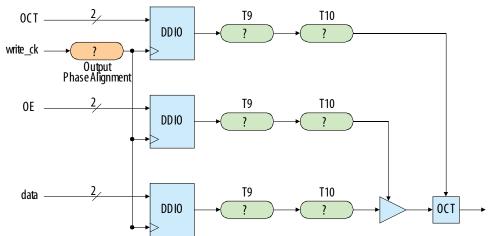
This stage applies only to DDR2, DDR3, LPDDR2, and RLDRAM II protocols; it does not apply to the QDR II and QDR II+ protocols.

Memory clock signals and DQ/DM and DQS signals have specific relationships mandated by the memory device. The PHY must ensure that these relationships are met by skewing DQ/DM and DQS signals. The relationships between DQ/DM and DQS and memory clock signals must meet the tDQSS, tDSS, and tDSH timing constraints.

The sequencer calibrates the write data path using a variety of random burst patterns to compensate for the jitter on the output data path. Simple write patterns are insufficient to ensure a reliable write operation because they might cause imprecise DQS-to-CK alignments, depending on the actual capture circuitry on a memory device. The write patterns in the write leveling stage have a burst length of 8, and are generated by a linear feedback shift register in the form of a pseudo-random binary sequence.

The write data path architecture is the same for DQ, DM, and DQS pins. The following figure illustrates the write data path for a DQ signal. The phase coming out of the Output Phase Alignment block can be set to different values to center-align DQS with respect to DQ, and it is the same for data, OE, and OCT of a given output.

Figure 29. Write Data Path







In write leveling, the sequencer performs write operations with different delay and phase settings, followed by a read. The sequencer can implement any phase shift between 0° and 720° (depending on device and configuration). The sequencer uses the Output Phase Alignment for coarse delays and T9 and T10 for fine delays; T9 has 15 taps of 50 ps each, and T10 has 7 taps of 50 ps each.

The DQS signal phase is held at $+90^{\circ}$ with respect to DQ signal phase (Stratix IV example).

Note:

Coarse delays are called *phases*, and fine delays are called *delays*; phases are process, voltage, and temperature (PVT) compensated, delays are not (depending on family).

For 28 nm devices:

- I/O delay chains are not PVT compensated.
- DQS input delay chain is PVT compensated.
- Leveling delay chains are PVT compensated (does not apply to Arria V or Cyclone V devices).
- T11 delay chain for postamble gating has PVT and nonPVT compensated modes, but the PVT compensated mode is not used.

Note:

Delay and phase values used in this section are examples, for illustrative purposes. Your exact values may vary depending on device and configuration.

The sequencer writes and reads back several burst-length-8 patterns. Because the sequencer has not performed per-bit deskew on the write data path, not all bits are expected to pass the write test. However, for write calibration to succeed, at least one bit per group must pass the write test. The test begins by shifting the DQ/DQS phase until the first write operation completes successfully. The DQ/DQS signals are then delayed to the left by D5 and D6 to find the left edge for that working phase. Then DQ/DQS phase continues the shift to find the last working phase. For the last working phase, DQ/DQS is delayed in 50 ps steps to find the right edge of the last working phase.

The sequencer sweeps through all possible phase and delay settings for each DQ group where the data read back is correct, to define a window within which the PHY can reliably perform write operations. The sequencer picks the closest value to the center of that window as the phase/delay setting for the write data path.

1.17.6. Stage 3: Write Calibration Part Two-DQ/DQS Centering

The process of DQ/DQS centering in write calibration is similar to that performed in read calibration, except that write calibration is performed on the output path, using D5 and D6 delay chains.

1.17.7. Stage 4: Read Calibration Part Two—Read Latency Minimization

At this stage of calibration the sequencer adjusts LFIFO latency to determine the minimum read latency that guarantees correct reads.



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Read Latency Tuning

In general, DQ signals from different DQ groups may arrive at the FPGA in a staggered fashion. In a DIMM or multiple memory device system, the DQ/DQS signals from the first memory device arrive sooner, while the DQ/DQS signals from the last memory device arrive the latest at the FPGA.

LFIFO transfers data from the capture registers in IOE to the core and aligns read data to the AFI clock. Up to this point in the calibration process, the read latency has been a maximum value set initially by LFIFO; now, the sequencer progressively lowers the read latency until the data can no longer be transferred reliably. The sequencer then increases the latency by one cycle to return to a working value and adds an additional cycle of margin to assure reliable reads.

1.17.8. Calibration Signals

The following table lists signals produced by the calibration process.

Table 19. Calibration Signals

Signal	Description
afi_cal_fail	Asserts high if calibration fails.
afi_cal_success	Asserts high if calibration is successful.

1.17.9. Calibration Time

The time needed for calibration varies, depending on many factors including the interface width, the number of ranks, frequency, board layout, and difficulty of calibration. In general, designs using the Nios II-based sequencer will take longer to calibrate than designs using the RTL-based sequencer.

The following table lists approximate typical and maximum calibration times for various protocols.

Table 20. Approximate Calibration Times

Protocol	Typical Calibration Time	Maximum Calibration Time
DDR2, DDR3, LPDDR2, RLDRAM 3	50-250 ms	Can take several minutes if the interface is difficult to calibrate, or if calibration initially fails and exhausts multiple retries.
QDR II/II+, RLDRAM II (with Nios II-based sequencer)	50-100 ms	Can take several minutes if the interface is difficult to calibrate, or if calibration initially fails and exhausts multiple retries.
QDR II/II+, RLDRAM II (with RTL-based sequencer)	<5 ms	<5 ms

1.18. Document Revision History



Date	Version	Changes		
March 2023	2023.03.06	 Added subtitle to volume title. Added note to top of Functional Description - UniPHY topic. Removed references to Intel Arria 10 and Intel Stratix 10 devices and associated protocols. 		
May 2017	2017.05.08	Rebranded as Intel.		
October 2016	2016.10.31	Changed Note 3 to the Word-Aligned Writes figure, in the PHY-to- Controller Interfaces topic.		
May 2016	2016.05.02	Added statement that Efficiency Monitor and Protocol checker is not available for QDR II and QDR II+ SRAM, or for the MAX 10 device family, or for Arria V or Cyclone V designs using the Hard Memory Controller, to Efficiency Monitor and Protocol Checker topic.		
November 2015	2015.11.02	 Replaced the AFI 4.0 Specification with the AFI 3.0 Specification. Replaced instances of Quartus II with Quartus Prime. 		
May 2015	2015.05.04	Maintenance release.		
December 2014	2014.12.15	Added several parameters to the AFI Specification section: MEM_IF_BANKGROUP_WIDTH MEM_IF_CKE_WIDTH MEM_IF_ODT_WIDTH AFI_BANKGROUP_WIDTH AFI_CKE_WIDTH AFI_CKE_WIDTH AFI_ODT_WIDTH AFI_ODT_WIDTH AFI_ODT_WIDTH AFI_ODT_WIDTH AFI_ODT_WIDTH AFI_ODT_WIDTH AGI_Specification section: afi_addr afi_bg afi_c_n afi_enc_n afi_enc_n afi_alert_n afi_alert_n afi_alert_n afi_dinv Changed the Width information for several signals in the AFI Specification section: afi_dqs_burst afi_dqs_burst afi_st_refresh_done afi_seq_busy afi_ctl_long_idle		
August 2014	2014.08.15	 Added note about 32-bit word addresses to Register Maps and UniPHY Register Map tables. Changed register map information for address 0x004, bit 26, in UniPHY Register Map table. 		
December 2013	2013.12.16	Removed references to HardCopy. Removed DLL Offset Control Block. Removed references to SOPC Builder. Increased minimum recommended pulse width for global_reset_n signal to 100ns. Corrected terminology inconsistency. Added information explaining PVT compensation.		



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Date	Version	Changes
		Added quarter-rate information to PHY-to-Controller Interfaces section. Expanded descriptions of INIT_FAILING_STAGE and INIT_FAILING_SUBSTAGE in UniPHY Register map. Added footnote about afi_rlat signal to Calibration Status Signals table.
November 2012	3.1	 Moved Controller Register Map to Functional Description—HPC II Controller chapter. Updated Sequencer States information in Table 1–2. Enhanced Using a Custom Controller information. Enhanced Tracking Manager information. Added Ping Pong PHY information. Added RLDRAM 3 support. Added Arria V GZ support.
June 2012	3.0	 Added Shadow Registers section. Added LPDDR2 support. Added new AFI signals. Added Calibration Time section. Added Feedback icon.
November 2011	2.1	 Consolidated UniPHY information from 11.0 DDR2 and DDR3 SDRAM Controller with UniPHY User Guide, QDR II and QDR II+ SRAM Controller with UniPHY User Guide, and RLDRAM II Controller with UniPHY IP User Guide. Revised Reset and Clock Generation and Dedicated Clock Networks sections. Revised Figure 1–3 and Figure 1–5. Added Tracking Manager to Sequencer section. Revised Interfaces section for DLL, PLL, and OCT sharing interfaces. Revised Using a Custom Controller section. Added UniPHY Calibration Stages section; reordered stages 3 and 4, removed stage 5.



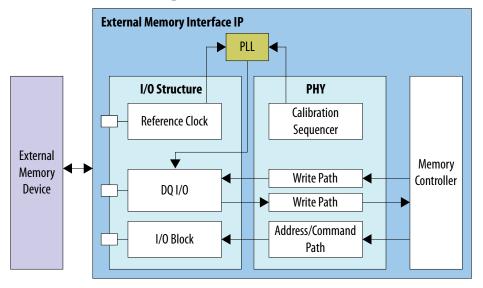




2. Functional Description—Intel MAX® 10 EMIF IP

Intel MAX® 10 FPGAs provide advanced processing capabilities in a low-cost, instanton, small-form-factor device featuring capabilities such as digital signal processing, analog functionality, Nios II embedded processor support and memory controllers.

Figure 30. Intel MAX 10 EMIF Block Diagram

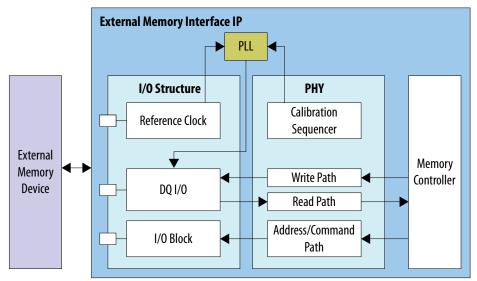


2.1. Intel MAX 10 EMIF Overview

Intel MAX 10 FPGAs provide advanced processing capabilities in a low-cost, instant-on, small-form-factor device featuring capabilities such as digital signal processing, analog functionality, Nios II embedded processor support and memory controllers.



Figure 31. Intel MAX 10 EMIF Block Diagram



2.2. External Memory Protocol Support

Intel MAX 10 FPGAs offer external memory interface support for DDR2, DDR3, DDR3L, and LPDDR2 protocols.

Table 21. Supported External Memory Configurations

External Memory Protocol	Maximum Frequency	Configuration
DDR3, DDR3L	303 MHz	x16 + ECC + Configuration and Status Register (CSR)
DDR2	200 MHz	x16 + ECC + Configuration and Status Register (CSR)
LPDDR2 ⁽¹⁾	200 MHz ⁽²⁾	x16

2.3. Intel MAX 10 Memory Controller

Intel MAX 10 FPGAs use the HPC II external memory controller.

2.4. Intel MAX 10 Low Power Feature

The Intel MAX 10 low power feature is automatically activated when the self refresh or low power down modes are activated. The low power feature sends the afi_mem_clk_disable signal to stop the clock used by the controller.

⁽²⁾ To achieve the specified performance, constrain the memory device I/O and core power supply variation to within $\pm 3\%$. By default, the frequency is 167 MHz.



⁽¹⁾ Intel MAX 10 devices support only single-die LPPDR2.



To conserve power, the Intel MAX 10 UniPHY IP core performs the following functions:

- Tri-states the address and command signals except CKE and RESET_N signals
- Disables the input buffer of DDR input

Note:

The Intel MAX 10 low power feature is available from version 15.0 of the Intel Quartus[®] Prime software. To enable this feature, regenerate your Intel MAX 10 UniPHY IP core using the Intel Quartus Prime software version 15.0 or later.

2.5. Intel MAX 10 Memory PHY

Intel MAX 10 devices employ UniPHY, but without using DLLs for calibration. The physical layer implementation for Intel MAX 10 external memory interfaces provides a calibrated read path and a static write path.

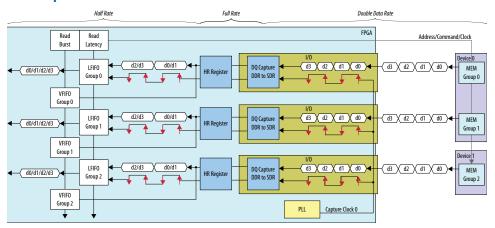
2.5.1. Supported Topologies

The memory PHY supports DDR2 and DDR3 protocols with up to two discrete memory devices, and the LPDDR2 protocol with one discrete memory device.

2.5.2. Read Datapath

One PLL output is used to capture data from the memory during read operations. The clock phase is calibrated by the sequencer before the interface is ready for use.

Figure 32. Read Datapath



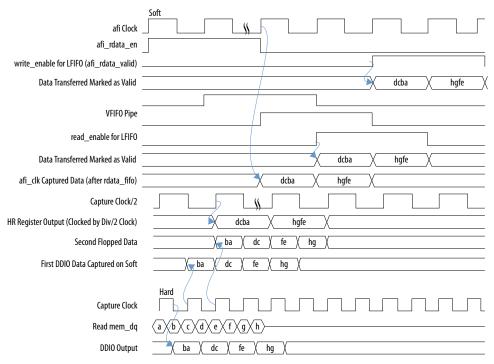
For DDR3 interfaces, two PLL outputs capture data from the memory devices during a read. In a 24-bit interface—whether the top 8 bits are used by ECC or not—the supported topology is two discrete DDR3 devices of 16-bit and 8-bit DQ each. Each discrete device has a dedicated capture clock output from the PLL.

For LPDDR2 interfaces, the supported configuration is a single memory device with memory width of 16-bit DQ. The other PLL output is used for DQS tracking purposes, because the tDQSCK drift might cause data capture to fail otherwise. The tracking clock is a shifted capture clock used to sample the DQS signal. By capturing the DQS signal, the system can compensate for DQS signal drift.





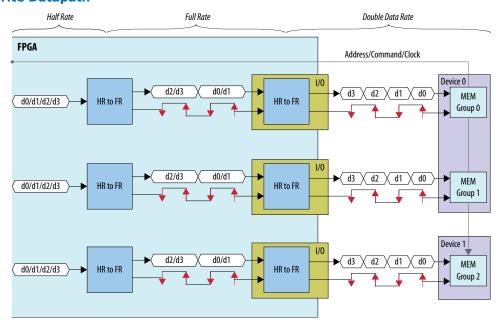
Figure 33. Read Datapath Timing Diagram



2.5.3. Write Datapath

The write datapath is a static path and is timing analyzed to meet timing requirements.

Figure 34. Write Datapath



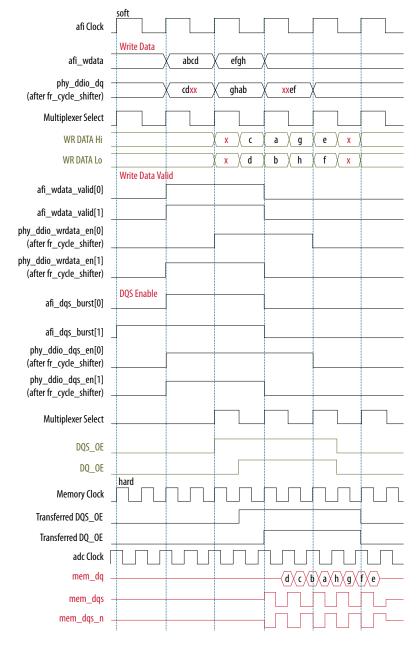






In the PHY write data path, for even write latency the write data valid, write data, and dqs enable pass through one stage of $fr_cycle_shifter$ in a flow through path. For odd memory write latency, the output is shifted by a full-rate clock cycle. The full-rate cycle-shifted output feeds into a simple DDIO.

Figure 35. Write Datapath Timing Diagram







2.5.4. Address and Command Datapath

Implementation of the address and command datapath differs between DDR2/DDR3 and LPDDR2, because of the double data-rate command in LPDDR2.

LPDDR2

For LPDDR2, CA is four bits wide on the AFI interface. The least significant bit of CA is captured by a negative-edge triggered flop, and the most-significant bit of CA is captured by a positive-edge triggered flop, before multiplexing to provide maximum setup and hold margins for the AFI clock-to-MEM clock data transfer.

DDR2/DDR3

For DDR2/DDR3, the full-rate register and MUX architecture is similar to LPDDR2, but both phases are driven with the same signal. The DDR3 address and command signal is not clocked by the write/ADC clock as with LPDDR2, but by the inverted MEM clock, for better address and command margin.

Chip Select

Because the memory controller can drive both phases of cs_n in half-rate, the signal is fully exposed to the AFI side.

2.5.5. Sequencer

The sequencer employs an RTL-based state machine which assumes control of the interface at reset (whether at initial startup or when the IP is reset) and maintains control throughout the calibration process. The sequencer relinquishes control to the memory controller only after successful calibration.

The sequencer consists of a calibration state machine, together with a read-write (RW) manager, PHY Manager, and PLL Manager.

Figure 36. Sequencer Architecture

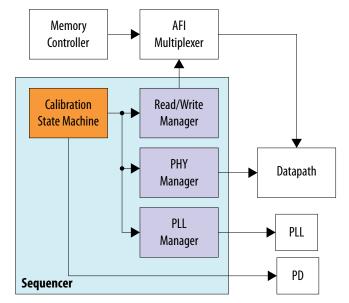
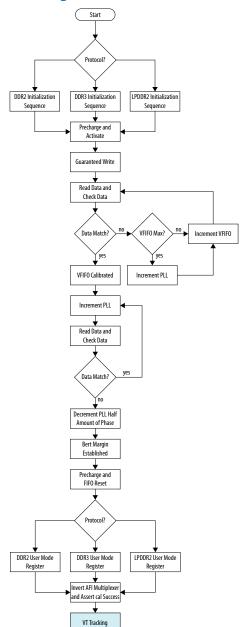






Figure 37. Calibration State Machine Stages





RW Manager

The read-write (RW) manager encapsulates the protocol to read and write to the memory device through the Altera PHY Interface (AFI). It provides a buffer that stores the data to be sent to and read from memory, and provides the following commands:

- Write configuration—configures the memory for use. Sets up burst lengths, read and write latencies, and other device specific parameters.
- Refresh—initiates a refresh operation at the DRAM. The sequencer also provides a register that determines whether the RW manager automatically generates refresh signals.
- Enable or disable multi-purpose register (MPR)—for memory devices with a special register that contains calibration specific patterns that you can read, this command enables or disables access to the register.
- Activate row—for memory devices that have both rows and columns, this
 command activates a specific row. Subsequent reads and writes operate on this
 specific row.
- Precharge—closes a row before you can access a new row.
- Write or read burst—writes or reads a burst length of data.
- Write guaranteed—writes with a special mode where the memory holds address and data lines constant. Intel guarantees this type of write to work in the presence of skew, but constrains to write the same data across the entire burst length.
- Write and read back-to-back—performs back-to-back writes or reads to adjacent banks. Most memory devices have strict timing constraints on subsequent accesses to the same bank, thus back-to-back writes and reads have to reference different banks.
- Protocol-specific initialization—a protocol-specific command required by the initialization sequence.

PHY Manager

The PHY Manager provides access to the PHY for calibration, and passes relevant calibration results to the PHY. For example, the PHYManager sets the VFIFO and LFIFO buffer parameters resulting from calibration, signals the PHY when the memory initialization sequence finishes, and reports the pass/fail status of calibration.

PLL Manager

The PLL Manager controls the phase of capture clocks during calibration. The output phases of individual PLL outputs can be dynamically adjusted relative to each other and to the reference clock without having to load the scan chain of the PLL. The phase is shifted by 1/8th of the period of the voltage-controlled oscillator (VCO) at a time. The output clocks are active during this dynamic phase-shift process.

A PLL counter increments with every phase increase and decrements with every phase reduction. The PLL Manager records the amount by which the PLL counter has shifted since the last reset, enabling the sequencer and tracking manager to determine whether the phase boundary has been reached.



2.6. Calibration

The purpose of calibration is to exercise the external memory interface to find an optimal window for capture clock. There is no calibration for writing data or for address and command output; these paths are analyzed by the Timing Analyzer to meet timing requirements.

The calibration algorithm assumes that address and command signals can reliably be sent to the external memory device, and that write data is registered with DOS.

2.6.1. Read Calibration

Read calibration consists of two primary parts: capture clock and VFIFO buffer calibration, and read latency tuning.

A VFIFO buffer is a FIFO buffer that is calibrated to reflect the read latency of the interface. The calibration process selects the correct read pointer of the FIFO. The VFIFO function delays the controller's afi_rdata_valid signal to align to data captured internally to the PHY. LFIFO buffers are FIFO buffers which ensure that data from different DQS groups arrives at the user side at the same time. Calibration ensures that data arrives at the user side with minimal latency.

Capture Clock and VFIFO Calibration

Capture clock and VFIFO calibration performs the following steps:

- Executes a guaranteed write routine in the read-write (RW) manager.
- Sweeps VFIFO buffer values, beginning at 0, in the PHY Manager.
 - For each adjustment of the VFIFO buffer, sweeps the capture clock phase in the PLL Manager to find the first phase that works. This is accomplished by issuing a read to the RW Manager and performing a bit check. Data is compared for all data bits.
- Increments the capture clock phase in the PLL Manager until capture clock phase values are exhausted or until the system stops working. If there are no more capture clock phase values to try, calibration increments the VFIFO buffer value in the PHY Manager, and phase sweep again until the system stops working.
 - Completion of this step establishes a working range of values.
- As a final step, calibration centers the capture clock phase within the working range.

Read Latency Tuning

Read latency tuning performs the following steps to achieve the optimal latency value:

- Assigns one LFIFO buffer for each DQ group.
- Aligns read data to the AFI clock.
- Gradually reduces LFIFO latency until reads fail, then increases latency to find the minimum value that yields reliable operation.

2.6.2. Write Calibration

There is no calibration routine for writing data.





2.7. Sequencer Debug Information

Following calibration, the sequencer loads a set of debug information onto an output port. You can use the Signal Tap logic analyzer to access the debug information in the presynthesized design.

You could also bring this port to a register, to latch the value and make it accessible to a host processor.

The output port where the debug information is available is not normally connected to anything, so it could be removed during synthesis.

Signal name: phy_cal_debug_info

Module: <corename>_s0.v

The signal is 32 bits wide, and is defined in the following table.

Table 22. Sequencer Debug Data

best_comp_result [23:16]	Best data comparison result on a per-pin basis from the Read-Write Manager. Pin 16 - 23. Any mismatch on respective pin data comparison produces a high bit. If calibration fails, the result is a non-zero value. When calibration passes, the result is zero.
best_comp_result [15:8]	Best data comparison result on a per-pin basis from the Read-Write Manager. Pin 8 - 15. Any mismatch on respective pin data comparison produces a high bit. If calibration fails, the result is a non-zero value. When calibration passes, the result is zero.
best_comp_result [7:0]	Best data comparison result on a per-pin basis from the Read-Write Manager. Pin 0 - 7. Any mismatch on respective pin data comparison produces a high bit. If calibration fails, the result is a non-zero value. When calibration passes, the result is zero.
margin [7:0]	Margin found by the sequencer if calibration passes. Number represents the amount of subsequent PLL phase where valid data is found. If calibration fails, this number is zero. When calibration passes, this value is non-zero.

Debug Example and Interpretation

The following table illustrates possible debug signal values and their interpretations.



	best_comp_result [23:16]	best_comp_result [15:8]	best_comp_result [7:0]	margin [7:0]
Passing result	0000 0000	0000 0000	0000 0000	0001 0000
Interpretation	No failing pins.	No failing pins.	No failing pins.	16 phases of margin for valid window. Ideal case for 300Mhz interface.
Failing result	0010 0000	1111 1111	0000 0000	0000 0000
Interpretation	Pin 21 failing.	All pins failing, pin 8-15.	No failing pins.	No valid window.

2.8. Register Maps

This topic provides register information for Intel MAX 10 EMIF.

Table 23. Controller Register Map

Address	Description	
0x100 - 0x126	Reserved	
0x130	ECC control register	
0x131	ECC status register	
0x132	ECC error address register	

UniPHY does not have a configuration and status register. The HPC II controller does have a configuration and status register, when configured for ECC.

Related Information

Soft Controller Register Map on page 183

2.9. Document Revision History

Table 24. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Changed instances of <i>Quartus II</i> to <i>Quartus Prime</i> .
May 2015	2015.05.04	 Updated the external memory protocol support. Added topic about the low power feature.
December 2014	2014.12.15	Initial release.







3. Functional Description—Hard Memory Interface

The hard (on-chip) memory interface components are available in the Arria V and Cyclone V device families.

The Arria V device family includes hard memory interface components supporting DDR2 and DDR3 SDRAM memory protocols at speeds of up to 533 MHz. For the Quartus II software version 12.0 and later, the Cyclone V device family supports both hard and soft interface support.

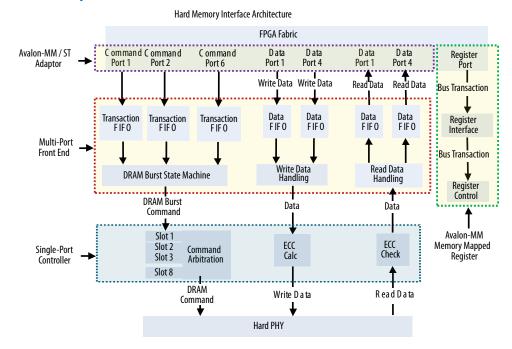
The Arria V device family supports both hard and soft interfaces for DDR3 and DDR2, and soft interfaces for LPDDR2 SDRAM, QDR II SRAM, and RLDRAM II memory protocols. The Cyclone V device family supports both hard and soft interfaces for DDR3, DDR2, and LPDDR2 SDRAM memory protocols.

The hard memory interface consists of three main parts, as follows:

- The multi-port front end (MPFE), which allows multiple independent accesses to the hard memory controller.
- The hard memory controller, which initializes, refreshes, manages, and communicates with the external memory device.
- The hard PHY, which provides the physical layer interface to the external memory device.



Figure 38. Hard Memory Interface Architecture



3.1. Multi-Port Front End (MPFE)

The multi-port front end and its associated fabric interface provide up to six command ports, four read-data ports and four write-data ports, through which user logic can access the hard memory controller. Each port can be configured as read only or write only, or read and write ports may be combined to form bidirectional data ports. Ports can be 32, 64, 128, or 256 data bits wide, depending on the number of ports used and the type (unidirectional or bidirectional) of the port.

Fabric Interface

The fabric interface provides communication between the Avalon-ST-like internal protocol of the hard memory interface and the external Avalon-MM protocol. The fabric interface supports frequencies in the range of 10 MHz to one-half of the memory interface frequency. For example, for an interface running at 533 MHz, the maximum user logic frequency is 267 MHz. The MPFE handles the clock crossing between user logic and the hard memory interface.

The multi-port front end read and write FIFO depths are 8, and the command FIFO depth is 4. The FIFO depths are not configurable.

Operation Ordering

Requests arriving at a given port are executed in the order in which they are received.

Requests arriving at different ports have no guaranteed order of service, except when a first transaction has completed before the second arrives.







3.2. Multi-port Scheduling

Multi-port scheduling is governed by two considerations: the absolute priority of a request and the weighting of a port. User-configurable priority and weight settings determine the absolute and relative scheduling policy for each port.

3.2.1. Port Scheduling

The evaluation of absolute priority ensures that ports carrying higher-priority traffic are served ahead of ports carrying lower-priority traffic. The scheduler recognizes eight priority levels, with higher values representing higher priorities. Priority is absolute; for example, any transaction with priority seven will always be scheduled before transactions of priority six or lower.

When ports carry traffic of the same absolute priority, relative priority is determined based on port weighting. Port weighting is a five-bit value, and is determined by a weighted round robin (WRR) algorithm.

The scheduler can alter priority if the latency target for a transaction is exceeded. The scheduler tracks latency on a per-port basis, and counts the cycles that a transaction is pending. Each port has a priority escalation register and a pending counter engagement register. If the number of cycles in the pending counter engagement register elapse without a pending transaction being served, that transaction's priority is esclated.

To ensure that high-priority traffic is served quickly and that long and short bursts are effectively interleaved on ports, bus transactions longer than a single DRAM burst are scheduled as a series of DRAM bursts, with each burst arbitrated separately.

The scheduler uses a form of deficit round robin (DRR) scheduling algorithm which corrects for past over-servicing or under-servicing of a port. Each port has an associated weight which is updated every cycle, with a user-configured weight added to it and the amount of traffic served subtracted from it. The port with the highest weighting is considered the most eligible.

To ensure that lower priority ports do not build up large running weights while higher priority ports monopolize bandwidth, the hard memory controller's DRR weights are updated only when a port matches the scheduled priority. Hence, if three ports have traffic, two being priority 7 and one being priority 4, the weights for both ports at priority 7 are updated but the port with priority 4 remains unchanged.

3.2.2. DRAM Burst Scheduling

DRAM burst scheduling recognizes addresses that access the same column/row combination—also known as open page accesses. Such operations are always served in the order in which they are received in the single-port controller.

Selection of DRAM operations is a two-stage process; first, each pending transaction must wait for its timers to be eligible for execution, then the transaction arbitrates against other transactions that are also eligible for execution.



The following rules govern transaction arbitration:

- High priority operations take precedence over lower priority operations
- If multiple operations are in arbitration, read operations have precedence over write operations
- If multiple operations still exist, the oldest is served first

A high-priority transaction in the DRAM burst scheduler wins arbitration for that bank immediately if the bank is idle and the high-priority transaction's chip select/row/column address does not match an address already in the single-port controller. If the bank is not idle, other operations to that bank yield until the high-priority operation is finished. If the address matches another chip select/row/column, the high-priority transaction yeilds until the earlier transaction is completed.

You can force the DRAM burst scheduler to serve transactions in the order that they are received, by setting a bit in the register set.

3.2.3. DRAM Power Saving Modes

The hard memory controller supports two DRAM power-saving modes: self-refresh, and fast/slow all-bank precharge powerdown exit. Engagement of a DRAM power saving mode can occur due to inactivity, or in response to a user command.

The user command to enter power-down mode forces the DRAM burst-scheduling bank-management logic to close all banks and issue the power-down command. You can program the controller to power down when the DRAM burst-scheduling queue is empty for a specified number of cycles; the DRAM is reactivated when an active DRAM command is received.

3.3. MPFE Signal Descriptions

The following table describes the signals for the multi-port front end.

Table 25. MPFE Signals

Signal	Direction	Description
avl_ <signal_name>_# (1)</signal_name>	_	Local interface signals.
mp_cmd_clk_#_clk (1)	Input	Clock for the command FIFO buffer. (3) Follow Avalon-MM master frequency. Maximum frequency is one-half of the interface frequency, and subject to timing closure.
mp_cmd_reset_n_#_reset_n (1)	Input	Asynchronous reset signal for command FIFO buffer.
mp_rfifo_clk_#_clk (2)	Input	Clock for the read data FIFO buffer. Follow Avalon-MM master frequency. Maximum frequency is one-half of the interface frequency, and subject to timing closure.
mp_rfifo_reset_n_#_reset_n (2)	Input	Asynchronous reset signal for read data FIFO buffer.
mp_wfifo_clk_#_clk (2)	Input	Clock for the write data FIFO buffer. Follow Avalon-MM master frequency. Maximum frequency is one-half of the interface frequency, and subject to timing closure.
mp_wfifo_reset_n_#_reset_n (2)	Input	Asynchronous reset signal for write data FIFO buffer.
	<u>'</u>	continued



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Signal	Direction	Description
bonding_in_1/2/3	Input	Bonding interface input port. Connect second controller bonding output port to this port according to the port sequence.
bonding_out_1/2/3	Output	Bonding interface output port. Connect this port to the second controller bonding intput port according to the port sequence.

Notes to Table:

- 1. # represents the number of the slave port. Values are 0-5.
- 2. # represents the number of the slave port. Values are 0-3.
- 3. The command FIFO buffers have two stages. The first stage is 4 bus transaction deep per port. After port scheduling, the commands are placed in the second stage FIFO buffer, which is 8 DRAM transactions deep. The second stage FIFO buffer is used to optimize memory operations where bank look ahead and data reordering occur. The write data buffer is 32 deep and read buffer is 64 deep.

Every input interface (command, read data, and write data) has its own clock domain. Each command port can be connected to a different clock, but the read data and write data ports associated with a command port must connect to the same clock as that command port. Each input interface uses the same reset signal as its clock.

By default, the IP generates all clock signals regardless of the MPFE settings, but all unused ports and FIFO buffers are connected to ground.

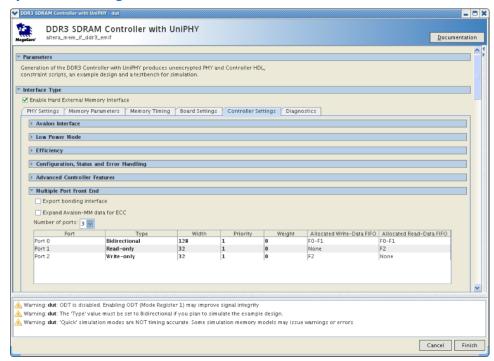
The command ports can be used only in unidirectional configurations, with either 4 write and 2 read, 3 write and 3 read, or 2 write and 4 read scenarios. For bidirectional ports, the number of clocks is reduced from 6 to a maximum of 4.

For the scenario depicted in the following figure:

- command port 0 is associated with read and write data FIFO 0 and 1
- command port 1 is associated with read data FIFO 2
- command port 2 is associated with write data FIFO 2



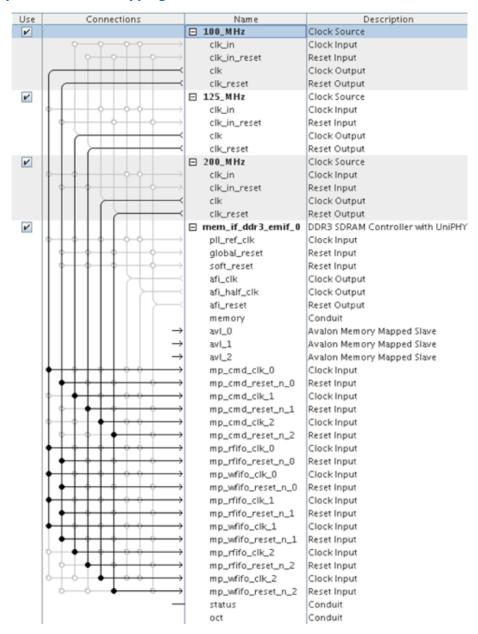
Figure 39. Sample MPFE Configuration



Therefore, if port 0 (avl_0) is clocked by a 100 MHz clock signal, mp_cmd_clk_0, mp_rfifo_clk_0, mp_rfifo_clk_1, mp_wfifo_clk_0, and mp_wfifo_clk_1 must all be connected to the same 100 MHz clock, as illustrated below.



Figure 40. Sample Connection Mapping



3.4. Hard Memory Controller

The hard memory controller initializes, refreshes, manages, and communicates with the external memory device.

Note:

The hard memory controller is functionally similar to the High Performance Controller II (HPC II). For information on signals, refer to the *Functional Description—HPC II Controller* chapter.



Related Information

Functional Description—HPC II Controller on page 157

3.4.1. Clocking

The ports on the MPFE can be clocked at different frequencies, and synchronization is maintained by cross-domain clocking logic in the MPFE.

Command ports can connect to different clocks, but the data ports associated with a given command port must be attached to the same clock as that command port. For example, a bidirectional command port that performs a 64-bit read/write function has its read port and write port connected to the same clock as the command port. Note that these clocks are separate from the EMIF core generated clocks.

3.4.2. Reset

The ports of the MPFE must connect to the same reset signal.

When the reset signal is asserted, it resets the command and data FIFO buffer in the MPFE without resetting the hard memory controller.

Note:

The global_reset_n and soft_reset_n signals are asynchronous. You must include a false_path or relaxed delay timing exception in the project Synopsys Design Constraint File (.sdc) to avoid unnecessary recovery and removal analysis.

For easiest management of reset signals, Intel recommends the following sequence at power-up:

- Initially global_reset_n, soft_reset_n, and the MPFE reset signals are all asserted.
- 2. global reset n is deasserted.
- 3. Wait for pll_locked to transition high.
- 4. soft reset n is deasserted.
- 5. (Optional) If you encounter difficulties, wait for the controller signal local_cal_success to go high, indicating that the external memory interface has successfully completed calibration, before deasserting the MPFE FIFO reset signals. This will ensure that read/write activity cannot occur until the interface is successfully calibrated.

3.4.3. DRAM Interface

The DRAM interface is 40 bits wide, and can accommodate 8-bit, 16-bit, 16-bit plus ECC, 32-bit, or 32-bit plus ECC configurations. Any unused I/Os in the DRAM interface can be reused as user I/Os.

The DRAM interface supports DDR2 and DDR3 memory protocols, and LPDDR2 for Cyclone V only. Fast and medium speed grade devices are supported to 533 MHz for Arria V and 400 MHz for Cyclone V.





3.4.4. ECC

The hard controller supports both error-correcting code (ECC) calculated by the controller and by the user. Controller ECC code employs standard Hamming logic which can detect and correct single-bit errors and detect double-bit errors. The controller ECC is available for 16-bit and 32-bit widths, each requiring an additional 8 bits of memory, resulting in an actual memory width of 24-bits and 40-bits, respectively.

In user ECC mode, all bits are treated as data bits, and are written to and read from memory. User ECC can implement nonstandard memory widths such as 24-bit or 40-bit, where ECC is not required.

Controller ECC

Controller ECC provides the following features:

Byte Writes—The memory controller performs a read/modify/write operation to keep ECC valid when a subset of the bits of a word is being written. If an entire word is being written (but less than a full burst) and the DM pins are connected, no read is necessary and only that word is updated. If controller ECC is disabled, byte-writes have no performance impact.

ECC Write Backs—When a read operation detects a correctable error, the memory location is scheduled for a read/modify/write operation to correct the single-bit error.

User ECC—User ECC is 24-bits or 40-bits wide; with user ECC, the controller performs no ECC checking. The controller employs memory word addressing with byte enables, and can handle arbitrary memory widths. User ECC does not disable byte writes; hence, you must ensure that any byte writes do not result in corrupted ECC.

3.4.5. Bonding of Memory Controllers

Bonding is a feature that allows data to be split between two memory controllers, providing the ability to service bandwidth streams similar to a single 64-bit controller. Bonding works by dividing data buses in proportion to the memory widths, and always sending a transaction to both controllers. When signals are returned, bonding ensures that both sets of signals are returned identically.

Bonding can be applied to asymetric controllers, and allows controllers to have different memory clocks. Bonding does not attempt to synchronize the controllers. Bonding supports only one port. The Avalon port width can be varied from 64-bit to 256-bit; 32-bit port width is not supported.

The following signals require bonding circuitry:

Read data return—This bonding allows read data from the two controllers to return with effectively one ready signal to the bus master that initiated the bus transaction.

Write ready—For Avalon-MM, this is effectively bonding on the waitrequest signal.

Write acknowledge—Synchronization on returning the write completed signal.

For each of the above implementations, data is returned in order, hence the circuitry must match up for each valid cycle.





Bonded FIFO buffers must have identical FIFO numbers; that is, read FIFO 1 on controller 1 must be paired with Read FIFO 1 on controller 2.

Data Return Bonding

Long loop times can lead to communications problems when using bonded controllers. The following effects are possible when using bonded controllers:

- If one memory controller completes its transaction and receives new data before the other controller, then the second controller can send data as soon as it arrives, and before the first controller acknowledges that the second controller has data.
- If the first controller has a single word in its FIFO buffer and the second controller receives single-word transactions, the second controller must determine whether the second word is a valid signal or not.

To accommodate the above effects, the hard controller maintains two counters for each bonded pair of FIFO buffers and implements logic that monitors those counters to ensure that the bonded controllers receive the same data on the same cycle, and that they send the data out on the same cycle.

FIFO Ready

FIFO ready bonding is used for write command and write data buses. The implementation is similar to the data return bonding.

Bonding Latency Impact

Bonding has no latency impact on ports that are not bonded.

Bonding Controller Usage

Arria V and Cyclone V devices employ three shared bonding controllers to manage the read data return bonding, write acknowledge bonding, and command/write data ready bonding.

The three bonding controllers require three pairs of bonding I/Os, each based on a six port count; this means that a bonded hard memory controller requires 21 input signals and 21 output signals for its connection to the fabric, and another 21 input signals and 21 output signals to the paired hard memory controller.

Note:

The hard processor system (HPS) hard memory controller cannot be bonded with another hard memory controller on the FPGA portion of the device.

Bonding Configurations and Parameter Requirements

Intel has verified hard memory controller bonding between two interfaces with the following configuration:

- Same clock source
- · Same memory clock frequency
- Same memory parameters and timings (except interface width)
- Same controller settings.
- Same port width in MPFE settings

Bonding supports only one port. The Avalon port width can be varied from 64-bits to 256-bits; a 32-bit port width is not supported.



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3.5. Hard PHY

A physical layer interface (PHY) is embedded in the periphery of the Arria V device, and can run at the same high speed as the hard controller and hard sequencer. This hard PHY is located next to the hard controller. Differing device configurations have different numbers and sizes of hard controller and hard PHY pairs.

The hard PHY implements logic that connects the hard controller to the I/O ports. Because the hard controller and AFI interface support high frequencies, a portion of the sequencer is implemented as hard logic. The Nios II processor, the instruction/data RAM, and the Avalon fabric of the sequencer are implemented as core soft logic. The read/write manger and PHY manager components of the sequencer, which must operate at full rate, are implemented as hard logic in the hard PHY.

3.5.1. Interconnections

The hard PHY resides on the device between the hard controller and the I/O register blocks. The hard PHY is instantiated or bypassed entirely, depending on the parameterization that you specify.

The hard PHY connects to the hard memory controller and the core, enabling the use of either the hard memory controller or a software-based controller. (You can have the hard controller and hard PHY, or the soft controller and soft PHY; however, the combination of soft controller with hard PHY is not supported.) The hard PHY also connects to the I/O register blocks and the DQS logic. The path between the hard PHY and the I/O register blocks can be bypassed, but not reconfigured—in other words, if you use the hard PHY datapath, the pins to which it connects are predefined and specified by the device pin table.

3.5.2. Clock Domains

The hard PHY contains circuitry that uses the following clock domains:

AFI clock domain (pll_afi_clk) —The main full-rate clock signal that synchronizes most of the circuit logic.

Avalon clock domain (pll_avl_clk) —Synchronizes data on the internal Avalon bus, namely the Read/Write Manager, PHY Manager, and Data Manager data. The data is then transferred to the AFI clock domain. To ensure reliable data transfer between clock domains, the Avalon clock period must be an integer multiple of the AFI clock period, and the phases of the two clocks must be aligned.

Address and Command clock domain (pll_addr_cmd_clk) —Synchronizes the global asychronous reset signal, used by the I/Os in this clock domain.

3.5.3. Hard Sequencer

The sequencer initializes the memory device and calibrates the I/Os, with the objective of maximizing timing margins and achieving the highest possible performance.



When the hard memory controller is in use, a portion of the sequncer must run at full rate; for this reason, the Read/Write Manager, PHY Manager, and Data Manager are implemented as hard components within the hard PHY. The hard sequencer communicates with the soft-logic sequencer components (including the Nios II processor) via an Avalon bus.

3.5.4. MPFE Setup Guidelines

The following instructions provide information on configuring the multi-port front end of the hard memory interface.

- To enable the hard memory interface, turn on Enable Hard External Memory Interface in the Interface Type tab in the parameter editor.
- To export bonding interface ports to the top level, turn on Export bonding interface in the Multiple Port Front End pulldown on the Controller Settings tab in the parameter editor.
 - Note: The system exports three bonding-in ports and three bonding-out ports. You must generate two controllers and connect the bonding ports manually.
- To expand the interface data width from a maximum of 32 bits to a maximum of 40 bits, turn on Enable Avalon-MM data for ECC in the Multiple Port Front End pulldown on the Controller Settings tab in the parameter editor.
 - Note: The controller does not perform ECC checking when this option is turned on.
- Select the required Number of ports for the multi-port front end in the Multiple Port Front End pulldown on the Controller Settings tab in the parameter editor.
 - Note: The maximum number of ports is 6, depending on the port type and width. The maximum port width is 256 bits, which is the maximum data width of the read data FIFO and write data FIFO buffers.
- 5. The table in the **Multiple Port Front End** pulldown on the **Controller Settings** tab in the parameter editor lists the ports that are created. The columns in the table describe each port, as follows:
 - Port: Indicates the port number.
 - **Type**: Indicates whether the port is read only, write only, or bidirectional.
 - Width: To achieve optimum MPFE throughput, Intel recommends setting the MPFE data port width according to the following calculation:
 - $2 \times (frequency ratio of HMC to user logic) \times (interface data width)$

For example, if the frequency of your user logic is one-half the frequency of the hard memory controller, you should set the port width to be 4x the interface data width. If the frequency ratio of the hard memory controller to user logic is a fractional value, you should use a larger value; for example, if the ratio is 1.5, you can use 2.





- Priority: The priority setting specifies the priority of the slave port, with higher values representing higher priority. The slave port with highest priority is served first.
- **Weight**: The weight setting has a range of values of 0–31, and specifies the relative priority of a slave port, with higher weight representing higher priority. The weight value can determine relative bandwidth allocations for slave ports with the same priority values. For example, if two ports have the same priority value, and weight values of 4 and 6, respectively, the port with a weight of 4 will receive 40% of the bus bandwidth, while the port with a weight of 6 will receive 60% of the bus bandwidth—assuming 100% total available bus bandwidth.

3.5.5. Soft Memory Interface to Hard Memory Interface Migration Guidelines

The following instructions provide information on mapping your soft memory interface to a hard memory interface.

Pin Connections

- 1. The hard and soft memory controllers have compatible pinouts. Assign interface pins to the hard memory interface according to the pin table.
- Ensure that your soft memory interface pins can fit into the hard memory interface. The hard memory interface can support a maximum of a 40-bit interface with user ECC, or a maximum of 80-bits with same-side bonding. The soft memory interface does not support bonding.
- 3. Follow the recommended board layout guidelines for the hard memory interface.

Software Interface Preparation

Observe the following points in preparing your soft memory interface for migration to a hard memory interface:

- You cannot use the hard PHY without also using the hard memory controller.
- The hard memory interface supports only full-rate controller mode.
- Ensure that the MPFE data port width is set according to the soft memory interface half-rate mode Avalon data width.
- The hard memory interface uses a different Avalon port signal naming convention than the software memory interface. Ensure that you change the avl_<signal_name> signals in the soft memory interface to .avl_<signal_name>_0 signals in the hard memory interface.
- The hard memory controller MPFE includes an additional three clocks and three reset ports (CMD port, RFIFO port, and WFIFO port) that do not exist with the soft memory controller. You should connect the user logic clock signal to the MPFE clock port, and the user logic reset signal to the MPFE reset port.
- In the soft memory interface, the half-rate afi_clk is a user logic clock. In the hard memory interface, afi_clk is a full-rate clock, because the core fabric might not be able to achieve full-rate speed. When you migrate your soft memory interface to a hard memory interface, you need to supply an additional slower rate clock. The maximum clock rate supported by core logic is one-half of the maximum interface frequency.

Latency





Overall, you should expect to see slightly more latency when using the hard memory controller and multi-port front end, than when using the soft memory controller.

The hard memory controller typically exhibits lower latency than the soft memory controller; however, the multi-port front end does introduce additional latency cycles due to FIFO buffer stages used for synchronization. The MPFE cannot be bypassed, even if only one port is needed.

3.5.6. Bonding Interface Guidelines

Bonding allows a single data stream to be split between two memory controllers, providing the ability to expand the interface data width similar to a single 64-bit controller. This section provides some guidelines for setting up the bonding interface.

- 1. Bonding interface ports are exported to the top level in your design. You should connect each bonding_in* port in one hard memory controller to the corresponding bonding_out_*port in the other hard memory controller, and vice versa.
- 2. You should modify the Avalon signal connections to drive the bonding interface with a single user logic/master, as follows:
 - a. AND both avl_ready signals from both hard memory controllers before the signals enter the user logic.
 - b. AND both avl_rdata_valid signals from both hard memory controllers before the signals enter the user logic. (The avl_rdata_valid signals should be identical for both hard memory controllers.)
 - Branch the following signals from the user logic to both hard memory controllers:
 - avl_burstbegin
 - avl_addr
 - avl_read_req
 - avl_write_req
 - avl size
 - d. Split the following signals according to each multi-port front end data port width:
 - avl rdata
 - avl_wdata
 - avl_be

3.6. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Maintenance release.
		continued



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Date	Version	Changes			
May 2015	2015.05.04	Maintenance release.			
December 2014	21014.12.15	Maintenance release.			
August 2014	2014.08.15	Updated descriptions of mp_cmd_reset_n_#_reset_n, mp_rfifo_reset_n_#_reset_n, and mp_wfifo_reset_n_#_reset_n in the MPFE Signals table. Added Reset section to Hard Memory Controller section.			
December 2013	2013.12.16	 Added footnote about command FIFOs to MPFE Signals table. Added information about FIFO depth for the MPFE. Added information about hard memory controller bonding. Reworded protocol-support information for Arria V and Cyclone V devices. 			
November 2012	2.1	Added Hard Memory Interface Implementation Guidelines. Moved content of EMI-Related HPS Features in SoC Devices section to chapter 4, Functional Description—HPS Memory Controller.			
June 2012	2.0	 Added EMI-Related HPS Features in SoC Devices. Added LPDDR2 support. Added Feedback icon. 			
November 2011	1.0	Initial release.			





4. Functional Description—HPS Memory Controller

The hard processor system (HPS) SDRAM controller subsystem provides efficient access to external SDRAM for the Arm* Cortex*-A9 microprocessor unit (MPU) subsystem, the level 3 (L3) interconnect, and the FPGA fabric.

Note:

This chapter applies to the HPS architecture of Arria V and Cyclone V memory controllers only.

The SDRAM controller provides an interface between the FPGA fabric and HPS. The interface accepts Advanced Microcontroller Bus Architecture (AMBA*) Advanced eXtensible Interface (AXI*) and Avalon Memory-Mapped (Avalon-MM) transactions, converts those commands to the correct commands for the SDRAM, and manages the details of the SDRAM access.

4.1. Features of the SDRAM Controller Subsystem

The SDRAM controller subsystem offers programming flexibility, port and bus configurability, error correction, and power management.

- Support for double data rate 2 (DDR2), DDR3, and low-power DDR2 (LPDDR2) SDRAM
- Flexible row and column addressing with the ability to support up to 4 Gb of memory per chip select
- Optional 8-bit integrated error correction code (ECC) for 16- and 32-bit data widths⁽³⁾
- User-configurable memory width of 8, 16, 16+ECC, 32, 32+ECC
- User-configurable timing parameters
- Two chip selects (DDR2 and DDR3)
- Command reordering (look-ahead bank management)
- Data reordering (out of order transactions)
- User-controllable bank policy on a per port basis for either closed page or conditional open page accesses
- User-configurable priority support with both absolute and weighted round-robin scheduling
- Flexible FPGA fabric interface with up to 6 ports that can be combined for a data width up to 256 bits using Avalon-MM and AXI interfaces
- Power management supporting self refresh, partial array self refresh (PASR), power down, and LPDDR2 deep power down

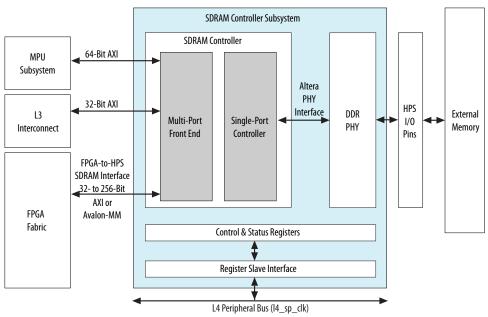
⁽³⁾ The level of ECC support is package dependent.



4.2. SDRAM Controller Subsystem Block Diagram

The SDRAM controller subsystem connects to the MPU subsystem, the L3 interconnect, and the FPGA fabric. The memory interface consists of the SDRAM controller, the physical layer (PHY), control and status registers (CSRs), and their associated interfaces.

Figure 41. SDRAM Controller Subsystem High-Level Block Diagram



SDRAM Controller

The SDRAM controller provides high performance data access and run-time programmability. The controller reorders data to reduce row conflicts and bus turn-around time by grouping read and write transactions together, allowing for efficient traffic patterns and reduced latency.

The SDRAM controller consists of a multiport front end (MPFE) and a single-port controller. The MPFE provides multiple independent interfaces to the single-port controller. The single-port controller communicates with and manages each external memory device.

The MPFE FPGA-to-HPS SDRAM interface port has an asynchronous FIFO buffer followed by a synchronous FIFO buffer. Both the asynchronous and synchronous FIFO buffers have a read and write data FIFO depth of 8, and a command FIFO depth of 4. The MPU subsystem 64-bit AXI port and L3 interconnect 32-bit AXI port have asynchronous FIFO buffers with read and write data FIFO depth of 8, and command FIFO depth of 4.



DDR PHY

The DDR PHY provides a physical layer interface for read and write memory operations between the memory controller and memory devices. The DDR PHY has dataflow components, control components, and calibration logic that handle the calibration for the SDRAM interface timing.

Related Information

Memory Controller Architecture on page 92

4.3. SDRAM Controller Memory Options

Bank selects, and row and column address lines can be configured to work with SDRAMs of various technology and density combinations.

Table 26. SDRAM Controller Interface Memory Options

Memory Type	Mbits	Column Address Bit Width	Bank Select Bit Width	Row Address Bit Width	Page Size	MBytes
DDR2	256	10	2	13	1024	32
	512	10	2	14	1024	64
	1024 (1 Gb)	10	3	14	1024	128
	2048 (2 Gb)	10	3	15	1024	256
	4096 (4 Gb)	10	3	16	1024	512
DDR3	512	10	3	13	1024	64
	1024 (1 Gb)	10	3	14	1024	128
	2048 (2 Gb)	10	3	15	1024	256
	4096 (4 Gb)	10	3	16	1024	512
LPDDR2	64	9	2	12	512	8
	128	10	2	12	1024	16
	256	10	2	13	1024	32
	512	11	2	13	2048	64
	1024 (1 Gb) - S2 ⁽⁵⁾	11	2	14	2048	128
	1024 (1 Gb) -S4	11	3	13	2048	128
	2048 (2 Gb) - S2 ⁽⁵⁾	11	2	15	2048	256
	2048	11	3	14	2048	256
						continued

⁽⁴⁾ For all memory types shown in this table, the DQ width is 8.



⁽⁵⁾ S2 signifies a 2n prefetch size

⁽⁶⁾ S4 signifies a 4n prefetch size



Memory Type	Mbits	Column Address Bit Width	Bank Select Bit Width	Row Address Bit Width	Page Size	MBytes
	(2 Gb) -S4 ⁽⁶⁾					
	4096 (4 Gb)	12	3	14	4096	512

4.4. SDRAM Controller Subsystem Interfaces

4.4.1. MPU Subsystem Interface

The SDRAM controller connects to the MPU subsystem with a dedicated 64-bit AXI interface, operating on the mpu_12_ram_clk clock domain.

4.4.2. L3 Interconnect Interface

The SDRAM controller interfaces to the L3 interconnect with a dedicated 32-bit AXI interface, operating on the 13 main clk clock domain.

4.4.3. CSR Interface

The CSR interface connects to the level 4 (L4) bus and operates on the 14_sp_clk clock domain. The MPU subsystem uses the CSR interface to configure the controller and PHY, for example setting the memory timing parameter values or placing the memory in a low power state. The CSR interface also provides access to the status registers in the controller and PHY.

4.4.4. FPGA-to-HPS SDRAM Interface

The FPGA-to-HPS SDRAM interface provides masters implemented in the FPGA fabric access to the SDRAM controller subsystem in the HPS. The interface has three port types that are used to construct the following AXI or Avalon-MM interfaces:

- Command ports—issue read and write commands, and for receive write acknowledge responses
- 64-bit read data ports—receive data returned from a memory read
- 64-bit write data ports—transmit write data

The FPGA-to-HPS SDRAM interface supports six command ports, allowing up to six Avalon-MM interfaces or three AXI interfaces. Each command port can be used to implement either a read or write command port for AXI, or be used as part of an Avalon-MM interface. The AXI and Avalon-MM interfaces can be configured to support 32-, 64-, 128-, and 256-bit data.

⁽⁴⁾ For all memory types shown in this table, the DQ width is 8.



Table 27. FPGA-to-HPS SDRAM Controller Port Types

Port Type	Available Number of Ports
Command	6
64-bit read data	4
64-bit write data	4

The FPGA-to-HPS SDRAM controller interface can be configured with the following characteristics:

- Avalon-MM interfaces and AXI interfaces can be mixed and matched as required by the fabric logic, within the bounds of the number of ports provided to the fabric.
- Because the AXI protocol allows simultaneous read and write commands to be issued, two SDRAM control ports are required to form an AXI interface.
- Because the data ports are natively 64-bit, they must be combined if wider data paths are required for the interface.
- Each Avalon-MM or AXI interface of the FPGA-to-HPS SDRAM interface operates on an independent clock domain.
- The FPGA-to-HPS SDRAM interfaces are configured during FPGA configuration.

The following table shows the number of ports needed to configure different bus protocols, based on type and data width.

Table 28. FPGA-to-HPS SDRAM Port Utilization

Bus Protocol	Command Ports	Read Data Ports	Write Data Ports
32- or 64-bit AXI	2	1	1
128-bit AXI	2	2	2
256-bit AXI	2	4	4
32- or 64-bit Avalon-MM	1	1	1
128-bit Avalon-MM	1	2	2
256-bit Avalon-MM	1	4	4
32- or 64-bit Avalon-MM write-only	1	0	1
128-bit Avalon-MM write-only	1	0	2
256-bit Avalon-MM write-only	1	0	4
32- or 64-bit Avalon-MM read-only	1	1	0
128-bit Avalon-MM read-only	1	2	0
256-bit Avalon-MM read-only	1	4	0
	,	!	1

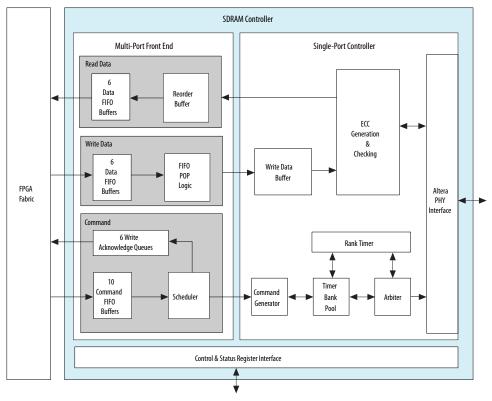
4.5. Memory Controller Architecture

The SDRAM controller consists of an MPFE, a single-port controller, and an interface to the CSRs.





Figure 42. SDRAM Controller Block Diagram



4.5.1. Multi-Port Front End

The Multi-Port Front End (MPFE) is responsible for scheduling pending transactions from the configured interfaces and sending the scheduled memory transactions to the single-port controller. The MPFE handles all functions related to individual ports.

The MPFE consists of three primary sub-blocks.

Command Block

The command block accepts read and write transactions from the FPGA fabric and the HPS. When the command FIFO buffer is full, the command block applies backpressure by deasserting the ready signal. For each pending transaction, the command block calculates the next SDRAM burst needed to progress on that transaction. The command block schedules pending SDRAM burst commands based on the user-supplied configuration, available write data, and unallocated read data space.

Write Data Block

The write data block transmits data to the single-port controller. The write data block maintains write data FIFO buffers and clock boundary crossing for the write data. The write data block informs the command block of the amount of pending write data for each transaction so that the command block can calculate eligibility for the next SDRAM write burst.





Read Data Block

The read data block receives data from the single-port controller. Depending on the port state, the read data block either buffers the data in its internal buffer or passes the data straight to the clock boundary crossing FIFO buffer. The read data block reorders out-of-order data for Avalon-MM ports.

In order to prevent the read FIFO buffer from overflowing, the read data block informs the command block of the available buffer area so the command block can pace read transaction dispatch.

4.5.2. Single-Port Controller

The single-port logic is responsible for following actions:

- Queuing the pending SDRAM bursts
- Choosing the most efficient burst to send next
- Keeping the SDRAM pipeline full
- Ensuring all SDRAM timing parameters are met

Transactions passed to the single-port logic for a single page in SDRAM are guaranteed to be executed in order, but transactions can be reordered between pages. Each SDRAM burst read or write is converted to the appropriate Altera PHY interface (AFI) command to open a bank on the correct row for the transaction (if required), execute the read or write command, and precharge the bank (if required).

The single-port logic implements command reordering (looking ahead at the command sequence to see which banks can be put into the correct state to allow a read or write command to be executed) and data reordering (allowing data transactions to be dispatched even if the data transactions are executed in an order different than they were received from the multi-port logic).

The single-port controller consists of eight sub-modules.

4.5.2.1. Command Generator

The command generator accepts commands from the MPFE and from the internal ECC logic, and provides those commands to the timer bank pool.

Related Information

Memory Controller Architecture on page 92

For more information, refer to the SDRAM Controller Block diagram.

4.5.2.2. Timer Bank Pool

The timer bank pool is a parallel queue that operates with the arbiter to enable data reordering. The timer bank pool tracks incoming requests, ensures that all timing requirements are met, and, on receiving write-data-ready notifications from the write data buffer, passes the requests to the arbiter

Related Information

Memory Controller Architecture on page 92

For more information, refer to the SDRAM Controller Block diagram.





4.5.2.3. Arbiter

The arbiter determines the order in which requests are passed to the memory device. When the arbiter receives a single request, that request is passed immediately. When multiple requests are received, the arbiter uses arbitration rules to determine the order to pass requests to the memory device.

Related Information

Memory Controller Architecture on page 92
For more information, refer to the SDRAM Controller Block diagram.

4.5.2.4. Rank Timer

The rank timer performs the following functions:

- Maintains rank-specific timing information
- Ensures that only four activates occur within a specified timing window
- · Manages the read-to-write and write-to-read bus turnaround time
- Manages the time-to-activate delay between different banks

Related Information

Memory Controller Architecture on page 92
For more information, refer to the SDRAM Controller Block diagram.

4.5.2.5. Write Data Buffer

The write data buffer receives write data from the MPFE and passes the data to the PHY, on approval of the write request.

Related Information

Memory Controller Architecture on page 92
For more information, refer to the SDRAM Controller Block diagram.

4.5.2.6. ECC Block

The ECC block consists of an encoder and a decoder-corrector, which can detect and correct single-bit errors, and detect double-bit errors. The ECC block can correct single- bit errors and detect double-bit errors resulting from noise or other impairments during data transmission.

Note: The level of ECC support is package dependent.

Related Information

Memory Controller Architecture on page 92
For more information, refer to the SDRAM Controller Block diagram.

4.5.2.7. AFI Interface

The AFI interface provides communication between the controller and the PHY.



Related Information

Memory Controller Architecture on page 92
For more information, refer to the SDRAM Controller Block diagram.

4.5.2.8. CSR Interface

The CSR interface is accessible from the L4 bus. The interface allows code in the HPS MPU or soft IP cores in the FPGA fabric to configure and monitor the SDRAM controller.

Related Information

Memory Controller Architecture on page 92
For more information, refer to the SDRAM Controller Block diagram.

4.6. Functional Description of the SDRAM Controller Subsystem

4.6.1. MPFE Operation Ordering

Operation ordering is defined and enforced within a port, but not between ports. All transactions received on a single port for overlapping addresses execute in order. Requests arriving at different ports have no guaranteed order of service, except when a first transaction has completed before the second arrives.

Avalon-MM does not support write acknowledgement. When a port is configured to support Avalon-MM, you should read from the location that was previously written to ensure that the write operation has completed. When a port is configured to support AXI, the master accessing the port can safely issue a read operation to the same address as a write operation as soon as the write has been acknowledged. To keep write latency low, writes are acknowledged as soon as the transaction order is guaranteed—meaning that any operations received on any port to the same address as the write operation are executed after the write operation.

To reduce read latency, the single-port logic can return read data out of order to the multi-port logic. The returned data is rearranged to its initial order on a per port basis by the multi-port logic and no traffic reordering occurs between individual ports.

Read Data Handling

The MPFE contains a read buffer shared by all ports. If a port is capable of receiving returned data then the read buffer is bypassed. If the size of a read transaction is smaller than twice the memory interface width, the buffer RAM cannot be bypassed. The lowest memory latency occurs when the port is ready to receive data and the full width of the interface is utilized.

4.6.2. MPFE Multi-Port Arbitration

The HPS SDRAM controller multi-port front end (MPFE) contains a programmable arbiter. The arbiter decides which MPFE port gains access to the single-port memory controller.

The SDRAM transaction size that is arbitrated is a burst of two beats. This burst size ensures that the arbiter does not favor one port over another when the incoming transaction size is a large burst.





The arbiter makes decisions based on two criteria: priority and weight. The priority is an absolute arbitration priority where the higher priority ports always win arbitration over the lower priority ports. Because multiple ports can be set to the same priority, the weight value refines the port choice by implementing a round-robin arbitration among ports set to the same priority. This programmable weight allows you to assign a higher arbitration value to a port in comparison to others such that the highest weighted port receives more transaction bandwidth than the lower weighted ports of the same priority.

Before arbitration is performed, the MPFE buffers are checked for any incoming transactions. The priority of each port that has buffered transactions is compared and the highest priority wins. If multiple ports are of the same highest priority value, the port weight is applied to determine which port wins. Because the arbiter only allows SDRAM-sized bursts into the single-port memory controller, large transactions may need to be serviced multiple times before the read or write command is fully accepted to the single-port memory controller. The MPFE supports dynamic tuning of the priority and weight settings for each port, with changes committed into the SDRAM controller at fixed intervals of time.

Arbitration settings are applied to each port of the MPFE. The memory controller supports a mix of Avalon-MM and AXI protocols. As defined in the "Port Mappings" section, the Avalon-MM ports consume a single command port while the AXI ports consume a pair of command ports to support simultaneous read and write transactions. In total, there are ten command ports for the MPFE to arbitrate. The following table illustrates the command port mapping within the HPS as well as the ports exposed to the FPGA fabric.

Table 29. HPS SDRAM MPFE Command Port Mapping

Command Port	Allowed Functions	Data Size		
0, 2, 4	FPGA fabric AXI read command ports FPGA fabric Avalon-MM read or write command ports	32-bit to 256-bit data		
1, 3, 5	FPGA fabric AXI write command ports FPGA fabric Avalon-MM read or write command ports			
6	L3 AXI read command port	32-bit data		
7	MPU AXI read command port	64-bit data		
8	L3 AXI write command port	32-bit data		
9	MPU AXI write command port	64-bit data		

When the FPGA ports are configured for AXI, the command ports are always assigned in groups of two starting with even number ports 0, 2, or 4 assigned to the read command channel. For example, if you configure the first FPGA-to-SDRAM port as AXI and the second port as Avalon-MM, you can expect the following mapping:

- Command port 0 = AXI read
- Command port 1 = AXI write
- Command port 2 = Avalon-MM read and write





Setting the MPFE Priority

The priority of each of the ten command ports is configured through the userpriority field of the mppriority register. This 30-bit register uses 3 bits per port to configure the priority. The lowest priority is 0x0 and the highest priority is 0x7. The bits are mapped in ascending order with bits [2:0] assigned to command port 0 and bits [29:27] assigned to command port 9.

Setting the MPFE Static Weights

The static weight settings used in the round-robin command port priority scheme are programmed in a 128-bit field distributed among four 32-bit registers:

- mpweight 0 4
- mpweight_1_4
- mpweight_2_4
- mpweight 3 4

Each port is assigned a 5-bit value within the 128-bit field, such that port 0 is assigned to bits [4:0] of the $mpweight_0_4$ register, port 1 is assigned to bits [9:5] of the $mpweight_0_4$ register up to port 9, which is assigned to bits[49:45] contained in the $mpweight_1_4$ register. The valid weight range for each port is 0x0 to 0x1F, with larger static weights representing a larger arbitration share.

Bits[113:50] in the mpweight_1_4, mpweight_2_4 and mpweight_3_4 registers, hold the sum of weights for each priority. This 64-bit field is divided into eight fields of 8-bits, each representing the sum of static weights. Bits[113:50] are mapped in ascending order with bits [57:50] holding the sum of static weights for all ports with priority setting 0x0, and bits [113:106] holding the sum of static weights for all ports with priority setting 0x7.

Example Using MPFE Priority and Weights

In this example, the following settings apply:

- FPGA MPFE ports 0 is assigned to AXI read commands and port 1 is assigned to AXI write commands.
- FPGA MPFE port 2 is assigned to Avalon-MM read and write commands.
- L3 master ports (ports 6 and 8) and the MPU ports (port 7 and 9) are given the lowest priority but the MPU ports are configured with more arbitration static weight than the L3 master ports.
- The FPGA MPFE command ports are given the highest priority; however, AXI ports
 0 and 1 are given a larger static weight because they carry the highest priority
 traffic in the entire system. Assigning a high priority and larger static weight
 ensures ports 0 and 1 receives the highest quality-of-service (QoS).

The table below details the port weights and sum of weights.





Table 30. SDRAM MPFE Port Priority, Weights and Sum of Weights

Priority	· ·					Sum of Weig hts					
-	Port 0	Port 1	Port 2	Port 3	Port 4	Port 5	Port 6	Port 7	Port 8	Port 9	-
1	10	10	5	0	0	0	0	0	0	0	25
0	0	0	0	0	0	0	1	4	1	4	10

If the FPGA-to-SDRAM ports are configured according to the table and if both ports are accessed concurrently, you can expect the AXI port to receive 80% of the total service. This value is determined by taking the sum of port 0 and 1 weights divided by the total weight for all ports of priority 1. The remaining 20% of bandwidth is allocated to the Avalon-MM port. With these port settings, any FPGA transaction buffered by the MPFE for either slave port blocks the MPU and L3 masters from having their buffered transactions serviced. To avoid transaction starvation, you should assign ports the same priority level and adjust the bandwidth allocated to each port by adjusting the static weights.

MPFE Weight Calculation

The MPFE applies a deficit round-robin arbitration scheme to determine which port is serviced. The larger the port weight, the more often it is serviced. Ports are serviced only when they have buffered transactions and are set to the highest priority of all the ports that also have buffered transactions. The arbiter determines which port to service by examining the running weight of all the same ports at the same priority level and the largest running weight is serviced.

Each time a port is drained of all transactions, its running weight is set to 0x80. Each time a port is serviced, the static weight is added and the sum of weights is subtracted from the running weight for that port. Each time a port is not serviced (same priority as another port but has a lower running weight), the static weight for the port is added to the running weight of the port for that particular priority level. The running weight additions and subtractions are only applied to one priority level, so any time ports of a different priority level are being serviced, the running weight of a lower priority port is not modified.



MPFE Multi-Port Arbitration Considerations for Use

When using MPFE multi-port arbitration, the following considerations apply:

 To ensure that the dynamic weight value does not roll over when a port is serviced, the following equation should always be true:

```
(sum of weights - static weight) < 128
```

If the running weight remains less than 128, arbitration for that port remains functional.

- The memory controller commits the priority and weight registers into the MPFE arbiter once every 10 SDRAM clock cycles. As a result, when the mppriority register and mpweight_*_4 registers are configured at run time, the update interval can occur while the registers are still being written and ports can have different priority or weights than intended for a brief period. Because the mppriority and mpweight_*_4 registers can be updated in a single 32-bit transaction, Intel recommends updating first to ensure that transactions that need to be serviced have the appropriate priority after the next update. Because the static weights are divided among four 32-bit registers
- In addition to the mppriority register and mpweight_*_* registers, the remappriority register adds another level of priority to the port scheduling. By programming bit N in the priorityremap field of the remappriority register, any port with an absolute priority N is sent to the front of the single port command queue and is serviced before any other transaction. Please refer to the remappriority register for more details.

The scheduler is work-conserving. Write operations can only be scheduled when enough data for the SDRAM burst has been received. Read operations can only be scheduled when sufficient internal memory is free and the port is not occupying too much of the read buffer.

4.6.3. MPFE SDRAM Burst Scheduling

SDRAM burst scheduling recognizes addresses that access the same row/bank combination, known as open page accesses. Operations to a page are served in the order in which they are received by the single-port controller. Selection of SDRAM operations is a two-stage process. First, each pending transaction must wait for its timers to be eligible for execution. Next, the transaction arbitrates against other transactions that are also eligible for execution.

The following rules govern transaction arbitration:

- High-priority operations take precedence over lower-priority operations
- If multiple operations are in arbitration, read operations have precedence over write operations
- If multiple operations still exist, the oldest is served first

A high-priority transaction in the SDRAM burst scheduler wins arbitration for that bank immediately if the bank is idle and the high-priority transaction's chip select, row, or column fields of the address do not match an address already in the single-port controller. If the bank is not idle, other operations to that bank yield until the high-priority operation is finished. If the chip select, row, and column fields match an earlier transaction, the high-priority transaction yields until the earlier transaction is completed.



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Clocking

The FPGA fabric ports of the MPFE can be clocked at different frequencies. Synchronization is maintained by clock-domain crossing logic in the MPFE. Command ports can operate on different clock domains, but the data ports associated with a given command port must be attached to the same clock as that command port.

Note:

A command port paired with a read and write port to form an Avalon-MM interface must operate at the same clock frequency as the data ports associated with it.

4.6.4. Single-Port Controller Operation

The single-port controller increases the performance of memory transactions through command and data re-ordering, enforcing bank policies, combining write operations and allowing burst transfers. Correction of single-bit errors and detection of double-bit errors is handled in the ECC module of the single-port Controller.

SDRAM Interface

The SDRAM interface is up to 40 bits wide and can accommodate 8-bit, 16-bit, 16-bit plus ECC, 32-bit, or 32-bit plus ECC configurations, depending on the device package. The SDRAM interface supports LPDDR2, DDR2, and DDR3 memory protocols.

4.6.4.1. Command and Data Reordering

The heart of the SDRAM controller is a command and data reordering engine. Command reordering allows banks for future transactions to be opened before the current transaction finishes.

Data reordering allows transactions to be serviced in a different order than they were received when that new order allows for improved utilization of the SDRAM bandwidth. Operations to the same bank and row are performed in order to ensure that operations which impact the same address preserve the data integrity.

The following figure shows the relative timing for a write/read/write/read command sequence performed in order and then the same command sequence performed with data reordering. Data reordering allows the write and read operations to occur in bursts, without bus turnaround timing delay or bank reassignment.

Figure 43. Data Reordering Effect



The SDRAM controller schedules among all pending row and column commands every clock cycle.



4.6.4.2. Bank Policy

The bank policy of the SDRAM controller allows you to request that a transaction bank remain open after an operation has finished so that future accesses do not delay in activating the same bank and row combination. The controller supports only eight simultaneously-opened banks, so an open bank might get closed if the bank resource is needed for other operations.

Open bank resources are allocated dynamically as SDRAM burst transactions are scheduled. Bank allocation is requested automatically by the controller when an incoming transaction spans multiple SDRAM bursts or by the extended command interface. When a bank must be reallocated, the least-recently-used open bank is used as the replacement.

If the controller determines that the next pending command causes the bank request to not be honored, the bank might be held open or closed depending on the pending operation. A request to close a bank with a pending operation in the timer bank pool to the same row address causes the bank to remain open. A request to leave a bank open with a pending command to the same bank but a different row address causes a precharge operation to occur.

4.6.4.3. Write Combining

The SDRAM controller combines write operations from successive bursts on a port where the starting address of the second burst is one greater than the ending address of the first burst and the resulting burst length does not overflow the 11-bit burst-length counters.

Write combining does not occur if the previous bus command has finished execution before the new command has been received.

4.6.4.4. Burst Length Support

The controller supports burst lengths of 2, 4, 8, and 16. Data widths of 8, 16, and 32 bits are supported for non-ECC operation and data widths of 24 and 40 bits are supported for operations with ECC enabled. The following table shows the type of SDRAM for each burst length.

Table 31. SDRAM Burst Lengths

Burst Length	SDRAM
4	LPDDR2, DDR2
8	DDR2, DDR3, LPDDR2
16	LPDDR2

Width Matching

The SDRAM controller automatically performs data width conversion.



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4.6.4.5. ECC

The single-port controller supports memory ECC calculated by the controller. The controller ECC employs standard Hamming logic to detect and correct single-bit errors and detect double-bit errors. The controller ECC is available for 16-bit and 32-bit widths, each requiring an additional 8 bits of memory, resulting in an actual memory width of 24-bits and 40-bits, respectively.

Note:

The level of ECC support is package dependent.

Functions the controller ECC provides are:

- Byte Writes
- ECC Write Backs
- Notification of ECC Errors

4.6.4.5.1. Byte Writes

The memory controller performs a read-modify-write operation to ensure that the ECC data remains valid when a subset of the bits of a word is being written.

Byte writes with ECC enabled are executed as a read-modify-write. Typical operations only use a single entry in the timer bank pool. Controller ECC enabled sub-word writes use two entries. The first operation is a read and the second operation is a write. These two operations are transferred to the timer bank pool with an address dependency so that the write cannot be performed until the read data has returned. This approach ensures that any subsequent operations to the same address (from the same port) are executed after the write operation, because they are ordered on the row list after the write operation.

If an entire word is being written (but less than a full burst) and the DM pins are connected, no read is necessary and only that word is updated. If controller ECC is disabled, byte-writes have no performance impact.

4.6.4.5.2. ECC Write Backs

If the controller ECC is enabled and a read operation results in a correctable ECC error, the controller corrects the location in memory, if write backs are enabled. The correction results in scheduling a new read-modify-write.

A new read is performed at the location to ensure that a write operation modifying the location is not overwritten. The actual ECC correction operation is performed as a read-modify-write operation. ECC write backs are enabled and disabled through the cfg_enable_ecc_code_overwrites field in the ctrlcfg register.

Note:

Double-bit errors do not generate read-modify-write commands. Instead, double-bit error address and count are reported through the erraddr and dbecount registers, respectively. In addition, a double-bit error interrupt can be enabled through the dramintr register.



4.6.4.5.3. User Notification of ECC Errors

When an ECC error occurs, an interrupt signal notifies the MPU subsystem, and the ECC error information is stored in the status registers. The memory controller provides interrupts for single-bit and double-bit errors.

The status of interrupts and errors are recorded in status registers, as follows:

- The dramsts register records interrupt status.
- The dramintr register records interrupt masks.
- The sbecount register records the single-bit error count.
- The dbecount register records the double-bit error count.
- The erraddr register records the address of the most recent error.

For a 32-bit interface, ECC is calculated across a span of 8 bytes, meaning the error address is a multiple of 8 bytes (4-bytes*2 burst length). To find the byte address of the word that contains the error, you must multiply the value in the erraddr register by 8.

4.6.4.6. Interleaving Options

The controller supports the following address-interleaving options:

- Non-interleaved
- Bank interleave without chip select interleave
- Bank interleave with chip select interleave

The following interleaving examples use 512 megabits (Mb) x 16 DDR3 chips and are documented as byte addresses. For RAMs with smaller address fields, the order of the fields stays the same but the widths may change.

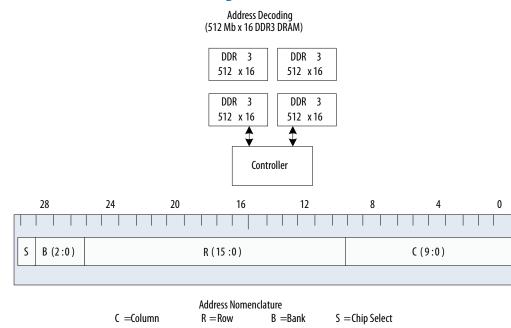
Non-interleaved

RAM mapping is non-interleaved.





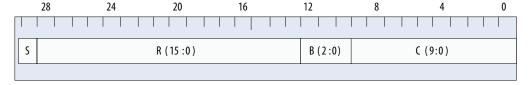
Figure 44. Non-interleaved Address Decoding



Bank Interleave Without Chip Select Interleave

Bank interleave without chip select interleave swaps row and bank from the non-interleaved address mapping. This interleaving allows smaller data structures to spread across all banks in a chip.

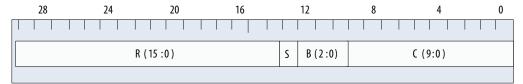
Figure 45. Bank Interleave Without Chip Select Interleave Address Decoding



Bank Interleave with Chip Select Interleave

Bank interleave with chip select interleave moves the row address to the top, followed by chip select, then bank, and finally column address. This interleaving allows smaller data structures to spread across multiple banks and chips (giving access to 16 total banks for multithreaded access to blocks of memory). Memory timing is degraded when switching between chips.

Figure 46. Bank Interleave With Chip Select Interleave Address Decoding







4.6.4.7. AXI-Exclusive Support

The single-port controller supports AXI-exclusive operations. The controller implements a table shared across all masters, which can store up to 16 pending writes. Table entries are allocated on an exclusive read and table entries are deallocated on a successful write to the same address by any master.

Any exclusive write operation that is not present in the table returns an exclusive fail as acknowledgement to the operation. If the table is full when the exclusive read is performed, the table replaces a random entry.

Note:

When using AXI-exclusive operations, accessing the same location from Avalon-MM interfaces can result in unpredictable results.

4.6.4.8. Memory Protection

The single-port controller has address protection to allow the software to configure basic protection of memory from all masters in the system. If the system has been designed exclusively with AMBA masters, TrustZone® is supported. Ports that use Avalon-MM can be configured for port level protection.

Memory protection is based on physical addresses in memory. The single-port controller can configure up to 20 rules to allow or prevent masters from accessing a range of memory based on their AxIDs, level of security and the memory region being accessed. If no rules are matched in an access, then default settings take effect.

The rules are stored in an internal protection table and can be accessed through indirect addressing offsets in the protruledwr register in the CSR. To read a specific rule, set the readrule bit and write the appropriate offset in the ruleoffset field of the protruledwr register.

To write a new rule, three registers in the CSR must be configured:

1. The protportdefault register is programmed to control the default behavior of memory accesses when no rules match. When a bit is clear, all default accesses from that port pass. When a bit is set, all default accesses from that port fails. The bits are assigned as follows:

Table 32. protportdefault register

Bits	Description
31:10	reserved
9	When this bit is set to 1, deny CPU writes during a default transaction. When this bit is clear, allow CPU writes during a default transaction.
8	When this bit is set to 1, deny L3 writes during a default transaction. When this bit is clear, allow L3 writes during a default transaction.
7	When this bit is set to 1, deny CPU reads during a default transaction. When this bit is clear, allow CPU reads during a default transaction.
6	When this bit is set to 1, deny L3 reads during a default transaction. When this bit is clear, allow L3 reads during a default transaction.
5:0	When this bit is set to 1, deny accesses from FPGA-to-SDRAM ports 0 through 5 during a default transaction.
	continued





Bits	Description	
	When this bit is clear, allow accesses from FPGA-to-SDRAM ports 0 through 5 during a default transaction.	

- 2. The protruleid register gives the bounds of the AxID value that allows an access
- 3. The protruledata register configures the specific security characteristics for a rule.

Once the registers are configured, they can be committed to the internal protection table by programming the ruleoffset field and setting the writerule bit in the protruledwr register.

Secure and non-secure regions are specified by rules containing a starting address and ending address with 1 MB boundaries for both addresses. You can override the port defaults and allow or disallow all transactions.

The following table lists the fields that you can specify for each rule.

Table 33. Fields for Rules in Memory Protection Table

Field	Width	Description
Valid	1	Set to 1 to activate the rule. Set to 0 to deactivate the rule.
Port Mask ⁽⁷⁾	10	Specifies the set of ports to which the rule applies, with one bit representing each port, as follows: bits 0 to 5 correspond to FPGA fabric ports 0 to 5, bit 6 corresponds to AXI L3 interconnect read, bit 7 is the CPU read, bit 8 is L3 interconnect write, and bit 9 is the CPU write.
AxID_low ⁽⁷⁾	12	Low transfer AxID of the rules to which this rule applies. Incoming transactions match if they are greater than or equal to this value. Ports with smaller AxIDs have the AxID shifted to the lower bits and zero padded at the top.
AxID_high (7)	12	High transfer AxID of the rules to which this rule applies. Incoming transactions match if they are less than or equal to this value.
Address_low	12	Points to a 1MB block and is the lower address. Incoming addresses match if they are greater than or equal to this value.
Address_high	12	Upper limit of address. Incoming addresses match if they are less than or equal to this value.
Protection	2	A value of 0x0 indicates that the rule applies to non-secure transactions; a value of 0x1 indicates the rule applies to non-secure transactions. Values 0x2 and 0x3 set the region to shared, meaning both secure and non-secure accesses are valid.
Fail/allow	1	Set this value to 1 to force the operation to fail or succeed.

Each port has a default access status of either allow or fail. Rules with the opposite allow/fail value can override the default. The system evaluates each transaction against every rule in the memory protection table. If a transaction arrives at a port that defaults to access allowed, it fails only if a rule with the fail bit matches the

⁽⁷⁾ Although AxID and Port Mask could be redundant, including both in the table allows possible compression of rules. If masters connected to a port do not have contiguous AxIDs, a port-based rule might be more efficient than an AxID-based rule, in terms of the number of rules needed.





transaction. Conversely, if a transaction arrives at a port that has the default rule set to access denied, it allows access only if there is a matching rule that forces accessed allowed. Transactions that fail the protection rules return a slave error (SLVERR).

The recommended sequence for writing a rule is:

- 1. Write the protruledwr register fields as follows:
 - ruleoffset = offset selected by user that points to indirect offset in an internal protection table..
 - writerule = 0
 - readrule = 0
- 2. Write the protruleaddr, protruleid, and protruledata registers so you configure the rule you would like to enforce.
- 3. Write the protruledwr register fields as follows:
 - ruleoffset = offset of the rule that needs to be written
 - writerule = 1
 - readrule = 0

Similarly, the recommended sequence for reading a rule is:

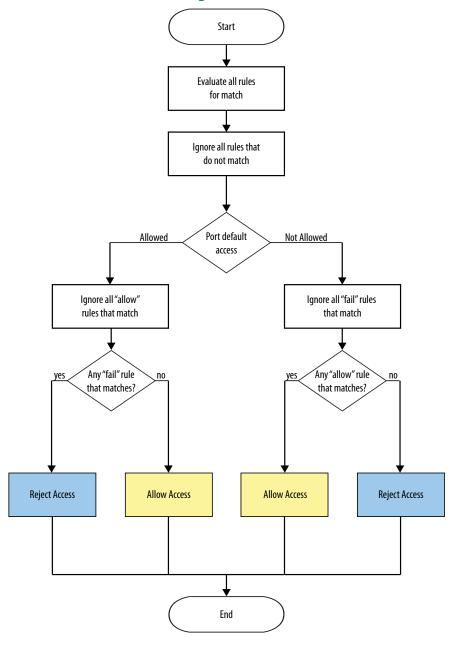
- 1. Write the protruledwr register fields as follows:
 - ruleoffset = offset of the rule that needs to be written
 - writerule = 0
 - readrule = 0
- 2. Write the protruledwr register fields as follows:
 - ruleoffset = offset of the rule that needs to be read
 - writerule = 0
 - readrule = 1
- 3. Read the values of the protruleaddr, protruleid, and protruledata registers to determine the rule parameters.

The following figure represents an overview of how the protection rules are applied. There is no priority among the 20 rules. All rules are always evaluated in parallel.





Figure 47. SDRAM Protection Access Flow Diagram



Exclusive transactions are security checked on the read operation only. A write operation can occur only if a valid read is marked in the internal exclusive table. Consequently, a master performing an exclusive read followed by a write, can write to memory only if the exclusive read was successful.

Related Information

ARM TrustZone*

For more information about TrustZone* refer to the ARM website.





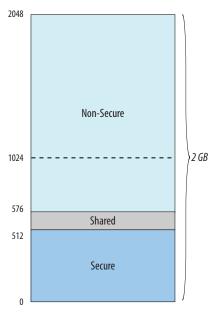
4.6.4.9. Example of Configuration for TrustZone

For a TrustZone* configuration, memory is TrustZone divided into a range of memory accessible by secure masters and a range of memory accessible by non-secure masters. The two memory address ranges may have a range of memory that overlaps.

This example implements the following memory configuration:

- 2 GB total RAM size
- 0-512 MB dedicated secure area
- 513-576 MB shared area
- 577—2048 MB dedicated non-secure area

Figure 48. Example Memory Configuration



In this example, each port is configured by default to disallow all accesses. The following table shows the two rules programmed into the memory protection table.

Table 34. Rules in Memory Protection Table for Example Configuration

Rule #	Port Mask	AxID Low	AxID High	Address Low	Address High	protruledata.security	Fail/Allow
1	0x3FF (1023)	0x000	0xFFF (4095)	0	576	0x1	Allow
2	0x3FF (1023)	0x000	0xFFF (4095)	512	2047	0x0	Allow

The port mask value, AxID Low, and AxID High, apply to all ports and all transfers within those ports. Each access request is evaluated against the memory protection table, and fails unless there is a rule match allowing a transaction to complete successfully.





Table 35. Result for a Sample Set of Transactions

Operation	Source	Address Accesses	Security Access Type	Result	Comments
Read	СРИ	4096	secure	Allow	Matches rule 1.
Write	СРИ	536, 870, 912	secure	Allow	Matches rule 1.
Write	L3 attached masters	605, 028, 350	secure	Fail	Does not match rule 1 (out of range of the address field), does not match rule 2 (protection bit incorrect).
Read	L3 attached masters	4096	non-secure	Fail	Does not match rule 1 (AxPROT signal value wrong), does not match rule 2 (not in address range).
Write	СРИ	536, 870, 912	non-secure	Allow	Matches rule 2.
Write	L3 attached masters	605, 028, 350	non-secure	Allow	Matches rule 2.

Note:

If a master is using the Accelerator Coherency Port (ACP) to maintain cache coherency with the Cortex-A9 MPCore processor, then the address ranges in the rules of the memory protection table should be made mutually exclusive, such that the secure and non-secure regions do not overlap and any area that is shared is part of the non-secure region. This configuration prevents coherency issues from occurring.

4.7. SDRAM Power Management

The SDRAM controller subsystem supports the following power saving features in the SDRAM:

- Partial array self-refresh (PASR)
- Power down
- Deep power down for LPDDR2

To enable self-refresh for the memories of one or both chip selects, program the selfshreq bit and the sefrfshmask bit in the lowpwreq register.

Power-saving mode initiates either due to a user command or from inactivity. The number of idle clock cycles after which a memory can be put into power-down mode is programmed through the autopdycycles field of the lowpwrtiming register.

Power-down mode forces the SDRAM burst-scheduling bank-management logic to close all banks and issue the power down command. The SDRAM automatically reactivates when an active SDRAM command is received.

To enable deep power down request for the LPDDR2 memories of one or both chip selects, program the deeppwrdnreq bit and the deepwrdnmask field of the lowpwreq register.

Other power-down modes are performed only under user control.



4.8. DDR PHY

The DDR PHY connects the memory controller and external memory devices in the speed critical command path.

The DDR PHY implements the following functions:

- Calibration—the DDR PHY supports the JEDEC-specified steps to synchronize the memory timing between the controller and the SDRAM chips. The calibration algorithm is implemented in software.
- Memory device initialization—the DDR PHY performs the mode register write operations to initialize the devices. The DDR PHY handles re-initialization after a deep power down.
- Single-data-rate to double-data-rate conversion.

4.9. Clocks

All clocks are assumed to be asynchronous with respect to the ddr_dqs_clk memory clock. All transactions are synchronized to memory clock domain.

Table 36. SDRAM Controller Subsystem Clock Domains

Clock Name	Description
ddr_dq_clk	Clock for PHY
ddr_dqs_clk	Clock for MPFE, single-port controller, CSR access, and PHY
ddr_2x_dqs_clk	Clock for PHY that provides up to 2 times ddr_dq_clk frequency
14_sp_clk	Clock for CSR interface
mpu_12_ram_clk	Clock for MPU interface
13_main_clk	Clock for L3 interface
f2h_sdram_c1k[5:0]	Six separate clocks used for the FPGA-to-HPS SDRAM ports to the FPGA fabric

In terms of clock relationships, the FPGA fabric connects the appropriate clocks to write data, read data, and command ports for the constructed ports.

4.10. Resets

The SDRAM controller subsystem supports a full reset (cold reset) and a warm reset. The SDRAM controller can be configured to preserve memory contents during a warm reset.

To preserve memory contents, the reset manager can request that the single-port controller place the SDRAM in self-refresh mode prior to issuing the warm reset. If self-refresh mode is enabled before the warm reset to preserve memory contents, the PHY and the memory timing logic is not reset, but the rest of the controller is reset.





4.10.1. Taking the SDRAM Controller Subsystem Out of Reset

When a cold or warm reset is issued in the HPS, the Reset Manager resets this module and holds it in reset until software releases it.

After the MPU boots up, it can deassert the reset signal by clearing the appropriate bits in the Reset Manager's corresponding reset trigger.

4.11. Port Mappings

The memory interface controller has a set of command, read data, and write data ports that support AXI3, AXI4 and Avalon-MM. Tables are provided to identify port assignments and functions.

Table 37. Command Port Assignments

Command Port	Allowed Functions	
0, 2, 4	FPGA fabric AXI read command ports FPGA fabric Avalon-MM read or write command ports	
1, 3, 5	FPGA fabric AXI write command ports FPGA fabric Avalon-MM read or write command ports	
6	L3 AXI read command port	
7	MPU AXI read command port	
8	L3 AXI write command port	
9	MPU AXI write command port	

Table 38. Read Port Assignments

Read Port	Allowed Functions
0, 1, 2, 3	64-bit read data from the FPGA fabric. When 128-bit data read ports are created, then read data ports 0 and1 get paired as well as 2 and 3.
4	32-bit L3 read data port
5	64-bit MPU read data port

Table 39. Write Port Assignments

Write Port	Allowed Functions
0, 1, 2, 3	64-bit write data from the FPGA fabric. When 128-bit data write ports are created, then write data ports 0 and 1 get paired as well as 2 and 3.
4	32-bit L3 write data port
5	64-bit MPU write data port

4.12. Initialization

The SDRAM controller subsystem has control and status registers (CSRs) which control the operation of the controller including DRAM type, DRAM timing parameters and relative port priorities. It also has a small set of bits which depend on the FPGA fabric to configure ports between the memory controller and the FPGA fabric; these bits are set for you when you configure your implementation using the HPS GUI in Platform Designer (Standard).



The CSRs are configured using a dedicated slave interface, which provides access to the registers. This region controls all SDRAM operation, MPFE scheduler configuration, and PHY calibration.

The FPGA fabric interface configuration is programmed into the FPGA fabric and the values of these register bits can be read by software. The ports can be configured without software developers needing to know how the FPGA-to-HPS SDRAM interface has been configured.

4.12.1. FPGA-to-SDRAM Protocol Details

The following topics summarize signals for the Avalon-MM Bidirectional port, Avalon-MM Write Port, Avalon-MM Read Port, and AXI port.

Note:

If your device has multiple FPGA hardware images, then the same FPGA-to-SDRAM port configuration should be used across all designs.

4.12.1.1. Avalon-MM Bidirectional Port

The Avalon-MM bidirectional ports are standard Avalon-MM ports used to dispatch read and write operations.

Each configured Avalon-MM bidirectional port consists of the signals listed in the following table.

Table 40. Avalon-MM Bidirectional Port Signals

Name	Bit Width	Input/Output Direction	Function
clk	1	In	Clock for the Avalon-MM interface
read	1	In	Indicates read transaction (8)
write	1	In	Indicates write transaction (8)
address	32	In	Address of the transaction
readdata	32, 64, 128, or 256	Out	Read data return
readdatavalid	1	Out	Indicates the readdata signal contains valid data in response to a previous read request.
writedata	32, 64, 128, or 256	In	Write data for a transaction
byteenable	4, 8, 16, 32	In	Byte enables for each write byte lane
waitrequest	1	Out	Indicates need for additional cycles to complete a transaction
burstcount	11	In	Transaction burst length. The value of the maximum burstcount parameter must be a power of 2.

⁽⁸⁾ The Avalon-MM protocol does not allow read and write transactions to be posted concurrently.





The read and write interfaces are configured to the same size. The byte-enable size scales with the data bus size.

Related Information

Avalon Interface Specifications

Information about the Avalon-MM protocol

4.12.1.2. Avalon-MM Write-Only Port

The Avalon-MM write-only ports are standard Avalon-MM ports used to dispatch write operations. Each configured Avalon-MM write port consists of the signals listed in the following table.

Table 41. Avalon-MM Write-Only Port Signals

Name	Bits	Direction	Function
reset	1	In	Reset
clk	1	In	Clock
write	1	In	Indicates write transaction
address	32	In	Address of the transaction
writedata	32, 64, 128, or 256	In	Write data for a transaction
byteenable	4, 8, 16, 32	In	Byte enables for each write byte
waitrequest	1	Out	Indicates need for additional cycles to complete a transaction
burstcount	11	In	Transaction burst length

Related Information

Avalon Interface Specifications

Information about the Avalon-MM protocol

4.12.1.3. Avalon-MM Read Port

The Avalon-MM read ports are standard Avalon-MM ports used only to dispatch read operations. Each configured Avalon-MM read port consists of the signals listed in the following table.

Table 42. Avalon-MM Read Port Signals

Name	Bits	Direction	Function	
reset	1	In	Reset	
clk	1	In	Clock	
read	1	In	Indicates read transaction	
address	32	In	Address of the transaction	
continued				





Name	Bits	Direction	Function
readdata	32, 64, 128, or 256	Out	Read data return
readdatavalid	1	Out	Flags valid cycles for read data return
waitrequest	1	Out	Indicates the need for additional cycles to complete a transaction. Needed for read operations when delay is needed to accept the read command.
burstcount	11	In	Transaction burst length

Related Information

Avalon Interface Specifications

Information about the Avalon-MM protocol

4.12.1.4. AXI Port

The AXI port uses an AXI-3 interface. Each configured AXI port consists of the signals listed in the following table. Because the AXI protocol allows simultaneous read and write commands to be issued, two SDRAM control ports are required to form an AXI interface.

Table 43. AXI Port Signals

Name	Bits	Direction	Channel	Function
ARESETn	1	In	n/a	Reset
ACLK	1	In	n/a	Clock
AWID	4	In	Write address	Write identification tag
AWADDR	32	In	Write address	Write address
AWLEN	4	In	Write address	Write burst length
AWSIZE	3	In	Write address	Width of the transfer size
AWBURST	2	In	Write address	Burst type
AWLOCK	2	In	Write address	Lock type signal which indicates if the access is exclusive; valid values are 0x0 (normal access) and 0x1 (exclusive access)
AWCACHE	4	In	Write address	Cache policy type
AWPROT	3	In	Write address	Protection-type signal used to indicate whether a transaction is secure or non-secure
AWREADY	1	Out	Write address	Indicates ready for a write command
AWVALID	1	In	Write address	Indicates valid write command.
WID	4	In	Write data	Write data transfer ID
WDATA	32, 64, 128 or 256	In	Write data	Write data
WSTRB	4, 8, 16, 32	In	Write data	Byte-based write data strobe. Each bit width corresponds to 8 bit wide transfer for 32-bit wide to 256-bit wide transfer.
			•	continued





Name	Bits	Direction	Channel	Function
WLAST	1	In	Write data	Last transfer in a burst
WVALID	1	In	Write data	Indicates write data and strobes are valid
WREADY	1	Out	Write data	Indicates ready for write data and strobes
BID	4	Out	Write response	Write response transfer ID
BRESP	2	Out	Write response	Write response status
BVALID	1	Out	Write response	Write response valid signal
BREADY	1	In	Write response	Write response ready signal
ARID	4	In	Read address	Read identification tag
ARADDR	32	In	Read address	Read address
ARLEN	4	In	Read address	Read burst length
ARSIZE	3	In	Read address	Width of the transfer size
ARBURST	2	In	Read address	Burst type
ARLOCK	2	In	Read address	Lock type signal which indicates if the access is exclusive; valid values are 0x0 (normal access) and 0x1 (exclusive access)
ARCACHE	4	In	Read address	Lock type signal which indicates if the access is exclusive; valid values are 0x0 (normal access) and 0x1 (exclusive access)
ARPROT	3	In	Read address	Protection-type signal used to indicate whether a transaction is secure or non-secure
ARREADY	1	Out	Read address	Indicates ready for a read command
ARVALID	1	In	Read address	Indicates valid read command
RID	4	Out	Read data	Read data transfer ID
RDATA	32, 64, 128 or 256	Out	Read data	Read data
RRESP	2	Out	Read data	Read response status
RLAST	1	Out	Read data	Last transfer in a burst
RVALID	1	Out	Read data	Indicates read data is valid
RREADY	1	In	Read data	Read data channel ready signal

Related Information

ARM AMBA Open Specification

For information on AMBA Open Specifications, including information about the AXI-3 interface, refer to the ARM website.

4.13. SDRAM Controller Subsystem Programming Model

SDRAM controller configuration occurs through software programming of the configuration registers using the CSR interface.





4.13.1. HPS Memory Interface Architecture

The configuration and initialization of the memory interface by the Arm processor is a significant difference compared to the FPGA memory interfaces, and results in several key differences in the way the HPS memory interface is defined and configured.

Boot-up configuration of the HPS memory interface is handled by the initial software boot code, not by the FPGA programmer, as is the case for the FPGA memory interfaces. The Intel Quartus Prime software is involved in defining the configuration of I/O ports which is used by the boot-up code, as well as timing analysis of the memory interface. Therefore, the memory interface must be configured with the correct PHY-level timing information. Although configuration of the memory interface in Platform Designer (Standard) is still necessary, it is limited to PHY- and board-level settings.

4.13.2. HPS Memory Interface Configuration

To configure the external memory interface components of the HPS, open the HPS interface by selecting the Arria V/Cyclone V Hard Processor System component in Platform Designer (Standard). Within the HPS interface, select the EMIF tab to open the EMIF parameter editor.

The EMIF parameter editor contains four additional tabs: PHY Settings, Memory Parameters, Memory Timing, and Board Settings. The parameters available on these tabs are similar to those available in the parameter editors for non-SoC device families.

There are significant differences between the EMIF parameter editor for the Hard Processor System and the parameter editors for non-SoC devices, as follows:

- Because the HPS memory controller is not configurable through the Intel Quartus Prime software, the Controller and Diagnostic tabs, which exist for non-SoC devices, are not present in the EMIF parameter editor for the hard processor system.
- Unlike the protocol-specific parameter editors for non-SoC devices, the EMIF parameter editor for the Hard Processor System supports multiple protocols, therefore there is an SDRAM Protocol parameter, where you can specify your external memory interface protocol. By default, the EMIF parameter editor assumes the DDR3 protocol, and other parameters are automatically populated with DDR3-appropriate values. If you select a protocol other than DDR3, change other associated parameter values appropriately.
- Unlike the memory interface clocks in the FPGA, the memory interface clocks for the HPS are initialized by the boot-up code using values provided by the configuration process. You may accept the values provided by UniPHY, or you may use your own PLL settings. If you choose to specify your own PLL settings, you must indicate that the clock frequency that UniPHY should use is the requested clock frequency, and not the achieved clock frequency calculated by UniPHY.

Note:

The HPS does not support EMIF synthesis generation, compilation, or timing analysis. The HPS hard memory controller cannot be bonded with another hard memory controller on the FPGA portion of the device.





4.13.3. HPS Memory Interface Simulation

Platform Designer (Standard) provides a complete simulation model of the HPS memory interface controller and PHY, providing cycle-level accuracy, comparable to the simulation models for the FPGA memory interface.

The simulation model supports only the skip-cal simulation mode; quick-cal and full-cal are not supported. An example design is not provided. However, you can create a test design by adding the traffic generator component to your design using Platform Designer (Standard). Also, the HPS simulation model does not use external memory pins to connect to the DDR memory model; instead, the memory model is incorporated directly into the HPS SDRAM interface simulation modules. The memory instance incorporated into the HPS model is in the simulation model hierarchy at: hps 0/fpga interfaces/f2sdram/hps sdram inst/mem/

Simulation of the FPGA-to-SDRAM interfaces requires that you first bring the interfaces out of reset, otherwise transactions cannot occur. Connect the H2F reset to the F2S port resets and add a stage to your testbench to assert and deassert the H2F reset in the HPS. Appropriate Verilog code is shown below:

```
initial
begin
   // Assert reset
   <base name>.hps.fpga_interfaces.h2f_reset_inst.reset_assert();
   // Delay
   #1
   // Deassert reset
   <base name>.hps.fpga_interfaces.h2f_reset_inst.reset_deassert();
end
```

4.13.4. Generating a Preloader Image for HPS with EMIF

To generate a preloader image for an HPS-based external memory interface, you must complete the following tasks:

- Create a project in Platform Designer (Standard).
- Create a top-level file and add constraints.
- Create a preloader BSP file.
- Create a preloader image.

4.13.4.1. Creating a Project in Platform Designer (Standard)

Before you can generate a preloader image, you must create a project in Platform Designer (Standard), as follows:

- 1. On the **Tools** menu in the Intel Quartus Prime software, click **Platform Designer** (**Standard**).
- 2. Under Component library, expand Embedded Processor System, select Hard Processor System and click Add.
- 3. Specify parameters for the **FPGA Interfaces**, **Peripheral Pin Multiplexing**, and **HPS Clocks**, based on your design requirements.
- 4. On the **SDRAM** tab, select the SDRAM protocol for your interface.
- 5. Populate the necessary parameter fields on the **PHY Settings**, **Memory Parameters**, **Memory Timing**, and **Board Settings** tabs.





- 6. Add other components in your design and make the appropriate bus connections.
- 7. Save the project.
- 8. Click **Generate** on the **Generation** tab. Platform Designer (Standard) generates the design.

4.13.4.2. Creating a Top-Level File and Adding Constraints

This topic describes adding your Platform Designer (Standard) system to your toplevel design and adding constraints to your design.

- 1. Add your Platform Designer (Standard) system to your top-level design.
- 2. Add the Intel Quartus Prime IP files (.qip) generated in step 2, to your Intel Quartus Prime project.
- 3. Perform analysis and synthesis on your design.
- 4. Constrain your EMIF design by running the <variation_name>_p0_pin_assignments.tcl pin constraints script.
- 5. Add other necessary constraints—such as timing constraints, location assignments, and pin I/O standard assignments—for your design.
- 6. Compile your design to generate an SRAM object file (.sof) and the hardware handoff files necessary for creating a preloader image.

Note: You must regenerate the hardware handoff files whenever the HPS configuration changes; for example, due to changes in Peripheral Pin Multiplexing or I/O standard for HPS pins.

Related Information

Intel SoC FPGA Embedded Design Suite User's Guide

For more information on how to create a preloader BSP file and image.

4.14. Debugging HPS SDRAM in the Preloader

To assist in debugging your design, tools are available at the preloader stage.

- UART or semihosting printout
- Simple memory test
- Debug report
- Predefined data patterns

The following topics provide procedures for implementing each of the above tools.

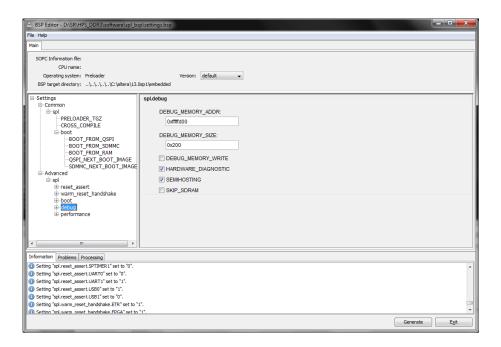
4.14.1. Enabling UART or Semihosting Printout

UART printout is enabled by default. If UART is not available on your system, you can use semihosting together with the debugger tool. To enable semihosting in the Preloader, follow these steps:

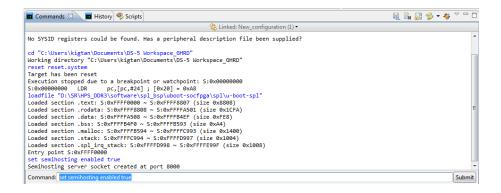
When you create the .bsp file in the BSP Editor, select **SEMIHOSTING** in the spl.debug window.







2. Enable semihosting in the debugger, by typing set semihosting enabled true at the command line in the debugger.



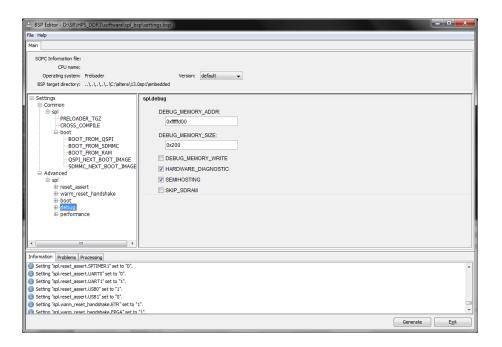
4.14.2. Enabling Simple Memory Test

After the SDRAM is successfully calibrated, a simple memory test may be performed using the debugger.

 When you create the .bsp file in the BSP Editor, select HARDWARE_DIAGNOSTIC in the spl.debug window.







2. The simple memory test assumes SDRAM with a memory size of 1 GB. If your board contains a different SDRAM memory size, open the file <design folder> \spl_bsp\uboot-socfpga\include\configs\socfpga_cyclone5.h in a text editor, and change the PHYS_SDRAM_1_SIZE parameter at line 292 to specify your actual memory size in bytes.

```
socfpga_cyclone5.h
        * Hardware drivers
279
281 🗐/*
       * SDRAM Memory Map
282
283
       /* We have 1 bank of DRAM */
284
      #define CONFIG_NR_DRAM_BANKS
285
                                         1
286
       /* SDRAM Bank #1 */
287
       #define CONFIG SYS SDRAM BASE
                                       0x00000000
       /* SDRAM memory size */
288
289 ##ifdef CONFIG_SOCFPGA_VIRTUAL_TARGET
       #define PHYS_SDRAM_1_SIZE
290
                                     0x80000000
291
       #else
292
       define PHYS_SDRAM_1_SIZE 0x40000000
293
       #endif
294
       /* SDRAM Bank #1 base address */
       #define PHYS SDRAM_1
                                     CONFIG SYS SDRAM BASE
295
296
       /* memtest setup */
       /* Begin and end addresses of the area used by the simple memory test.c */
297
       #define CONFIG_SYS_MEMTEST_START 0x00000000
298
       #define CONFIG_SYS_MEMTEST_END
299
                                      PHYS SDRAM 1 SIZE
300
```

3. The simple memory test assumes SDRAM with a memory size of 1 GB. If your board contains a different SDRAM memory size, open the file <design folder> \spl_bsp\uboot-socfpga\include\configs\socfpga_arria5.h in a text editor, and change the PHYS_SDRAM_1_SIZE parameter at line 292 to specify your actual memory size in bytes.



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```
socfpga_cyclone5.h
         * Hardware drivers
280
281
282
        * SDRAM Memory Map
283
        /* We have 1 bank of DRAM */
284
        #define CONFIG NR DRAM BANKS
285
        /* SDRAM Bank #1 */
286
287
        #define CONFIG SYS SDRAM BASE
                                           0x00000000
288
        /* SDRAM memory size */
     #ifdef CONFIG_SOCFPGA_VIRTUAL_TARGET
289
290
        #define PHYS_SDRAM_1_SIZE
                                        0x80000000
291
        #else
        #define PHYS SDRAM 1 SIZE 0x40000000
292
293
        #endif
294
        /* SDRAM Bank #1 base address */
        #define PHYS_SDRAM_1
                                        CONFIG_SYS_SDRAM_BASE
295
296
        /* memtest setup */
297
        /* Begin and end addresses of the area used by the simple memory test.c ^{*}/
        #define CONFIG_SYS_MEMTEST_START 0x00000000
#define CONFIG_SYS_MEMTEST_END PHYS_SDRAM_1_SIZE
298
299
300
```

4.14.3. Enabling the Debug Report

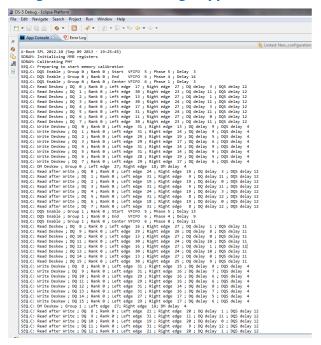
You can enable the SDRAM calibration sequencer to produce a debug report on the UART printout or semihosting output. To enable the debug report, follow these steps:

- 1. After you have enabled the UART or semihosting, open the file roject
 directory>\hps_isw_handoff\sequencer_defines.hin a text editor.
- 2. Locate the line #define RUNTIME_CAL_REPORT 0 and change it to #define RUNTIME_CAL_REPORT 1.





Figure 49. Semihosting Printout With Debug Support Enabled



4.14.3.1. Analysis of Debug Report

The following analysis helps you interpret the debug report.

- The Read Deskew and Write Deskew results shown in the debug report are before calibration. (Before calibration results are actually from the window seen during calibration, and are most useful for debugging.)
- For each DQ group, the Write Deskew, Read Deskew, DM Deskew, and Read after Write results map to the before-calibration margins reported in the EMIF Debug Toolkit.

Note: The Write Deskew, Read Deskew, DM Deskew, and Read after Write results are reported in delay steps (nominally 25ps, in Arria V and Cyclone V devices), not in picoseconds.

 DQS Enable calibration is reported as a VFIFO setting (in one clock period steps), a phase tap (in one-eighth clock period steps), and a delay chain step (in 25ps steps).

```
SEQ.C: DQS Enable; Group 0; Rank 0; Start VFIFO 5; Phase 6; Delay 4
SEQ.C: DQS Enable; Group 0; Rank 0; End VFIFO 6; Phase 5; Delay 9
SEQ.C: DQS Enable; Group 0; Rank 0; Center VFIFO 6; Phase 2; Delay 1
```

Analysis of DQS Enable results: A VFIFO tap is 1 clock period, a phase is 1/8 clock period (45 degrees) and delay is nominally 25ps per tap. The DQSen window is the difference between the start and end—for the above example, assuming a frequency of 400 MHz (2500ps), that calculates as follows: start is 5*2500 + 6*2500/8 + 4*25 = 14475ps. By the same calculation, the end is 16788ps. Consequently, the DQSen window is 2313ps.





• The size of a read window or write window is equal to (left edge + right edge) * delay chain step size. Both the left edge and the right edge can be negative or positive.:

```
SEQ.C: Read Deskew ; DQ 0 ; Rank 0 ; Left edge 18 ; Right edge 27 ; DQ delay 0 ; DQS delay 8
SEQ.C: Write Deskew ; DQ 0 ; Rank 0 ; Left edge 30 ; Right edge 17 ; DQ delay 6 ; DQS delay 4
```

Analysis of DQ and DQS delay results: The DQ and DQS output delay (write) is the D5 delay chain. The DQ input delay (read) is the D1 delay chain, the DQS input delay (read) is the D4 delay chain.

• Consider the following example of latency results:

```
SEQ.C: LFIFO Calibration ; Latency 10
```

Analysis of latency results: This is the calibrated PHY read latency. The EMIF Debug Toolkit does not report this figure. This latency is reported in clock cycles.

Consider the following example of FOM results:

```
SEQ.C: FOM IN = 83
SEQ.C: FOM OUT = 91
```

Analysis of FOM results: The FOM IN value is a measure of the health of the read interface; it is calculated as the sum over all groups of the minimum margin on DQ plus the margin on DQS, divided by 2. The FOM OUT is a measure of the health of the write interface; it is calculated as the sum over all groups of the minimum margin on DQ plus the margin on DQS, divided by 2. You may refer to these values as indicators of improvement when you are experimenting with various termination schemes, assuming there are no individual misbehaving DQ pins.

• The debug report does not provide delay chain step size values. The delay chain step size varies with device speed grade. Refer to your device data sheet for exact incremental delay values for delay chains.

Related Information

Functional Description-UniPHY

For more information about calibration, refer to the *Calibration Stages* section in the *Functional Description-UniPHY* chapter of the *External Memory Interface Handbook* .

4.14.4. Writing a Predefined Data Pattern to SDRAM in the Preloader

You can include your own code to write a predefined data pattern to the SDRAM in the preloader for debugging purposes.

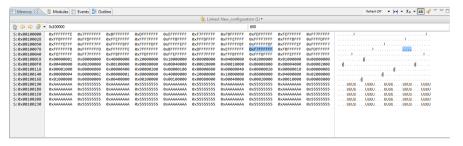
Adding the following code to the ${\tt spl.c}$ file causes the controller to write walking 1s and walking 0s, repeated five times, to the SDRAM.





```
ulong
                  data_temp[3];
                      expected_data[3];
       ulong
   ulong
                  read_data;
                     i = 0; //counter to loop different data pattern
       int
       int.
                    num_address;
      num_address=50;
      data_temp[1]=0X00000001; //initial data for walking 1 pattern
      data_temp[2]=0XAAAAAAAA; //initial data for A->5 switching
      expected_data[0]=0XFFFFFFE; //initial data for walking 0 pattern
      expected_data[1]=0X00000001; //initial data for walking 1 pattern
      expected_data[2]=0XAAAAAAA; //initial data for A->5 switching
      for (i=0;i<3;i++) {
   printf("\nSTARTED %08X DATA PATTERN !!!!\n",data_temp[i]);
    /*write*/
   for (cnt = (0+i*num\_address); cnt < ((i+1)*num\_address); cnt++) {
       addr = base + cnt;  /* pointer arith! */
       sync ();
          *addr = data_temp[i];
       data_temp[i]=ROTATE_RIGHT(data_temp[i]);
   /*read*/
   for (cnt = (0+i*num\_address); cnt < ((i+1)*num\_address); cnt = cnt++ ) {
       addr = base + cnt; /* pointer arith! */
       sync ();
       read_data=*addr;
             printf("Address:%X Expected: %08X Read:%08X \n",addr,
expected_data[i],read_data);
             if (expected_data[i] !=read_data) {
              puts("!!!!!FAILED!!!!!\n\n");
       hang();
           }
               expected_data[i]=ROTATE_RIGHT(expected_data[i]);
====//End Of Code//=====
```

Figure 50. Memory Contents After Executing Example Code



4.15. SDRAM Controller Address Map and Register Definitions

This section lists the SDRAM register address map and describes the registers.

4.15.1. SDRAM Controller Address Map

Address map for the SDRAM Interface registers





Base Address: 0xFFC20000

SDRAM Controller Module

Register	Offset	Width	Acces	Reset Value	Description
ctrlcfg on page 129	0x5000	32	RW	0x0	Controller Configuration Register
dramtiming1 on page 131	0x5004	32	RW	0x0	DRAM Timings 1 Register
dramtiming2 on page 131	0x5008	32	RW	0x0	DRAM Timings 2 Register
dramtiming3 on page 132	0x500C	32	RW	0x0	DRAM Timings 3 Register
dramtiming4 on page 133	0x5010	32	RW	0x0	DRAM Timings 4 Register
lowpwrtiming on page 134	0x5014	32	RW	0x0	Lower Power Timing Register
dramodt on page 134	0x5018	32	RW	0x0	ODT Control Register
dramaddrw on page 135	0x502C	32	RW	0x0	DRAM Address Widths Register
dramifwidth on page 136	0x5030	32	RW	0x0	DRAM Interface Data Width Register
dramsts on page 137	0x5038	32	RW	0x0	DRAM Status Register
dramintr on page 137	0x503C	32	RW	0x0	ECC Interrupt Register
sbecount on page 138	0x5040	32	RW	0x0	ECC Single Bit Error Count Register
dbecount on page 139	0x5044	32	RW	0x0	ECC Double Bit Error Count Register
erraddr on page 139	0x5048	32	RW	0x0	ECC Error Address Register
dropcount on page 140	0x504C	32	RW	0x0	ECC Auto-correction Dropped Count Register
dropaddr on page 140	0x5050	32	RW	0x0	ECC Auto-correction Dropped Address Register
lowpwreq on page 141	0x5054	32	RW	0x0	Low Power Control Register
lowpwrack on page 142	0x5058	32	RW	0x0	Low Power Acknowledge Register
staticcfg on page 143	0x505C	32	RW	0x0	Static Configuration Register
ctrlwidth on page 143	0x5060	32	RW	0x0	Memory Controller Width Register
portcfg on page 144	0x507C	32	RW	0x0	Port Configuration Register
fpgaportrst on page 146	0x5080	32	RW	0x0	FPGA Ports Reset Control Register
protportdefault on page 147	0x508C	32	RW	0x0	Memory Protection Port Default Register
protruleaddr on page 148	0x5090	32	RW	0x0	Memory Protection Address Register
protruleid on page 148	0x5094	32	RW	0x0	Memory Protection ID Register
protruledata on page 149	0x5098	32	RW	0x0	Memory Protection Rule Data Register
protrulerdwr on page 150	0x509C	32	RW	0x0	Memory Protection Rule Read-Write Register
mppriority on page 151	0x50AC	32	RW	0x0	Scheduler priority Register
remappriority on page 152	0x50E0	32	RW	0x0	Controller Command Pool Priority Remap Register



Port Sum of Weight Register

Register	Offset	Width	Acces	Reset Value	Description
mpweight_0_4 on page 153	0x50B0	32	RW	0x0	Port Sum of Weight Register[1/4]
mpweight_1_4 on page 153	0x50B4	32	RW	0x0	Port Sum of Weight Register[2/4]
mpweight_2_4 on page 154	0x50B8	32	RW	0x0	Port Sum of Weight Register[3/4]
mpweight_3_4 on page 154	0x50BC	32	RW	0x0	Port Sum of Weight Register[4/4]

4.15.1.1. SDRAM Controller Module Register Descriptions

Address map for the SDRAM controller and multi-port front-end. All registers in this group reset to zero.

Offset: 0x5000

ctrlcfg on page 129

dramtiming1 on page 131

dramtiming2 on page 131

dramtiming3 on page 132

dramtiming4 on page 133

lowpwrtiming on page 134

dramodt on page 134

dramaddrw on page 135

dramifwidth on page 136

dramsts on page 137

dramintr on page 137

sbecount on page 138

dbecount on page 139

erraddr on page 139

dropcount on page 140

dropaddr on page 140

lowpwreq on page 141

lowpwrack on page 142

staticcfg on page 143

ctrlwidth on page 143

portcfg on page 144

fpgaportrst on page 146

protportdefault on page 147

protruleaddr on page 148

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protrulerdwr on page 150
mppriority on page 151
remappriority on page 152
Port Sum of Weight Register Register Descriptions on page 153

4.15.1.1.1 ctrlcfg

The Controller Configuration Register determines the behavior of the controller.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25000

Offset: 0x5000

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

							Bit F	ields							
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved						burst intre n RW 0x0	nodmp ins RW 0x0	dqstr ken RW 0x0	starvelimit RW 0x0					
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
reord eren RW 0x0	gendb e RW 0x0	gensb e RW 0x0	cfg_e nable _ecc_ code_ overw rites RW 0x0	eccco rren RW 0x0	eccen RW 0x0		order 0x0	membl RW 0x0						memtype RW 0x0	

ctrlcfg Fields

Bit	Name	Description	Access	Reset
25	bursttermen	Set to a one to enable the controller to issue burst terminate commands. This must only be set when the DRAM memory type is LPDDR2.	RW	0x0
24	burstintren	Set to a one to enable the controller to issue burst interrupt commands. This must only be set when the DRAM memory type is LPDDR2.	RW	0x0
23	nodmpins	Set to a one to enable DRAM operation if no DM pins are connected.	RW	0x0
22	dqstrken	Enables DQS tracking in the PHY.	RW	0x0
21:1 6	starvelimit Specifies the number of DRAM burst transactions an individual transaction will allow to reorder ahead of it before its priority is raised in the memory controller.		RW	0x0
			contin	ued



Bit	Name		Descr	iption	Access	Reset				
15	reorderen	operation	controls whether the cons to optimize SDRAM look a one.	ontroller can re-order bandwidth. It should generally	RW	0x0				
14	gendbe		to memory. This should	of double bit errors in data only be used for testing	RW	0x0				
13	gensbe		to memory. This should	of single bit errors in data only be used for testing	RW	0x0				
12	cfg_enable_ecc_code_ov erwrites	when a	correctable ECC error is	rwrites. ECC overwrites occur s seen and cause a new read/ or that location to clear the ECC	RW	0x0				
11	ecccorren		auto correction of the re	ead data returned when single	RW	0x0				
10	eccen	be set in	the generation and chec f the memory connected ts wide. If you set this, sdata field in the statice	RW	0x0					
9:8	addrorder	Progran mappin SDRAM	This bit field selects the order for address interleaving. Programming this field with different values gives different mappings between the AXI or Avalon-MM address and the SDRAM address. Program this field with the following binary values to select the ordering.							
		Value	Description	Address Interleaving						
		0x0								
		0x1	chip, bank, row, column	No interleaving						
		0x2	row, chip, bank, column	Bank interleaved with rank (chip select) interleaving						
		0x3	reserved	N/A						
		Intel re	commends programmin	g addrorder to 0x0 or 0x2.						
7:3	memb1	are valides selected with 8 (dependent program with 2,	d for JEDEC allowed DRA I in cfg_type. For DDR3, binary "01000"), for DD ing on the exact DRAM on the with 4, 8, or 16 and	atic decimal value. Legal values AM values for the DRAM , this should be programmed bR2 it can be either 4 or 8 chip. LPDDR2 can be and LPDDR can be programmed brogram the membl field in the	RW	0x0				
2:0	memtype	This bit field selects the memory type. This field can be programmed with the following binary values:								
		Value	e Descripti	on						
		0x0	Reserved							
		0x1								
		0x2								
		0x3								





Bit	Name		Description		Access	Reset
				1		
		Value	Description			
		0x4	Memory type is LPDDR2 SDRAM			
		0x5-0x7	Reserved			
				•		

4.15.1.1.2. dramtiming1

This register implements JEDEC standardized timing parameters. It should be programmed in clock cycles, for the value specified by the memory vendor.

Module Instance	Base Address	Register Address			
sdr	0xFFC20000	0xFFC25004			

Offset: 0x5004

Access: RW

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	trfc RW 0x0							tfaw RW 0x0						trrd RW 0x0	
15	14	13	12	11	10	9	8	7 6 5 4 3 2					2	1	0
trrd tcl RW 0x0 RW 0x0							tal RW 0x0				to RW				

dramtiming1 Fields

Bit	Name	Description	Access	Reset
31:2 4	trfc	The refresh cycle timing parameter.	RW	0x0
23:1 8	tfaw	The four-activate window timing parameter.	RW	0x0
17:1 4	trrd	The activate to activate, different banks timing parameter.	RW	0x0
13:9	tcl	Memory read latency.	RW	0x0
8:4	tal	Memory additive latency.	RW	0x0
3:0	tcwl	Memory write latency.	RW	0x0

4.15.1.1.3. dramtiming2

This register implements JEDEC standardized timing parameters. It should be programmed in clock cycles, for the value specified by the memory vendor.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25008

Offset: 0x5008





Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
:	Reserved			twtr RW 0x0			twr RW 0x0			trp RW 0x0				trcd RW 0x0	
15	14	13	12	12 11 10 9			8 7 6 5				4	3	2	1	0
	trcd RW 0x0								trefi RW 0x0						

dramtiming2 Fields

Bit	Name	Description	Access	Reset
28:2 5	twtr	The write to read timing parameter.	RW	0x0
24:2 1	twr	The write recovery timing.	RW	0x0
20:1 7	trp	The precharge to activate timing parameter.	RW	0x0
16:1 3	trcd	The activate to read/write timing parameter.	RW	0x0
12:0	trefi	The refresh interval timing parameter.	RW	0x0

4.15.1.1.4. dramtiming3

This register implements JEDEC standardized timing parameters. It should be programmed in clock cycles, for the value specified by the memory vendor.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC2500C

Offset: 0x500C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.





	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
Reserved								tccd RW 0x0			tmrd RW 0x0				
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
tmrd trc RW RW 0x0 0x0								tras RW 0x0				tr RW	tp 0x0		

dramtiming3 Fields

Bit	Name	Description	Access	Reset
22:1 9	tccd	The CAS to CAS delay time.	RW	0x0
18:1 5	tmrd	Mode register timing parameter.	RW	0x0
14:9	trc	The activate to activate timing parameter.	RW	0x0
8:4	tras	The activate to precharge timing parameter.	RW	0x0
3:0	trtp	The read to precharge timing parameter.	RW	0x0

4.15.1.1.5. dramtiming4

This register implements JEDEC standardized timing parameters. It should be programmed in clock cycles, for the value specified by the memory vendor.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25010

Offset: 0x5010

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31 30 29 28 27 26 25 24 23 22 21 20 19 18 17 1e												16			
	Reserved							minpwrsavecycles pwrdownexit RW 0x0 RW 0x0							
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	pwrdownexit RW 0x0									selfrf RW	shexit 0x0				



dramtiming4 Fields

Bit	Name	Description	Access	Reset
23:2	minpwrsavecycles	The minimum number of cycles to stay in a low power state. This applies to both power down and self-refresh and should be set to the greater of tPD and tCKESR.	RW	0x0
19:1 0	pwrdownexit	The power down exit cycles, tXPDLL.	RW	0x0
9:0	selfrfshexit	The self refresh exit cycles, tXS.	RW	0x0

4.15.1.1.6. lowpwrtiming

This register controls the behavior of the low power logic in the controller.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25014

Offset: 0x5014

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31 30 29 28 27 26 25 24 23 22 21 20 19 18 17 1											16				
Reserved											clkdisablecycles RW 0x0				
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	autopdcycles RW 0x0														

lowpwrtiming Fields

Bit	Name	Description	Access	Reset
19:1 6	clkdisablecycles	Set to a the number of clocks after the execution of an self- refresh to stop the clock. This register is generally set based on PHY design latency and should generally not be changed.	RW	0x0
15:0	autopdcycles	The number of idle clock cycles after which the controller should place the memory into power-down mode.	RW	0x0

4.15.1.1.7. dramodt

This register controls which \mathtt{ODT} pin asserts with chip select 0 (CS0) assertion and which \mathtt{ODT} pin asserts with chip select 1 (CS1) assertion.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25018

Offset: 0x5018





Access: RW

Important: To prevent indeterminate system behavior, reserved areas of memory must not be

accessed by software or hardware. Any area of the memory map that is not explicitly

defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved							С	fg_read_ RW		р	cf	g_write		ip	

dramodt Fields

Bit	Name	Description	Access	Reset
7:4	cfg_read_odt_chip	This register controls which ODT pin is asserted during reads. Bits[5:4] select the ODT pin that asserts with CS0 and bits[7:6] select the ODT pin that asserts with CS1. For example, a value of 0x9 asserts ODT[0] for accesses CS0 and ODT[1] for accesses with CS1. This field can be set to 0x1 is there is only one chip select available.	RW	0x0
3:0	cfg_write_odt_chip	This register controls which ODT pin is asserted during writes. Bits[1:0] select the ODT pin that asserts with CS0 and bits[3:2] select the ODT pin that asserts with CS1. For example, a value of 0x9 asserts ODT[0] for accesses CS0 and ODT[1] for accesses with CS1. This field can be set to 0x1 is there is only one chip select available.	RW	0x0

4.15.1.1.8. dramaddrw

This register configures the width of the various address fields of the DRAM. The values specified in this register must match the memory devices being used.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC2502C

Offset: 0x502C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
csbits bankbits RW 0x0 RW 0x0					rowbits RW 0x0					colbits RW 0x0					



dramaddrw Fields

Bit	Name	Description	Access	Reset
15:1	csbits	This field defines the number of chip select address bits. Set this field to 0x0 for single chip select and to 0x1 for two chip selects. When this field is set to 0x1, you may use rank interleaved mode by programming the ctrlcfg.addrorder field to 0x2. If you are using a single rank memory interface (csbits=0x0), you may not enable the rank interleaved mode (ctrlcfg.addrorder must be set less than 0x2). When this field is set to 0x1 to enable dual ranks, the chip select (cs) bit of the incoming address is used to determine which chip select is active. When the chip select bit of the incoming address is 0, chip select 0 becomes active. When the chip select 1 becomes active.	RW	0x0
12:1 0	bankbits	The number of bank address bits for the memory devices in your memory interface.	RW	0x0
9:5	rowbits	The number of row address bits for the memory devices in your memory interface.	RW	0x0
4:0	colbits	The number of column address bits for the memory devices in your memory interface.	RW	0x0

4.15.1.1.9. dramifwidth

This register controls the interface width of the SDRAM controller.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25030

Offset: 0x5030

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved										ifw: RW	idth 0x0			

dramifwidth Fields

Bit	Name	Name Description								
7:0	ifwidth	This register controls the width of the SDRAM interface, including any bits used for ECC. For example, for a 32-bit interface with ECC, program this register to 0x28. The ctrlwidth register must also be programmed.	RW	0x0						





4.15.1.1.10. dramsts

This register provides the status of the calibration and ECC logic.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25038

Offset: 0x5038

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved									corrd rop RW 0x0	dbeer r RW 0x0	sbeer r RW 0x0	calfa il RW 0x0	calsu ccess RW 0x0		

dramsts Fields

Bit	Name	Description	Access	Reset
4	corrdrop	This bit is set to 1 when any auto-corrections have been dropped.	RW	0x0
3	dbeerr	This bit is set to 1 when any ECC double bit errors are detected.	RW	0x0
2	sbeerr	This bit is set to 1 when any ECC single bit errors are detected.	RW	0x0
1	calfail	This bit is set to 1 when the PHY is unable to calibrate.	RW	0x0
0	calsuccess	This bit will be set to 1 if the PHY was able to successfully calibrate.	RW	0x0

4.15.1.1.11. dramintr

This register can enable, disable and clear the SDRAM error interrupts.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC2503C

Offset: 0x503C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.



	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved									intrc lr RW 0x0	corrd ropma sk RW 0x0	dbema sk RW 0x0	sbema sk RW 0x0	intre n RW 0x0		

dramintr Fields

Bit	Name	Description	Access	Reset
4	intrclr	Writing to this self-clearing bit clears the interrupt signal. Writing to this bit also clears the error count and error address registers: sbecount, dbecount, dropcount, erraddr, and dropaddr.	RW	0x0
3	corrdropmask	Set this bit to a one to mask interrupts for an ECC correction write back needing to be dropped. This indicates a burst of memory errors in a short period of time.	RW	0x0
2	dbemask	Mask the double bit error interrupt.	RW	0x0
1	sbemask	Mask the single bit error interrupt.	RW	0x0
0	intren	Enable the interrupt output.	RW	0x0

4.15.1.1.12. sbecount

This register tracks the single-bit error count.

Module Instance	Base Address	Register Address		
sdr	0xFFC20000	0xFFC25040		

Offset: 0x5040

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved										co: RW	unt 0x0			

sbecount Fields

Bit	Name	Description		Reset
7:0	count	Reports the number of single bit errors that have occurred since the status register counters were last cleared.	RW	0x0





4.15.1.1.13. dbecount

This register tracks the double-bit error count.

Module Instance	Base Address	Register Address		
sdr	0xFFC20000	0xFFC25044		

Offset: 0x5044

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved										coi RW				

dbecount Fields

Bit	Name	Name Description		Reset
7:0	count	Reports the number of double bit errors that have occurred since the status register counters were last cleared.	RW	0x0

4.15.1.1.14. erraddr

This register holds the address of the most recent ECC error.

Module Instance	Base Address	Register Address
sdr	0xffC20000	0xFFC25048

Offset: 0x5048

Access: RW

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	addr RW 0x0														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	addr RW 0x0														

erraddr Fields

Bit	Name	Description	Access	Reset
31:0	addr	The address of the most recent ECC error.	RW	0x0



Bit	Name	Name Description					
		Note: For a 32-bit interface, ECC is calculated across a span of 8 bytes, meaning the error address is a multiple of 8 bytes (4 bytes*2 burst length). To find the byte address of the word that contains the error, you must multiply the value in the erraddr register by 8.					

4.15.1.1.15. dropcount

This register holds the address of the most recent ECC error.

Module Instance	Base Address	Register Address		
sdr	0xFFC20000	0xFFC2504C		

Offset: 0x504C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Res							rved							
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved										corrdro				

dropcount Fields

Bit	Name	Description	Access	Reset
7:0	corrdropcount	This gives the count of the number of ECC write back transactions dropped due to the internal FIFO overflowing.	RW	0x0

4.15.1.1.16. dropaddr

This register holds the last dropped address.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25050

Offset: 0x5050

Access: RW



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	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	corrdropaddr RW 0x0														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	corrdropaddr RW 0x0														

dropaddr Fields

Bit	Name	Description	Access	Reset
31:0	corrdropaddr	This register gives the last address which was dropped.	RW	0x0

4.15.1.1.17. lowpwreq

This register instructs the controller to put the DRAM into a power down state. Note that some commands are only valid for certain memory types.

Module Instance	Base Address	Register Address
sdr	0xffC20000	0xFFC25054

Offset: 0x5054

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved									selfrf RW	shmask 0x0	selfr shreq RW 0x0	1	rdnmas k 0x0	deepp wrdnr eq RW 0x0	



lowpwreq Fields

Bit	Name	Description	Access	Reset
5:4	selfrfshmask	Write a one to each bit of this field to have a self refresh request apply to both chips.	RW	0x0
3	selfrshreq	Write a one to this bit to request the RAM be put into a self refresh state. This bit is treated as a static value so the RAM will remain in self-refresh as long as this register bit is set to a one. This power down mode can be selected for all DRAMs supported by the controller.	RW	0x0
2:1	deeppwrdnmask	Write ones to this register to select which DRAM chip selects will be powered down. Typical usage is to set both of these bits when deeppwrdnreq is set but the controller does support putting a single chip into deep power down and keeping the other chip running.	RW	0x0
0	deeppwrdnreq	Write a one to this bit to request a deep power down. This bit should only be written with LPDDR2 DRAMs, DDR3 DRAMs do not support deep power down.	RW	0x0

4.15.1.1.18. lowpwrack

This register gives the status of the power down commands requested by the Low Power Control register.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25058

Offset: 0x5058

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
											selfr fshac k RW 0x0	deepp wrdna ck RW 0x0			

lowpwrack Fields

Bit	Name	Description	Access	Reset
1	selfrfshack	This bit is a one to indicate that the controller is in a self-refresh state.	RW	0x0
0	deeppwrdnack	This bit is set to a one after a deep power down has been executed	RW	0x0





4.15.1.1.19. staticcfg

This register controls configuration values which cannot be updated during active transfers. First configure the membl and econ fields and then re-write these fields while setting the applycfg bit. The applycfg bit is write only.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC2505C

Offset: 0x505C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved apply useec membl cfg casda RW 0x0 Cfg Casda Cfg Casda Cfg Cfg														

staticcfg Fields

Bit	Name	Description	Access	Reset
3	applycfg	Write with this bit set to apply all the settings loaded in SDR registers to the memory interface. This bit is write-only and always returns 0 if read.	RW	0x0
2	useeccasdata	This field allows the FPGA ports to directly access the extra data bits that are normally used to hold the ECC code. The interface width must be set to 24 or 40 in the dramifwidth register. If you set this, you must clear the eccen field in the ctrlcfg register.	RW	0x0
1:0	memb1	This field specifies the DRAM burst length. The following encodings set the burst length: • 0x0= Burst length of 2 clocks • 0x1= Burst length of 4 clocks • 0x2= Burst length of 8 clocks • 0x3= Burst length of 16 clocks If you program the this field, you must also set the membl field in the ctrlcfg register.	RW	0x0

4.15.1.1.20. ctrlwidth

This register controls the width of the physical DRAM interface.

Module Instance	Base Address	Register Address			
sdr	0xFFC20000	0xFFC25060			



Offset: 0x5060

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved									ctrlv RW					

ctrlwidth Fields

Bit	Name		Description	Access	Reset
1:0	ctrlwidth	This fie	d specifies the SDRAM controller interface width:	RW	0x0
		Value	Description		
		0x0 8-bit interface width			
	width		16-bit (no ECC) or 24-bit (ECC enabled) interface width		
			32-bit (no ECC) or 40-bit (ECC enabled) interface width		
		Addition	nally, you must program the dramifwidth register.		

4.15.1.1.21. portcfg

Each bit of the autopchen field maps to one of the control ports. If a port executes mostly sequential memory accesses, the corresponding autopchen bit should be 0. If the port has highly random accesses, then its autopchen bit should be set to 1.

Module Instance	Base Address	Register Address		
sdr	0xFFC20000	0xFFC2507C		

Offset: 0x507C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.





	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved									autopchen RW 0x0					
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
autopchen RW 0x0					Reserved portprotocol RO 0x0										

portcfg Fields

Auto-Precharge Enable: One bit is assigned to each control port. For each bit, the encodings are as follows: Value	Access	Reset
0x0 The controller requests an automatic precharge following a bus command completion (close the row automatically) 0x1 The controller attempts to keep a row open. All active ports with random dominated operations should set the autopehen bit to 1. The bits in this field correspond to the control ports as follows: Bit 9 CPU write	RW	0x0
following a bus command completion (close the row automatically) 0x1 The controller attempts to keep a row open. All active ports with random dominated operations should set the autopchen bit to 1. The bits in this field correspond to the control ports as follows: Bit 9 CPU write		
active ports with random dominated operations should set the autopchen bit to 1. The bits in this field correspond to the control ports as follows: Bit 9 CPU write Bit 8 L3 write Bit 7 CPU read Bit 6 L3 read Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4 Bit 3 FPGA-to-SDRAM port 3 Bit 2 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 5:0 portprotocol Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
follows: Bit 9 CPU write		
Bit 8 L3 write Bit 7 CPU read Bit 6 L3 read Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4 Bit 3 FPGA-to-SDRAM port 3 Bit 2 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 7 CPU read Bit 6 L3 read Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 3 Bit 2 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 6 L3 read Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4 Bit 3 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4 Bit 3 FPGA-to-SDRAM port 3 Bit 2 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 4 FPGA-to-SDRAM port 4 Bit 3 FPGA-to-SDRAM port 3 Bit 2 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 3 FPGA-to-SDRAM port 3 Bit 2 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 2 FPGA-to-SDRAM port 2 Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 1 FPGA-to-SDRAM port 1 Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 0 FPGA-to-SDRAM port 0 Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
5:0 portprotocol Port Protocol: You can read this field to determine the protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
protocol configuration of each of the FPGA-to-SDRAM ports. The bits in this field correspond to the control ports as follows: Bit 5 FPGA-to-SDRAM port 5 Bit 4 FPGA-to-SDRAM port 4		
Bit 4 FPGA-to-SDRAM port 4	RO	0x0
Bit 3 FPGA-to-SDRAM port 3		
Bit 2 FPGA-to-SDRAM port 2		
Bit 1 FPGA-to-SDRAM port 1		
	con	tinued





Bit	Name	Description	Access	Reset
		Bit 0 FPGA-to-SDRAM port 0 When you read the corresponding port bit after the FPGA has been configured, it will have one of the following values:		
		Value Protocol Configuration Type 0x1 AXI (reset value for all ports) 0x0 Avalon-MM		
		Note: The value in this field is only valid after the fabric has been configured.		
		Note: The AXI protocol requires both a read and a write port. Therefore, you must ensure that AXI ports are allocated in the pairs (port 0, port 1), (port 2, port 3), and (port 4, port 5).		
		Aside from the requirement noted above, AXI and Avalon-MM ports can be mixed freely.		

4.15.1.1.22. fpgaportrst

This register implements functionality to allow the CPU to control when the MPFE will enable the ports to the FPGA fabric.

Module Instance	Base Address	Register Address		
sdr	0xFFC20000	0xFFC25080		

Offset: 0x5080

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved portrstn															
	RW 0x0														

fpgaportrst Fields

Bit	Name	Description	Access	Reset
13:0	portrstn	This register should be written to with a 1 to enable the selected FPGA port to exit reset. Writing a bit to a zero will stretch the port reset until the register is written. Read data ports are connected to bits 3:0, with read data port 0 at bit 0 to read data port 3 at bit 3. Write data ports 0 to 3 are mapped to 4 to 7, with write data port 0 connected to bit 4 to write data port 3 at bit 7. Command ports are connected to	RW	0x0





Bit	Name	Description	Access	Reset
		bits 8 to 13, with command port 0 at bit 8 to command port 5 at bit 13. Expected usage would be to set all the bits at the same time but setting some bits to a zero and others to a one is supported.		

4.15.1.1.23. protportdefault

This register controls the default protection assignment for a port. Ports which have explicit rules which define regions which are illegal to access should set the bits to pass by default. Ports which have explicit rules which define legal areas should set the bit to force all transactions to fail. Leaving this register to all zeros should be used for systems which do not desire any protection from the memory controller.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC2508C

Offset: 0x508C

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Reserved					portdefault RW 0x0									

protportdefault Fields

Bit	Name		Description		Access	Reset
9:0	portdefault	a bit is	nines the default action for specified zero, the specified access is allowed one, the specified access is denied	RW	0x0	
		Bit 9	CPU write			
		Bit 8	L3 write			
		Bit 7	CPU read			
		Bit 6	L3 read			
		Bit 5	Access to FPGA-to-SDRAM port 5			
		Bit 4	Access to FPGA-to-SDRAM port 4			
		Bit 3	Access to FPGA-to-SDRAM port 3			
		Bit 2	Access to FPGA-to-SDRAM port 2			
		Bit 1	Access to FPGA-to-SDRAM port 1			



Bit	Name	Description	Access	Reset
		Bit 0 Access to FPGA-to-SDRAM port 0		

4.15.1.1.24. protruleaddr

This register is used to control the memory protection for port 0 transactions. Address ranges can either be used to allow access to memory regions or disallow access to memory regions. If TrustZone is being used, access can be enabled for protected transactions or disabled for unprotected transactions. The default state of this register is to allow all access. Address values used for protection are only physical addresses.

Module Instance	Base Address	Register Address		
sdr	0xFFC20000	0xffC25090		

Offset: 0x5090

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved						highaddr RW 0x0								
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	highaddr RW 0x0								addr 0x0						

protruleaddr Fields

Bit	Name	Description	Access	Reset
23:1	highaddr	Upper 12 bits of the address for a check. Address is compared to be greater than or equal to the address of a transaction. Note that since AXI transactions cannot cross a 4K byte boundary, the transaction start and transaction end address must also fall within the same 1MByte block pointed to by this address pointer.	RW	0x0
11:0	lowaddr	Lower 12 bits of the address for a check. Address is compared to be less than or equal to the address of a transaction. Note that since AXI transactions cannot cross a 4K byte boundary, the transaction start and transaction end address must also fall within the same 1MByte block pointed to by this address pointer.	RW	0x0

4.15.1.1.25. protruleid

This register configures the AxID for a given protection rule.





Module Instance	Base Address	Register Address
sdr	0xffC20000	0xFFC25094

Offset: 0x5094

Access: RW

Important: T

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved						highid RW 0x0								
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	highid RW 0x0								lov RW						

protruleid Fields

Bit	Name	Description	Access	Reset
23:1	highid	AxID for the protection rule. Incoming AxID needs to be less than or equal to this value. For all AxIDs from a port, AxID high should be programmed to all ones.	RW	0x0
11:0	lowid	AXID for the protection rule. Incoming AXID needs to be greater than or equal to this value. For all AXIDs from a port, AXID high should be programmed to all ones.	RW	0x0

4.15.1.1.26. protruledata

This register configures the protection memory characteristics of each protection rule.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC25098

Offset: 0x5098

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.



	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	•	•					Rese	rved			•	•		•	
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
									secu RW	ox0					

protruledata Fields

Bit	Name		Description	Access	Reset			
13	ruleresult		Set this bit to a one to force a protection failure, zero to allow the access the succeed $% \left(1\right) =\left(1\right) \left(1\right$					
12:3	portmask	If a port's bit clear, the rul	The bits in this field determine which ports the rule applies to. If a port's bit is set, the rule applies to that port; if the bit is clear, the rule does not apply. The bits in this field correspond to the control ports as follows:					
		Bit 9 CPU	write					
		Bit 8 L3 w	rite					
		Bit 7 CPU	read					
		Bit 6 L3 re	ead					
		Bit 5 FPGA	A-to-SDRAM port 5					
		Bit 4 FPGA	Bit 4 FPGA-to-SDRAM port 4					
		Bit 3 FPG/						
		Bit 2 FPGA	A-to-SDRAM port 2					
		Bit 1 FPG/	A-to-SDRAM port 1					
		Bit 0 FPGA	A-to-SDRAM port 0					
		&						
2	validrule	Set to bit to invalidate a r	a one to make a rule valid, set to a zero to rule.	RW	0x0			
1:0	security	Valid security	RW	0x0				
		Value						
		0x0						
		0x1						
		0x2 or 0x3						

4.15.1.1.27. protrulerdwr

This register is used to perform read and write operations to the internal protection table.





Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC2509C

Offset: 0x509C

Access: RW

Important: To pr

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved														
15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0								0						
Reserved							readr ule RW 0x0	write rule RW 0x0		r	uleoffse RW 0x0	et			

protrulerdwr Fields

Bit	Name	Description	Access	Reset
6	readrule	Write to this bit to have the memory_prot_data register loaded with the value from the internal protection table at offset. Table value will be loaded before a rdy is returned so read data from the register will be correct for any follow-on reads to the memory_prot_data register.	RW	0x0
5	writerule	Write to this bit to have the memory_prot_data register to the table at the offset specified by port_offset. Bit automatically clears after a single cycle and the write operation is complete.	RW	0x0
4:0	ruleoffset	This field defines which of the 20 rules in the protection table you want to read or write.	RW	0x0

4.15.1.1.28. mppriority

This register is used to configure the DRAM burst operation scheduling.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC250AC

Offset: 0x50AC

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.



	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
Rese	Reserved userpriority RW 0x0														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	userpriority RW 0x0														

mppriority Fields

Bit	Name	Description	Access	Reset
29:0	userpriority	User Priority: This field sets the absolute user priority of each port, which is represented as a 3-bit value. 0x0 is the lowest priority and 0x7 is the highest priority. Port 0 is configured by programming userpriority[2:0], port 1 is configured by programming userpriority[5:3], port 2 is configured by programming userpriority[8:6], and so on.	RW	0x0

4.15.1.1.29. remappriority

This register applies another level of port priority after a transaction is placed in the single port queue.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC250E0

Offset: 0x50E0

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
Reserved															
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved										priori	tyremap 0x0				

remappriority Fields

Bit	Name	Description	Access	Reset
7:0	priorityremap	Each bit of this field represents a priority level. If bit N in the priorityremap field is set, then any port transaction with absolute user priority of N jumps to the front of the single port queue and is serviced ahead of any transactions in the queue. For example, if bit 5 is set in the priorityremap field of the remappriority register, then any port transaction with a userpriority value of 0x5 in the mppriority register is serviced ahead of any other transaction already in the single port queue.	RW	0x0





4.15.1.1.30. Port Sum of Weight Register Register Descriptions

This register is used to configure the DRAM burst operation scheduling.

Offset: 0xb0

mpweight_0_4 on page 153 mpweight_1_4 on page 153 mpweight_2_4 on page 154 mpweight_3_4 on page 154

mpweight_0_4

This register is used to configure the DRAM burst operation scheduling.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC250B0

Offset: 0x50B0

Access: RW

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	staticweight_31_0 RW 0x0														
15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
	staticweight_31_0 RW 0x0														

mpweight_0_4 Fields

Bit	Name	Description	Access	Reset
31:0	staticweight_31_0	Set static weight of the port. Each port is programmed with a 5 bit value. Port 0 is bits 4:0, port 1 is bits 9:5, up to port 9 being bits 49:45	RW	0x0

mpweight_1_4

This register is used to configure the DRAM burst operation scheduling.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC250B4

Offset: 0x50B4

Access: RW



	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	sumofweights_13_0 RW 0x0								staticweight _49_32 RW 0x0						
15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
	staticweight_49_32 RW 0x0														

mpweight_1_4 Fields

Bit	Name	Description	Access	Reset
31:1 8	sumofweights_13_0	Set the sum of static weights for particular user priority. This register is used as part of the deficit round robin implementation. It should be set to the sum of the weights for the ports	RW	0x0
17:0	staticweight_49_32	Set static weight of the port. Each port is programmed with a 5 bit value. Port 0 is bits 4:0, port 1 is bits 9:5, up to port 9 being bits 49:45	RW	0x0

mpweight_2_4

This register is used to configure the DRAM burst operation scheduling.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC250B8

Offset: 0x50B8

Access: RW

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	sumofweights_45_14 RW 0x0														
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	sumofweights_45_14 RW 0x0														

mpweight_2_4 Fields

Bit	Name	Description	Access	Reset
31:0	sumofweights_45_14	Set the sum of static weights for particular user priority. This register is used as part of the deficit round robin implementation. It should be set to the sum of the weights for the ports	RW	0x0

mpweight_3_4

This register is used to configure the DRAM burst operation scheduling.

Module Instance	Base Address	Register Address
sdr	0xFFC20000	0xFFC250BC



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Offset: 0x50BC

Access: RW

Important:

To prevent indeterminate system behavior, reserved areas of memory must not be accessed by software or hardware. Any area of the memory map that is not explicitly

defined as a register space or accessible memory is considered reserved.

	Bit Fields														
31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
	Reserved							sumofweights _63_46 RW 0x0							
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	sumofweights_63_46 RW 0x0														

mpweight_3_4 Fields

	Bit	Name	Description	Access	Reset
1	17:0	sumofweights_63_46	Set the sum of static weights for particular user priority. This register is used as part of the deficit round robin implementation. It should be set to the sum of the weights for the ports	RW	0x0

4.16. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Added note to first topic.Rebranded as Intel.
October 2016	2016.10.28	Maintenance release
May 2016	2016.05.03	Maintenance release
November 2015	2015.11.02	Added information regarding calculation of ECC error byte address location from erraddr register in "User Notification of ECC Errors" sectoin Added information regarding bus response to memory protection transaction failure in "Memory Protection" section Clarified "Protection" row in "Fields for Rules in Memory Protection" table in the "Memory Protection" section Clarified protruledata.security column in "Rules in Memory Protection Table for Example Configuration" table in the "Example of Configuration for TrustZone" section Added note about double-bit error functionality in "ECC Write Backs" subsection of "ECC" section Added the "DDR Calibration" subsection under "DDR PHY" section
May 2015	2015.05.04	Added the recommended sequence for writing or reading a rule in the "Memory Protection" section.
		continued



Date	Version	Changes
December 2014	2014.12.15	Added SDRAM Protection Access Flow Diagram to "Memory Protection" subsection in the "Single-Port Controller Operation" section. Changed the "SDRAM Multi-Port Scheduling" section to "SDRAM Multi-Port Arbitration" and added detailed information on how to use and program the priority and weighted arbitration scheme.
June 2014	2014.6.30	 Added Port Mappings section. Added SDRAM Controller Memory Options section. Enhanced Example of Configuration for TrustZone section. Added SDRAM Controller address map and registers.
December 2013	2013.12.30	 Added Generating a Preloader Image for HPS with EMIF section. Added Debugging HPS SDRAM in the Preloader section. Enhanced Simulation section.
November 2012	1.1	Added address map and register definitions section.
January 2012	1.0	Initial release.







5. Functional Description—HPC II Controller

The High Performance Controller II works with the UniPHY-based DDR2, DDR3, and LPDDR2 interfaces. The controller provides high memory bandwidth, high clock rate performance, and run-time programmability. The controller can reorder data to reduce row conflicts and bus turn-around time by grouping reads and writes together, allowing for efficient traffic patterns and reduced latency.

Note:

The controller described here is the High Performance Controller II (HPC II) with advanced features for designs generated in the Quartus II software version 11.0 and later, and the Quartus Prime software. Designs created in earlier versions and regenerated in version 11.0 and later do not inherit the new advanced features; for information on HPC II without the version 11.0 and later advanced features, refer to the External Memory Interface Handbook for Quartus II version 10.1.

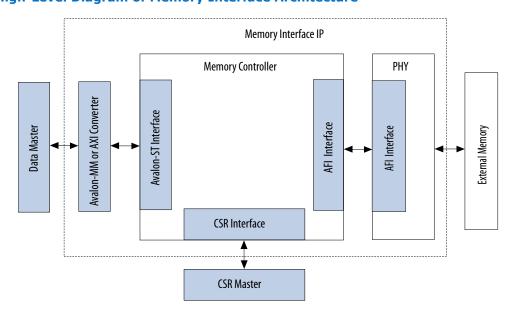
Related Information

External Memory Interface Handbook, v10.1

5.1. HPC II Memory Interface Architecture

The memory interface consists of the memory controller logic block, the physical logic layer (PHY), and their associated interfaces. The following figure shows a high-level block diagram of the overall external memory interface architecture.

Figure 51. **High-Level Diagram of Memory Interface Architecture**



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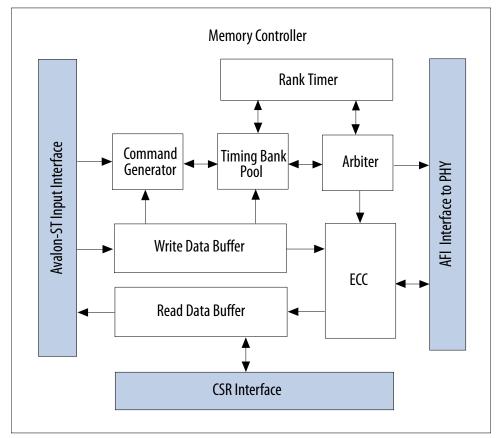


5.2. HPC II Memory Controller Architecture

The memory controller logic block uses an Avalon Streaming (Avalon-ST) interface as its native interface, and communicates with the PHY layer by the Altera PHY Interface (AFI).

The following figure shows a block diagram of the memory controller architecture.

Figure 52. Memory Controller Architecture Block Diagram



Avalon-ST Input Interface

The Avalon-ST interface serves as the entry point to the memory controller, and provides communication with the requesting data masters.

For information about the Avalon interface, refer to Avalon Interface Specifications.

AXI to Avalon-ST Converter

The HPC II memory controller includes an AXI to Avalon-ST converter for communication with the AXI protocol. The AXI to Avalon-ST converter provides write address, write data, write response, read address, and read data channels on the AXI interface side, and command, write data, and read data channels on the Avalon-ST interface side.



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Handshaking

The AXI protocol employs a handshaking process similar to the Avalon-ST protocol, based on ready and valid signals.

Command Channel Implementation

The AXI interface includes separate read and write channels, while the Avalon-ST interface has only one command channel. Arbitration of the read and write channels is based on these policies:

- Round robin
- Write priority—write channel has priority over read channel
- Read priority—read channel has priority over write channel

You can choose an arbitration policy by setting the COMMAND_ARB_TYPE parameter to one of ROUND_ROBIN, WRITE_PRIORITY, or READ_PRIORITY in the alt mem ddrx axi st converter.v file.

Data Ordering

The AXI specification requires that write data IDs must arrive in the same order as write address IDs are received. Similarly, read data must be returned in the same order as its associated read address is received.

Consequently, the AXI to Avalon-ST converter does not support interleaving of write data; all data must arrive in the same order as its associated write address IDs. On the read side, the controller returns read data based on the read addresses received.

Burst Types

The AXI to Avalon-ST converter supports the following burst types:

- Incrementing burst—the address for each transfer is an increment of the previous transfer address; the increment value depends on the size of the transfer.
- Wrapping burst—similar to the incrementing burst, but wraps to the lower address
 when the burst boundary is reached. The starting address must be aligned to the
 size of the transfer. Burst length must be 2, 4, 8, or 16. The burst wrap boundary
 = burst size * burst length.

Related Information

Avalon Interface Specifications

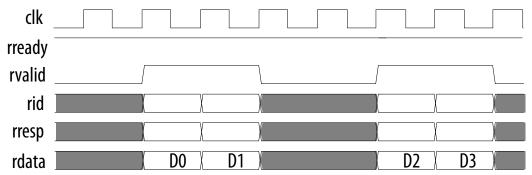
5.2.1. Backpressure Support

The write response and read data channels do not support data transfer with backpressure; consequently, you must assert the ready signal for the write response and read data channels to 1 to ensure acceptance of data at any time.

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For information about data transfer with and without backpressure, refer to the *Avalon Interface Specifications*.

Related Information

Avalon Interface Specifications

5.2.2. Command Generator

The command generator accepts commands from the front-end Avalon-ST interface and from local ECC internal logic, and provides those commands to the timing bank pool.

5.2.3. Timing Bank Pool

The timing bank pool is a parallel queue that works with the arbiter to enable data reordering. The timing bank pool tracks incoming requests, ensures that all timing requirements are met and, upon receiving write-data-ready notification from the write data buffer, passes the requests to the arbiter in an ordered and efficient manner.

5.2.4. Arbiter

The arbiter determines the order in which requests are passed to the memory device. When the arbiter receives a single request, that request is passed immediately; however, when multiple requests are received, the arbiter uses arbitration rules to determine the order in which to pass requests to the memory device.

Arbitration Rules

The arbiter uses the following arbitration rules:

- If only one master is issuing a request, grant that request immediately.
- If there are outstanding requests from two or more masters, the arbiter applies the following tests, in order:
- Is there a read request? If so, the arbiter grants the read request ahead of any write requests.
- If neither of the above conditions apply, the arbiter grants the oldest request first.





5.2.5. Rank Timer

The rank timer maintains rank-specific timing information, and performs the following functions:

- Ensures that only four activates occur within a specified timing window.
- Manages the read-to-write and write-to-read bus turnaround time.
- Manages the time-to-activate delay between different banks.

5.2.6. Read Data Buffer and Write Data Buffer

The read data buffer receives data from the PHY and passes that data through the input interface to the master. The write data buffer receives write data from the input interface and passes that data to the PHY, upon approval of the write request.

5.2.7. ECC Block

The error-correcting code (ECC) block comprises an encoder and a decoder-corrector, which can detect and correct single-bit errors, and detect double-bit errors. The ECC block can remedy errors resulting from noise or other impairments during data transmission.

5.2.8. AFI and CSR Interfaces

The AFI interface provides communication between the controller and the physical layer logic (PHY). The CSR interface provides communication with your system's internal control status registers.

For more information about AFI signals, refer to AFI 3.0 Specification in the Functional Description - UniPHY chapter.

Note: Unaligned reads and writes on the AFI interface are not supported.

Related Information

- Avalon Interface Specifications
- Functional Description—UniPHY on page 8

5.3. HPC II Controller Features

The HPC II memory controller offers a variety of features.

5.3.1. Data Reordering

The controller implements data reordering to maximize efficiency for read and write commands. The controller can reorder read and write commands as necessary to mitigate bus turn-around time and reduce conflict between rows.



Inter-bank data reordering reorders commands going to different bank addresses. Commands going to the same bank address are not reordered. This reordering method implements simple hazard detection on the bank address level.

The controller implements logic to limit the length of time that a command can go unserved. This logic is known as starvation control. In starvation control, a counter is incremented for every command served. You can set a starvation limit, to ensure that a waiting command is served immediately, when the starvation counter reaches the specified limit.

5.3.2. Pre-emptive Bank Management

Data reordering allows the controller to issue bank-management commands preemptively, based on the patterns of incoming commands. The desired page in memory can be already open when a command reaches the AFI interface.

5.3.3. Quasi-1T and Quasi-2T

One controller clock cycle equals two memory clock cycles in a half-rate interface, and to four memory clock cycles in a quarter-rate interface. To fully utilize the command bandwidth, the controller can operate in Quasi-1T half-rate and Quasi-2T quarter-rate modes.

In Quasi-1T and Quasi-2T modes, the controller issues two commands on every controller clock cycle. The controller is constrained to issue a row command on the first clock phase and a column command on the second clock phase, or vice versa. Row commands include activate and precharge commands; column commands include read and write commands.

The controller operates in Quasi-1T in half-rate mode, and in Quasi-2T in quarter-rate mode; this operation is transparent and has no user settings.

5.3.4. User Autoprecharge Commands

The autoprecharge read and autoprecharge write commands allow you to indicate to the memory device that this read or write command is the last access to the currently open row. The memory device automatically closes or autoprecharges the page it is currently accessing so that the next access to the same bank is quicker.

This command is useful for applications that require fast random accesses.

Since the HPC II controller can reorder transactions for best efficiency, when you assert the <code>local_autopch_req</code> signal, the controller evaluates the current command and buffered commands to determine the best autoprecharge operation.

5.3.5. Address and Command Decoding Logic

When the main state machine issues a command to the memory, it asserts a set of internal signals. The address and command decoding logic turns these signals into AFI-specific commands and address.



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The following signals are generated:

- Clock enable and reset signals: afi_cke, afi_rst_n
- Command and address signals: afi_cs_n, afi_ba, afi_addr, afi_ras_n, afi_cas_n, afi_we_n

5.3.6. Low-Power Logic

There are two types of low-power logic: the user-controlled self-refresh logic and automatic power-down with programmable time-out logic.

User-Controlled Self-Refresh

When you assert the <code>local_self_rfsh_req signal</code>, the controller completes any currently executing reads and writes, and then interrupts the command queue and immediately places the memory into self-refresh mode. When the controller places the memory into self-refresh mode, it responds by asserting an acknowledge signal, <code>local_self_rfsh_ack</code>. You can leave the memory in self-refresh mode for as long as you choose.

To bring the memory out of self-refresh mode, you must deassert the request signal, and the controller responds by deasserting the acknowledge signal when the memory is no longer in self-refresh mode.

Note:

If a user-controlled refresh request and a system-generated refresh request occur at the same time, the user-controlled refresh takes priority; the system-generated refresh is processed only after the user-controlled refresh request is completed.

Automatic Power-Down with Programmable Time-Out

The controller automatically places the memory in power-down mode to save power if the requested number of idle controller clock cycles is observed in the controller. The **Auto Power Down Cycles** parameter on the **Controller Settings** tab allows you to specify a range between 1 to 65,535 idle controller clock cycles. The counter for the programmable time-out starts when there are no user read or write requests in the command queue. Once the controller places the memory in power-down mode, it responds by asserting the acknowledge signal, local_power_down_ack.

5.3.7. ODT Generation Logic

The on-die termination (ODT) generation logic generates the necessary ODT signals for the controller, based on the scheme that Intel recommends.

DDR2 SDRAM

Note: There is no ODT for reads.

Table 44. ODT—DDR2 SDRAM Single Slot Single Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt[0]

Note: There is no ODT for reads.





Table 45. ODT—DDR2 SDRAM Single Slot Dual Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt[0]
mem_cs[1]	mem_odt[1]

Table 46. ODT—DDR2 SDRAM Dual Slot Single Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt[1]
mem_cs[1]	mem_odt[0]

Table 47. ODT-DDR2 SDRAM Dual Slot Dual Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt[2]
mem_cs[1]	mem_odt[3]
mem_cs[2]	mem_odt[0]
mem_cs[3]	mem_odt[1]

DDR3 SDRAM

Note: There is no ODT for reads.

Table 48. ODT—DDR3 SDRAM Single Slot Single Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt[0]

Note: There is no ODT for reads.

Table 49. ODT-DDR3 SDRAM Single Slot Dual Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt[0]
mem_cs[1]	mem_odt[1]

Table 50. ODT—DDR3 SDRAM Dual Slot Single Chip-select Per DIMM (Write)

Write On	ODT Enabled
mem_cs[0]	mem_odt [0] and mem_odt [1]
mem_cs[1]	mem_odt [0] and mem_odt [1]





Table 51. ODT—DDR3 SDRAM Dual Slot Single Chip-select Per DIMM (Read)

Read On	ODT Enabled
mem_cs[0]	mem_odt[1]
mem_cs[1]	mem_odt[0]

Table 52. ODT—DDR3 SDRAM Dual Slot Dual Chip-select Per DIMM (Write)

Write On	ODT Enabled			
mem_cs[0]	mem_odt [0] and mem_odt [2]			
mem_cs[1]	mem_odt [1]and mem_odt [3]			
mem_cs[2]	mem_odt [0]and mem_odt [2]			
mem_cs[3]	mem_odt [1]and mem_odt [3]			

Table 53. ODT—DDR3 SDRAM Dual Slot Dual Rank Per DIMM (Read)

Read On	ODT Enabled
mem_cs[0]	mem_odt[2]
mem_cs[1]	mem_odt[3]
mem_cs[2]	mem_odt[0]
mem_cs[3]	mem_odt[1]

5.3.8. Burst Merging

The burst merging feature improves controller efficiency by merging two burst chop commands of sequential addresses into one burst length command. Burst merging is opportunistic and happens when the controller receives commands faster than it can process (for example, Avalon commands of multiple burst length) or when the controller temporarily stops processing commands due to Refresh.

The burst merging feature is turned off by default when you generate a controller. If your traffic exercises patterns that you can merge, you should turn on burst merging, as follows:

- 1. In a text editor, open the <variation_name>_c0.v top-level file for your design.
- 2. Search for the ENABLE_BURST_MERGE parameter in the .v file.
- 3. Change the ENABLE_BURST_MERGE value from 0 to 1.

5.3.9. ECC

The ECC logic comprises an encoder and a decoder-corrector, which can detect and correct single-bit errors, and detect double-bit errors. The ECC logic is available in multiples of 16, 24, 40, and 72 bits.



Note:

For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, ECC logic is limited to widths of 24 and 40.

- The ECC logic has the following features:
- Has Hamming code ECC logic that encodes every 64, 32, 16, or 8 bits of data into 72, 40, 24, or 16 bits of codeword.
- Has a latency increase of one clock for both writes and reads.
- For a 128-bit interface, ECC is generated as one 64-bit data path with 8-bits of ECC path, plus a second 64-bit data path with 8-bits of ECC path.
- Detects and corrects all single-bit errors.
- Detects all double-bit errors.
- Counts the number of single-bit and double-bit errors.
- Accepts partial writes, which trigger a read-modify-write cycle, for memory devices with DM pins.
- Can inject single-bit and double-bit errors to trigger ECC correction for testing and debugging purposes.
- Generates an interrupt signal when an error occurs.

Note:

When using ECC, you must initialize your entire memory content to zero before beginning to write to the memory. If you do not initialize the content to zero, and if you read from uninitialized memory locations without having first written to them, you will see junk data which will trigger an ECC interrupt.

When a single-bit or double-bit error occurs, the ECC logic triggers the ecc_interrupt signal to inform you that an ECC error has occurred. When a single-bit error occurs, the ECC logic reads the error address, and writes back the corrected data. When a double-bit error occurs, the ECC logic does not do any error correction but it asserts the avl_rdata_error signal to indicate that the data is incorrect. The avl rdata error signal follows the same timing as the avl_rdata_valid signal.

Enabling autocorrection allows the ECC logic to delay all controller pending activities until the correction completes. You can disable autocorrection and schedule the correction manually when the controller is idle to ensure better system efficiency. To manually correct ECC errors, follow these steps:

- 1. When an interrupt occurs, read out the SBE_ERROR register. When a single-bit error occurs, the SBE_ERROR register is equal to one.
- 2. Read out the ERR ADDR register.
- 3. Correct the single-bit error by issuing a dummy write to the memory address stored in the ERR_ADDR register. A dummy write is a write request with the local_be signal zero, that triggers a partial write which is effectively a read-modify-write event. The partial write corrects the data at that address and writes it back.

5.3.9.1. Partial Writes

The ECC logic supports partial writes.



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Along with the address, data, and burst signals, the Avalon-MM interface also supports a signal vector, <code>local_be</code>, that is responsible for byte-enable. Every bit of this signal vector represents a byte on the data-bus. Thus, a logic low on any of these bits instructs the controller not to write to that particular byte, resulting in a partial write. The ECC code is calculated on all bytes of the data-bus. If any bytes are changed, the IP core must recalculate the ECC code and write the new code back to the memory.

For partial writes, the ECC logic performs the following steps:

- 1. The ECC logic sends a read command to the partial write address.
- 2. Upon receiving a return data from the memory for the particular address, the ECC logic decodes the data, checks for errors, and then merges the corrected or correct dataword with the incoming information.
- The ECC logic issues a write to write back the updated data and the new ECC code.

The following corner cases can occur:

- A single-bit error during the read phase of the read-modify-write process. In this
 case, the IP core corrects the single-bit error first, increments the single-bit error
 counter and then performs a partial write to this corrected decoded data word.
- A double-bit error during the read phase of the read-modify-write process. In this case, the IP core increments the double-bit error counter and issues an interrupt. The IP core writes a new write word to the location of the error. The ECC status register keeps track of the error information.

The following figures show partial write operations for the controller, for full and half rate configurations, respectively.

Figure 54. Partial Write for the Controller--Full Rate

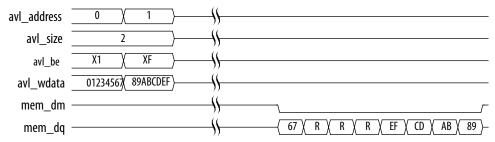
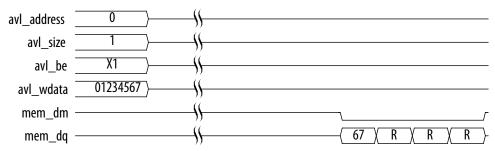


Figure 55. Partial Write for the Controller--Half Rate





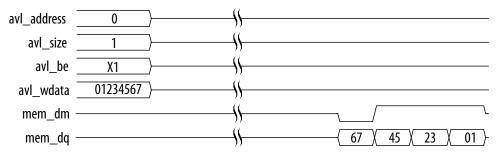


5.3.9.2. Partial Bursts

DIMMs that do not have the DM pins do not support partial bursts. You must write a minimum (or multiples) of memory-burst-length-equivalent words to the memory at the same time.

The following figure shows a partial burst operation for the controller.

Figure 56. Partial Burst for Controller



5.4. External Interfaces

This section discusses the interfaces between the controller and other external memory interface components.

5.4.1. Clock and Reset Interface

The clock and reset interface is part of the AFI interface.

The controller can have up to two clock domains, which are synchronous to each other. The controller operates with a single clock domain when there is no integrated half-rate bridge, and with two-clock domains when there is an integrated half-rate bridge. The clocks are provided by UniPHY.

The main controller clock is afi_clk, and the optional half-rate controller clock is afi_half_clk. The main and half-rate clocks must be synchronous and have a 2:1 frequency ratio. The optional quarter-rate controller clock is afi_quarter_clk, which must also be synchronous and have a 4:1 frequency ratio.

5.4.2. Avalon-ST Data Slave Interface

The Avalon-ST data slave interface consists of the following Avalon-ST channels, which together form a single data slave:

- The command channel, which serves as command and address for both read and write operations.
- The write data channel, which carries write data.
- The read data channel, which carries read data.

Related Information

Avalon Interface Specifications





5.4.3. AXI Data Slave Interface

The AXI data interface consists of the following channels, which communicate with the Avalon-ST interface through the AXI to Avalon-ST converter:

- The write address channel, which carries address information for write operations.
- The write data channel, which carries write data.
- The write response channel, which carries write response data.
- The read address channel, which carries address information for read operations.
- The read data channel, which carries read data.

5.4.3.1. Enabling the AXI Interface

This section provides guidance for enabling the AXI interface.

- 1. To enable the AXI interface, first open in an editor the file appropriate for the required flow, as indicated below:
 - For synthesis flow: <working_dir>/<variation_name>/
 <variation_name>_c0.v
 - For simulation flow: <working_dir>/<variation_name>_sim/
 <variation_name>/<variation_name>_c0.v
 - Example design fileset for synthesis: <working_dir>/
 <variation_name>_example_design/example_project/
 <variation_name>_example/submodules/
 <variation_name>_example_if0_c0.v
 - Example design fileset for simulation: <working_dir>/
 <variation_name>_example_design/simulation/verilog/submodules/
 <variation_name>_example_sim_e0_if0_c0.v
- 2. Locate and remove the **alt_mem_ddrx_mm_st_converter** instantiation from the .v file opened in the preceding step.
- Instantiate the alt_mem_ddrx_axi_st_converter module into the open .v file.
 Refer to the following code fragment as a guide:

```
module ? # ( parameter
// AXI parameters
AXI_ID_WIDTH = <replace parameter value>,
AXI_ADDR_WIDTH = <replace parameter value>,
AXI_LEN_WIDTH = <replace parameter value>,
AXI_SIZE_WIDTH = <replace parameter value>,
AXI_BURST_WIDTH = <replace parameter value>,
AXI_LOCK_WIDTH = <replace parameter value>,
AXI_CACHE_WIDTH = <replace parameter value>,
AXI_PROT_WIDTH = <replace parameter value>,
AXI_DATA_WIDTH = <replace parameter value>,
AXI_RESP_WIDTH = <replace parameter value>
// Existing ports
// AXI Interface ports
// Write address channel
input wire [AXI_ID_WIDTH - 1 : 0] awid,
input wire [AXI_ADDR_WIDTH - 1 : 0] awaddr,
input wire [AXI_LEN_WIDTH - 1 : 0] awlen,
input wire [AXI_SIZE_WIDTH - 1 : 0] awsize
input wire [AXI_BURST_WIDTH - 1 : 0] awburst,
input wire [AXI_LOCK_WIDTH - 1 : 0] awlock,
```





```
input wire [AXI_CACHE_WIDTH - 1 : 0] awcache,
input wire [AXI_PROT_WIDTH - 1 : 0] awprot,
input wire awvalid,
output wire awready,
// Write data channel
input wire [AXI_ID_WIDTH - 1 : 0] wid,
input wire [AXI_DATA_WIDTH - 1 : 0] wdata,
input wire [AXI_DATA_WIDTH / 8 - 1 : 0] wstrb,
input wire wlast,
input wire wvalid,
output wire wready,
// Write response channel
output wire [AXI_ID_WIDTH - 1 : 0] bid,
output wire [AXI_RESP_WIDTH - 1 : 0] bresp,
output wire bvalid,
input wire bready,
// Read address channel
input wire [AXI_ID_WIDTH - 1 : 0] arid,
input wire [AXI_ADDR_WIDTH - 1 : 0] araddr,
input wire [AXI_LEN_WIDTH - 1 : 0] arlen,
input wire [AXI_SIZE_WIDTH - 1 : 0] arsize,
input wire [AXI_BURST_WIDTH - 1 : 0] arburst,
input wire [AXI_LOCK_WIDTH - 1 : 0] arlock,
input wire [AXI_CACHE_WIDTH - 1 : 0] arcache,
input wire [AXI_PROT_WIDTH - 1 : 0] arprot,
input wire arvalid,
output wire arready
// Read data channel
output wire [AXI_ID_WIDTH - 1 : 0] rid,
output wire [AXI_DATA_WIDTH - 1 : 0] rdata,
output wire [AXI_RESP_WIDTH - 1 : 0] rresp,
output wire rlast,
output wire rvalid,
input wire rready
// Existing wire, register declaration and instantiation
// AXI interface instantiation
alt_mem_ddrx_axi_st_converter #
.AXI_ID_WIDTH (AXI_ID_WIDTH ),
.AXI_ADDR_WIDTH (AXI_ADDR_WIDTH ),
.AXI_LEN_WIDTH (AXI_LEN_WIDTH )
.AXI_SIZE_WIDTH (AXI_SIZE_WIDTH )
.AXI_BURST_WIDTH (AXI_BURST_WIDTH ),
.AXI_LOCK_WIDTH (AXI_LOCK_WIDTH ),
.AXI_CACHE_WIDTH (AXI_CACHE_WIDTH ),
.AXI_PROT_WIDTH (AXI_PROT_WIDTH ),
.AXI_DATA_WIDTH (AXI_DATA_WIDTH ),
.AXI_RESP_WIDTH (AXI_RESP_WIDTH ),
.ST_ADDR_WIDTH (ST_ADDR_WIDTH ),
.ST_SIZE_WIDTH (ST_SIZE_WIDTH ),
.ST_ID_WIDTH (ST_ID_WIDTH ),
.ST_DATA_WIDTH (ST_DATA_WIDTH ),
.COMMAND_ARB_TYPE (COMMAND_ARB_TYPE)
a0
.ctl_clk (afi_clk),
.ctl_reset_n (afi_reset_n),
.awid (awid),
.awaddr (awaddr),
.awlen (awlen),
.awsize (awsize),
.awburst (awburst),
.awlock (awlock),
.awcache (awcache)
.awprot (awprot),
.awvalid (awvalid),
.awready (awready),
.wid (wid),
```





```
.wdata (wdata),
.wstrb (wstrb),
.wlast (wlast),
.wvalid (wvalid),
.wready (wready),
.bid (bid),
.bresp (bresp),
.bvalid (bvalid),
.bready (bready),
.arid (arid),
.araddr (araddr),
.arlen (arlen),
.arsize (arsize),
.arburst (arburst),
.arlock (arlock),
.arcache (arcache),
.arprot (arprot),
.arvalid (arvalid),
.arready (arready),
.rid (rid),
.rdata (rdata),
.rresp (rresp),
.rlast (rlast),
.rvalid (rvalid),
.rready (rready),
.itf_cmd_ready (ng0_native_st_itf_cmd_ready),
.itf_cmd_valid (a0_native_st_itf_cmd_valid),
.itf_cmd (a0_native_st_itf_cmd);
.itf_cmd_address (a0_native_st_itf_cmd_address)
.itf_cmd_burstlen (a0_native_st_itf_cmd_burstlen),
.itf_cmd_id (a0_native_st_itf_cmd_id),
.itf_cmd_priority (a0_native_st_itf_cmd_priority),
.itf_cmd_autoprecharge (a0_native_st_itf_cmd_autopercharge),
.itf_cmd_multicast (a0_native_st_itf_cmd_multicast),
.itf_wr_data_ready (ng0_native_st_itf_wr_data_ready),
.itf_wr_data_valid (a0_native_st_itf_wr_data_valid),
.itf_wr_data (a0_native_st_itf_wr_data),
.itf_wr_data_byte_en (a0_native_st_itf_wr_data_byte_en),
.itf_wr_data_begin (a0_native_st_itf_wr_data_begin),
.itf_wr_data_last (a0_native_st_itf_wr_data_last),
.itf_wr_data_id (a0_native_st_itf_wr_data_id),
.itf_rd_data_ready (a0_native_st_itf_rd_data_ready),
.itf_rd_data_valid (ng0_native_st_itf_rd_data_valid),
.itf_rd_data (ng0_native_st_itf_rd_data),
.itf_rd_data_error (ng0_native_st_itf_rd_data_error),
.itf_rd_data_begin (ng0_native_st_itf_rd_data_begin),
.itf_rd_data_last (ng0_native_st_itf_rd_data_last),
.itf_rd_data_id (ng0_native_st_itf_rd_data_id)
);
```

- 4. Set the required parameters for the AXI interface. The following table lists the available parameters.
- Export the AXI interface to the top-level wrapper, making it accessible to the AXI master
- 6. To add the AXI interface to the Quartus Prime project:
 - On the Assignments > Settings menu in the Quartus Prime software, open the File tab.
 - Add the alt_mem_ddrx_axi_st_converter.v file to the project.





5.4.3.2. AXI Interface Parameters

Table 54. AXI Interface Parameters

Parameter Name	Description / Value			
AXI_ID_WIDTH	Width of the AXI ID bus. Default value is 4.			
AXI_ADDR_WIDTH	Width of the AXI address bus. Must be set according to the Avalon interface address and data bus width as shown below:AXI_ADDR_WIDTH = LOCAL_ADDR_WIDTH + log2(LOCAL_DATA_WIDTH/8)LOCAL_ADDR_WIDTH is the memory controller Avalon interface address width.LOCAL_DATA_WIDTH is the memory controller Avalon data interface width.			
AXI_LEN_WIDTH	Width of the AXI length bus. Default value is 8. Should be set to LOCAL_SIZE_WIDTH - 1, where LOCAL_SIZE_WIDTH is the memory controller Avalon interface burst size width			
AXI_SIZE_WIDTH	Width of the AXI size bus. Default value is 3.			
AXI_BURST_WIDTH	Width of the AXI burst bus. Default value is 2.			
AXI_LOCK_WIDTH	Width of the AXI lock bus. Default value is 2.			
AXI_CACHE_WIDTH	Width of the AXI cache bus. Default value is 4.			
AXI_PROT_WIDTH	Width of the AXI protection bus. Default value is 3.			
AXI_DATA_WIDTH	Width of the AXI data bus. Should be set to match the Avalon interface data bus width.AXI_DATA_WIDTH = LOCAL_DATA_WIDTH, where LOCAL_DATA_WIDTH is the memory controller Avalon interface input data width.			
AXI_RESP_WIDTH	Width of the AXI response bus. Default value is 2.			
ST_ADDR_WIDTH	Width of the Avalon interface address. Must be set to match the Avalon interface address bus width.ST_ADDR_WIDTH = LOCAL_ADDR_WIDTH, where LOCAL_ADDR_WIDTH is the memory controller Avalon interface address width.			
ST_SIZE_WIDTH	Width of the Avalon interface burst size.ST_SIZE_WIDTH = AXI_LEN_WIDTH + 1			
ST_ID_WIDTH	Width of the Avalon interface ID. Default value is 4.ST_ID_WIDTH = AXI_ID_WIDTH			
ST_DATA_WIDTH	Width of the Avalon interface data.ST_DATA_WIDTH = AXI_DATA_WIDTH.			
COMMAND_ARB_TYPE	Specifies the AXI command arbitration type, as shown:ROUND_ROBIN: arbitrates between read and write address channel in round robin fashion. Default option.WRITE_PRIORITY: write address channel has priority if both channels send request simultaneously.READ_PRIORITY: read address channel has priority if both channels send request simultaneously.			
REGISTERED	Setting this parameter to 1 adds an extra register stage in the AXI interface and incurs one extra clock cycle of latency. Default value is 1.			

5.4.3.3. AXI Interface Ports

Table 55. AXI Interface Ports

Name	Direction	Description		
awid	Input	AXI write address channel ID bus.		
awaddr	Input	AXI write address channel address bus.		
awlen	Input	AXI write address channel length bus.		
awsize	Input	AXI write address channel size bus.		
awburst	Input	AXI write address channel burst bus.(Interface supports only INCR and WRAP burst types.)		
awlock	Input	AXI write address channel lock bus.(Interface does not support this feature.)		
awcache	Input	AXI write address channel cache bus.(Interface does not support this feature.)		
		continued		





Name	Direction	Description	
awprot	Input	AXI write address channel protection bus.(Interface does not support this feature.)	
awvalid	Input	AXI write address channel valid signal.	
awready	Output	AXI write address channel ready signal.	
wid	Input	AXI write address channel ID bus.	
wdata	Input	AXI write address channel data bus.	
wstrb	Input	AXI write data channel strobe bus.	
wlast	Input	AXI write data channel last burst signal.	
wvalid	Input	AXI write data channel valid signal.	
wready	Output	AXI write data channel ready signal.	
bid	Output	AXI write response channel ID bus.	
bresp	Output	AXI write response channel response bus.Response encoding information:'b00 - OKAY'b01 - Reserved'b10 - Reserved'b11 - Reserved	
bvalid	Output	AXI write response channel valid signal.	
bready	Input	AXI write response channel ready signal. Must be set to 1. Interface does not support back pressure for write response channel.	
arid	Input	AXI read address channel ID bus.	
araddr	Input	AXI read address channel address bus.	
arlen	Input	AXI read address channel length bus.	
arsize	Input	AXI read address channel size bus.	
arburst	Input	AXI read address channel burst bus.(Interface supports only INCR and WRAP burst types.)	
arlock	Input	AXI read address channel lock bus.(Interface does not support this feature.)	
arcache	Input	AXI read address channel cache bus.(Interface does not support this feature.)	
arprot	Input	AXI read address channel protection bus.(Interface does not support this feature.)	
arvalid	Input	AXI read address channel valid signal.	
arready	Output	AXI read address channel ready signal.	
rid	Output	AXI read data channel ID bus.	
rdata	Output	AXI read data channel data bus.	
rresp	Output	AXI read data channel response bus.Response encoding information:'b00 - OKAY'b01 - Reserved'b10 - Data error'b11 - Reserved	
rlast	Output	AXI read data channel last burst signal.	
rvalid	Output	AXI read data channel valid signal.	
rready	Input	AXI read data channel ready signal.Must be set to 1. Interface does not support back pressure for write response channel.	

For information about the AXI specification, refer to the ARM * website.

Related Information

www.arm.com





5.4.4. Controller-PHY Interface

The interface between the controller and the PHY is part of the AFI interface. The controller assumes that the PHY performs all necessary calibration processes without any interaction with the controller.

For more information about AFI signals, refer to AFI 3.0 Specification.

5.4.5. Memory Side-Band Signals

The HPC II controller supports several optional side-band signals.

Self-Refresh (Low Power) Interface

The optional low power self-refresh interface consists of a request signal and an acknowledgement signal, which you can use to instruct the controller to place the memory device into self-refresh mode. This interface is clocked by afi_clk.

When you assert the request signal, the controller places the memory device into self-refresh mode and asserts the acknowledge signal. To bring the memory device out of self-refresh mode, you deassert the request signal; the controller then deasserts the acknowledge signal when the memory device is no longer in self-refresh mode.

Note:

For multi-rank designs using the HPC II memory controller, a self-refresh and a user-refresh cannot be made to the same memory chip simultaneously. Also, the self-refresh ack signal indicates that at least one device has entered self-refresh, but does not necessarily mean that all devices have entered self-refresh.

User-Controlled Refresh Interface

The optional user-controlled refresh interface consists of a request signal, a chip select signal, and an acknowledgement signal. This interface provides increased control over worst-case read latency and enables you to issue refresh bursts during idle periods. This interface is clocked by afi_clk.

When you assert a refresh request signal to instruct the controller to perform a refresh operation, that request takes priority over any outstanding read or write requests that might be in the command queue. In addition to the request signal, you must also choose the chip to be refreshed by asserting the refresh chip select signal along with the request signal. If you do not assert the chip select signal with the request signal, unexpected behavior may result.

The controller attempts to perform a refresh as long as the refresh request signal is asserted; if you require only one refresh, you should deassert the refresh request signal after the acknowledgement signal is received. If you maintain the request signal high after the acknowledgement is sent, it would indicate that further refresh is required. You should deassert the request signal after the required number of acknowledgement/refresh is received from the controller. You can issue up to a maximum of nine consecutive refresh commands.

Note:

For multi-rank designs using the HPC II memory controller, a self-refresh and a user-refresh cannot be made to the same memory chip simultaneously.





Configuration and Status Register (CSR) Interface

The controller has a configuration and status register (CSR) interface that allows you to configure timing parameters, address widths, and the behavior of the controller. The CSR interface is a 32-bit Avalon-MM slave of fixed address width; if you do not need this feature, you can disable it to save area.

This interface is clocked by csr_clk, which is the same as afi_clk, and is always synchronous relative to the main data slave interface.

5.4.6. Controller External Interfaces

The following table lists the controller's external interfaces.

Table 56. **Summary of Controller External Interfaces**

Interface Name	Display Name	Туре	Description	
Clock and Reset Interf	ace	•	•	
Clock and Reset Interface Interface		AFI (1)	Clock and reset generated by UniPHY to the controller.	
Avalon-ST Data Slave	Interface	•		
Command Channel Avalon-ST Data Slave Interface		Avalon-ST (2)	Address and command channel for read and write, single command single data (SCSD).	
Write Data Channel Avalon-ST Data Slave Interface		Avalon-ST (2)	Write Data Channel, single command multiple data (SCMD).	
Read Data Channel Avalon-ST Data Slave Interface		Avalon-ST (2)	Read data channel, SCMD with read data error response.	
Controller-PHY Interfa	ice	•		
AFI 3.0	AFI Interface	AFI (1)	Interface between controller and PHY.	
Memory Side-Band Sig	ınals	,		
Self Refresh (Low Power) Interface	Self Refresh (Low Power) Interface	Avalon Control & Status Interface (2)	SDRAM-specific signals to place memory into low-power mode.	
User-Controller Refresh Interface	User-Controller Refresh Interface	Avalon Control & Status Interface (2)	SDRAM-specific signals to request memory refresh.	
Configuration and Stat	tus Register (CSR) Interface	,		
CSR	Configuration and Status Register Interface	Avalon-MM (2)	Enables on-the-fly configuration of memory timing parameters, address widths, and controller behaviour.	

Notes:

- 1. For information about AFI signals, refer to AFI 3.0 Specification in the Functional Description UniPHY chapter.
- 2. For information about Avalon signals, refer to Avalon Interface Specifications.

Related Information

- **Avalon Interface Specifications**
- Functional Description—UniPHY on page 8





5.5. Top-Level Signals Description

The top-level signals include clock and reset signals, local interface signals, controller interface signals, and CSR interface signals.

5.5.1. Clock and Reset Signals

The following table lists the clock and reset signals.

Note: The suffix _n denotes active low signals.

Table 57. Clock and Reset Signals

Name	Direction	Description
global_reset_n	Input	The asynchronous reset input to the controller. The IP core derives all other reset signals from resynchronized versions of this signal. This signal holds the PHY, including the PLL, in reset while low.
pll_ref_clk	Input	The reference clock input to PLL.
phy_clk	Output	The system clock that the PHY provides to the user. All user inputs to and outputs from the controller must be synchronous to this clock.
reset_phy_clk_n	Output	The reset signal that the PHY provides to the user. The IP core asserts reset_phy_clk_n asynchronously and deasserts synchronously to phy_clk clock domain.
aux_full_rate_clk	Output	An alternative clock that the PHY provides to the user. This clock always runs at the same frequency as the external memory interface. In half-rate designs, this clock is twice the frequency of the phy_clk and you can use it whenever you require a 2x clock. In full-rate designs, the same PLL output as the phy_clk signal drives this clock.
aux_half_rate_clk	Output	An alternative clock that the PHY provides to the user. This clock always runs at half the frequency as the external memory interface. In full-rate designs, this clock is half the frequency of the <code>phy_clk</code> and you can use it, for example to clock the user side of a half-rate bridge. In half-rate designs, or if the Enable Half Rate Bridge option is turned on. The same PLL output that drives the <code>phy_clk</code> signal drives this clock.
dll_reference_clk	Output	Reference clock to feed to an externally instantiated DLL.
reset_request_n	Output	Reset request output that indicates when the PLL outputs are not locked. Use this signal as a reset request input to any system-level reset controller you may have. This signal is always low when the PLL is trying to lock, and so any reset logic using Intel advises you detect a reset request on a falling edge rather than by level detection.
soft_reset_n	Input	Edge detect reset input for control by other system reset logic. Assert to cause a complete reset to the PHY, but not to the PLL that the PHY uses.
seriesterminationcontrol	Input (for OCT slave)	Required signal for PHY to provide series termination calibration value. Must be connected to a user-instantiated OCT control block (alt_oct) or another UniPHY instance that is set to OCT master mode.
	Output (for OCT master)	Unconnected PHY signal, available for sharing with another PHY.
parallelterminationcontrol	Input (for OCT slave)	Required signal for PHY to provide series termination calibration value. Must be connected to a user-instantiated OCT control block (alt_oct) or another UniPHY instance that is set to OCT master mode.
		continued





Direction	Description	
Output (for OCT master)	Unconnected PHY signal, available for sharing with another PHY.	
Input (for OCT master)	Must connect to calibration resistor tied to GND on the appropriate RDN pin on the device. (Refer to appropriate device handbook.)	
Input (for OCT master)	Must connect to calibration resistor tied to Vccio on the appropriate RUP pin on the device. (See appropriate device handbook.)	
Input	Allows the use of DLL in another PHY instance in this PHY instance. Connect the export port on the PHY instance with a DLL to the import port on the other PHY instance.	
Output	Clock for the configuration and status register (CSR) interface, which is the same as afi_clk and is always synchronous relative to the main data slave interface.	
	Output (for OCT master) Input (for OCT master) Input (for OCT master) Input Input	

5.5.2. Local Interface Signals

The following table lists the controller local interface signals.

Table 58. **Local Interface Signals**

Signal Name	Direction	Description
		Memory address at which the burst should start. By default, the IP core maps local address to the bank interleaving scheme. You can change the ordering via the Local-to-Memory Address Mapping option in the Controller Settings page.
		This signal must remain stable only during the first transaction of a burst. The constantBurstBehavior property is always false for UniPHY controllers.
		The IP core sizes the width of this bus according to the following equations: • Full rate controllers:
		For one chip select: width = row bits + bank bits + column bits - 1
		For multiple chip selects: width = chip bits* + row bits + bank bits + column bits - 1
avl_addr[] ⁽¹⁾	Input	If the bank address is 2 bits wide, row is 13 bits wide and column is 10 bits wide, the local address is 24 bits wide. To map local_address to bank, row and column address:
		avl_addr is 24 bits wide avl_addr[23:11]= row address[12:0] avl_addr[10:9] = bank address [1:0] avl_addr[8:0] = column address[9:1]
		The IP core ignores the least significant bit (LSB) of the column address (multiples of two) on the memory side, because the local data width is twice that of the memory data bus width.
		Half rate controllers: For one chip select: width = row bits + bank bits + column bits - 2
		For multiple chip selects: width = chip bits* + row bits + bank bits + column bits - 2
	1	continued

^{1.} Applies only to the hard memory controller with multiport front end available in Arria V and Cyclone V devices.



Signal Name	Direction	Description
		If the bank address is 2 bits wide, row is 13 bits wide and column is 10 bits wide, the local address is 23 bits wide. To map local_address to bank, row and column address:
		<pre>avl_addr is 23 bits wide avl_addr[22:10] = row address[12:0] avl_addr[9:8] = bank address [1:0] avl_addr[7:0] = column address[9:2]</pre>
		The IP core ignores two LSBs of the column address (multiples of four) on the memory side, because the local data width is four times that of the memory data bus width.
		Quarter rate controllers:
		For one chip select: width = row bits + bank bits + column bits - 3
		For multiple chip selects: width = chip bits* + row bits + bank bits + column bits - 3
		If the bank address is 2 bits wide, row is 13 bits wide and column is 10 bits wide, the local address is 22 bits wide.
		(* chip bits is a derived value indicating the number of address bits necessary to uniquely address every memory rank in the system; this value is not user configurable.)
		Full-rate hard memory controllers (Arria V and Cyclone V):
		For one chip select: width = row bits + bank bits + column bits - log2(local avalon data width/memory DQ width)
		For multiple chip selects: width = chip bits* + row bits + bank bits + column bits - log2(local avalon data width/memory data width)
		If the local Avalon data width is 32, the memory DQ width is 8, the bank address is 3 bits wide, the row is 12 bits wide and the column is 8 bits wide, the local address is 21 bits wide. To map local_address to bank, row and column address:
		avl_addr is 21 bits wide
		avl_addr[20:9] = row address[11:0]
		avl_addr[8:6] = bank address [2:0]
		avl_addr[5:0] = column address[7:2]
		The IP core ignores the two least significant bits of the column address on the memory side because the local data width is four times that of the memory data bus width (Multi-Port Frontend).
avl_be[] (2)	Input	Byte enable signal, which you use to mask off individual bytes during writes. avl_be is active high; mem_dm is active low.
		The controller supports any combination of byte enables which translate directly through to the memory interface data mask (DM) signals.
		To map avl_wdata and avl_be to mem_dq and mem_dm, consider a full-rate design with 32-bit avl_wdata and 16-bit mem_dq.
		avl_wdata = < 22334455 >< 667788AA >< BBCCDDEE> avl_be = < 1100 >< 0110 >< 1010 >
		These values map to:
		Mem_dq = <4455><2233><88AA><6677> <ddee><bbcc> Mem_dm = <1 1 ><0 0 ><0 1 ><1 0 ><0 1 ><0 1 ></bbcc></ddee>
avl_burstbegin ⁽³⁾	Input	The Avalon burst begin strobe, which indicates the beginning of an Avalon burst. Unlike all other Avalon-MM signals, the burst begin signal is not dependant on avl_ready.
		For write transactions, assert this signal at the beginning of each burst transfer and keep this signal high for one cycle per burst transfer, even if the slave deasserts avl_ready. The IP core samples this signal at the rising edge of phy_clk when avl_write_req is asserted. After the slave deasserts the avl_ready signal, the master keeps all the write request signals asserted until avl_ready signal becomes high again.
		continued





Signal Name	Direction	Description
		For read transactions, assert this signal for one clock cycle when read request is asserted and avl_addr from which the data should be read is given to the memory. After the slave deasserts avl_ready (waitrequest_n in Avalon interface), the master keeps all the read request signals asserted until avl_ready becomes high again.
avl_read_req (4)	Input	Read request signal. You cannot assert read request and write request signals at the same time. The controller must deassert reset_phy_clk_n before you can assert avl_read_req.
local_refresh_req	Input	User-controlled refresh request. If Enable User Auto-Refresh Controls option is turned on, <code>local_refresh_req</code> becomes available and you are responsible for issuing sufficient refresh requests to meet the memory requirements. This option allows complete control over when refreshes are issued to the memory including grouping together multiple refresh commands. Refresh requests take priority over read and write requests, unless the IP core is already processing the requests.
local_refresh_chip	Input	Controls which chip to issue the user refresh to. The IP core uses this active high signal with <code>local_refresh_req</code> . This signal is as wide as the memory chip select. This signal asserts a high value to each bit that represents the refresh for the corresponding memory chip. For example: If <code>local_refresh_chip</code> signal is assigned with a value of <code>4'b0101</code> , the controller refreshes the memory chips 0 and 2, and memory chips 1 and 3 are not refreshed.
avl_size[] ⁽⁵⁾	Input	Controls the number of beats in the requested read or write access to memory, encoded as a binary number. In UniPHY, the IP core supports Avalon burst lengths from 1 to 1024. The IP core derives the width of this signal based on the burst count that you specify in the Maximum Avalon-MM burst length option. With the derived width, you specify a value ranging from 1 to the local maximum burst count specified. This signal must remain stable only during the first transaction of a burst. The constantBurstBehavior property is always false for
avl_wdata[] (6)	Input	UniPHY controllers. Write data bus. The width of avl_wdata is twice that of the memory data bus for a full-rate controller, four times the memory data bus for a half-rate controller, and eight times the memory data bus for a quarter-rate controller. If Generate power-of-2 data bus widths for Platform Designer and SOPC Builder is enabled, the width is rounded down to the nearest power of 2.
avl_write_req ⁽⁷⁾	Input	Write request signal. You cannot assert read request and write request signal at the same time. The controller must deassert reset_phy_clk_n before you can assert avl_write_req.
local_autopch_req (8)	Input	User control of autoprecharge. If you turn on Enable Auto- Precharge Control , the <code>local_autopch_req</code> signal becomes available and you can request the controller to issue an autoprecharge write or autoprecharge read command. These commands cause the memory to issue a precharge command to the current bank at the appropriate time without an explicit precharge
		command from the controller. This feature is particularly useful if you know the current read or write is the last one you intend to issue to the currently open row. The next time you need to use that bank, the access could be quicker as the controller does not need to precharge the bank before activating the row you wish to access.
		Upon receipt of the local_autopch_req signal, the controller evaluates the pending commands in the command buffer and determines the most efficient autoprecharge operation to perform, reordering commands if necessary.
		The controller must deassert reset_phy_clk_n before you can assert local_autopch_req.
		continued





Signal Name	Direction	Description
local_self_rfsh_chip	Input	Controls which chip to issue the user refresh to. The IP core uses this active high signal with <code>local_self_rfsh_req</code> . This signal is as wide as the memory chip select. This signal asserts a high value to each bit that represents the refresh for the corresponding memory chip. For example: If <code>local_self_rfsh_chip</code> signal is assigned with a value of <code>4'b0101</code> , the controller refreshes the memory chips <code>0</code> and <code>2</code> , and memory chips <code>1</code> and <code>3</code> are not refreshed.
local_self_rfsh_req	Input	User control of the self-refresh feature. If you turn on Enable Self-Refresh Controls , you can request that the controller place the memory devices into a self-refresh state by asserting this signal. The controller places the memory in the self-refresh state as soon as it can without violating the relevant timing parameters and responds by asserting <code>local_self_rfsh_ack</code> . You can hold the memory in the self-refresh state by keeping this signal asserted. You can release the memory from the self-refresh state at any time by deasserting <code>local_self_rfsh_req</code> and the controller responds by deasserting <code>local_self_rfsh_ack</code> when it has successfully brought the memory out of the self-refresh state.
local_init_done	Output	When the memory initialization, training, and calibration are complete, the PHY sequencer asserts ctrl_usr_mode_rdy to the memory controller, which then asserts this signal to indicate that the memory interface is ready for use.
local_cal_success	Output	When the memory initialization, training, and calibration completes successfully, the controller asserts this signal coincident with local_init_done to indicate the memory interface is ready for use.
local_cal_fail	Output	When the memory initialization, training, or calibration fails, the controller asserts this signal to indicate that calibration failed. The local_init_done signal will not assert when local_cal_fail asserts.
avl_rdata[] ⁽⁹⁾	Output	Read data bus. The width of avl_rdata is twice that of the memory data bus for a full rate controller; four times the memory data bus for a half rate controller. If Generate power-of-2 data bus widths for Platform Designer and SOPC Builder is enabled, the width is rounded down to the nearest power of 2.
avl_rdata_error (10)	Output	Asserted if the current read data has an error. This signal is only available if you turn on Enable Error Detection and Correction Logic . The controller asserts this signal with the avl_rdata_valid signal. If the controller encounters double-bit errors, no correction is made and the controller asserts this signal.
avl_rdata_valid (11)	Output	Read data valid signal. The avl_rdata_valid signal indicates that valid data is present on the read data bus.
avl_ready (12)	Output	The avl_ready signal indicates that the controller is ready to accept request signals. If controller asserts the avl_ready signal in the clock cycle that it asserts a read or write request, the controller accepts that request. The controller deasserts the avl_ready signal to indicate that it cannot accept any more requests. The controller can buffer eight read or write requests, after which the avl_ready signal goes low. The avl_ready signal is deasserted when any of the following are true: The Timing bank Pool is full. The FIFO register that stores read data from the memory device is full. The write data FIFO register is full. The controller is waiting for write data when in ECC mode.
		continued





Signal Name	Direction	Description
local_refresh_ack	Output	Refresh request acknowledge, which the controller asserts for one clock cycle every time it issues a refresh. Even if you do not turn on Enable User Auto-Refresh Controls , local_refresh_ack still indicates to the local interface that the controller has just issued a refresh command.
local_self_rfsh_ack	Output	Self refresh request acknowledge signal. The controller asserts and deasserts this signal in response to the local_self_rfsh_req signal.
local_power_down_ack	Output	Auto power-down acknowledge signal. The controller asserts this signal for one clock cycle every time auto power-down is issued.
ecc_interrupt (13)	Output	Interrupt signal from the ECC logic. The controller asserts this signal when the ECC feature is turned on, and the controller detects an error.

Notes to Table:

- 1. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_addr becomes a per port value, avl_addr_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 2. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_be becomes a per port value, avl_be_#, where # is a numeral from 0-5, based on the number of ports selected in the Controller tab.
- 3. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_burstbegin becomes a per port value, avl_burstbegin_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 4. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_read_req becomes a per port value, avl_read_req_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 5. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_size becomes a per port value, avl_size_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 6. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_wdata becomes a per port value, avl_wdata_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 7. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_write_req becomes a per port value, avl_write_req_#, where # is a numeral from 0-5, based on the number of ports selected in the Controller tab.
- 8. This signal is not applicable to the hard memory controller.
- 9. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_rdata becomes a per port value, avl_rdata_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 10. This signal is not applicable to the hard memory controller.
- 11. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_rdata_valid becomes a per port value, avl_rdata_valid_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 12. For the hard memory controller with multiport front end available in Arria V and Cyclone V devices, avl_ready becomes a per port value, avl_ready_#, where # is a numeral from 0–5, based on the number of ports selected in the Controller tab.
- 13. This signal is not applicable to the hard memory controller.

5.5.3. Controller Interface Signals

The following table lists the controller interface signals.

Table 59. Interface Signals

Signal Name	Direction	Description
mem_dq[]	Bidirectional	Memory data bus. This bus is half the width of the local read and write data busses.
mem_dqs[]	Bidirectional	Memory data strobe signal, which writes data into the memory device and captures read data into the Intel device.
		continued





Signal Name	Direction	Description
mem_dqs_n[]	Bidirectional	Inverted memory data strobe signal, which with the mem_dqs signal improves signal integrity.
mem_ck	Output	Clock for the memory device.
mem_ck_n	Output	Inverted clock for the memory device.
mem_addr[]	Output	Memory address bus.
mem_ac_parity (1)	Output	Address or command parity signal generated by the PHY and sent to the DIMM. DDR3 SDRAM only.
mem_ba[]	Output	Memory bank address bus.
mem_cas_n	Output	Memory column address strobe signal.
mem_cke[]	Output	Memory clock enable signals.
mem_cs_n[]	Output	Memory chip select signals.
mem_dm[]	Output	Memory data mask signal, which masks individual bytes during writes.
mem_odt	Output	Memory on-die termination control signal.
mem_ras_n	Output	Memory row address strobe signal.
mem_we_n	Output	Memory write enable signal.
parity_error_n (1)	Output	This signal is not used and should be ignored. The PHY does not have capture circuity to trigger on the falling edge of mem_error_out_n. See below for a complete description of mem_error_out_n, and recommendations.
mem_err_out_n (1)	Input	This is an output of registered DIMMs. When an address-and-command parity error is detected, DDR3 registered DIMMs assert the mem_err_out_n signal in accordance with the memory buffer configuration. Unlike ECC on the data bus, the controller does not automatically correct errors on the address-and-command bus. You should connect this pin to your own falling edge detection circuitry in order to capture when a parity error occurs. Upon error detection, action may be taken such as causing a system interrupt, or an appropriate event.

^{1.} This signal is for registered DIMMs only.

5.5.4. CSR Interface Signals

The following table lists the CSR interface signals.

Table 60. CSR Interface Signals

Signal Name	Direction	Description	
csr_addr[]	Input	Register map address.The width of csr_addr is 16 bits.	
		continue	4





Direction	Description
Input	Byte-enable signal, which you use to mask off individual bytes during writes. csr_be is active high.
Output	Clock for the configuration and status register (CSR) interface, which is the same as $\mathtt{afi_clk}$ and is always synchronous relative to the main data slave interface.
Input	Write data bus. The width of csr_wdata is 32 bits.
Input	Write request signal. You cannot assert csr_write_req and csr_read_req signals at the same time.
Input	Read request signal. You cannot assert csr_read_req and csr_write_req signals at the same time.
Output	Read data bus. The width of csr_rdata is 32 bits.
Output	Read data valid signal. The csr_rdata_valid signal indicates that valid data is present on the read data bus.
Output	The csr_waitrequest signal indicates that the HPC II is busy and not ready to accept request signals. If the csr_waitrequest signal goes high in the clock cycle when a read or write request is asserted, that request is not accepted. If the csr_waitrequest signal goes low, the HPC II is then ready to accept more requests.
	Input Output Input Input Output Output Output

5.5.5. Soft Controller Register Map

The soft controller register map allows you to control the soft memory controller settings.

Note: Dynamic reconfiguration is not currently supported.

The following table lists the register map for the controller.

Soft Controller Register Map Table 61.

Address	Bit	Name	Default	Access	Description
0x100	0	Reserved.	0	_	Reserved for future use.
	1	Reserved.	0	_	Reserved for future use.
	2	Reserved.	0	_	Reserved for future use.
	7:3	Reserved.	0	_	Reserved for future use.
	13:8	Reserved.	0	_	Reserved for future use.
	30:14	Reserved.	0	_	Reserved for future use.
0x110	15:0	AUTO_PD_CYCLES	0x0	Read write	The number of idle clock cycles after which the controller should place the memory into powerdown mode. The controller is considered to be idle if there are no commands in the command queue. Setting this register to 0 disables the auto power-down
					continued

^{1.} Applies only to the hard memory controller with multiport front end available in Arria V and Cyclone V devices.



Reserved. Reserved. Reserved for future use.	Address	Bit	Name	Default	Access	Description
17						mode. The default value of this register depends on the values set during the generation of the design.
18		16	Reserved.	0	_	Reserved for future use.
19 Reserved. 0 — Reserved for future use.		17	Reserved.	0	_	Reserved for future use.
21:20 ADDR_ORDER 00 Read write 00 - Chip, row, bank, colt - Chip, bank, row, column reserved for future use. 12 Reserved for future use. 12 Reserved for future use. 13 Reserved for future use. 14 Reserved for future use. 15 Reserved for future use. 16 Reserved for future use. 17 Reserved for future use. 17 Reserved for future use. 18 Reserved for future use. 18 Reserved for future use. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in memory interface. 19 Read write for the memory devices in your memory interface. 19 Read write for the memory int		18	Reserved.	0	_	Reserved for future use.
Chip, bank, row, column reserved for future use. 17 Reserved for future use. 17 Reserved for future use. 24:23 Reserved. 0 — Reserved for future use. 24:23 Reserved. 0 — Reserved for future use. 30:24 Reserved 0 — Reserved for future use. 20:24 Reserved 0 — Reserved for future use. 20:25 Reserved		19	Reserved.	0	_	Reserved for future use.
24:23 Reserved. 0 — Reserved for future use.		21:20	ADDR_ORDER	00	Read write	00 - Chip, row, bank, column.01 - Chip, bank, row, column.10 - reserved for future use.11 - Reserved for future use.
30:24 Reserved 0 — Reserved for future use.		22	Reserved.	0	_	Reserved for future use.
Ox120 7:0 Column address width — Read write The number of column address vyour memory interface. The range of legal values is 7- 15:8 Row address width — Read write The number of row address for the memory devices in memory interface. The range of legal values is 12-16. 19:16 Bank address width — Read write The number of bank address width — Read write The number of bank address width — Read write The number of bank address bits for the memory devices in memory interface. The range of legal values is 2-3. 23:20 Chip select address width — Read write The number of chip select address bits for the memory interface. The range of legal values is 0-2. If there is one single chip select in the minterface, set this bit to 0 31:24 Reserved. 0 — Reserved for future use. 0x121 31:0 Data width representation (word) The number of DQS bits in memory interface. This bit is value by the number pins per DQS pin (typicall) 0x122 7:0 Chip select representation — Read only The number of chip select binary representation. For example, a design with 2 selects has the value of 00000011.		24:23	Reserved.	0	_	Reserved for future use.
bits for the memory devices in range of legal values is 7- 15:8 Row address width		30:24	Reserved	0	_	Reserved for future use.
Part	0x120	7:0	Column address width	_	Read write	The number of column address bits for the memory devices in your memory interface. The range of legal values is 7-12.
Chip select address width Read write The number of chip select address bits for the memory interface. The range of leg values is 2-3.		15:8	Row address width	_	Read write	The number of row address bits for the memory devices in your memory interface. The range of legal values is 12-16.
address bits for the memory devices in your memory interface. The range of lev values is 0-2. If there is on single chip select in the minterface, set this bit to 0. 31:24 Reserved. O Reserved for future use. Ox121 31:0 Data width representation (word) The number of DQS bits in memory interface. This bit used to derive the width of memory interface by multithis value by the number pins per DQS pin (typicall ox122) 7:0 Chip select representation Read only The number of chip select binary representation. For example, a design with 2 selects has the value of 00000011.		19:16	Bank address width	_	Read write	The number of bank address bits for the memory devices in your memory interface. The range of legal values is 2-3.
0x121 31:0 Data width representation (word) — Read only memory interface. This bit used to derive the width of memory interface by multithis value by the number pins per DQS pin (typicall) 0x122 7:0 Chip select representation — Read only Read only binary representation. For example, a design with 2 selects has the value of 00000011.		23:20	Chip select address width	_	Read write	The number of chip select address bits for the memory devices in your memory interface. The range of legal values is 0-2. If there is only one single chip select in the memory interface, set this bit to 0.
(word) (word) memory interface. This bit used to derive the width of memory interface by mult this value by the number pins per DQS pin (typicall) 7:0 Chip select representation Read only The number of chip select binary representation. For example, a design with 2 selects has the value of 00000011.		31:24	Reserved.	0	_	Reserved for future use.
binary representation. For example, a design with 2 selects has the value of 00000011.	0x121	31:0		_	Read only	The number of DQS bits in the memory interface. This bit can be used to derive the width of the memory interface by multiplying this value by the number of DQ pins per DQS pin (typically 8).
31:8 Reserved. 0 — Reserved for future use.	0x122	7:0	Chip select representation	_	Read only	
		31:8	Reserved.	0	_	Reserved for future use.
timing parameter. The rar legal values is 2-11 cycles	0x123	3:0	tRCD	_	Read write	The activate to read or write a timing parameter. The range of legal values is 2-11 cycles.





Address	Bit	Name	Default	Access	Description
	7:4	tRRD	_	Read write	The activate to activate a timing parameter. The range of legal values is 2-8 cycles.
	11:8	tRP	_	Read write	The precharge to activate a timing parameter. The range of legal values is 2-11 cycles.
	15:12	tMRD	_	Read write	The mode register load time parameter. This value is not used by the controller, as the controller derives the correct value from the memory type setting.
	23:16	tRAS	_	Read write	The activate to precharge a timing parameter. The range of legal values is 4-29 cycles.
	31:24	tRC	_	Read write	The activate to activate a timing parameter. The range of legal values is 8-40 cycles.
0x124	3:0	tWTR	_	Read write	The write to read a timing parameter. The range of legal values is 1-10 cycles.
	7:4	tRTP	_	Read write	The read to precharge a timing parameter. The range of legal values is 2-8 cycles.
	15:8	tFAW	_	Read write	The four-activate window timing parameter. The range of legal values is 6-32 cycles.
	31:16	Reserved.	0	_	Reserved for future use.
0x125	15:0	tREFI	_	Read write	The refresh interval timing parameter. The range of legal values is 780-6240 cycles.
	23:16	tRFC	_	Read write	The refresh cycle timing parameter. The range of legal values is 12-255 cycles.
	31:24	Reserved.	0	_	Reserved for future use.
0x126	3:0	Reserved.	0	_	Reserved for future use.
	7:4	Reserved.	0	-	Reserved for future use.
	11:8	Reserved.	0	_	Reserved for future use.
	15:12	Reserved.	0	_	Reserved for future use.
	23:16	Burst Length	_	Read write	Value must match memory burst length.
	31:24	Reserved.	0	_	Reserved for future use.
0x130	0	ENABLE_ECC	1	Read write	When this bit equals 1, it enables the generation and checking of ECC. This bit is only active if ECC was enabled during IP parameterization.
	1	ENABLE_AUTO_CORR	_	Read write	When this bit equals 1, it enables auto-correction when a single-bit error is detected.
					continued



Address	Bit	Name	Default	Access	Description
	2	GEN_SBE	0	Read write	When this bit equals 1, it enables the deliberate insertion of single-bit errors, bit 0, in the data written to memory. This bit is used only for testing purposes.
	3	GEN_DBE	0	Read write	When this bit equals 1, it enables the deliberate insertion of double-bit errors, bits 0 and 1, in the data written to memory. This bit is used only for testing purposes.
	4	ENABLE_INTR	1	Read write	When this bit equals 1, it enables the interrupt output.
	5	MASK_SBE_INTR	0	Read write	When this bit equals 1, it masks the single-bit error interrupt.
	6	MASK_DBE_INTR	0	Read write	When this bit equals 1, it masks the double-bit error interrupt
	7	CLEAR	0	Read write	When this bit equals 1, writing to this self-clearing bit clears the interrupt signal, and the error status and error address registers.
	8	MASK_CORDROP_INTR	0	Read write	When this bit equals 1, the dropped autocorrection error interrupt is dropped.
	9	Reserved.	0	_	Reserved for future use.
0x131	0	SBE_ERROR	0	Read only	Set to 1 when any single-bit errors occur.
	1	DBE_ERROR	0	Read only	Set to 1 when any double-bit errors occur.
	2	CORDROP_ERROR	0	Read only	Value is set to 1 when any controller-scheduled autocorrections are dropped.
	7:3	Reserved.	0	_	Reserved for future use.
	15:8	SBE_COUNT	0	Read only	Reports the number of single-bit errors that have occurred since the status register counters were last cleared.
	23:16	DBE_COUNT	0	Read only	Reports the number of double-bit errors that have occurred since the status register counters were last cleared.
	31:24	CORDROP_COUNT	0	Read only	Reports the number of controller- scheduled autocorrections dropped since the status register counters were last cleared.
0x132	31:0	ERR_ADDR	0	Read only	The address of the most recent ECC error. This address is a memory burst-aligned local address.
					continued





Address	Bit	Name	Default	Access	Description
0x133	31:0	CORDROP_ADDR	0	Read only	The address of the most recent autocorrection that was dropped. This is a memory burst-aligned local address.
0x134	0	REORDER_DATA	_	Read write	
	15:1	Reserved.	0	-	Reserved for future use.
	23:16	STARVE_LIMIT	0	Read write	Number of commands that can be served before a starved command.
	31:24	Reserved.	0	_	Reserved for future use.

5.5.6. Hard Controller Register Map

The hard controller register map allows you to control the hard memory controller settings.

Note: Dynamic reconfiguration is not currently supported.

The following table lists the register map for the hard controller.

Table 62. Hard Controller Register Map

Address	Bit	Name	Default	Access	Description
0x000	3:0	CFG_CAS_WR_LAT	0	Read/Write	Memory write latency.
0x001	4:0	CFG_ADD_LAT	0	Read/Write	Memory additive latency.
0x002	4:0	CFG_TCL	0	Read/Write	Memory read latency.
0x003	3:0	CFG_TRRD	0	Read/Write	The activate to activate different banks timing parameter.
0x004	5:0	CFG_TFAW	0	Read/Write	The four-activate window timing parameter.
0x005	7:0	CFG_TRFC	0	Read/Write	The refresh cycle timing parameter.
0x006	12:0	CFG_TREFI	0	Read/Write	The refresh interval timing parameter.
0×008	3:0	CFG_TREFI	0	Read/Write	The activate to read/write timing parameter.
0x009	3:0	CFG_TRP	0	Read/Write	The precharge to activate timing parameter.
0x00A	3:0	CFG_TWR	0	Read/Write	The write recovery timing.
0×00B	3:0	CFG_TWTR	0	Read/Write	The write to read timing parameter.
0x00C	3:0	CFG_TRTP	0	Read/Write	The read to precharge timing parameter.
0x00D	4:0	CFG_TRAS	0	Read/Write	The activate to precharge timing parameter.
		<u> </u>			continued





Address	Bit	Name	Default	Access	Description
0x00E	5:0	CFG_TRC	0	Read/Write	The activate to activate timing parameter.
0x00F	15:0	CFG_AUTO_PD_CYCLES	0	Read/Write	The number of idle clock cycles after which the controller should place the memory into power-down mode.
0x011	9:0	CFG_SELF_RFSH_EXIT_CYCLES	0	Read/Write	The self-refresh exit cycles.
0x013	9:0	CFG_PDN_EXIT_CYCLES	0	Read/Write	The power down exit cycles.
0x015	3:0	CFG_TMRD	0	Read/Write	Mode register timing parameter.
0x016	4:0	CFG_COL_ADDR_WIDTH	0	Read/Write	The number of column address bits for the memory devices in your memory interface.
0x017	4:0	CFG_ROW_ADDR_WIDTH	0	Read/Write	The number of row address bits for the memory devices in your memory interface.
0x018	2:0	CFG_BANK_ADDR_WIDTH	0	Read/Write	The number of bank address bits for the memory devices in your memory interface.
0x019	2:0	CFG_CS_ADDR_WIDTH	0	Read/Write	The number of chip select address bits for the memory devices in your memory interface.
0x035	3:0	CFG_TCCD	0	Read/Write	CAS#-to-CAS# command delay.
0x035	3:0	CFG_WRITE_ODT_CHIP	0	Read/Write	CAS#-to-CAS# command delay.
0x037	3:0	CFG_READ_ODT_CHIP	0	Read/Write	Read ODT Control.
0x040	2:0	CFG_TYPE	0	Read/Write	Selects memory type.
	7:3	CFG_BURST_LENGTH	0	Read/Write	Configures burst length as a static decimal value.
	9:8	CFG_ADDR_ORDER	0	Read/Write	Address order selection.
	10	CFG_ENABLE_ECC	0	Read/Write	Enable the generation and checking of ECC.
	11	CFG_ENABLE_AUTO_CORR	0	Read/Write	Enable auto correction when single bit error is detected.
	12	CFG_GEN_SBE	0	Read/Write	When this bit equals 1, it enables the deliberate insertion of single-bit errors, bit 0, in the data written to memory. This bit is used only for testing purposes.
	13	CFG_GEN_DBE	0	Read/Write	When this bit equals 1, it enables the deliberate insertion of double-bit errors, bits 0 and 1, in the data written to memory. This bit is used only for testing purposes.
	14	CFG_REORDER_DATA	0	Read/Write	Enable Data Reordering.
	15	CFG_USER_RFSH	0	Read/Write	Enable User Refresh.
					continued





Address	Bit	Name	Default	Access	Description
	16	CFG_REGDIMM_ENABLE	0	Read/Write	REG DIMM Configuration.
	17	CFG_ENABLE_DQS_TRACKING	0	Read/Write	Enable DQS Tracking.
	18	CFG_OUTPUT_REGD	0	Read/Write	Enable Registered Output.
19		CFG_ENABLE_NO_DM	0	Read/Write	No Data Mask Configuration.
	20	CFG_ENABLE_ECC_CODE_OVE RWRITES	0	Read/Write	Enable ECC Code Overwrite in Double Error Bit Detection.
0x043	7:0	CFG_INTERFACE_WIDTH	0	Read/Write	Memory Interface Width.
0x044	3:0	CFG_DEVICE_WIDTH	0	Read/Write	Memory Device Width.
0x045	0	CFG_CAL_REQ	0	Read/Write	Request re-calibration.
	6:1	CFG_CLOCK_OFF	0	Read/Write	Disable memory clock.
0x047	0	STS_CAL_SUCCESS	0	Read Only	Calibration Success.
	1	STS_CAL_FAIL	0	Read Only	Calibration Fail.
	2	STS_SBE_ERROR	0	Read Only	Single Bit Error Detected.
	3	STS_DBE_ERROR	0	Read Only	Double Bit Error Detected.
	4	STS_CORR_DROPPED	0	Read Only	Auto Correction Dropped.
0x048	0	CFG_ENABLE_INTR	0	Read/Write	Enable Interrupt
	1	CFG_MASK_SBE_INTR	0	Read/Write	Mask Single Bit Error Interrupt.
	2	CFG_MASK_DBE_INTR	0	Read/Write	Mask Double Bit Error Interrupt.
	3	CFG_MASK_DBE_INTR	0	Write Clear	Clear Interrupt.
0x049	7:0	STS_SBD_COUNT	0	Read Only	Reports the number of SBE errors that have occurred since the status register counters were last cleared.
0x04A	7:0	STS_DBE_COUNT	0	Read Only	Reports the number of SBE errors that have occurred since the status register counters were last cleared.
0x04B	31:0	STS_ERR_ADDR	0	Read Only	The address of the most recent ECC error.
0x04F	0	CFG_MASK_CORR_DROPPED_I NTR	0	Read/Write	Auto Correction Dropped Count.
0x050	7:0	CFG_MASK_CORR_DROPPED_I NTR	0	Read Only	Auto Correction Dropped Count.
0x051	31:0	STS_CORR_DROPPED_ADDR	0	Read Only	Auto Correction Dropped Address.
0x055	5:0	CFG_STARVE_LIMIT	0	Read/Write	Starvation Limit.
0x056	1:0	CFG_MEM_BL	0	Read/Write	Burst Length.
	2	CFG_MEM_BL	0	Read/Write	ECC Enable.
0x057	1:0	CFG_MEM_BL	0	Read/Write	Specifies controller interface width.
0x058	11:0	CMD_PORT_WIDTH	0	Read/Write	Specifies per command port data width.
	•	•	•	•	continued





Address	Bit	Name	Default	Access	Description
0x05A	11:0	CMD_FIFO_MAP	0	Read/Write	Specifies command port to Write FIFO association.
0x05C	11:0	CFG_CPORT_RFIFO_MAP	0	Read/Write	Specifies command port to Read FIFO association.
	23:12	CFG_RFIFO_CPORT_MAP	0	Read/Write	Port assignment (0 - 5) associated with each of the N FIFO.
	31:24	CFG_WFIFO_CPORT_MAP	0	Read/Write	Port assignment (0 - 5) associated with each of the N FIFO. (con't)
0x05D	3:0	CFG_WFIFO_CPORT_MAP	0	Read/Write	Port assignment (0 - 5) associated with each of the N FIFO.
	14:4	CFG_CPORT_TYPE	0	Read/Write	Command port type.
0x062	2:0	CFG_CLOSE_TO_FULL	0	Read/Write	Indicates when the FIFO has this many empty entries left.
	5:3	CFG_CLOSE_TO_EMPTY	0	Read/Write	Indicates when the FIFO has this many valid entries left.
	11:6	CFG_CLOSE_TO_EMPTY	0	Read/Write	Port works in synchronous mode.
	12	CFG_INC_SYNC	0	Read/Write	Set the number of FF as clock synchronizer.
0x067	5:0	CFG_ENABLE_BONDING	0	Read/Write	Enables bonding for each of the control ports.
	7:6	CFG_DELAY_BONDING	0	Read/Write	Set to the value used for the bonding input to bonding output delay.
0x069	5:0	CFG_AUTO_PCH_ENABLE	0	Read/Write	Control auto-precharage options.
0x06A	17:0	MP_SCHEDULER_PRIORITY	0	Read/Write	Set absolute user priority of the port
0x06D	29:0	RCFG_ST_WT	0	Read/Write	Set static weight of the port.
	31:30	RCFG_SUM_PRI_WT	0	Read/Write	Set the sum of static weights for particular user priority.
0x06E	31:0	RCFG_SUM_PRI_WT	0	Read/Write	Set the sum of static weights for particular user priority.
0x06F	29:0	RCFG_SUM_PRI_WT	0	Read/Write	Set the sum of static weights for particular user priority.
0x0B9	0	CFG_DISABLE_MERGING	0	Read/Write	Set to a one to disable command merging.

5.6. Sequence of Operations

Various blocks pass information in specific ways in response to write, read, and read-modify-write commands.





Write Command

When a requesting master issues a write command together with write data, the following events occur:

- The input interface accepts the write command and the write data.
- The input interface passes the write command to the command generator and the write data to the write data buffer.
- The command generator processes the command and sends it to the timing bank pool.
- Once all timing requirements are met and a write-data-ready notification has been received from the write data buffer, the timing bank pool sends the command to the arbiter.
- When rank timing requirements are met, the arbiter grants the command request from the timing bank pool and passes the write command to the AFI interface.
- The AFI interface receives the write command from the arbiter and requests the corresponding write data from the write data buffer.
- The PHY receives the write command and the write data, through the AFI interface.

Read Command

When a requesting master issues a read command, the following events occur:

- The input interface accepts the read command.
- The input interface passes the read command to the command generator.
- The command generator processes the command and sends it to the timing bank pool.
- Once all timing requirements are met, the timing bank pool sends the command to the arbiter.
- When rank timing requirements are met, the arbiter grants the command request from the timing bank pool and passes the read command to the AFI interface.
- The AFI interface receives the read command from the arbiter and passes the command to the PHY.
- The PHY receives the read command through the AFI interface, and returns read data through the AFI interface.
- The AFI interface passes the read data from the PHY to the read data buffer.
- The read data buffer sends the read data to the master through the input interface.





Read-Modify-Write Command

A read-modify-write command can occur when enabling ECC for partial write, and for ECC correction commands. When a read-modify-write command is issued, the following events occur:

- The command generator issues a read command to the timing bank pool.
- The timing bank pool and arbiter passes the read command to the PHY through the AFI interface.
- The PHY receives the read command, reads data from the memory device, and returns the read data through the AFI interface.
- The read data received from the PHY passes to the ECC block.
- The read data is processed by the write data buffer.
- When the write data buffer issues a read-modify-write data ready notification to the command generator, the command generator issues a write command to the timing bank pool. The arbiter can then issue the write request to the PHY through the AFI interface.
- When the PHY receives the write request, it passes the data to the memory device.

5.7. Document Revision History

Date	Version	Changes
March 2023	2023.03.06	In the <i>Local Interface Signals</i> topic, added a sentence to the description of the avl_be signal.
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Changed instances of <i>Quartus II</i> to <i>Quartus Prime</i> . Added CFG_GEN_SBE and CFG_GEN_DBE to <i>Hard Controller Register Map</i> table.
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Renamed Controller Register Map to Soft Controller Register Map. Added Hard Controller Register Map.
August 2014	2014.08.15	 Added "asynchronous" to descriptions of mp_cmd_reset_n_#_reset_n, mp_rfifo_reset_n_#_reset_n, and mp_wfifo_reset_n_#_reset_n signals in the MPFE Signals table. Added Reset description to Hard Memory Controller section. Added full-rate hard memory controller information for Arria V and Cyclone V to description of avl_addr[] in the Local Interface Signals table. Reworded avl_burstbegin description in the Local Interface Signals table.
December 2013	2013.12.16	Removed references to ALTMEMPHY. Removed references to SOPC Builder. Removed Half-Rate Bridge information. Modified Burst Merging description. Expanded description of avl_ready in Local Interface Signals table. continued





Date	Version	Changes
		 Added descriptions of local_cal_success and local_cal_fail to Local Interface Signals table. Modified description of avl_size in Local Interface Signals table. Added guidance to initialize memory before use.
November 2012	2.1	 Added Controller Register Map information. Added Burst Merging information. Updated User-Controlled Refresh Interface information. Changed chapter number from 4 to 5.
June 2012	2.0	Added LPDDR2 support. Added Feedback icon.
November 2011	1.1	 Revised Figure 5-1. Added AXI to Avalon-ST Converter information. Added AXI Data Slave Interface information. Added Half-Rate Bridge information.







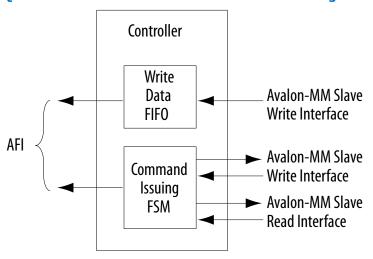
6. Functional Description—QDR II Controller

The QDR II and QDR II+ controllers translate memory requests from the Avalon Memory-Mapped (Avalon-MM) interface to AFI, while satisfying timing requirements imposed by the memory configuration. QDR II and QDR II+ SRAM have unidirectional data buses, therefore read and write operations are highly independent of each other and each has its own interface and state machine.

6.1. Block Description

The following figure shows a block diagram of the QDR II and QDR II+ SRAM controller architecture.

Figure 57. QDR II and QDR II+ SRAM Controller Architecture Block Diagram



6.1.1. Avalon-MM Slave Read and Write Interfaces

The read and write blocks accept read and write requests, respectively, from the Avalon-MM interface. Each block has a simple state machine that represents the state of the command and address registers, which stores the command and address when a request arrives.

The read data passes through without the controller registering it, as the PHY takes care of read latency. The write data goes through a pipeline stage to delay for a fixed number of cycles as specified by the write latency. In the full-rate burst length of four controller, the write data is also multiplexed into a burst of 2, which is then multiplexed again in the PHY to become a burst of 4 in DDR.

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The user interface to the controller has separate read and write Avalon-MM interfaces because reads and writes are independent of each other in the memory device. The separate channels give efficient use of available bandwidth.

6.1.2. Command Issuing FSM

The command-issuing finite-state machine (FSM) has two states: INIT and INIT_COMPLETE. In the INIT_COMPLE TE state, commands are issued immediately as requests arrive using combinational logic and do not require state transitions.

6.1.3. AFI

The QDR II and QDR II+ controller communicates with the PHY using the Altera PHY interface (AFI).

In the full-rate burst-length-of-two configuration, the controller can issue both read and write commands in the same clock cycle. In the memory device, both commands are clocked on the positive edge, but the read address is clocked on the positive edge, while the write address is clocked on the negative edge. Care must be taken on how these signals are ordered in the AFI.

For the half-rate burst-length-of-four configuration, the controller also issues both read and write commands, but the AFI width is doubled to fill two memory clocks per controller clock. Because the controller issues only one write command and one read command per controller clock, the AFI read and write signals corresponding to the other memory cycle are tied to no operation (NOP).

For the full-rate burst-length-of-four configuration, the controller alternates between issuing read and write commands every clock cycle. The memory device requires two clock cycles to complete the burst-length-of-four operation and requires an interleaving of read and write commands.

For information on the AFI, refer to AFI 3.0 Specification in chapter 1, Functional Description - UniPHY.

Related Information

- AFI 3.0 Specification on page 35
- Functional Description—UniPHY on page 8

6.2. Avalon-MM and Memory Data Width

The following table lists the data width ratio between the memory interface and the Avalon-MM interface.

The half-rate controller does not support burst-of-2 devices because it under-uses the available memory bandwidth. Regardless of full or half-rate decision and the device burst length, the Avalon-MM interface must supply all the data for the entire memory burst in a single clock cycle. Therefore the Avalon-MM data width of the full-rate controller with burst-of-4 devices is four times the memory data width. For width-expanded configurations, the data width is further multiplied by the expansion factor (not shown in table 5-1 and 5-2).



Table 63. Data Width Ratio

Memory Burst Length	Half-Rate Designs	Full-Rate Designs
QDR II 2-word burst	No Support	2:1
QDR II and QDR II+ 4-word burst	4.	:1

6.3. Signal Descriptions

The following tables lists the signals of the controller's Avalon-MM slave interface.

Table 64. Avalon-MM Slave Read Signals

UniPHY Signal Name	Width	Direction	Avalon-MM Signal Type
avl_r_ready	1	Out	waitrequest_n
avl_r_read_req	1	In	read
avl_r_addr	15-25	In	address
avl_r_rdata_valid	1	Out	readdatavalid
avl_r_rdata	9, 18, 36 (or 8, 16, 32 if power- of-2-bus is enabled in the controller)	Out	readdata
avl_r_size	log_2(MAX_BURS T_SIZE) + 1		burstcount

Note:

To obtain the actual signal width, you must multiply the widths in the above table by the data width ratio and the width expansion ratio.

Table 65. Avalon-MM Slave Write Signals

UniPHY Signal Name	Width	Direction	Avalon-MM Signal Type
avl_w_ready	1	Out	waitrequest_n
avl_w_write_req	1	In	write
avl_w_addr	15-25	In	address
avl_w_wdata	9, 18, 36 (or 8, 16, 32 if power- of-2-bus is enabled in the controller)	In	writedata
avl_w_be	1,2,4	In	byteenable
avl_w_size	log_2(MAX_BURS T_SIZE) + 1	In	burstcount





Note:

To obtain the actual signal width, you must multiply the widths in the above table by the data width ratio and the width expansion ratio.

6.4. Document Revision History

Date	Version	Changes
March 2023	2023.03.06	Removed references to Intel Arria 10 and Intel Stratix 10 devices and associated protocols.
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Maintenance release.
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	 Added QDR II+ Xtreme throughout the chapter. Added full-rate, burst-length-of-four information to AFI section. Revised Avalon-MM Slave Read Signals table to include Arria 10 information. Revised Avalon-MM Slave Write Signals table to include Arria 10 information.
December 2013	2013.12.16	Removed references to SOPC Builder.
November 2012	3.3	Changed chapter number from 5 to 6.
June 2012	3.2	Added Feedback icon.
November 2011	3.1	Harvested Controller chapter from 11.0 QDR II and QDR II+ SRAM Controller with UniPHY User Guide.





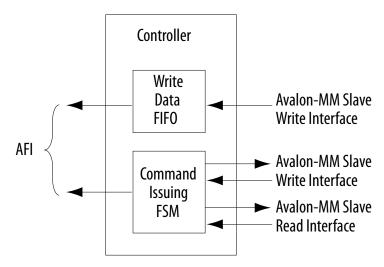
7. Functional Description—RLDRAM II Controller

The RLDRAM II controller translates memory requests from the Avalon Memory-Mapped (Avalon-MM) interface to AFI, while satisfying timing requirements imposed by the memory configurations.

7.1. Block Description

The following figure shows a block diagram of the RLDRAM II controller architecture.

Figure 58. RLDRAM II Controller Architecture Block Diagram



7.1.1. Avalon-MM Slave Interface

The Avalon-MM slave interface accepts read and write requests. A simple state machine represents the state of the command and address registers, which stores the command and address when a request arrives.

The Avalon-MM slave interface decomposes the Avalon-MM address to the memory bank, column, and row addresses. The IP automatically maps the bank address to the LSB of the Avalon address vector.



The Avalon-MM slave interface includes a burst adaptor, which has two parts:

- The first part is a read and write request combiner that groups requests to sequential addresses into the native memory burst. Given that the second request arrives within the read and write latency window of the first request, the controller can combine and satisfy both requests with a single memory transaction.
- The second part is the burst divider in the front end of the Avalon-MM interface, which breaks long Avalon bursts into individual requests of sequential addresses, which then pass to the controller state machine.

7.1.2. Write Data FIFO Buffer

The write data FIFO buffer accepts write data from the Avalon-MM interface. The AFI controls the subsequent consumption of the FIFO buffer write data.

7.1.3. Command Issuing FSM

The command issuing finite-state machine (FSM) has three states.

The controller is in the INIT state when the PHY initializes the memory. Upon receiving the afi_cal_success signal, the state transitions to INIT_COMPLETE. If the calibration fails, afi_cal_fail is asserted and the state transitions to INIT_FAIL. The PHY receives commands only in the INIT_COMPLETE state.

When a refresh request arrives at the state machine at the same time as a read or write request, the refresh request takes precedence. The read or write request waits until there are no more refresh requests, and is issued immediately if timing requirements are met.

7.1.4. Refresh Timer

With automatic refresh, the refresh timer periodically issues refresh requests to the command issuing FSM. The refresh interval can be set at generation.

7.1.5. Timer Module

The timer module contains one DQ timer and eight bank timers (one per bank). The DQ timer tracks how often read and write requests can be issued, to avoid bus contention. The bank timers track the cycle time (tRC).

The 8-bit wide output bus of the bank timer indicates to the command issuing FSM whether each bank can be issued a read, write, or refresh command.

7.1.6. AFI

The RLDRAM II controller communicates with the PHY using the AFI interface. For information on the AFI, refer to AFI 3.0 Specification in Functional Description - UniPHY.

Related Information

- AFI 3.0 Specification on page 35
- Functional Description—UniPHY on page 8



7.2. User-Controlled Features

The **General Settings** tab of the parameter editor contains several features which are disabled by default. You can enable these features as required for your external memory interface.

7.2.1. Error Detection Parity

The error detection feature asserts an error signal if it detects any corrupted data during the read process.

The error detection parity protection feature creates a simple parity encoder block which processes all read and write data. For every 8 bits of write data, a parity bit is generated and concatenated to the data before it is written to the memory. During the subsequent read operation, the parity bit is checked against the data bits to ensure data integrity.

When you enable the error detection parity protection feature, the local data width is reduced by one. For example, a nine-bit memory interface will present eight bits of data to the controller interface.

You can enable error detection parity protection in the **Controller Settings** section of the **General Settings** tab of the parameter editor.

7.2.2. User-Controlled Refresh

The user-controlled refresh feature allows you to take control of the refresh process that the controller normally performs automatically. You can control when refresh requests occur, and, if there are multiple memory devices, you control which bank receives the refresh signal.

When you enable this feature, you disable auto-refresh, and assume responsibility for maintaining the necessary average periodic refresh rate. You can enable user-controlled refresh in the **Controller Settings** section of the **General Settings** tab of the parameter editor.

7.3. Avalon-MM and Memory Data Width

The following table lists the data width ratio between the memory interface and the Avalon-MM interface. The half-rate controller does not support burst-of-2 devices because it under-uses the available memory bandwidth.

Table 66. Data Width Ratio

Memory Burst Length	Half-Rate Designs	Full-Rate Designs
2-word	No Support	2:1
4-word	4:1	
8-word		

7.4. Signal Descriptions

The following table lists the signals of the controller's Avalon-MM slave interface.







For information on the AFI signals, refer to AFI 3.0 Specification in Functional Description - UniPHY.

Table 67. **Avalon-MM Slave Signals**

Signal	Width	Direction	Avalon-MM Signal Type	Description
avl_size	1 to 11	In	burstcount	_
avl_ready	1	Out	waitrequest_n	_
avl_read_req	1	In	read	_
avl_write_req	1	In	write	_
avl_addr	□ 25	In	address	_
avl_rdata_valid	1	Out	readdatavalid	_
avl_rdata	18, 36, 72, 144	Out	readdata	_
avl_wdata	18, 36, 72, 144	In	writedata	_

Note:

- 1. If you are using Platform Designer, the data width of the Avalon-MM interface is restricted to powers of two. Non-power-of-two data widths are available with the IP Catalog.
- 2. The RLDRAM II controller does not support the byteenable signal. If the RLDRAM II controller is used with the Avalon-MM Efficiency Monitor and Protocol Checker, data corruption can occur if the byteenable signal on the efficiency monitor is used. For example, this can occur if using the JTAG Avalon-MM Master component to drive the efficiency monitor.

Related Information

- AFI 3.0 Specification on page 35
- Functional Description—UniPHY on page 8

7.5. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Maintenance release.
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	Removed occurrence of MegaWizard Plug-In Manager.
December 2013	2013.12.16	Removed references to SOPC Builder.
		continued



Date	Version	Changes
November 2012	3.3	Changed chapter number from 6 to 7.
June 2012	3.2	Added Feedback icon.
November 2011	3.1	Harvested Controller chapter from 11.0 RLDRAM II Controller with UniPHY IP User Guide.







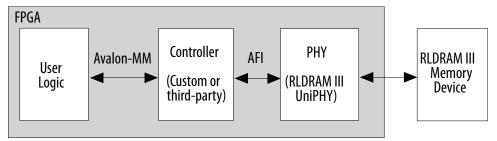
8. Functional Description—RLDRAM 3 PHY-Only IP

The RLDRAM 3 PHY-only IP works with a customer-supplied memory controller to translate memory requests from user logic to RLDRAM 3 memory devices, while satisfying timing requirements imposed by the memory configurations.

8.1. Block Description

The RLDRAM 3 UniPHY-based IP is a PHY-only offering which you can use with a thirdparty controller or a controller that you develop yourself. The following figure shows a block diagram of the RLDRAM 3 system architecture.

Figure 59. **RLDRAM 3 System Architecture**



8.2. Features

The RLDRAM 3 UniPHY-based IP supports features available from major RLDRAM 3 device vendors at speeds of up to 800 MHz.

The following list summarizes key features of the RLDRAM 3 UniPHY-based IP:

- support for Arria V GZ and Stratix V devices
- standard AFI interface between the PHY and the memory controller
- guarter-rate and half-rate AFI interface
- maximum frequency of 533 MHz for half-rate operation and 800 MHz for quarterrate operation
- burst length of 2, 4, or 8
- x18 and x36 memory organization
- common I/O device support
- nonmultiplexed addressing
- multibank write and refresh protocol (programmable through mode register)
- optional use of data mask pins

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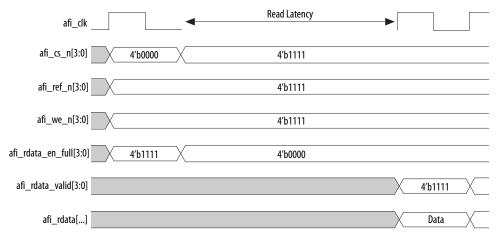


8.3. RLDRAM 3 AFI Protocol

The RLDRAM 3 UniPHY-based IP communicates with the memory controller using an AFI interface that follows the AFI 3.0 specification. To maximize bus utilization efficiency, the RLDRAM 3 UniPHY-based IP can issue multiple memory read/write operations within a single AFI cycle.

The following figure illustrates AFI bus activity when a quarter-rate controller issues four consecutive burst-length 2 read requests.

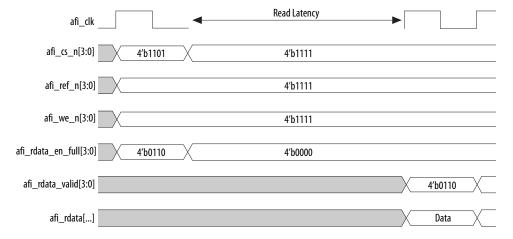
Figure 60. AFI Bus Activity for Quarter-Rate Controller Issuing Four Burst-Length 2
Read Requests



The controller does not have to begin a read or write command using channel 0 of the AFI bus. The flexibility afforded by being able to begin a command on any bus channel can facilitate command scheduling in the memory controller.

The following figure illustrates the AFI bus activity when a quarter-rate controller issues a single burst-length 4 read command to the memory on channel 1 of the AFI bus.

Figure 61. AFI Bus Activity for Quarter-Rate Controller Issuing One Burst-Length 4 Read Request







Note:

For information on the AFI, refer to AFI 3.0 Specification in Functional Description - UniPHY.

Related Information

- AFI 3.0 Specification on page 35
- Functional Description—UniPHY on page 8

8.4. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Maintenance release.
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	Added RLDRAM 3 Controller with Arria 10 EMIF Interfaces.
December 2013	2013.12.16	Maintenance release.
November 2012	1.0	Initial release.







9. Functional Description—Example Designs

Generation of your external memory interface IP creates two independent example designs. These example designs illustrate how to instantiate and connect the memory interface for both synthesis and simulation flows.

9.1. UniPHY-Based Example Designs

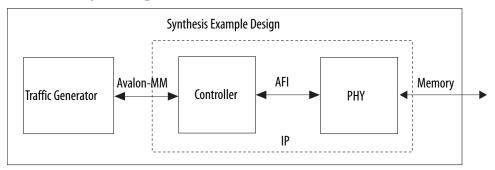
For UniPHY-based interfaces, two independent example designs are created, each containing independent RTL files and other project files. You should compile or simulate these designs separately, and the files should not be mixed. Nonetheless, the designs are related, as the simulation example design builds upon the design of the synthesis example design.

9.1.1. Synthesis Example Design

The synthesis example design contains the major blocks shown in the figure below.

- A traffic generator, which is a synthesizable Avalon-MM example driver that implements a pseudo-random pattern of reads and writes to a parameterized number of addresses. The traffic generator also monitors the data read from the memory to ensure it matches the written data and asserts a failure otherwise.
- An instance of the memory interface, which includes:
 - A memory controller that moderates between the Avalon-MM interface and the AFI interface.
 - The PHY, which serves as an interface between the memory controller and external memory devices to perform read and write operations.

Figure 62. Synthesis Example Design

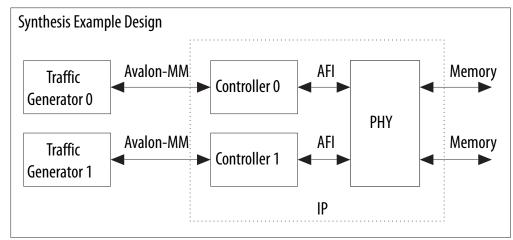


If you are using the Ping Pong PHY feature, the synthesis example design includes two traffic generators issuing commands to two independent memory devices through two independent controllers and a common PHY, as shown in the following figure.

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Figure 63. Synthesis Example Design for Ping Pong PHY



If you are using RLDRAM 3, the traffic generator in the synthesis example design communicates directly with the PHY using AFI, as shown in the following figure. If you are using RLDRAM 3, the traffic generator in the synthesis example design communicates directly with the PHY using AFI, as shown in the following figure.

Figure 64. Synthesis Example Design for RLDRAM 3 Interfaces

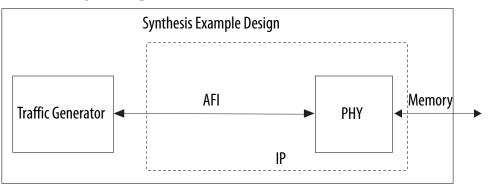
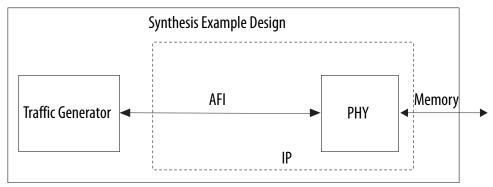


Figure 65. Synthesis Example Design for RLDRAM 3 Interfaces







Note:

If one or more of the **PLL Sharing Mode**, **DLL Sharing Mode**, or **OCT Sharing Mode** parameters are set to any value other than **No Sharing**, the synthesis example design will contain two traffic generator/memory interface instances. The two traffic generator/memory interface instances are related only by shared PLL/DLL/OCT connections as defined by the parameter settings. The traffic generator/memory interface instances demonstrate how you can make such connections in your own designs.

Note:

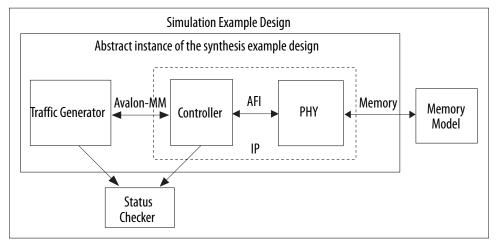
Third-party synthesis flow as described in *Intel Quartus Prime Standard Edition User Guide: Third-party Synthesis* is not a supported flow for EMIF IP.

9.1.2. Simulation Example Design

The simulation example design contains the major blocks shown in the following figure.

- An instance of the synthesis example design. As described in the previous section, the synthesis example design contains a traffic generator and an instance of the memory interface. These blocks default to abstract simulation models where appropriate for rapid simulation.
- A memory model, which acts as a generic model that adheres to the memory
 protocol specifications. Frequently, memory vendors provide simulation models for
 their specific memory components that you can download from their websites.
- A status checker, which monitors the status signals from the external memory interface IP and the traffic generator, to signal an overall pass or fail condition.

Figure 66. Simulation Example Design

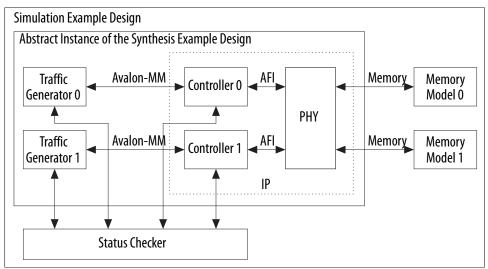


If you are using the Ping Pong PHY feature, the simulation example design includes two traffic generators issuing commands to two independent memory devices through two independent controllers and a common PHY, as shown in the following figure.





Figure 67. Simulation Example Design for Ping Pong PHY



If you are using RLDRAM 3, the traffic generator in the simulation example design communicates directly with the PHY using AFI, as shown in the following figure. If you are using RLDRAM 3, the traffic generator in the simulation example design communicates directly with the PHY using AFI, as shown in the following figure.

Figure 68. Simulation Example Design for RLDRAM 3 Interfaces

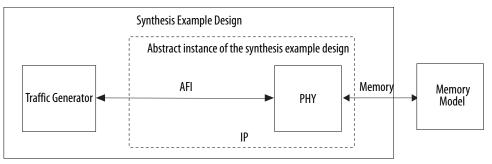
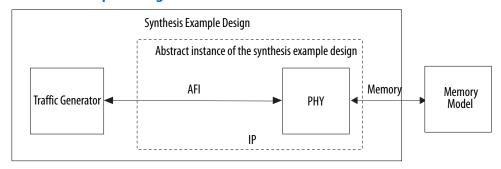


Figure 69. Simulation Example Design for RLDRAM 3 Interfaces





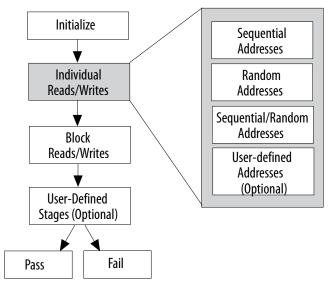


9.1.3. Traffic Generator and BIST Engine

The traffic generator and built-in self test (BIST) engine for Avalon-MM memory interfaces generates Avalon-MM traffic on an Avalon-MM master interface. The traffic generator creates read and write traffic, stores the expected read responses internally, and compares the expected responses to the read responses as they arrive. If all reads report their expected response, the pass signal is asserted; however, if any read responds with unexpected data a fail signal occurs.

Each operation generated by the traffic generator is a single write or block of writes followed by a single read or block of reads to the same addresses, which allows the driver to precisely determine the data that should be expected when the read data is returned by the memory interface. The traffic generator comprises a traffic generation block, the Avalon-MM interface and a read comparison block. The traffic generation block generates addresses and write data, which are then sent out over the Avalon-MM interface. The read comparison block compares the read data received from the Avalon-MM interface to the write data from the traffic generator. If at any time the data received is not the expected data, the read comparison block records the failure, finishes reading all the data, and then signals that there is a failure and the traffic generator enters a fail state. If all patterns have been generated and compared successfully, the traffic generator enters a pass state.

Figure 70. Example Driver Operations



Within the traffic generator, there are the following main states:

- Generation of individual read and writes
- · Generation of block read and writes
- The pass state
- · The fail state





Within each of the generation states there are the following substates:

- Seguential address generation
- Random address generation
- Mixed sequential and random address generation

For each of the states and substates, the order and number of operations generated for each substate is parameterizable—you can decide how many of each address pattern to generate, or can disable certain patterns entirely if you want. The sequential and random interleave substate takes in additions to the number of operations to generate. An additional parameter specifies the ratio of sequential to random addresses to generate randomly.

9.1.3.1. Read and Write Generation

The traffic generator block can generate individual or block reads and writes.

Individual Read and Write Generation

During the traffic generator's individual read and write generation state, the traffic generation block generates individual write followed by individual read Avalon-MM transactions, where the address for the transactions is chosen according to the specific substate. The width of the Avalon-MM interface is a global parameter for the driver, but each substate can have a parameterizable range of burst lengths for each operation.

Block Read and Write Generation

During the traffic generator's block read and write generation state, the traffic generator block generates a parameterizable number of write operations followed by the same number of read operations. The specific addresses generated for the blocks are chosen by the specific substates. The burst length of each block operation can be parameterized by a range of acceptable burst lengths.

9.1.3.2. Address and Burst Length Generation

The traffic generator block can perform sequential or random addressing.

Sequential Addressing

The sequential addressing substate defines a traffic pattern where addresses are chosen in sequential order starting from a user definable address. The number of operations in this substate is parameterizable.

Random Addressing

The random addressing substate defines a traffic pattern where addresses are chosen randomly over a parameterizable range. The number of operations in this substate is parameterizable.

Sequential and Random Interleaved Addressing

The sequential and random interleaved addressing substate defines a traffic pattern where addresses are chosen to be either sequential or random based on a parameterizable ratio. The acceptable address range is parameterizable as is the number of operations to perform in this substate.



9.1.3.3. Traffic Generator Signals

The following table lists the signals used by the traffic generator.

Table 68. Traffic Generator Signals

Signal	Signal Type		
clk	Input clock to traffic generator. For 28nm devices, use the AFI clock. For 20nm devices, use the emif_usr_clk.		
reset_n	Active low reset input. For 28nm devices, typically connected to afi_reset_n. For 20nm devices, typically connected to emif_usr_reset_n.		
avl_ready	Refer to Avalon Interface Specification.		
avl_write_req	Refer to Avalon Interface Specification.		
avl_read_req	Refer to Avalon Interface Specification.		
avl_addr	Refer to Avalon Interface Specification.		
avl_size	Refer to Avalon Interface Specification.		
avl_wdata	Refer to Avalon Interface Specification.		
avl_rdata	Refer to Avalon Interface Specification.		
avl_rdata_valid	Refer to Avalon Interface Specification.		
pnf_per_bit	Output. Bitwise pass/fail for last traffic generator read compare of AFI interface. No errors produvalue of all 1s.		
pnf_per_bit_persist	Output. Cumulative bitwise pass/fail for all previous traffic generator read compares of AFI interface. No errors produces value of all 1s.		
pass	Active high output when traffic generator tests complete successfully.		
fail	Active high output when traffic generator test does not complete successfully.		
test_complete	Active high output when traffic generator test completes.		

For information about the Avalon signals and the Avalon interface, refer to *Avalon Interface Specifications*.

Related Information

Avalon Interface Specifications

9.1.3.4. Traffic Generator Add-Ons

Some optional components that can be useful for verifying aspects of the controller and PHY operation are generated in conjunction with certain user-specified options. These add-on components are self-contained, and are not part of the controller or PHY, nor the traffic generator.





User Refresh Generator

The user refresh generator sends refresh requests to the memory controller when user refresh is enabled. The memory controller returns an acknowledgement signal and then issues the refresh command to the memory device.

The user refresh generator is created when you turn on **Enable User Refresh** on the **Controller Settings** tab of the parameter editor.

9.1.3.5. Traffic Generator Timeout Counter

The traffic generator timeout counter uses the Avalon interface clock.

When a test fails due to driver failure or timeout, the fail signal is asserted. When a test has failed, the traffic generator must be reset with the reset_n signal.

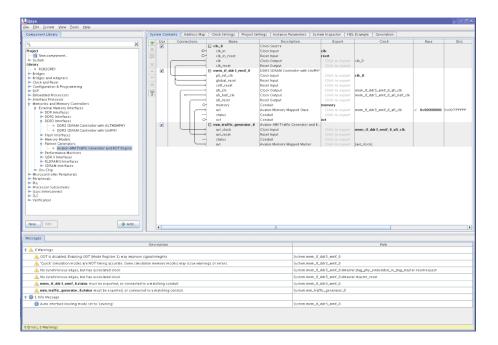
9.1.4. Creating and Connecting the UniPHY Memory Interface and the Traffic Generator in Platform Designer

The traffic generator can be used in Platform Designer as a stand-alone component for use within a larger system.

To create the system in Platform Designer, perform the following steps:

- 1. Start Platform Designer.
- On the **Project Settings** tab, select the required device from the **Device Family** list.
- In the Component Library, choose a UniPHY memory interface to instantiate. For example, under Library > Memories and Memory Controllers > External Memory Interfaces, select DDR3 SDRAM Controller with UniPHY Intel FPGA IP.
- 4. Configure the parameters for your instantiation of the memory interface.
- 5. In the Component Library, find the example driver and instantiate it in the system. For example, under Library > Memories and Memory Controllers > Pattern Generators, select Avalon-MM Traffic Generator and BIST Engine.
- 6. Configure the parameters for your instantiation of the example driver.
 - Note: The Avalon specification stipulates that Avalon-MM master interfaces issue byte addresses, while Avalon-MM slave interfaces accept word addresses. The default for the Avalon-MM Traffic Generator and BIST Engine is to issue word addresses. When using Platform Designer, you must enable the **Generate per byte address** setting in the traffic generator.
- 7. Connect the interfaces as illustrated in the following figure. At this point, you can generate synthesis RTL, Verilog or VHDL simulation RTL, or a simulation testbench system.





9.1.4.1. Notes on Configuring UniPHY IP in Platform Designer

This section includes notes and tips on configuring the UniPHY IP in Platform Designer.

- The address ranges shown for the Avalon-MM slave interface on the UniPHY
 component should be interpreted as byte addresses that an Avalon-MM master
 would address, despite the fact that this range is modified by configuring the word
 addresses width of the Avalon-MM slave interface on the UniPHY controller.
- The afi_clk clock source is the associated clock to the Avalon-MM slave interface
 on the memory controller. This is the ideal clock source to use for all IP
 components connected on the same Avalon network. Using another clock would
 cause Platform Designer to automatically instantiate clock-crossing logic,
 potentially degrading performance.
- The afi_clk clock rate is determined by the **Rate on Avalon-MM interface** setting on the UniPHY **PHY Settings** tab. The afi_half_clk clock interface has a rate which is further halved. For example, if **Rate on Avalon-MM interface** is set to **Half**, the afi_clk rate is half of the memory clock frequency, and the afi_half_clk is one quarter of the memory clock frequency.
- The global_reset input interface can be used to reset the UniPHY memory interface and the PLL contained therein. The soft_reset input interface can be used to reset the UniPHY memory interface but allow the PLL to remain locked. You can use the soft_reset input to reset the memory but to maintain the AFI clock output to other components in the system.





- Do not connect a reset request from a system component (such as a Nios II processor) to the UniPHY global_reset_n port. Doing so would reset the UniPHY PLL, which would propagate as a reset condition on afi_reset back to the requester; the resulting reset loop could freeze the system.
- Platform Designer generates an interconnect fabric for each Avalon network. The
 interconnect fabric is capable of burst and width adaptation. If your UniPHY
 memory controller is configured with an Avalon interface data width which is wider
 than an Avalon-MM master interface connected to it, you must enable the byte
 enable signal on the Avalon-MM slave interface, by checking the Enable AvalonMM byte-enable signal checkbox on the Controller Settings tab in the
 parameter editor.
- If you have a point-to-point connection from an Avalon-MM master to the Avalon-MM slave interface on the memory controller, and if the Avalon data width and burst length settings match, then the Avalon interface data widths may be multiples of either a power of two or nine. Otherwise, you must enable **Generate power-of-2 data bus widths for Platform Designer or SOPC Builder** on the **Controller Settings** tab of the parameter editor.

9.2. Document Revision History

Date	Version	Changes
March 2023	2023.03.06	 Removed references to Intel Arria 10 and Intel Stratix 10 devices and associated protocols. Added text to the third bullet of step 2 in the Compiling and Testing the Design in Hardware topic.
May 2017	2017.05.08	 Retitled EMIF Configurable Traffic Generator 2.0 Reference to Testing the EMIF Interface Using the Traffic Generator 2.0. Removed Configurable Traffic Generator Parameters section. Consolidated Traffic Generator 2.0 usage information in External Memory Interface Debug Toolkit chapter. Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	 Modified step 6 of Compiling and Testing the Design in Hardware. Added Configuring the Traffic Generator 2.0. Added The Traffic Generator 2.0 Report. Changed heading from EMIF Configurable Traffic Generator 2.0 for Arria 10 EMIF IP to EMIF Configurable Traffic Generator 2.0 Reference. Added Bypass the traffic generator repeated-writes/ repeated-reads test pattern, Bypass the traffic generator stress pattern, and Export Traffic Generator 2.0 configuration interface to Configurable Traffic Generator Parameters table. Removed Number of Traffic Generator 2.0 configuration interfaces. Added TG_WRITE_REPEAT_COUNT, TG_READ_REPEAT_COUNT, TG_DATA_MODE, and TG_BYTEEN_MODE to Configuration Options for Read/Write Generation table. Added Error Report Register Bits table to Test Information section. Corrected paths in Simulation and Hardware sections of Performing Your Own Tests Using Traffic Generator 2.0 topic.
November 2015	2015.11.02	 Added EMIF Configurable Traffic Generator 2.0 for Arria 10 EMIF IP. Added Arria 10 EMIF IP Example Design Quick Start Guide. Changed order of sections in chapter. Changed instances of Quartus II to Quartus Prime.





Date	Version	Changes
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	Removed occurrence of MegaWizard Plug-In Manager.
December 2013	2013.12.16	Removed references to SOPC Builder.
November 2012	1.3	 Added block diagrams of simulation and synthesis example designs for RLDRAM 3 and Ping Pong PHY. Changed chapter number from 7 to 9.
June 2012	1.2	Added Feedback icon.
November 2011	1.1	Added Synthesis Example Design and Simulation Example Design sections. Added Creating and Connecting the UniPHY Memory Interface and the Traffic Generator in Qsys. Revised Example Driver section as Traffic Generator and BIST Engine.







10. Introduction to UniPHY IP

The UniPHY IP is an interface between a memory controller and memory devices and performs read and write operations to the memory. The UniPHY IP creates the datapath between the memory device and the memory controller and user logic in various Intel devices.

The Intel FPGA DDR2, DDR3, and LPDDR2 SDRAM controllers with UniPHY Intel FPGA IP, QDR II and QDR II+ SRAM controllers with UniPHY Intel FPGA IP, RLDRAM II controller with UniPHY Intel FPGA IP, and RLDRAM 3 PHY-only IP provide low latency, high-performance, feature-rich interfaces to industry-standard memory devices. The DDR2, QDR II and QDR II+, and RLDRAM II controllers with UniPHY Intel FPGA IP offer full-rate and half-rate interfaces, while the DDR3 controller with UniPHY Intel FPGA IP and the RLDRAM 3 PHY-only IP offer half-rate and quarter-rate interfaces, and the LPDDR2 controller with UniPHY Intel FPGA IP offers a half-rate interface.

When you generate your external memory interface IP core, the system creates an example top-level project, consisting of an example driver, and your controller custom variation. The controller instantiates an instance of the UniPHY datapath.

The example top-level project is a fully-functional design that you can simulate, synthesize, and use in hardware. The example driver is a self-test module that issues read and write commands to the controller and checks the read data to produce the pass, fail, and test-complete signals.

If the UniPHY datapath does not match your requirements, you can create your own memory interface datapath using the ALTDLL, ALTDQ_DQS, ALTDQ_DQS2, ALTDQ, or ALTDQS IP cores, available in the Intel Quartus Prime software, but you are then responsible for all aspects of the design including timing analysis and design constraints.

10.1. Release Information

The following table provides information about this release of the DDR2 and DDR3 SDRAM, QDR II and QDR II+ SRAM, and RLDRAM II controllers with UniPHY, and the RLDRAM 3 PHY-only IP.

Table 69. Release Information

Item		Protocol								
	DDR2, DDR3, LPDDR2	QDR II	RLDRAM II	RLDRAM 3						
Version	13.1	13.1	13.1	13.1						
Release Date	November 2013	November 2013	November 2013	November 2013						
Ordering Code	IP-DDR2/UNI IP-DDR3/UNI IP-SDRAM/LPDDR2	IP-QDRII/UNI	IP-RLDII/UNI	_						

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Intel verifies that the current version of the Quartus Prime software compiles the previous version of each IP core. The *Intel FPGA IP Library Release Notes and Errata* report any exceptions to this verification. Intel does not verify compilation with IP core versions older than one release.

Related Information

Intel FPGA IP Library Release Notes

10.2. Device Support Levels

The following terms define the device support levels for Intel FPGA IP cores.

Intel FPGA IP Core Device Support Levels

- **Preliminary support**—Intel verifies the IP core with preliminary timing models for this device family. The IP core meets all functional requirements, but might still be undergoing timing analysis for the device family. You can use it in production designs with caution.
- **Final support**—Intel verifies the IP core with final timing models for this device family. The IP core meets all functional and timing requirements for the device family and can be used in production designs.

10.3. Device Family and Protocol Support

For information on the device and protocol support offered by each of the UniPHY-based external memory interface IPs, refer to External Memory Interface - Device Support on the Intel website.

For information about features and supported clock rates for external memory interfaces, refer to the *External Memory Interface Spec Estimator* on the Intel website.

Related Information

External Memory Interface Spec Estimator

10.4. UniPHY-Based External Memory Interface Features

The following table summarizes key feature support for Intel's UniPHY-based external memory interfaces.

Table 70. Feature Support

Key Feature			Prot	ocol		
	DDR2	DDR3	LPDDR2	QDR II	RLDRAM II	RLDRAM 3
High-performance controller II (HPC II)	Yes	Yes	Yes	_	_	_
Half-rate core logic and user interface	Yes	Yes	Yes	Yes	Yes	Yes
Full-rate core logic and user interface	Yes	_	_	Yes	Yes	_
Quarter-rate core logic and user interface	_	Yes (1)	_	_	_	Yes
						ontinued





Key Feature			Prot	ocol		
	DDR2	DDR3	LPDDR2	QDR II	RLDRAM II	RLDRAM 3
Dynamically generated Nios II-based sequencer	Yes	Yes	Yes	Yes	Yes	Yes
Choice of RTL-based or dynamically generated Nios® II-based sequencer	_	_	_	Yes (2) (3) (12)	Yes (12)	_
Available Efficiency Monitor and Protocol Checker (14)	Yes	Yes	Yes	-	Yes	Yes
DDR3L support	_	Yes (13)	_	_	_	_
UDIMM and RDIMM in any form factor	Yes	Yes (4) (5)	_	_	_	_
Multiple components in a single-rank UDIMM or RDIMM layout	Yes	Yes	_	_	-	_
LRDIMM	_	Yes	_	_	_	_
Burst length (half-rate)	8	_	8 or 16	4	4 or 8	2, 4, or 8
Burst length (full-rate)	4	_	_	2 or 4	2, 4, or 8	_
Burst length (quarter-rate)	_	8	_	_	_	2, 4, or 8
Burst length of 8 and burst chop of 4 (on the fly)	_	Yes	_	_	_	_
With leveling	240 MHz and above (10)	Yes (9) (10)	_	_	_	Yes
Without leveling	Below 240 MHz	_	Yes	-	_	_
Maximum data width	144 bits (6)	144 bits (6)	32 bits	72 bits	72 bits	72 bits
Reduced controller latency	_		_	Yes (2) (7)	Yes (2) (7)	_
Read latency	_	_	_	1.5 (QDR II) 2 or 2.5 (QDR II+)	_	_
ODT (in memory device)	_	Yes	_	QDR II+ only	Yes	Yes
x36 emulation mode	_	_	_	Yes (8) (10)	_	_

Notes:

- 1. For Arria V, Arria V GZ, and Stratix V devices only.
- 2. Not available in Arria II GX devices.
- 3. Nios II-based sequencer not available for full-rate interfaces.
- $4. \ \ \text{For DDR3, the DIMM form is not supported in Arria II GX, Arria II GZ, Arria V, or Cyclone V devices. }$
- 5. Arria II GZ uses leveling logic for discrete devices in DDR3 interfaces to achieve high speeds, but that leveling cannot be used to implement the DIMM form in DDR3 interfaces.
- 6. For any interface with data width above 72 bits, you must use software timing analysis of your complete design to determine the maximum clock rate.
- 7. The maximum achievable clock rate when reduced controller latency is selected must be attained through Quatrus Prime software timing analysis of your complete design.
- 8. Emulation mode allows emulation of a larger memory-width interface using multiple smaller memory-width interfaces. For example, an x36 QDR II or QDR II+ interface can be emulated using two x18 interfaces.
- 9. The leveling delay on the board between first and last DDR3 SDRAM component laid out as a DIMM must be less than 0.69 tCK.
- 10. Leveling is not available for Arria V or Cyclone V devices.
- 11.x36 emulation mode is not supported in Arria V, Arria V GZ, Cyclone V, or Stratix V devices.



Key Feature	Protocol							
	DDR2	DDR3	LPDDR2	QDR II	RLDRAM II	RLDRAM 3		

^{12.} The RTL-based sequencer is not available for QDR II or RLDRAM II interfaces on Arria V devices.

10.5. System Requirements

For system requirements and installation instructions, refer to *Intel FPGA Software Installation and Licensing* manual.

The DDR2, DDR3, and LPDDR2 SDRAM controllers with UniPHY Intel FPGA IP, QDR II and QDR II+ SRAM controllers with UniPHY Intel FPGA IP, RLDRAM II controller with UniPHY Intel FPGA IP, and RLDRAM 3 PHY-only IP are part of the Intel FPGA IP Library, which Intel distributes with the Intel Quartus Prime software.

Related Information

Intel FPGA Software Installation and Licensing Manual

10.6. Intel FPGA IP Core Verification

Intel has carried out extensive random, directed tests with functional test coverage using industry-standard models to ensure the functionality of the external memory controllers with UniPHY. Intel's functional verification of the external memory controllers with UniPHY use modified Denali models, with certain assertions disabled.

10.7. Resource Utilization

The following topics provide resource utilization data for the external memory controllers with UniPHY for supported device families.

10.7.1. DDR2, DDR3, and LPDDR2 Resource Utilization in Arria V Devices

The following table shows typical resource usage of the DDR2, DDR3, and LPDDR2 SDRAM controllers with UniPHY in the current version of Quartus Prime software for Arria V devices.

Table 71. Resource Utilization in Arria V Devices

Protocol	Memory Width (Bits)	Combinational ALUTS	Logic Registers	M10K Blocks	Memory (Bits)	Hard Memory Controller				
Controller										
DDR2 (Half	8	2286	1404	4	6560	0				
rate)	64	2304	1379	17	51360	0				
DDR2 (Fullrate)	32	0	0	0	0	1				
DDR3 (Half rate)	8	2355	1412	4	6560	0				
	•	•		•	,	continued				



^{13.} For Arria V, Arria V GZ, Cyclone V, and Stratix V.

^{14.} The Efficiency Monitor and Protocol Checker is is not available for QDR II and QDR II+ SRAM, or for the MAX 10 device family, or for Arria V or Cyclone V designs using the Hard Memory Controller.



Protocol	Memory Width (Bits)	Combinational ALUTS	Logic Registers	M10K Blocks	Memory (Bits)	Hard Memory Controller
	64	2372	1440	17	51360	0
DDR3 (Full rate)	32	0	0	0	0	1
LPDDR2 (Half	8	2230	1617	4	6560	0
rate)	32	2239	1600	10	25760	0
PHY				•		
DDR2 (Half	8	1652	2015	34	141312	0
rate)	64	1819	2089	34	174080	0
DDR2 (Fullrate)	32	1222	1415	34	157696	1
DDR3 (Half	8	1653	1977	34	141312	0
rate)	64	1822	2090	34	174080	0
DDR3 (Full rate)	32	1220	1428	34	157696	0
LPDDR2 (Half	8	2998	3187	35	150016	0
rate)	32	3289	3306	35	174592	0
Total				•		
DDR2 (Half	8	4555	3959	39	148384	0
rate)	64	4991	4002	52	225952	0
DDR2 (Fullrate)	32	1776	1890	35	158208	1
DDR3 (Half	8	4640	3934	39	148384	0
rate)	64	5078	4072	52	225952	0
DDR3 (Full rate)	32	1774	1917	35	158208	1
LPDDR2 (Half	8	5228	4804	39	156576	0
rate)	32	5528	4906	45	200352	0

10.7.2. DDR2 and DDR3 Resource Utilization in Arria II GZ Devices

The following table shows typical resource usage of the DDR2 and DDR3 SDRAM controllers with UniPHY in the current version of Quartus Prime software for Arria II GZ devices.

Table 72. Resource Utilization in Arria II GZ Devices

Protocol	Memory Width (Bits)	Combination al ALUTS	Logic Registers	Mem ALUTs	M9K Blocks	M144K Blocks	Memory (Bits)		
Controller									
DDR2 (Half	8	1,781	1,092	10	2	0	4,352		
rate)	16	1,784	1,092	10	4	0	8,704		
				<u> </u>	•		continued		





Protocol	Memory Width (Bits)	Combination al ALUTS	Logic Registers	Mem ALUTs	M9K Blocks	M144K Blocks	Memory (Bits)
	64	1,818	1,108	10	15	0	34,560
	72	1,872	1,092	10	17	0	39,168
DDR2 (Full	8	1,851	1,124	10	2	0	2,176
rate)	16	1,847	1,124	10	2	0	4,352
	64	1,848	1,124	10	8	0	17,408
	72	1,852	1,124	10	9	0	19,574
DDR3 (Half	8	1,869	1,115	10	2	0	4,352
rate)	16	1,868	1,115	10	4	0	8,704
	64	1,882	1,131	10	15	0	34,560
	72	1,888	1,115	10	17	0	39,168
PHY	·	1	-	1	1	1	
DDR2 (Half	8	2,560	2,042	183	22	0	157,696
rate)	16	2,730	2,262	183	22	0	157,696
	64	3,606	3,581	183	22	0	157,696
	72	3,743	3,796	183	22	0	157,696
DDR2 (Full	8	2,494	1,934	169	22	0	157,696
rate)	16	2,652	2,149	169	22	0	157,696
	64	3,519	3,428	169	22	0	157,696
	72	3,646	3,642	169	22	0	157,696
DDR3 (Half	8	2,555	2,032	187	22	0	157,696
rate)	16	3,731	2,251	187	22	0	157,696
	64	3,607	3,572	187	22	0	157,696
	72	3,749	3,788	187	22	0	157,696
Total							
DDR2 (Half	8	4,341	3,134	193	24	0	4,374
rate)	16	4,514	3,354	193	26	0	166,400
	64	5,424	4,689	193	37	0	192,256
	72	5,615	4,888	193	39	0	196,864
DDR2 (Full	8	4,345	3,058	179	24	0	159,872
rate)	16	4,499	3,273	179	24	0	162,048
	64	5,367	4,552	179	30	0	175,104
	72	5,498	4,766	179	31	0	177,280
DDR3 (Half	8	4,424	3,147	197	24	0	162,048
rate)	16	5,599	3,366	197	26	0	166,400
	64	5,489	4,703	197	37	0	192,256
	72	5,637	4,903	197	39	0	196,864





10.7.3. DDR2 and DDR3 Resource Utilization in Stratix III Devices

The following table shows typical resource usage of the DDR2 and DDR3 SDRAM controllers with UniPHY in the current version of Quartus Prime software for Stratix III devices.

Table 73. Resource Utilization in Stratix III Devices

Protocol	Memory Width (Bits)	Combination al ALUTS	Logic Registers	Mem ALUTs	M9K Blocks	M144K Blocks	Memory (Bits)
Controller							
DDR2 (Half	8	1,807	1,058	0	4	0	4,464
rate)	16	1,809	1,058	0	6	0	8,816
	64	1,810	1,272	10	14	0	32,256
	72	1,842	1,090	10	17	0	39,168
DDR2 (Full	8	1,856	1,093	0	4	0	2,288
rate)	16	1,855	1,092	0	4	0	4,464
	64	1,841	1,092	0	10	0	17,520
	72	1,834	1,092	0	11	0	19,696
DDR3 (Half	8	1,861	1,083	0	4	0	4,464
rate)	16	1,863	1,083	0	6	0	8,816
	64	1,878	1,295	10	14	0	32,256
	72	1,895	1,115	10	17	0	39,168
PHY		•		•	•	•	
DDR2 (Half	8	2,591	2,100	218	6	1	157,696
rate)	16	2,762	2,320	218	6	1	157,696
	64	3,672	3,658	242	6	1	157,696
	72	3,814	3,877	242	6	1	157,696
DDR2 (Full	8	2,510	1,986	200	6	1	157,696
rate)	16	2,666	2,200	200	6	1	157,696
	64	3,571	3,504	224	6	1	157,696
	72	3,731	3,715	224	6	1	157,696
DDR3 (Half	8	2,591	2,094	224	6	1	157,696
rate)	16	2,765	2,314	224	6	1	157,696
	64	3,680	3,653	248	6	1	157,696
	72	3,819	3,871	248	6	1	157,696
Total				1			'
DDR2 (Half	8	4,398	3,158	218	10	1	162,160
rate)	16	4,571	3,378	218	12	1	166,512
	64	5,482	4,930	252	20	1	189,952
							continued



Protocol	Memory Width (Bits)	Combination al ALUTS	Logic Registers	Mem ALUTs	M9K Blocks	M144K Blocks	Memory (Bits)
	72	5,656	4,967	252	23	1	196,864
DDR2 (Full	8	4,366	3,079	200	10	1	159,984
rate)	16	4,521	3,292	200	10	1	162,160
	64	5,412	4,596	224	16	1	175,216
	72	5,565	4,807	224	17	1	177,392
DDR3 (Half	8	4,452	3,177	224	10	1	162,160
rate)	16	4,628	3,397	224	12	1	166,512
	64	5,558	4,948	258	20	1	189,952
	72	5,714	4,986	258	23	1	196,864

10.7.4. DDR2 and DDR3 Resource Utilization in Stratix IV Devices

The following table shows typical resource usage of the DDR2 and DDR3 SDRAM controllers with UniPHY in the current version of Quartus Prime software for Stratix IV devices.

Table 74. Resource Utilization in Stratix IV Devices

Protocol	Memory Width (Bits)	Combination al ALUTS	Logic Registers	Mem ALUTs	M9K Blocks	M144K Blocks	Memory (Bits)
Controller	•						•
DDR2 (Half	8	1,785	1,090	10	2	0	4,352
rate)	16	1,785	1,090	10	4	0	8,704
	64	1,796	1,106	10	15	0	34,560
	72	1,798	1,090	10	17	0	39,168
DDR2 (Full	8	1,843	1,124	10	2	0	2,176
rate)	16	1,845	1,124	10	2	0	4,352
	64	1,832	1,124	10	8	0	17,408
	72	1,834	1,124	10	9	0	19,584
DDR3 (Half	8	1,862	1,115	10	2	0	4,352
rate)	16	1,874	1,115	10	4	0	8,704
	64	1,880	1,131	10	15	0	34,560
	72	1,886	1,115	10	17	0	39,168
PHY	•	•		•			1
DDR2 (Half	8	2,558	2,041	183	6	1	157,696
rate)	16	2,728	2,262	183	6	1	157,696
	64	3,606	3,581	183	6	1	157,696
	72	3,748	3,800	183	6	1	157,696
DDR2 (Full rate)	8	2,492	1,934	169	6	1	157,696
							continued



Protocol	Memory Width (Bits)	Combination al ALUTS	Logic Registers	Mem ALUTs	M9K Blocks	M144K Blocks	Memory (Bits)
	16	2,652	2,148	169	6	1	157,696
	64	3,522	3,428	169	6	1	157,696
	72	3,646	3,641	169	6	1	157,696
DDR3 (Half	8	2,575	2,031	187	6	1	157,696
rate)	16	2,732	2,251	187	6	1	157,696
	64	3,602	3,568	187	6	1	157,696
	72	3,750	3,791	187	6	1	157,696
Total	•						
DDR2 (Half	8	4,343	3,131	193	8	1	162,048
rate)	16	4,513	3,352	193	10	1	166,400
	64	5,402	4,687	193	21	1	192,256
	72	5,546	4,890	193	23	1	196,864
DDR2 (Full	8	4,335	3,058	179	8	1	159,872
rate)	16	4,497	3,272	179	8	1	162,048
	64	5,354	4,552	179	14	1	175,104
	72	5,480	4,765	179	15	1	177,280
DDR3 (Half	8	4,437	3,146	197	8	1	162,048
rate)	16	4,606	3,366	197	10	1	166,400
	64	5,482	4,699	197	21	1	192,256
	72	5,636	4,906	197	23	1	196,864

10.7.5. DDR2 and DDR3 Resource Utilization in Arria V GZ and Stratix V Devices

The following table shows typical resource usage of the DDR2 and DDR3 SDRAM controllers with UniPHY in the current version of Quartus Prime software for Arria V GZ and Stratix V devices.

Table 75. Resource Utilization in Arria V GZ and Stratix V Devices

Protocol	Memory Width (Bits)	Combinational LCs	Logic Registers	M20K Blocks	Memory (Bits)
Controller					
DDR2 (Half rate)	8	1,787	1,064	2	4,352
	16	1,794	1,064	4	8,704
	64	1,830	1,070	14	34,304
	72	1,828	1,076	15	38,400
DDR2 (Full rate)	8	2,099	1,290	2	2,176
	16	2,099	1,290	2	4,352
					continued





Protocol	Memory Width (Bits)	Combinational LCs	Logic Registers	M20K Blocks	Memory (Bits)
	64	2,126	1,296	7	16,896
	72	2,117	1,296	8	19,456
DDR3 (Quarter	8	2,101	1,370	4	8,704
rate)	16	2,123	1,440	7	16,896
	64	2,236	1,885	28	69,632
	72	2,102	1,870	30	74,880
DDR3 (Half rate)	8	1,849	1,104	2	4,352
	16	1,851	1,104	4	8,704
	64	1,853	1,112	14	34,304
	72	1,889	1,116	15	38,400
РНҮ		1		1	
DDR2 (Half rate)	8	2,567	1,757	13	157,696
	16	2,688	1,809	13	157,696
	64	3,273	2,115	13	157,696
	72	3,377	2,166	13	157,696
DDR2 (Full rate)	8	2,491	1,695	13	157,696
	16	2,578	1,759	13	157,696
	64	3,062	2,137	13	157,696
	72	3,114	2,200	13	157,696
DDR3 (Quarter	8	2,209	2,918	18	149,504
rate)	16	2,355	3,327	18	157,696
	64	3,358	5,228	18	182,272
	72	4,016	6,318	18	198,656
DDR3 (Half rate)	8	2,573	1,791	13	157,696
	16	2,691	1,843	13	157,696
	64	3,284	2,149	13	157,696
	72	3,378	2,200	13	157,696
Total					
DDR2 (Half rate)	8	4,354	2,821	15	162,048
	16	4,482	2,873	17	166,400
	64	5,103	3,185	27	192,000
	72	5,205	3,242	28	196,096
DDR2 (Full rate)	8	4,590	2,985	15	159,872
	16	4,677	3,049	15	162,048
	64	5,188	3,433	20	174,592
	_	1	1	1	continued





Protocol	Memory Width (Bits)	Combinational LCs	Logic Registers	M20K Blocks	Memory (Bits)
	72	5,231	3,496	21	177,152
DDR3 (Quarter	8	4,897	4,844	23	158,720
rate)	16	5,065	5,318	26	175,104
	64	6,183	7,669	47	252,416
	72	6,705	8,744	49	274,048
DDR3 (Half rate)	8	4,422	2,895	15	162,048
	16	4,542	2,947	17	166,400
	64	5,137	3,261	27	192,000
	72	5,267	3,316	28	196,096

10.7.6. QDR II and QDR II+ Resource Utilization in Arria V Devices

The following table shows typical resource usage of the QDR II and QDR II+ SRAM controllers with UniPHY in the current version of Quartus Prime software for Arria V devices.

Table 76. Resource Utilization in Arria V Devices

PHY Rate	Memory Width (Bits)	Combinational ALUTs	Logic Registers	M10K Blocks	Memory (Bits)	Hard Memory Controller
Controller	•					
Half	9	98	120	0	0	0
	18	96	156	0	0	0
	36	94	224	0	0	0
PHY	·					
Half	9	234	257	0	0	0
	18	328	370	0	0	0
	36	522	579	0	0	0
Total	•					
Half	9	416	377	0	0	0
	18	542	526	0	0	0
	36	804	803	0	0	0

10.7.7. QDR II and QDR II+ Resource Utilization in Arria II GX Devices

The following table shows typical resource usage of the QDR II and QDR II+ SRAM controllers with UniPHY in the current version of Quartus Prime software for Arria II GX devices.



Table 77. Resource Utilization in Arria II GX Devices

PHY Rate	Memory Width (Bits)	Combinational ALUTS	Logic Registers	Memory (Bits)	M9K Blocks
Half	9	620	701	0	0
	18	921	1122	0	0
	36	1534	1964	0	0
Full	9	584	708	0	0
	18	850	1126	0	0
	36	1387	1962	0	0

10.7.8. QDR II and QDR II+ Resource Utilization in Arria II GZ, Arria V GZ, Stratix III, Stratix IV, and Stratix V Devices

The following table shows typical resource usage of the QDR II and QDR II+ SRAM controllers with UniPHY in the current version of Quartus Prime software for Arria II GZ, Arria V GZ, Stratix III, Stratix IV, and Stratix V devices.

Table 78. Resource Utilization in Arria II GZ, Arria V GZ, Stratix III, Stratix IV, and Stratix V Devices

PHY Rate	Memory Width (Bits)	Combinational ALUTS	Logic Registers	Memory (Bits)	M9K Blocks
Half	9	602	641	0	0
	18	883	1002	0	0
	36	1457	1724	0	0
Full	9	586	708	0	0
	18	851	1126	0	0
	36	1392	1962	0	0

10.7.9. RLDRAM II Resource Utilization in Arria V Devices

The following table shows typical resource usage of the RLDRAM II Controller with UniPHY Intel FPGA IP in the current version of the Intel Quartus Prime software for Arria V devices.

Table 79. Resource Utilization in Arria V Devices

PHY Rate	Memory Width (Bits)	Combinational ALUTs	Logic Registers	M10K Blocks	Memory (Bits)	Hard Memory Controller
Controller					•	
Half	9	353	303	1	288	0
	18	350	324	2	576	0
	36	350	402	4	1152	0
PHY						
Half	9	295	474	0	0	0
	18	428	719	0	0	0
	•	'		'	•	continued





PHY Rate	Memory Width (Bits)	Combinational ALUTs	Logic Registers	M10K Blocks	Memory (Bits)	Hard Memory Controller
	36	681	1229	0	0	0
Total						
Half	9	705	777	1	288	0
	18	871	1043	2	576	0
	36	1198	1631	4	1152	0

10.7.10. RLDRAM II Resource Utilization in Arria II GZ, Arria V GZ, Stratix III, Stratix IV, and Stratix V Devices

The following table shows typical resource usage of the RLDRAM II Controller with UniPHY Intel FPGA IP in the current version of the Intel Quartus Prime software for Arria II GZ, Arria V GZ, Stratix III, Stratix IV, and Stratix V devices.

Table 80. Resource Utilization in Arria II GZ, Arria V GZ, Stratix III, Stratix IV, and Stratix V Devices (1)

PHY Rate	Memory Width (Bits)	Combinational ALUTS	Logic Registers	Memory (Bits)	M9K Blocks
Half	9	829	763	288	1
	18	1145	1147	576	2
	36	1713	1861	1152	4
Full	9	892	839	288	1
	18	1182	1197	576	1
	36	1678	1874	1152	2

Note to Table:

10.8. Document Revision History

Date	Version	Changes
March 2023	2023.03.06	Removed references to Intel Arria 10 and Intel Stratix 10 devices and associated protocols.
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Changed instances of <i>Quartus II</i> to <i>Quartus Prime</i> .
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	Removed occurrences of MegaWizard Plug-In Manager.
December 2013	2013.12.16	Removed references to ALTMEMPHY. Removed references to HardCopy.
	•	continued

^{1.} Half-rate designs use the same amount of memory as full-rate designs, but the data is organized in a different way (half the width, double the depth) and the design may need more M9K resources.



Date	Version	Changes
November 2012	2.1	 Added RLDRAM 3 support. Added LRDIMM support. Added Arria V GZ support. Changed chapter number from 8 to 10.
June 2012	2.0	 Added LPDDR2 support. Moved <i>Protocol Support Matrix</i> to Volume 1. Added Feedback icon.
November 2011	1.1	Combined Release Information, Device Family Support, Features list, and Unsupported Features list for DDR2, DDR3, QDR II, and RLDRAM II. Added Protocol Support Matrix. Combined Resource Utilization information for DDR2, DDR3, QDR II, and RLDRAM II. Updated data for 11.1.







11. Latency for UniPHY IP

Intel defines read and write latencies in terms of memory device clock cycles, which are always full-rate. There are two types of latencies that exists while designing with memory controllers—read and write latencies, which have the following definitions:

- Read latency—the amount of time it takes for the read data to appear at the local interface after initiating the read request.
- Write latency—the amount of time it takes for the write data to appear at the memory interface after initiating the write request.

Latency of the memory interface depends on its configuration and traffic patterns, therefore you should simulate your system to determine precise latency values. The numbers presented in this chapter are typical values meant only as guidelines.

Latency found in simulation may differ from latency found on the board, because functional simulation does not consider board trace delays and differences in process, voltage, and temperature. For a given design on a given board, the latency found may differ by one clock cycle (for full-rate designs), or two clock cycles (for quarter-rate or half-rate designs) upon resetting the board. The same design can yield different latencies on different boards.

Note:

For a half-rate controller, the local side frequency is half of the memory interface frequency. For a full-rate controller, the local side frequency is equal to the memory interface frequency.

11.1. DDR2 SDRAM LATENCY

The following table shows the DDR2 SDRAM latency in full-rate memory clock cycles.

Table 81. DDR2 SDRAM Controller Latency (In Full-Rate Memory Clock Cycles) (1) (2)

	Latency in Full-Rate Memory Clock Cycles								
Rate Controller Address & Command Command Command Read Controller Read Return Read Return Read Return Memory									
Half	10	EWL: 3	3-7	6	4	EWL: 26-30	EWL: 23		
		OWL: 4				OWL: 27-31	OWL: 24		
Full	5	0	3-7	4	10	22-26	19		

Notes to Table:

- 1. EWL = Even write latency
- 2. OWL = Odd write latency

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11.2. DDR3 SDRAM LATENCY

The following table shows the DDR3 SDRAM latency in full-rate memory clock cycles.

Table 82. DDR3 SDRAM Controller Latency (In Full-Rate Memory Clock Cycles) (1) (2) (3) (4)

	Latency in Full-Rate Memory Clock Cycles								
Rate	Controller Address & Command	PHY Address & Command	Memory Maximum Read	PHY Read Return	Controller Read Return	Round Trip	Round Trip Without Memory		
Quarter	20	EWER: 8	5-11	EWER: 16	8	EWER: 57- 63	EWER: 52		
		EWOR: 8		EWOR: 17		EWOR:58- 64	EWOR: 53		
		OWER: 11		OWER: 17		OWER:61- 67	OWER: 56		
		OWOR: 11		OWOR: 14		OWOR: 58- 64	OWOR: 53		
Half	10	EWER: 3	5-11	EWER: 7	4	EWER: 29- 35	EWER: 24		
		EWOR: 3		EWOR: 6		EWOR: 28- 34	EWOR: 23		
		OWER: 4		OWER: 6		OWER: 29- 35	OWER: 24		
		OWOR: 4		OWOR: 7		OWOR: 30- 36	OWOR: 25		
Full	5	0	5-11	4	10	24-30	19		

Notes to Table:

- 1. EWER = Even write latency and even read latency
- 2. EWOR = Even write latency and odd read latency
- 3. OWER = Odd write latency and even read latency
- 4. OWOR = Odd write latency and odd read latency

11.3. LPDDR2 SDRAM LATENCY

The following table shows the LPDDR2 SDRAM latency in full-rate memory clock cycles.

Table 83. LPDDR2 SDRAM Controller Latency (In Full-Rate Memory Clock Cycles) (1) (2) (3) (4)

	Latency in Full-Rate Memory Clock Cycles								
Rate	Controller Address & Command	PHY Address & Command	Memory Maximum Read	PHY Read Return	Controller Read Return	Round Trip	Round Trip Without Memory		
Half	10	EWER: 3	5-11	EWER: 7	4	EWER: 29- 35	EWER: 24		
		EWOR: 3		EWOR: 6		EWOR: 28- 34	EWOR: 23		
	continued								





	Latency in Full-Rate Memory Clock Cycles								
Rate	Controller Address & Command	PHY Address & Command	Memory Maximum Read	PHY Read Return	Controller Read Return	Round Trip	Round Trip Without Memory		
		OWER: 4		OWER: 6		OWER: 29- 35	OWER: 24		
		OWOR: 4		OWOR: 7		OWOR: 30- 36	OWOR: 25		
Full	5	0	5-11	4	10	24-30	19		

Notes to Table:

- 1. EWER = Even write latency and even read latency
- 2. EWOR = Even write latency and odd read latency
- 3. OWER = Odd write latency and even read latency
- 4. OWOR = Odd write latency and odd read latency

11.4. QDR II and QDR II+ SRAM Latency

The following table shows the latency in full-rate memory clock cycles.

Table 84. QDR II Latency (In Full-Rate Memory Clock Cycles) (1)

Latency in Full-Rate Memory Clock Cycles							
Rate	Controller Address & Command	PHY Address & Command	Memory Maximum Read	PHY Read Return	Controller Read Return	Round Trip	Round Trip Without Memory
Half 1.5 RL	2	5.5	1.5	7.0	0	16	14.5
Half 2.0 RL	2	5.5	2.0	6.5	0	16	14.0
Half 2.5 RL	2	5.5	2.5	6.0	0	16	13.5
Full 1.5 RL	2	1.5	1.5	4.0	1	10	8.5
Full 2.0 RL	2	1.5	2.0	4.5	1	11	9.0
Full 2.5 RL	2	1.5	2.5	4.0	1	11	8.5

Note to Table:

1. RL = Read latency

11.5. RLDRAM II Latency

The following table shows the latency in full-rate memory clock cycles.



Table 85. RLDRAM II Latency (In Full-Rate Memory Clock Cycles) (1) (2)

Latency in Full-Rate Memory Clock Cycles							
Rate	Controller Address & Command	PHY Address & Command	Memory Maximum Read	PHY Read Return	Controller Read Return	Round Trip	Round Trip Without Memory
Half	4	EWL: 1	3-8	EWL: 4	0	EWL: 12-17	EWL: 9
		OWL: 2		OWL: 4		OWL: 13-18	OWL: 10
Full	2	1	3-8	4	0	10-15	7

Notes to Table:

11.6. RLDRAM 3 Latency

The following table shows the latency in full-rate memory clock cycles.

Table 86. RLDRAM 3 Latency (In Full-Rate Memory Clock Cycles)

Latency in Full-Rate Memory Clock Cycles							
Rate	PHY Address & Command	Memory Maximum Read	PHY Read Return	Controller Read Return	Round Trip	Round Trip Without Memory	
Quarter	7	3-16	18	0	28-41	25	
Half	4	3-16	6	0	13-26	10	

11.7. Variable Controller Latency

The variable controller latency feature allows you to take advantage of lower latency for variations designed to run at lower frequency. When deciding whether to vary the controller latency from the default value of 1, be aware of the following considerations:

- Reduced latency can help achieve a reduction in resource usage and clock cycles in the controller, but might result in lower fMAX.
- Increased latency can help acheive greater fMAX, but might consume more clock cycles in the controller and result in increased resource usage.

If you select a latency value that is inappropriate for the target frequency, the system displays a warning message in the text area at the bottom of the parameter editor.

You can change the controller latency by altering the value of the **Controller Latency** setting in the **Controller Settings** section of the **General Settings** tab of the QDR II and QDR II+ SRAM Controller with UniPHY Intel FPGA IP parameter editor.

11.8. Document Revision History



^{1.} EWL = Even write latency

^{2.} OWL = Odd write latency



Date	Version	Changes			
May 2017	2017.05.08	Rebranded as Intel.			
October 2016	2016.10.31	Maintenance release.			
May 2016	2016.05.02	Maintenance release.			
November 2015	2015.11.02	Maintenance release.			
May 2015	2015.05.04	Maintenance release.			
December 2014	2014.12.15	Maintenance release.			
August 2014	2014.08.15	Maintenance release.			
December 2013	2013.12.16	Updated latency data for QDR II/II+.			
November 2012	2.1	Added latency information for RLDRAM 3.Changed chapter number from 9 to 11.			
June 2012	2.0	Added latency information for LPDDR2. Added Feedback icon.			
November 2011	1.0	Consolidated latency information from 11.0 DDR2 and DDR3 SDRAM Controller with UniPHY User Guide, QDR II and QDR II+ SRAM Controller with UniPHY User Guide, and RLDRAM II Controller with UniPHY IP User Guide. Updated data for 11.1.			







12. Timing Diagrams for UniPHY IP

The following topics contain timing diagrams for UniPHY-based external memory interface IP for supported protocols.

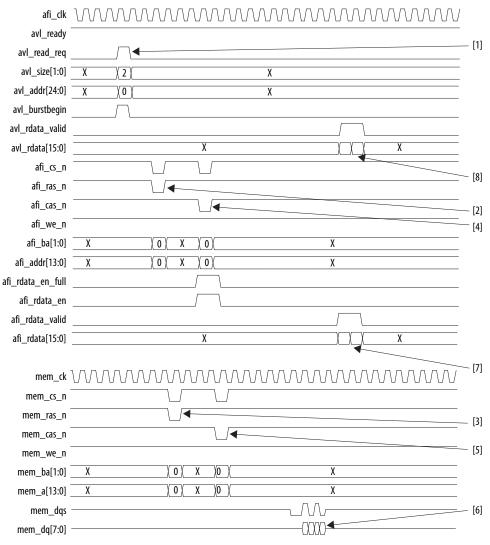
12.1. DDR2 Timing Diagrams

This topic contains timing diagrams for UniPHY-based external memory interface IP for DDR2 protocols.



The following figures present timing diagrams based on a Stratix III device:

Figure 71. Full-Rate DDR2 SDRAM Read



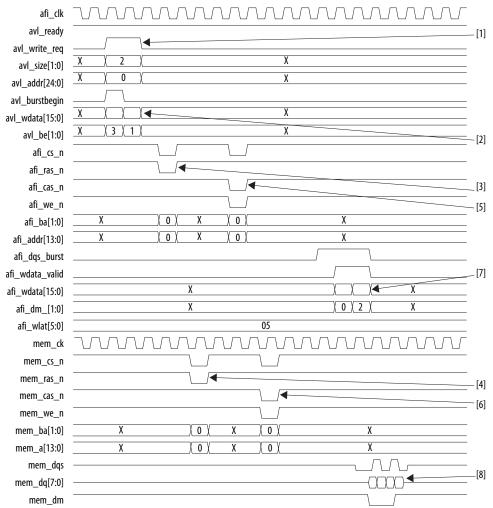
- 1. Controller receives read command.
- 2. Controller issues activate command to PHY.
- 3. PHY issues activate command to memory.
- 4. Controller issues read command to PHY.
- 5. PHY issues read command to memory.
- 6. PHY receives read data from memory.
- 7. Controller receives read data from PHY.
- 8. User logic receives read data from controller.







Figure 72. Full-Rate DDR2 SDRAM Write

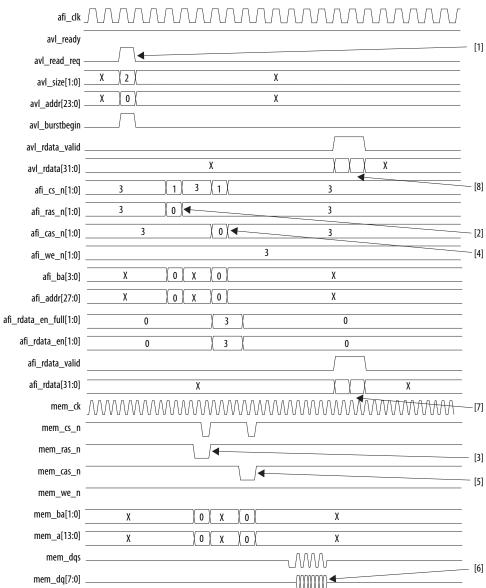


- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues activate command to PHY.
- 4. PHY issues activate command to memory.
- 5. Controller issues write command to PHY.
- 6. PHY issues write command to memory.
- 7. Controller sends write data to PHY.
- 8. PHY sends write data to memory.





Figure 73. Half-Rate DDR2 SDRAM Read

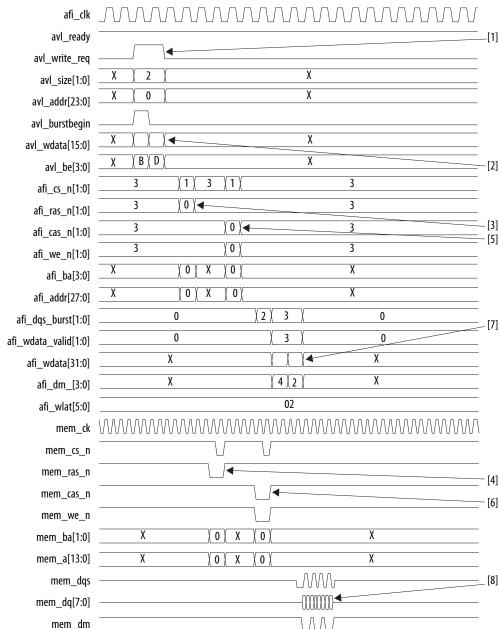


- 1. Controller receives read command.
- 2. Controller issues activate command to PHY.
- 3. PHY issues activate command to memory.
- 4. Controller issues read command to PHY.
- 5. PHY issues read command to memory.
- 6. PHY receives read data from memory.
- 7. Controller receives read data from PHY.
- 8. User logic receives read data from controller.





Figure 74. Half-Rate DDR2 SDRAM Write



- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues activate command to PHY.
- 4. PHY issues activate command to memory.
- 5. Controller issues write command to PHY.





- 6. PHY issues write command to memory.
- 7. Controller sends write data to PHY.
- 8. PHY sends write data to memory.

12.2. DDR3 Timing Diagrams

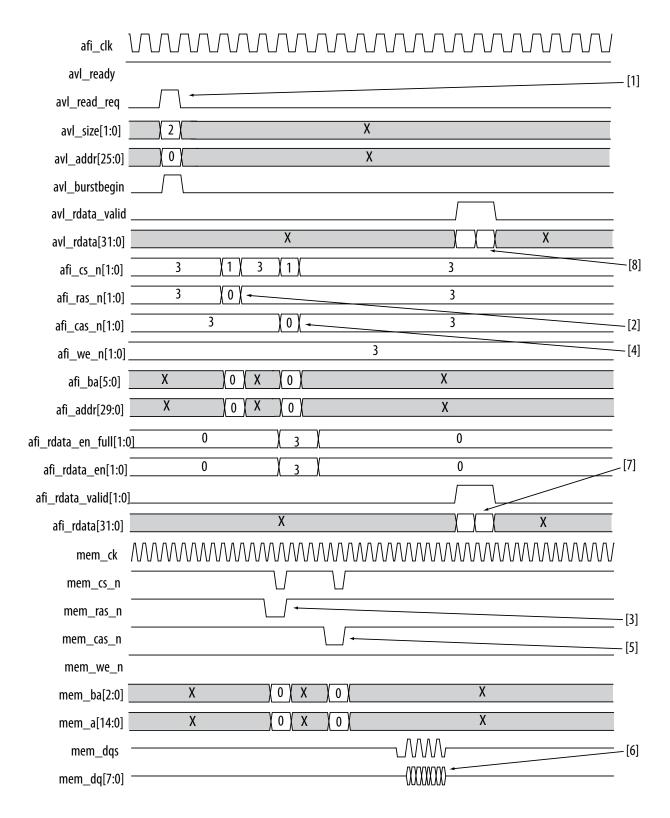
This topic contains timing diagrams for UniPHY-based external memory interface IP for DDR3 protocols.

The following figures present timing diagrams based on a Stratix III device





Figure 75. Half-Rate DDR3 SDRAM Read



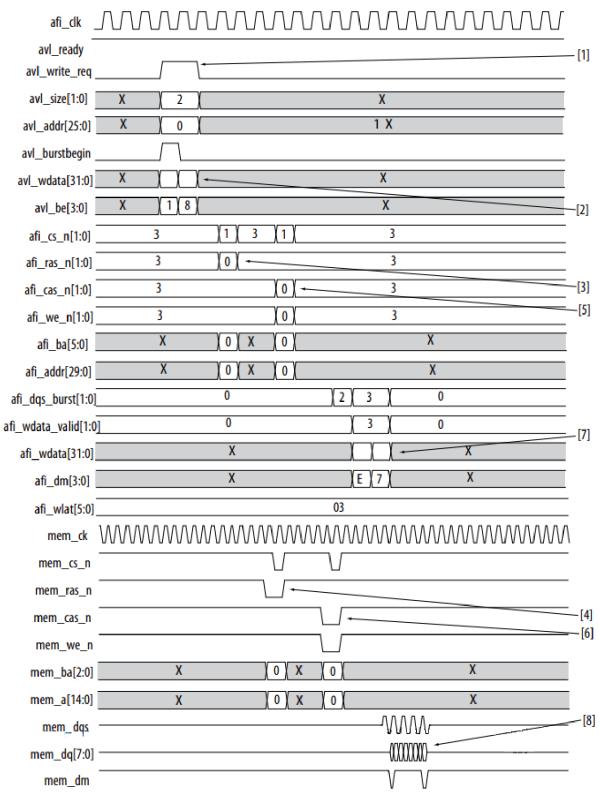


- 1. Controller receives read command.
- 2. Controller issues activate command to PHY.
- 3. PHY issues activate command to memory.
- 4. Controller issues read command to PHY.
- 5. PHY issues read command to memory.
- 6. PHY receives read data from memory.
- 7. Controller receives read data from PHY.
- 8. User logic receives read data from controller.





Figure 76. Half-Rate DDR3 SDRAM Writes



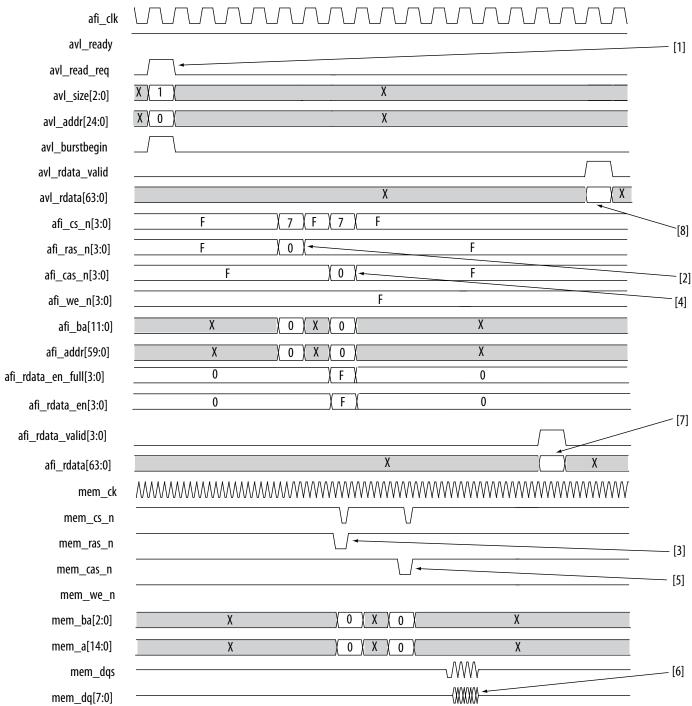


- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues activate command to PHY.
- 4. PHY issues activate command to memory.
- 5. Controller issues write command to PHY.
- 6. PHY issues write command to memory.
- 7. Controller sends write data to PHY.
- 8. PHY sends write data to memory.











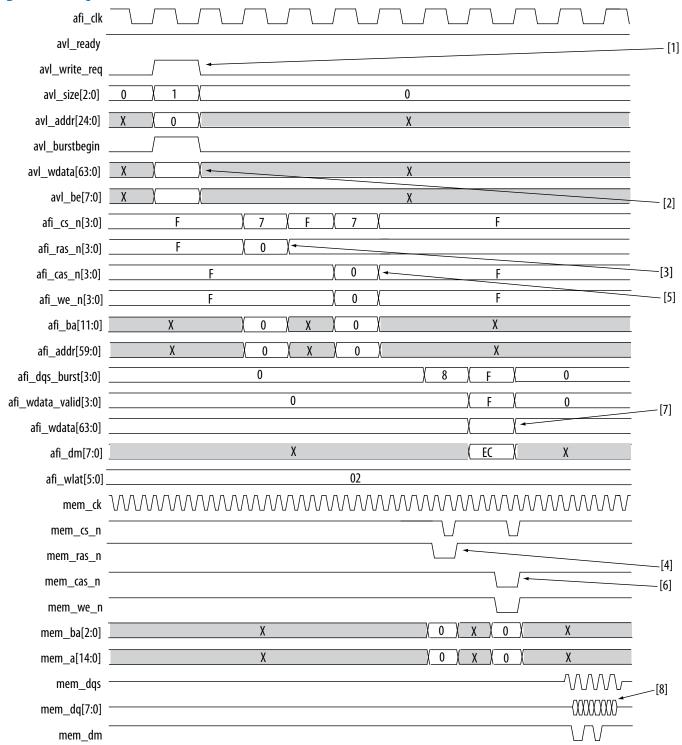
- 1. Controller receives read command.
- 2. Controller issues activate command to PHY.
- 3. PHY issues activate command to memory.
- 4. Controller issues read command to PHY.
- 5. PHY issues read command to memory.
- 6. PHY receives read data from memory
- 7. Controller receives read data from PHY
- 8. User logic receives read data from controller.













Notes for the above Figure:

- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues activate command to PHY
- 4. PHY issues activate command to memory.
- 5. Controller issues write command to PHY
- 6. PHY issues write command to memory
- 7. Controller sends write data to PHY
- 8. PHY sends write data to memory.

12.3. QDR II and QDR II+ Timing Diagrams

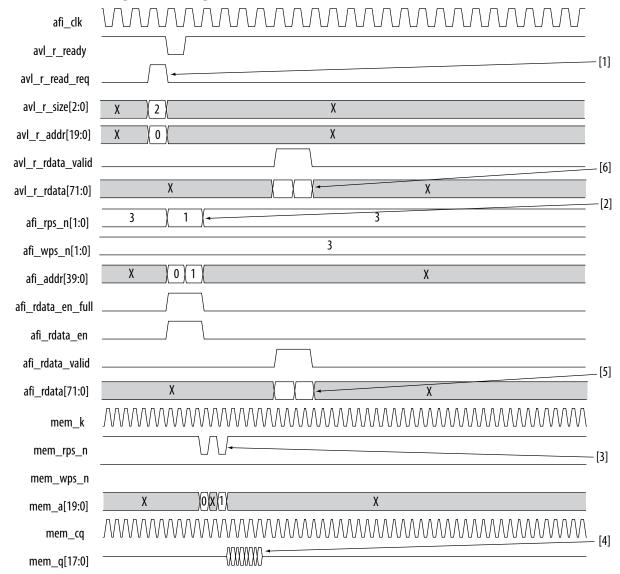
This topic contains timing diagrams for UniPHY-based external memory interface IP for QDR II and QDR II+ protocols.





The following figures present timing diagrams, based on a Stratix III device:

Figure 79. Half-Rate QDR II and QDR II+ SRAM Read

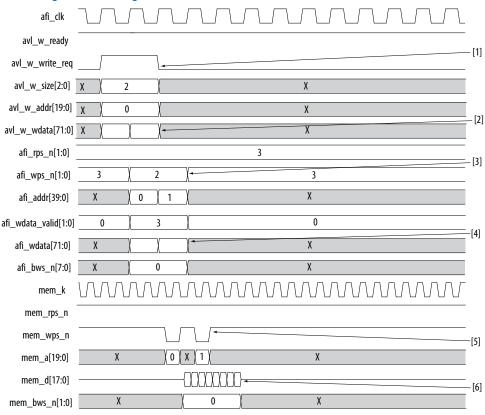


- 1. Controller receives read command.
- 2. Controller issues two read commands to PHY.
- 3. PHY issues two read commands to memory.
- 4. PHY receives read data from memory.
- 5. Controller receives read data from PHY.
- 6. User logic receives read data from controller.





Figure 80. Half-Rate QDR II and QDR II+ SRAM Write

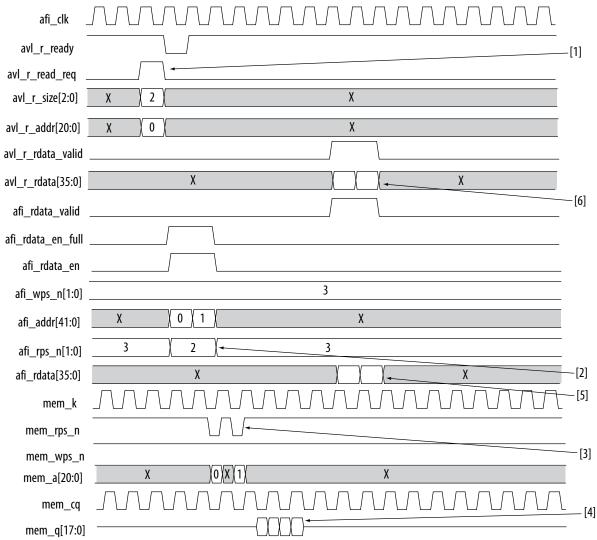


- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues two write commands to PHY.
- 4. Controller sends write data to PHY.
- 5. PHY issues two write commands to memory.
- 6. PHY sends write data to memory.







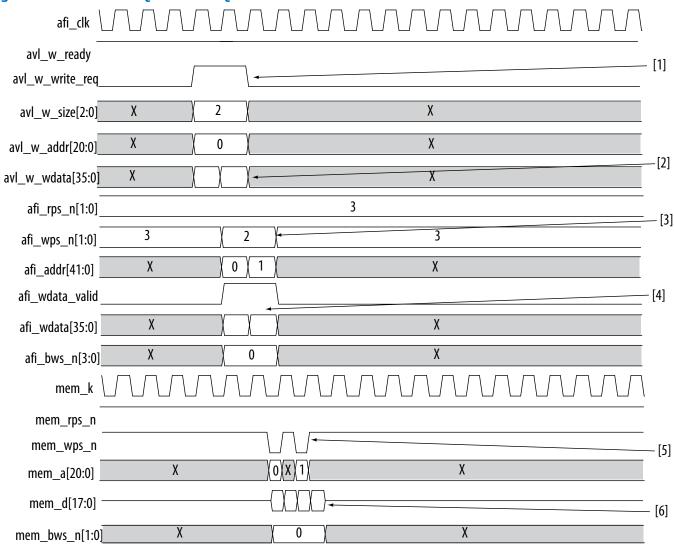


- 1. Controller receives read command.
- 2. Controller issues two read commands to PHY.
- 3. PHY issues two read commands to memory.
- 4. PHY receives read data from memory.
- 5. Controller receives read data from PHY.
- 6. User logic receives read data from controller.





Figure 82. Full-Rate QDR II and QDR II+ SRAM Write



- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues two write commands to PHY.
- 4. Controller sends write data to PHY.
- 5. PHY issues two write commands to memory.
- 6. PHY sends write data to memory.

12.4. RLDRAM II Timing Diagrams

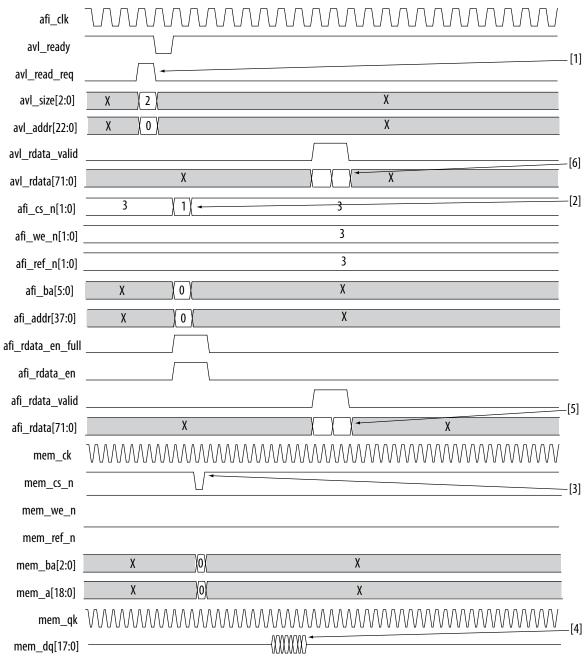
This topic contains timing diagrams for UniPHY-based external memory interface IP for RLDRAM protocols.





The following figures present timing diagrams, based on a Stratix III device:

Figure 83. Half-Rate RLDRAM II Read



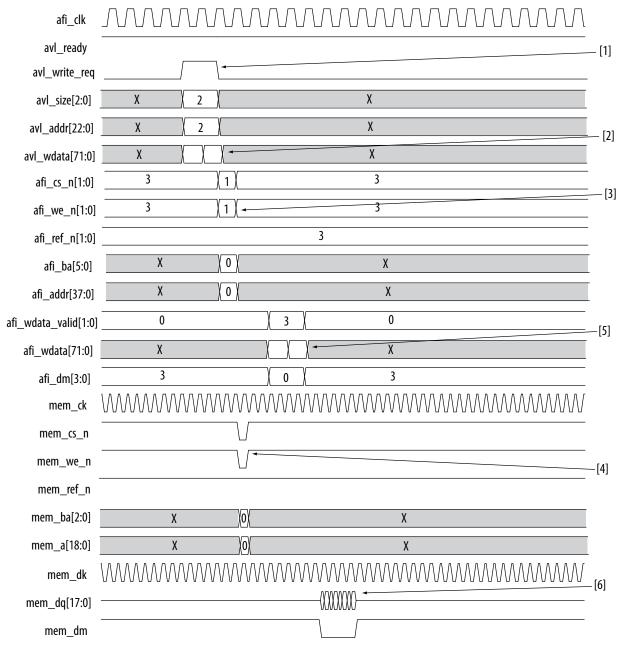
- 1. Controller receives read command.
- 2. Controller issues read command to PHY.
- 3. PHY issues read command to memory.





- 4. PHY receives read data from memory.
- 5. Controller receives read data from PHY.
- 6. User logic receives read data from controller.

Figure 84. Half-Rate RLDRAM II Write





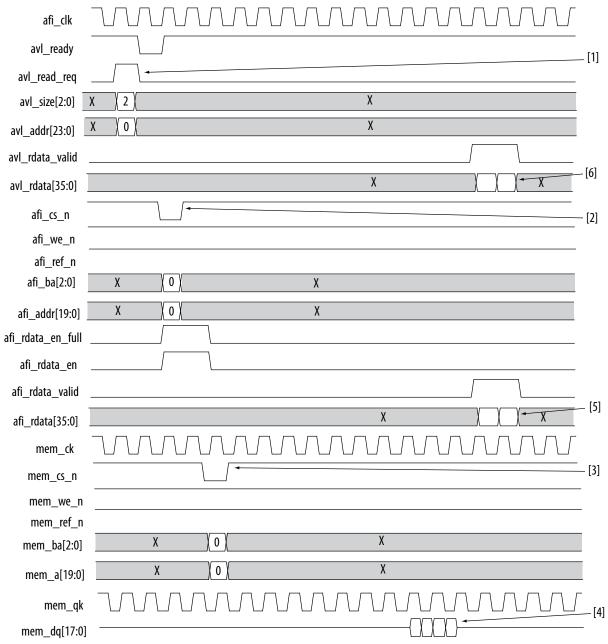


- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues write command to PHY.
- 4. PHY issues write command to memory.
- 5. Controller sends write data to PHY.
- 6. PHY sends write data to memory.





Figure 85. Full-Rate RLDRAM II Read



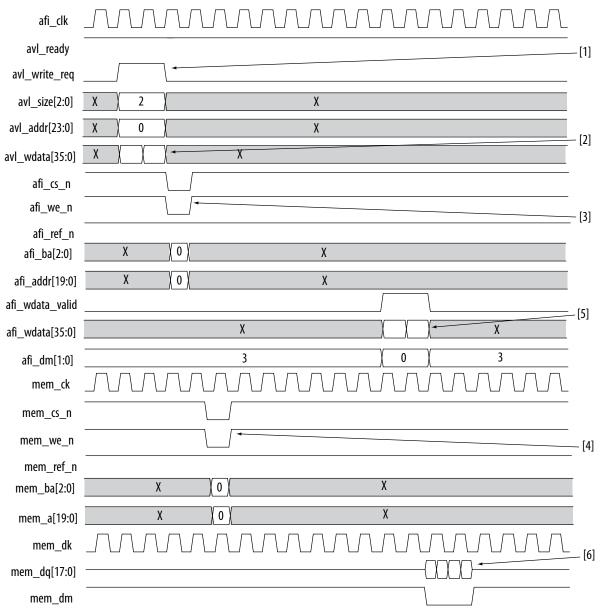
- 1. Controller receives read command.
- 2. Controller issues read command to PHY.
- 3. PHY issues read command to memory.





- 4. PHY receives read data from memory.
- 5. Controller receives read data from PHY.
- 6. User logic receives read data from controller.

Figure 86. Full-Rate RLDRAM II Write



- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues write command to PHY.



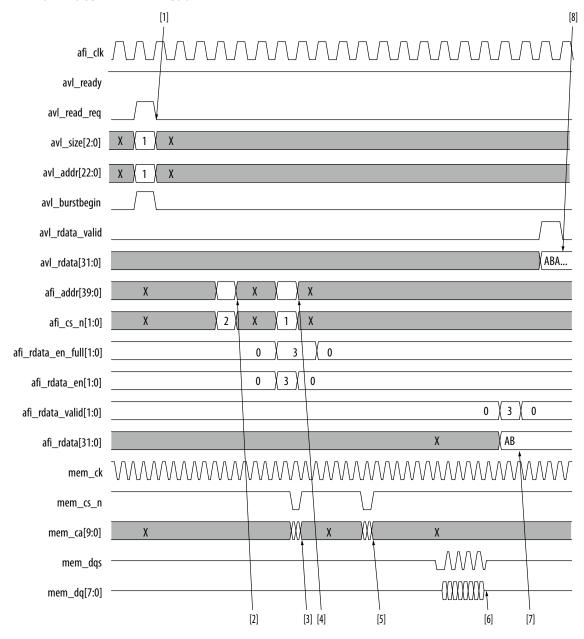


- 4. PHY issues write command to memory.
- 5. Controller sends write data to PHY.
- 6. PHY sends write data to memory.

12.5. LPDDR2 Timing Diagrams

This topic contains timing diagrams for UniPHY-based external memory interface IP for LPDDR2 protocols.

Figure 87. Half-Rate LPDDR2 Read





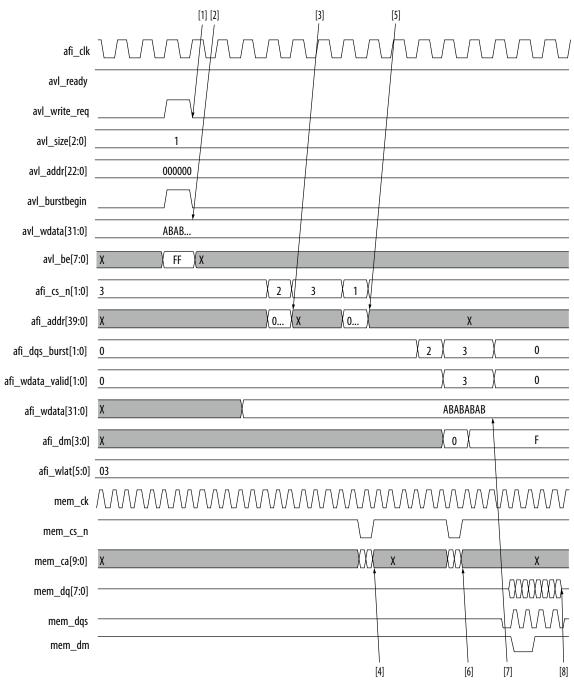


- 1. Controller receives read command.
- 2. Controller issues activate command to PHY.
- 3. PHY issues activate command to memory.
- 4. Controller issues read command to PHY.
- 5. PHY issues read command to memory.
- 6. PHY receives read data from memory.
- 7. Controller receives read data from PHY.
- 8. User logic receives read data from controller.





Figure 88. Half-Rate LPDDR2 Write



- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues activate command to PHY.

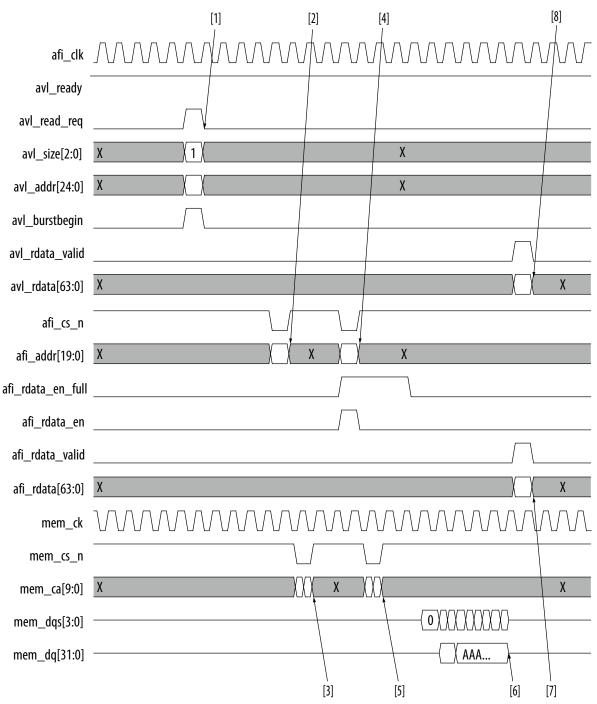


- 4. PHY issues activate command to memory.
- 5. Controller issues write command to PHY.
- 6. PHY issues write command to memory.
- 7. Controller sends write data to PHY.
- 8. PHY sends write data to memory.





Figure 89. Full-Rate LPDDR2 Read



- 1. Controller receives read command.
- 2. Controller issues activate command to PHY.
- 3. PHY issues activate command to memory.



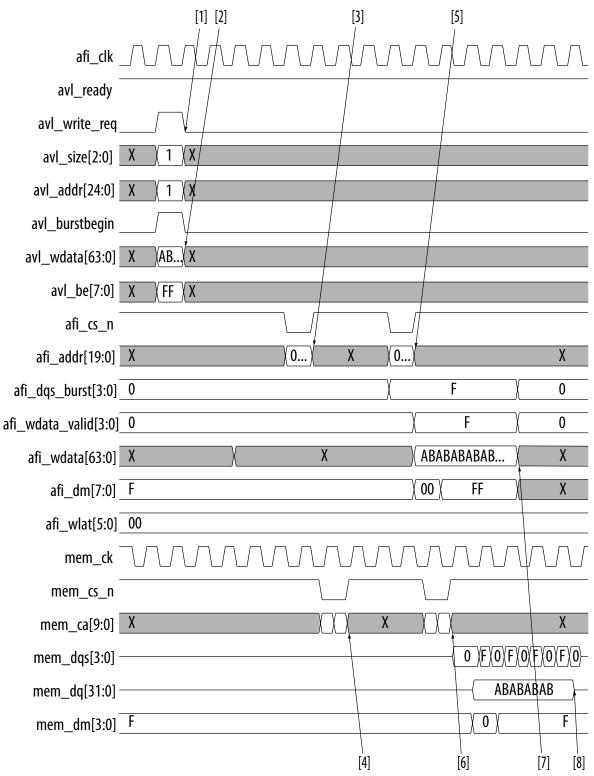


- 4. Controller issues read command to PHY.
- 5. PHY issues read command to memory.
- 6. PHY receives read data from memory.
- 7. Controller receives read data from PHY.
- 8. User logic receives read data from controller.





Figure 90. Full-Rate LPDDR2 Write





- 1. Controller receives write command.
- 2. Controller receives write data.
- 3. Controller issues activate command to PHY.
- 4. PHY issues activate command to memory.
- 5. Controller issues write command to PHY.
- 6. PHY issues write command to memory.
- 7. Controller sends write data to PHY.
- 8. PHY sends write data to memory.

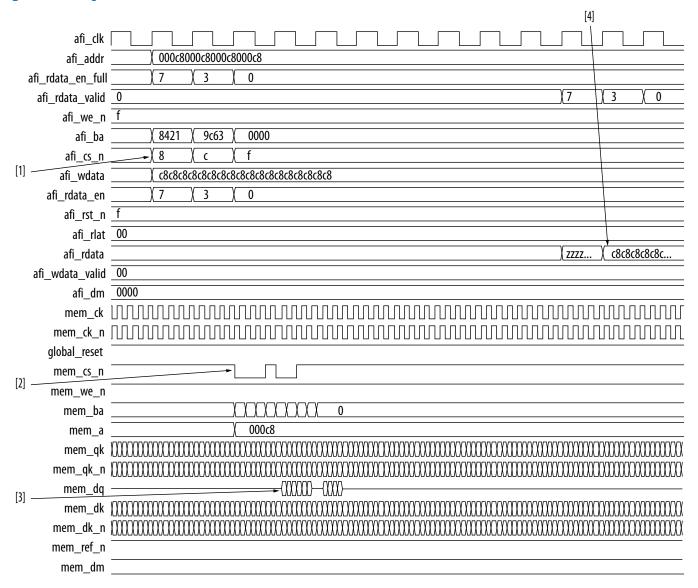
12.6. RLDRAM 3 Timing Diagrams

This topic contains timing diagrams for UniPHY-based external memory interface IP for RLDRAM 3 protocols.







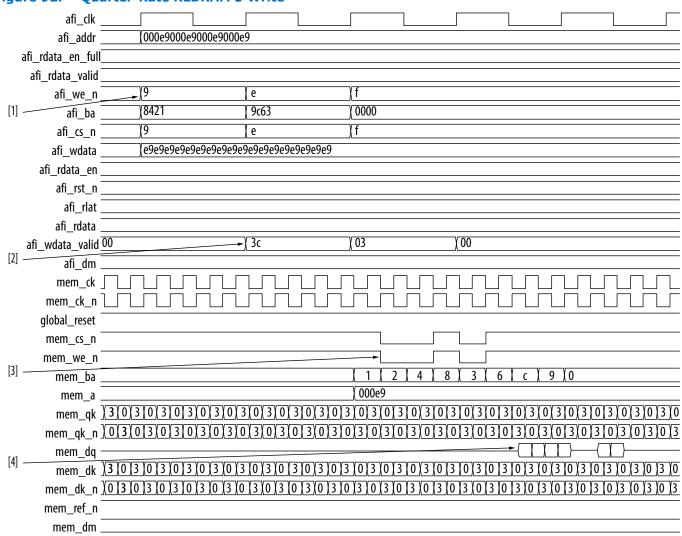


- 1. Controller issues read command to PHY.
- 2. PHY issues read command to memory.
- 3. PHY receives data from memory.
- 4. Controller receives read data from PHY.





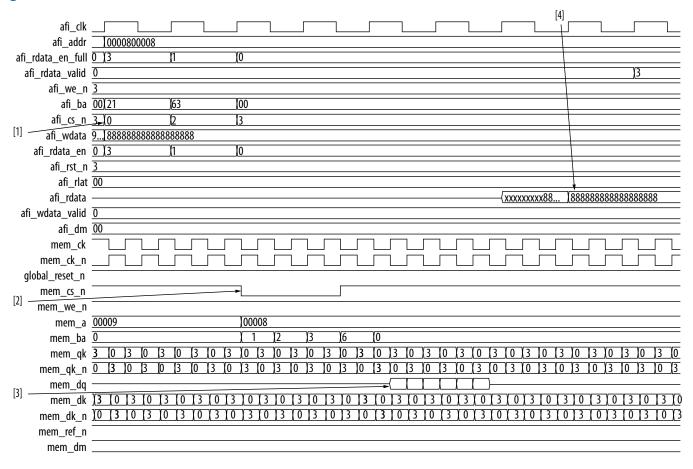




- 1. Controller issues write command to PHY.
- 2. Data ready from controller for PHY.
- 3. PHY issues write command to memory.
- 4. PHY sends read data to memory.



Figure 93. Half-rate RLDRAM 3 Read

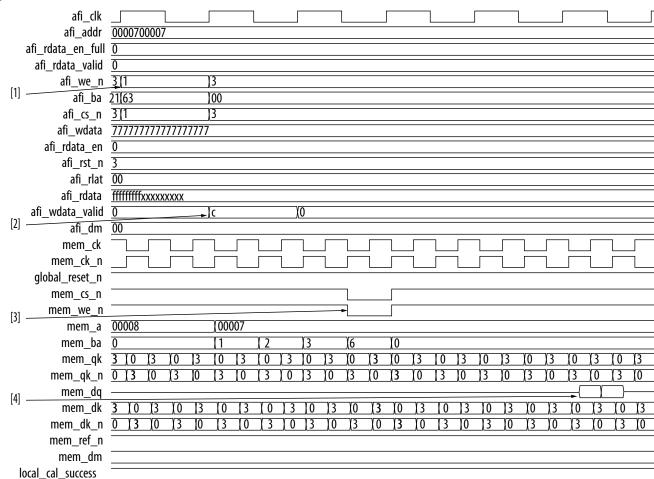


- 1. Controller issues read command to PHY.
- 2. PHY issues read command to memory.
- 3. PHY receives data from memory.
- 4. Controller receives read data from PHY.









- 1. Controller issues write command to PHY.
- 2. Data ready from controller for PHY.
- 3. PHY issues write command to memory.
- 4. PHY sends read data to memory.

12.7. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Maintenance release.
May 2015	2015.05.04	Maintenance release.
		continued





Date	Version	Changes
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	Maintenance release.
December 2013	2013.12.16	Updated timing diagrams for LPDDR2.
November 2012	2.1	Added timing diagrams for RLDRAM 3.Changed chapter number from 10 to 12.
June 2012	2.0	Added timing diagrams for LPDDR2. Added Feedback icon.
November 2011	1.1	Consolidated timing diagrams from 11.0 DDR2 and DDR3 SDRAM Controller with UniPHY User Guide, QDR II and QDR II+ SRAM Controller with UniPHY User Guide, and RLDRAM II Controller with UniPHY IP User Guide. Added Read and Write diagrams for DDR3 quarter-rate.





13. External Memory Interface Debug Toolkit

The EMIF Toolkit lets you run your own traffic patterns, diagnose and debug calibration problems, and produce margining reports for your external memory interface.

The toolkit is compatible with UniPHY-based external memory interfaces that use the Nios II-based sequencer, with toolkit communication enabled. Toolkit communication is on by default in versions 10.1 and 11.0 of UniPHY IP; for version 11.1 and later, toolkit communication is on whenever debugging is enabled on the Diagnostics tab of the IP core interface.

The EMIF Toolkit can communicate with several different memory interfaces on the same device, but can communicate with only one memory device at a time.

Note: The EMIF Debug Toolkit does not support MAX 10 devices.

13.1. User Interface

The EMIF toolkit provides a graphical user interface for communication with connections.

All functions provided in the toolkit are also available directly from the quartus_sh TCL shell, through the external_memif_toolkit TCL package. The availability of TCL support allows you to create scripts to run automatically from TCL. You can find information about specific TCL commands by running help -pkg external_memif_toolkit from the quartus_sh TCL shell.

If you want, you can begin interacting with the toolkit through the GUI, and later automate your workflow by creating TCL scripts. The toolkit GUI records a history of the commands that you run. You can see the command history on the History tab in the toolkit GUI.

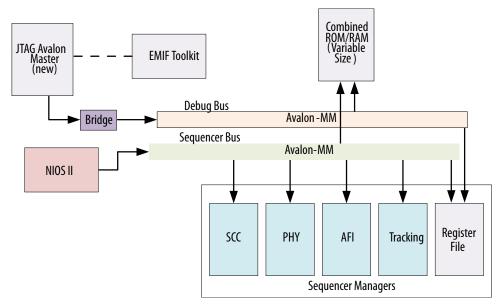
13.1.1. Communication

Communication between the EMIF Toolkit and external memory interface connections is achieved using a JTAG Avalon-MM master attached to the sequencer bus.

The following figure shows the structure of EMIF IP with JTAG Avalon-MM master attached to sequencer bus masters.



Figure 95. EMIF IP with JTAG Avalon-MM Master



13.1.2. Calibration and Report Generation

The EMIF Toolkit uses calibration differently, depending on the version of external memory interface in use. For versions 10.1 and 11.0 interfaces, the EMIF Toolkit causes the memory interface to calibrate several times, to produce the data from which the toolkit generates its reports. In version 11.1 and later, report data is generated during calibration, without need to repeat calibration. For version 11.1 and later, generated reports reflect the result of the previous calibration, without need to recalibrate unless you choose to do so.

13.2. Setup and Use

Before using the EMIF Toolkit, you should compile your design and program the target device with the resulting SRAM Object File (. sof). For designs compiled in the Quartus II software version 12.0 or earlier, debugging information is contained in the JTAG Debugging Information file (.jdi); however, for designs compiled in the Quartus II software version 12.1 or later, or the Intel Quartus Prime software, all debugging information resides in the .sof file.

You can run the toolkit using all your project files, or using only the Intel Quartus Prime Project File (.qpf), Intel Quartus Prime Settings File (.qsf), and .sof file; the .jdi file is also required for designs compiled prior to version 12.1. To ensure that all debugging information is correctly synchronized for designs compiled prior to version 12.1, ensure that the .sof and .jdi files that you used are generated during the same run of the Intel Quartus Prime Assembler.

After you have programmed the target device, you can run the EMIF Toolkit and open your project. You can then use the toolkit to create connections to the external memory interface.



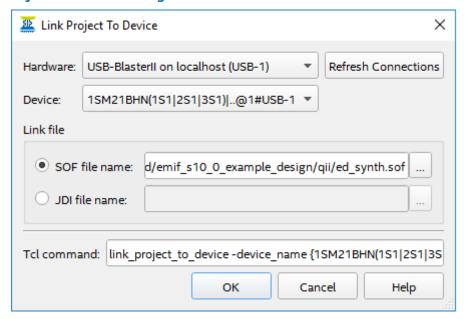
13.2.1. General Workflow

To use the EMIF Toolkit, you must link your compiled project to a device, and create a communication channel to the connection that you want to examine.

13.2.2. Linking the Project to a Device

- 1. To launch the toolkit, select External Memory Interface Toolkit from the Tools menu in the Intel Quartus Prime software.
- After you have launched the toolkit, open your project and click the **Initialize** connections task in the **Tasks** window, to initialize a list of all known
 connections.
- 3. To link your project to a specific device on specific hardware, perform the following steps:
 - a. Click the Link Project to Device task in the Tasks window.
 - Select the desired hardware from the Hardware dropdown menu in the Link Project to Device dialog box.
 - c. Select the desired device on the hardware from the **Device** dropdown menu in the **Link Project to Device** dialog box.
 - d. Select the correct **Link file type**, depending on the version of software in which your design was compiled:
 - If your design was compiled in the Quartus II software version 12.0 or earlier, select JDI as the Link file type, verify that the .jdi file is correct for your .sof file, and click Ok.
 - If your design was compiled in the Quartus II software version 12.1 or later, or the Intel Quartus Prime software, select SOF as the Link file type, verify that the .sof file is correct for your programmed device, and click Ok.

Figure 96. Link Project to Device Dialog Box







When you link your project to the device, the toolkit verifies all connections on the device against the information in the JDI or SOF file, as appropriate. If the toolkit detects any mismatch between the JDI file and the device connections, an error message is displayed.

For designs compiled using the Quartus II software version 12.1 or later, or the Intel Quartus Prime software, the SOF file contains a design hash to ensure the SOF file used to program the device matches the SOF file specified for linking to a project. If the hash does not match, an error message appears.

If the toolkit successfully verifies all connections, it then attempts to determine the connection type for each connection. Connections of a known type are listed in the Linked Connections report, and are available for the toolkit to use.

13.2.3. Establishing Communication to Connections

After you have completed linking the project, you can establish communication to the connections.

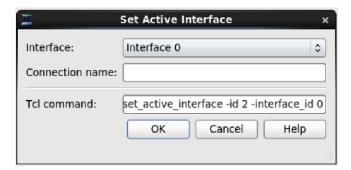
- 1. In the Tasks window,
 - Click Establish Memory Interface Connection to create a connection to the external memory interface.
 - Click Establish Efficiency Monitor Connection to create a connection to the efficiency monitor.
- 2. To create a communication channel to a connection, select the desired connection from the displayed pulldown menu of connections, and click **Ok**. The toolkit establishes a communication channel to the connection, creates a report folder for the connection, and creates a folder of tasks for the connection.
 - Note: By default, the connection and the reports and tasks folders are named according to the hierarchy path of the connection. If you want, you can specify a different name for the connection and its folders.
- 3. You can run any of the tasks in the folder for the connection; any resulting reports appear in the reports folder for the connection.

13.2.4. Selecting an Active Interface

If you have more than one external memory interface in an I/O column, you can select one instance as the active interface for debugging.

1. To select one of multiple EMIF instances in the same I/O column, select the active interface ID from the **Interface** pulldown menu in the **Set Active Interface** dialog box. This interface ID is the same ID that you have assigned to the given EMIF IP core in the **Calibration Debug Options** section of the **Diagnostics** tab.





Referring to the previous example in the *Configuring Your EMIF IP for Use With the Debug Toolkit* topic, interface 0 is associated with the first EMIF component interface, interface 1 is associated with the first HiLo interface, and interface 2 is associated with the first EMIF UDIMM interface.

2. If you want to generate reports for the new active interface, you must first recalibrate the interface.

13.2.5. Reports

The toolkit can generate a variety of reports, including summary, calibration, and margining reports for external memory interface connections. To generate a supported type of report for a connection, you run the associated task in the tasks folder for that connection.

Summary Report

The Summary Report provides an overview of the memory interface; it consists of the following tables:

- Summary table. Provides a high-level summary of calibration results. This table
 lists details about the connection, IP version, IP protocol, and basic calibration
 results, including calibration failures. This table also lists the estimated average
 read and write data valid windows, and the calibrated read and write latencies.
- Interface Details table. Provides details about the parameterization of the memory IP. This table allows you to verify that the parameters in use match the actual memory device in use.
- Groups Masked from Calibration table. Lists any groups that were masked from calibration when calibration occurred. Masked groups are ignored during calibration.
- Ranks Masked from Calibration tables (DDR2 and DDR3 only). Lists any ranks that were masked from calibration when calibration occurred. Masked ranks are ignored during calibration.





Calibration Report (UniPHY)

The Calibration Report provides detailed information about the margins observed before and after calibration, and the settings applied to the memory interface during calibration; it consists of the following tables:

• Per DQS Group Calibration table: Lists calibration results for each group. If a group fails calibration, this table also lists the reason for the failure.

Note: If a group fails calibration, the calibration routine skips all remaining groups. You can deactivate this behaviour by running the **Enable Calibration for All Groups On Failure** command in the toolkit.

- DQ Pin Margins Observed Before Calibration table: Lists the DQ pin margins observed before calibration occurs. You can refer to this table to see the per-bit skews resulting from the specific silicon and board that you are using.
- DQS Group Margins Observed During Calibration table: Lists the DQS group margins observed during calibration.
- DQ Pin Settings After Calibration and DQS Group Settings After Calibration table: Lists the settings made to all dynamically controllable parts of the memory interface as a result of calibration. You can refer to this table to see the modifications made by the calibration algorithm.

Margin Report

The Margin Report lists the post-calibration margins for each DQ and data mask pin, keeping all other pin settings constant; it consists of the following tables:

- DQ Pin Post Calibration Margins table. Lists the margin data in tabular format.
- Read Data Valid Windows report. Shows read data valid windows in graphical format.
- Write Data Valid Windows report. Shows write data valid windows in graphical format.

13.3. Operational Considerations

Some features and considerations are of interest in particular situations.

Specifying a Particular JDI File

Correct operation of the EMIF Toolkit depends on the correct JDI being used when linking the project to the device. The JDI file is produced by the Quartus Prime Assembler, and contains a list of all system level debug nodes and their heirarchy path names. If the default <code>.jdi</code> file name is incorrect for your project, you must specify the correct <code>.jdi</code> file. The <code>.jdi</code> file is supplied during the link-project-to-device step, where the <code>revision_name.jdi</code> file in the project directory is used by default. To supply an alternative <code>.jdi</code> file, click on the ellipse then select the correct <code>.jdi</code> file.

PLL Status

When connecting to DDR-based external memory interface connections, the PLL status appears in the Establish Connection dialog box when the IP is generated to use the CSR controller port, allowing you to immediately see whether the PLL status is locked. If the PLL is not locked, no communication can occur until the PLL becomes locked and the memory interface reset is deasserted.



When you are linking your project to a device, an error message will occur if the toolkit detects that a JTAG Avalon-MM master has no clock running. You can run the **Reindex Connections** task to have the toolkit rescan for connections and update the status and type of found connections in the Linked Connections report.

Margining Reports

The EMIF Toolkit can display margining information showing the post-calibration data-valid windows for reads and writes. Margining information is determined by individually modifying the input and output delay chains for each data and strobe/clock pin to determine the working region. The toolkit can display margining data in both tabular and hierarchial formats.

Group Masks

To aid in debugging your external memory interface, the EMIF Toolkit allows you to mask individual groups and ranks from calibration. Masked groups and ranks are skipped during the calibration process, meaning that only unmasked groups and ranks are included in calibration. Subsequent mask operations overwrite any previous masks.

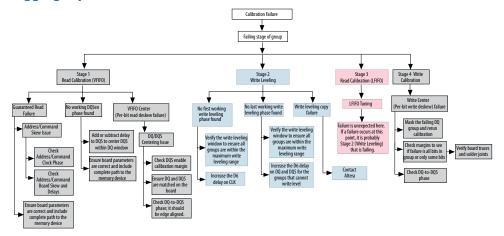
Note:

For information about calibration stages in UniPHY-based interfaces, refer to *UniPHY Calibration Stages* in the *Functional Description - UniPHY* chapter.

13.4. Troubleshooting

In the event of calibration failure, refer to the following figure to assist in troubleshooting your design. Calibration results and failing stages are available through the external memory interface toolkit.

Figure 97. Debugging Tips



13.5. Debug Report for Arria V and Cyclone V SoC Devices

The External Memory Interface Debug Toolkit and EMIF On-Chip Debug Port do not work with Arria V and Cyclone V SoC devices. Debugging information for Arria V and Cyclone V SoC devices is available by enabling a debug output report, which contains similar information.





13.5.1. Enabling the Debug Report for Arria V and Cyclone V SoC Devices

To enable a debug report for Arria V or Cyclone V SoC devices, perform the following steps:

- Open the <design_name>/hps_isw_handoff/sequencer_defines.h file in a text editor.
- 2. In the sequencer_defines.h file, locate the following line: #define RUNTIME CAL REPORT 0
- 3. Change #define RUNTIME_CAL_REPORT 0 to #define RUNTIME_CAL_REPORT 1, and save the file.
- 4. Generate the board support package (BSP) with semihosting enabled, or with UART output.

The system will now generate the debugging report as part of the calibration process.

13.5.2. Determining the Failing Calibration Stage for a Cyclone V or Arria V HPS SDRAM Controller

To determine the failing calibration stage, you must turn on the debug output report by setting the RUNTIME_CAL_REPORT option to 1 in the sequencer_defines.h file, located in the hps_isw_handoff directory.

If calibration fails, the following statements are printed in the debug output report:

```
SEQ.C: Calibration Failed
SEQ.C: Error Stage: <Num>
SEQ.C: Error Substage: <Num>
SEQ.C: Error Group: <Num>
```

To determine the stage and sub-stage, open the sequencer.h file in the hps_isw_handoff directory and look for the calibration defines:

```
/* calibration stages
#define CAL_STAGE_NIL 0
#define CAL_STAGE_VFIFO 1
#define CAL_STAGE_WLEVEL 2
#define CAL_STAGE_LFIFO 3
#define CAL_STAGE_WRITES 4
#define CAL_STAGE_FULLTEST 5
#define CAL_STAGE_REFRESH 6
#define CAL_STAGE_CAL_SKIPPED 7
#define CAL_STAGE_CAL_ABORTED 8
#define CAL_STAGE_VFIFO_AFTER_WRITES 9
 calibration substages */
#define CAL_SUBSTAGE_NIL 0
#define CAL_SUBSTAGE_GUARANTEED_READ 1
#define CAL_SUBSTAGE_DQS_EN_PHASE 2
#define CAL_SUBSTAGE_VFIFO_CENTER 3
#define CAL SUBSTAGE WORKING DELAY 1
#define CAL_SUBSTAGE_LAST_WORKING_DELAY 2
#define CAL_SUBSTAGE_WLEVEL_COPY 3
#define CAL_SUBSTAGE_WRITES_CENTER 1
#define CAL_SUBSTAGE_READ_LATENCY 1
#define CAL SUBSTAGE REFRESH 1
```

For details about the stages of calibration, refer to *Calibration Stages* in *Functional Description - UniPHY*.



Related Information

Calibration Stages on page 51

13.6. On-Chip Debug Port for UniPHY-based EMIF IP

The EMIF On-Chip Debug Port allows user logic to access the same calibration data used by the EMIF Toolkit, and allows user logic to send commands to the sequencer. You can use the EMIF On-Chip Debug Port to access calibration data for your design and to send commands to the sequencer just as the EMIF Toolkit would. The following information is available:

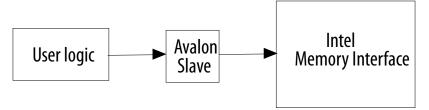
- · Pass/fail status for each DQS group
- Read and write data valid windows for each group

In addition, user logic can request the following commands from the sequencer:

- Destructive recalibration of all groups
- · Masking of groups and ranks
- · Generation of per-DQ pin margining data as part of calibration

The user logic communicates through an Avalon-MM slave interface as shown below.

Figure 98. User Logic Access



13.6.1. Access Protocol

The On-Chip Debug Port provides access to calibration data through an Avalon-MM slave interface. To send a command to the sequencer, user logic sends a command code to the command space in sequencer memory. The sequencer polls the command space for new commands after each group completes calibration, and continuously after overall calibration has completed.

The communication protocol to send commands from user logic to the sequencer uses a multistep handshake with a data structure as shown below, and an algorithm as shown in the figure which follows.

```
typedef struct_debug_data_struct {
...
// Command interaction
alt_u32 requested_command;
alt_u32 command_status;
alt_u32 command_parameters[COMMAND_PARAM_WORDS];...
}
```

To send a command to the sequencer, user logic must first poll the command_status word for a value of TCLDBG_TX_STATUS_CMD_READY, which indicates that the sequencer is ready to accept commands. When the sequencer is ready to accept



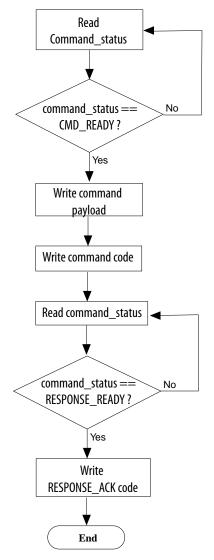


commands, user logic must write the command parameters into command_parameters, and then write the command code into requested_command.

The sequencer detects the command code and replaces <code>command_status</code> with <code>TCLDBG_TX_STATUS_CMD_EXE</code>, to indicate that it is processing the command. When the sequencer has finished running the command, it sets <code>command_status</code> to <code>TCLDBG_TX_STATUS_RESPONSE_READY</code> to indicate that the result of the command is available to be read. (If the sequencer rejects the requested command as illegal, it sets <code>command_status</code> to <code>TCLDBG_TX_STATUS_ILLEGAL_CMD</code>.)

User logic acknowledges completion of the command by writing TCLDBG_CMD_RESPONSE_ACK to requested_command. The sequencer responds by setting command_status back to STATUS_CMD_READY. (If an illegal command is received, it must be cleared using CMD_RESPONSE_ACK.)

Figure 99. Debugging Algorithm Flowchart







13.6.2. Command Codes Reference

The following table lists the supported command codes for the On-Chip Debug Port.

Table 87. Supported Command Codes

Command	Parameters	Description
TCLDBG_RUN_MEM_CALIBRATE	None	Runs the calibration routine.
TCLDBG_MARK_ALL_DQS_GROUPS_AS_VALID	None	Marks all groups as valid for calibration.
TCLDBG_MARK_GROUP_AS_SKIP	Group to skip	Mark the specified group to be skipped by calibration.
TCLDBG_MARK_ALL_RANKS_AS_VALID	None	Mark all ranks as valid for calibration
TCLDBG_MARK_RANK_AS_SKIP	Rank to skip	Mark the specified rank to be skipped by calibration.
TCLDBG_ENABLE_MARGIN_REPORT	None	Enables generation of the margin report.

13.6.3. Header Files

The external memory interface IP generates header files which identify the debug data structures and memory locations used with the EMIF On-Chip Debug Port. You should refer to these header files for information required for use with your core user logic. It is highly recommended to use a software component (such as a Nios II processor) to access the calibration debug data.

The header files are unique to your IP parameterization and version, therefore you must ensure that you are referring to the correct version of header for your design. The names of the header files are: **core_debug.h** and **core_debug_defines.h**. The header files reside in <design name> /<design name> s0 software.

13.6.4. Generating IP With the Debug Port

The following steps summarize the procedure for implementing your IP with the EMIF On-Chip Debug Port enabled.

- 1. Start the Quartus Prime software and generate a new external memory interface. For QDR II and RLDRAM II protocols, ensure that sequencer optimization is set to **Performance** (for Nios II-based sequencer).
- On the **Diagnostics** tab of the parameter editor, turn on **Enable EMIF On-Chip Debug Port**.
- Ensure that the EMIF On-Chip Debug Port interface type is set to Avalon-MM Slave.
- 4. Click Finish to generate your IP.
- 5. Find the Avalon interface in the top-level generated file. Connect this interface to your debug component.

```
input wire [19:0] seq_debug_addr, // seq_debug.address input wire seq_debug_read_req, // .read output wire [31:0] seq_debug_rdata, // .readdata input wire seq_debug_write_req, // .write input wire [31:0] seq_debug_wdata, // .writedata
```





```
output wire seq_debug_waitrequest, // .waitrequest input wire [3:0] seq_debug_be, // .byteenable output wire seq_debug_rdata_valid // .readdatavalid
```

If you are using UniPHY-based IP with the hard memory controller, also connect the seq_debug_clk and seq_debug_reset_in signals to clock and asynchronous reset signals that control your debug logic.

- 6. Find the **core_debug.h** and **core_debug_defines.h** header files in <design_name>/<design_name>_s0_software and include these files in your debug component code.
- 7. Write your debug component using the supported command codes, to read and write to the Avalon-MM interface.

The debug data structure resides at the memory address SEQ_CORE_DEBUG_BASE, which is defined in the **core_debug_defines.h** header file.

13.6.5. Example C Code for Accessing Debug Data

A typical use of the EMIF On-Chip Debug Port might be to recalibrate the external memory interface, and then access the reports directly using the summary_report_ptr, cal_report_ptr, and margin_report_ptr pointers, which are part of the debug data structure.

The following code sample illustrates:

```
* DDR3 UniPHY sequencer core access example
#include <stdio.h>
#include <unistd.h>
#include <io.h>
#include "core_debug_defines.h"
int send_command(volatile debug_data_t* debug_data_ptr, int command, int args[],
int num_args)
volatile int i, response;
// Wait until command status is ready
do {
 response = IORD_32DIRECT(&(debug_data_ptr->command_status), 0);
} while(response != TCLDBG_TX_STATUS_CMD_READY);
// Load arguments
if(num_args > COMMAND_PARAM_WORDS)
// Too many arguments
return 0;
for(i = 0; i < num\_args; i++)
IOWR_32DIRECT(&(debug_data_ptr->command_parameters[i]), 0, args[i]);
// Send command code
IOWR_32DIRECT(&(debug_data_ptr->requested_command), 0, command);
// Wait for acknowledgment
 response = IORD_32DIRECT(&(debug_data_ptr->command_status), 0);
} while(response != TCLDBG_TX_STATUS_RESPOSE_READY && response !=
TCLDBG_TX_STATUS_ILLEGAL_CMD);
// Acknowledge response
IOWR_32DIRECT(&(debug_data_ptr->requested_command), 0, TCLDBG_CMD_RESPONSE_ACK);
```





```
// Return 1 on success, 0 on illegal command
return (response != TCLDBG_TX_STATUS_ILLEGAL_CMD);
int main()
  volatile debug_data_t* my_debug_data_ptr;
  volatile debug_summary_report_t* my_summary_report_ptr;
  volatile debug_cal_report_t* my_cal_report_ptr;
  volatile debug_margin_report_t* my_margin_report_ptr;
volatile debug_cal_observed_dq_margins_t* cal_observed_dq_margins_ptr;
  int i, j, size;
  int args[COMMAND_PARAM_WORDS];
  // Initialize pointers to the debug reports
  my_debug_data_ptr = (debug_data_t*)SEQ_CORE_DEBUG_BASE;
  my_summary_report_ptr = (debug_summary_report_t*)
(IORD_32DIRECT(&(my_debug_data_ptr->summary_report_ptr), 0));
  my_cal_report_ptr = (debug_cal_report_t*)(IORD_32DIRECT(&(my_debug_data_ptr-
>cal_report_ptr), 0));
  my_margin_report_ptr = (debug_margin_report_t*)
(IORD_32DIRECT(&(my_debug_data_ptr->margin_report_ptr), 0));
  // Activate all groups and ranks
  send_command(my_debug_data_ptr, TCLDBG_MARK_ALL_DQS_GROUPS_AS_VALID, 0, 0);
  send_command(my_debug_data_ptr, TCLDBG_MARK_ALL_RANKS_AS_VALID, 0, 0);
send_command(my_debug_data_ptr, TCLDBG_ENABLE_MARGIN_REPORT, 0, 0);
  // Mask group 4
args[0] = 4;
  send_command(my_debug_data_ptr, TCLDBG_MARK_GROUP_AS_SKIP, args, 1);
send_command(my_debug_data_ptr, TCLDBG_RUN_MEM_CALIBRATE, 0, 0);
  // SUMMARY
  printf("SUMMARY REPORT\n");
  printf("mem_address_width: %u\n", IORD_32DIRECT(&(my_summary_report_ptr-
>mem_address_width), 0));
 printf("mem_bank_width: %u\n", IORD_32DIRECT(&(my_summary_report_ptr-
>mem_bank_width), 0));
  // etc...
  // CAL REPORT
  printf("CALIBRATION REPORT\n");
  // DQ read margins
  for(i = 0; i < RW_MGR_MEM_DATA_WIDTH; i++)</pre>
  cal_observed_dq_margins_ptr = &(my_cal_report_ptr->cal_dq_in_margins[i]);
  printf("0x%x DQ %d Read Margin (taps): -%d : %d\n", (unsigned
int)cal_observed_dq_margins_ptr, i,
  IORD_32DIRECT(&(cal_observed_dq_margins_ptr->left_edge), 0),
  IORD_32DIRECT(&(cal_observed_dq_margins_ptr->right_edge), 0));
  // etc...
  return 0;
```

13.7. Example Tcl Script for Running the Legacy EMIF Debug Toolkit

If you want, you can run the Legacy EMIF Debug Toolkit using a Tcl script. The following example Tcl script is applicable to all device families.

The following example Tcl script opens a file, runs the debug toolkit, and writes the resulting calibration reports to a file.





You should adjust the variables in the script to match your design. You can then run the script using the command quartus_sh -t example.tcl.

```
# Modify the following variables for your project
set project "ed_synth.qpf"
# Index of the programming cable. Can be listed using "get_hardware_names"
set hardware_index 1
# Index of the device on the specified cable. Can be listed using
"get_device_names"
set device_index 1
# SOF file containing the EMIF to debug
set sof "ed_synth.sof
# Connection ID of the EMIF debug interface. Can be listed using
"get_connections"
set connection_id 2
# Output file
set report "toolkit.rpt"
# The following code opens a project and writes its calibration reports to a
project_open $project
load_package ::quartus::external_memif_toolkit
initialize_connections
set hardware_name [lindex [get_hardware_names] $hardware_index]
set device_name [lindex [get_device_names -hardware_name $hardware_name]
$device_index]
link_project_to_device -device_name $device_name -hardware_name $hardware_name -
sof file $sof
establish_connection -id $connection_id
create_connection_report -id $connection_id -report_type summary
create_connection_report -id $connection_id -report_type calib
write_connection_target_report -id $connection_id -file $report
```

13.8. Document Revision History

Date	Version	Changes
March 2023	2023.03.06	Removed references to Intel Arria 10 and Intel Stratix 10 devices and associated protocols.
May 2017	2017.05.08	 Added Using the EMIF Debug Toolkit with Arria 10 HPS Interfaces topic. Added Calibration Adjustment Delay Step Sizes for Arria 10 Devices topic. Replaced EMIF Configurable Traffic Generator 2.0 section with new Traffic Generator 2.0 section. Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	 Added additional option to step 1 of Establishing Communication to Connections. Added sentence to second bullet in Eye Diagram. Expanded step 4 and added step 5, in Determining Margin. Added Configuring the Traffic Generator 2.0 and The Traffic Generator 2.0 Report.
November 2015	2015.11.02	 Changed title of Architecture section to User Interface. Added sentence to Driver Margining section stating that driver margining is not available if ECC is enabled. Removed note that the memory map for Arria 10 On-Chip Debug would be available in a future release. Created separate On-Chip Debug sections for UniPHY-based EMIF IP and Arria 10 EMIF IP. Changed title of Driver Margining (Arria 10 only) section to Driver Margining for Arria 10 EMIF IP.
	1	continued





Date	Version	Changes
		 Changed title of Read Setting and Apply Setting Commands (Arria 10 only) to Read Setting and Apply Setting Commands for Arria 10 EMIF IP. Added section Example Tcl Script for Running the EMIF Debug Toolkit. Changed instances of Quartus II to Quartus Prime.
May 2015	2015.05.04	 Added Determining the Failing Calibration Stage for a Cyclone V or Arria V HPS SDRAM Controller. Changed occurrences of On-Chip Debug Toolkit to On-Chip Debug Port. Added Driver Margining (Arria 10 only) and Determining Margin. Added Read Setting and Apply Setting Commands (Arria 10 only) and Reading or Applying Calibration Settings.
December 2014	2014.12.15	 Added paragraph to step 5 of Generating IP With the Debug Port. Added mention of seq_debug_clk and seq_debug_reset_in to step 5 of Generating IP With the Debug Port.
August 2014	2014.08.15	Maintenance release.
December 2013	2013.12.16	Maintenance release.
November 2012	2.2	 Changes to Setup and Use and General Workflow sections. Added EMIF On-Chip Debug Toolkit section Changed chapter number from 11 to 13.
August 2012	2.1	Added table of debugging tips.
June 2012	2.0	Revised content for new UnIPHY EMIF Toolkit. Added Feedback icon.
November 2011	1.0	Harvested 11.0 DDR2 and DDR3 SDRAM Controller with UniPHY EMIF Toolkit content.







14. Upgrading to UniPHY-based Controllers from **ALTMEMPHY-based Controllers**

The following topics describe the process of upgrading to UniPHY from DDR2 or DDR3 SDRAM High-Performance Controller II with ALTMEMPHY Designs.

NOTE: Designs that do not use the AFI cannot be upgraded to UniPHY. If your design uses non-AFI IP cores, Intel recommends that you start a new design with the UniPHY IP core. In addition, Intel recommends that any new designs targeting Stratix III, Stratix IV, or Stratix V use the UniPHY datapath.

To upgrade your ALTMEMPHY-based DDR2 or DDR3 SDRAM High-Performance Controller II design to a DDR2 or DDR3 SDRAM controller with UniPHY IP core, you must complete the tasks listed below:

- 1. Generating Equivalent Design
- 2. Replacing the ALTMEMPHY Datapath with UniPHY Datapath
- 3. Resolving Port Name Differences
- 4. Creating OCT Signals
- 5. Running Pin Assignments Script
- 6. Removing Obsolete Files
- 7. Simulating your Design

The following topics describe these tasks in detail.

Related Information

- Generating Equivalent Design on page 287
- Replacing the ALTMEMPHY Datapath with UniPHY Datapath on page 288
- Resolving Port Name Differences on page 288
- Creating OCT Signals on page 290
- Running Pin Assignments Script on page 290
- Removing Obsolete Files on page 290
- Simulating your Design on page 290
- Creating OCT Signals on page 290

14.1. Generating Equivalent Design

Create a new DDR2 or DDR3 SDRAM controller with UniPHY IP core, by following the steps in the Implementing and Parameterizing Memory IP chapter of the Design Guidelines volume, and apply the following guidelines:

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- Specify the same variation name as the ALTMEMPHY variation.
- Specify a directory different than the ALTMEMPHY design directory to prevent files from overwriting each other during generation.

To ease the migration process, ensure the UniPHY-based design you create is as similar as possible to the existing ALTMEMPHY-based design. In particular, you should ensure the following settings are the same in your UniPHY-based design:

- PHY settings tab
- FPGA speed grade
- PLL reference clock
- Memory clock frequency
- There is no need to change the default Address and command clock phase settings; however, if you have board skew effects in your ALTMEMPHY design, enter the difference between that clock phase and the default clock phase into the Address and command clock phase settings.
- **Memory Parameters** tab—all parameters must match.
- Memory Timing tab—all parameters must match.
- **Board settings** tab—all parameters must match.
- Controller settings tab—all parameters must match

Note:

In ALTMEMPHY-based designs you can turn off dynamic OCT. However, all UniPHY-based designs use dynamic parallel OCT and you cannot turn it off.

Related Information

Design Guidelines

14.2. Replacing the ALTMEMPHY Datapath with UniPHY Datapath

To replace the ALTMEMPHY datapath with the UniPHY datapath, follow these steps:

- 1. In the Quartus Prime software, open the Assignment Editor, on the Assignments menu click **Assignment Editor**.
- 2. Manually delete all of the assignments related to the external memory interface pins, except for the location assignments if you are preserving the pinout. By default, these pin names start with the mem prefix, though in your design they may have a different name.
- 3. Remove the old ALTMEMPHY .qip file from the project, as follows:
 - a. On the Assignments menu click Settings.
 - b. Specify the old .qip, and click Remove.

Your design now uses the UniPHY datapath.

14.3. Resolving Port Name Differences

Several port names in the ALTMEMPHY datapath are different than in the UniPHY datapath. The different names may cause compilation errors.





This topic describes the changes you must make in the RTL for the entity that instantiates the memory IP core. Each change applies to a specific port in the ALTMEMPHY datapath. Unconnected ports require no changes.

In some instances, multiple ports in ALTMEMPHY-based designs are mapped to a single port in UniPHY-based designs. If you use both ports in ALTMEMPHY-based designs, assign a temporary signal to the common port and connect it to the original wires. The following table shows the changes you must make.

Table 88. Changes to ALTMEMPHY Port Names

ALTMEMPHY Port	Changes
aux_full_rate_clk	The UniPHY-based design does not generate this signal. You can generate it if you require it.
aux_scan_clk	The UniPHY-based design does not generate this signal. You can generate it if you require it.
aux_scan_clk_reset_n	The UniPHY-based design does not generate this signal. You can generate it if you require it.
dll_reference_clk	The UniPHY-based design does not generate this signal. You can generate it if you require it.
dqs_delay_ctrl_export	This signal is for DLL sharing between ALTMEMPHY instances and is not applicable for UniPHY-based designs.
local_address	Rename to avl_addr.
local_be	Rename to avl_be.
local_burstbegin	Rename to avl_burstbegin.
local_rdata	Rename to avl_rdata.
local_rdata_valid	Rename to avl_rdata_valid.
local_read_req	Rename to avl_read_req.
local_ready	Rename to avl_ready.
local_size	Rename to avl_size.
local_wdata	Rename to avl_wdata.
local_write_req	Rename to avl_write_req.
mem_addr	Rename to mem_a.
mem_clk	Rename to mem_ck.
mem_clk_n	Rename to mem_ck_n.
mem_dqsn	Rename to mem_dqs_n.
oct_ctl_rs_value	Remove from design (see "Creating OCT Signals").
oct_ctl_rt_value	Remove from design (see "Creating OCT Signals").
phy_clk	Rename to afi_clk.
reset_phy_clk_n	Rename to afi_reset_n.
local_refresh_ack reset_request_n	The controller no longer exposes these signals to the top-level design, so comment out these outputs. If you need it, bring the wire out from the high-performance II controller entity in <pre>cproject_directory>/<variation name="">.v.</variation></pre>



Related Information

Creating OCT Signals on page 290

14.4. Creating OCT Signals

In ALTMEMPHY-based designs, the Quartus Prime Fitter creates the alt_oct block outside the IP core and connects it to the oct_ctl_rs_value and oct_ctl_rt_value signals.

In UniPHY-based designs, the OCT block is part of the IP core, so the design no longer requires these two ports. Instead, the UniPHY-based design requires two additional ports, oct_rup and oct_rdn (for Stratix III and Stratix IV devices), or oct_rzqin (for Stratix V devices). You must create these ports in the instantiating entity as input pins and connect to the UniPHY instance. Then route these pins to the top-level design and connect to the OCT R_{UP} and R_{DOWN} resistors on the board.

For information on OCT control block sharing, refer to "The OCT Sharing Interface" in this volume.

14.5. Running Pin Assignments Script

Remap your design by running analysis and synthesis.

When analysis and synthesis completes, run the pin assignments Tcl script and then verify the new pin assignments in the Assignment Editor.

14.6. Removing Obsolete Files

After you upgrade the design, you may remove the unnecessary ALTMEMPHY design files from your project.

To identify these files, examine the original ALTMEMPHY-generated .qip file in any text editor.

14.7. Simulating your Design

You must use the UniPHY memory model to simulate your new design.

To use the UniPHY memory model, follow these steps:

- 1. Edit your instantiation of the UniPHY datapath to ensure the <code>local_init_done</code>, <code>local_cal_success</code>, <code>local_cal_fail</code>, <code>soft_reset_n</code>, <code>oct_rdn</code>, <code>oct_rup</code>, <code>reset_phy_clk_n</code>, and <code>phy_clk</code> signals are at the top-level entity so that an instantiating testbench can refer to those signals.
- 2. To use the UniPHY testbench and memory model, generate the example design when generating your IP instantiation.
- Specify that your third-party simulator should use the UniPHY testbench and memory model instead of the ALTMEMPHY memory model, as follows:
 - On the Assignments menu, point to Settings and click the Project Settings window.
 - b. Select the **Simulation** tab, click **Test Benches**, click **Edit**, and replace the ALTMEMPHY testbench files with the following files:





- \roject directory>\<variation name>_example_design \simulation\verilog\submodules \altera_avalon_clock_source.sv or \roject directory> \<variation name>_example_design\simulation\vhdl \submodules\altera avalon clock source.vhd
- \cproject directory>\<variation name>_example_design \simulation\verilog\<variation name>_example_sim.v or \uniphy\<variation name>_example_design\simulation\vhdl \<variation name> example sim.vhd
- \\\ct directory>\<variation name>_example_design \simulation\verilog\submodules\verbosity_pkg.sv
- \roject directory>\<variation name>_example_design \simulation\verilog\submodules \status_checker_no_ifdef_params.sv or \roject directory> \<variation name>_example_design\simulation\vhdl \submodules\status_checker_no_ifdef_params.sv
- \<project directory>\<variation name>_example_design \simulation\verilog\submodules \alt_mem_if_common_ddr_mem_model_ddr3_mem_if_dm_pins_en_ mem_if_dqsn_en.sv or \<project directory>\<variation name>_example_design\simulation\vhdl\submodules \alt_mem_if_common_ddr_mem_model_ddr3_mem_if_dm_pins_en_ mem_if_dqsn_en.sv
- \
 \
 \
 \
 \simulation\verilog\submodules
 \alt_mem_if_ddr3_mem_model_top_ddr3_mem_if_dm_pins_en_me

 m_if_dqsn_en or \
 \
 \alt_mem_if_design\simulation\vhdl\submodules
 \alt_mem_if_ddr3_mem_model_top_ddr3_mem_if_dm_pins_en_me

 m_if_dqsn_en
- 4. Open the <variation name>_example_sim.v file and find the UniPHY-generated simulation example design module name below: <variation name> example sim e0.
- 5. Change the module name above to the name of your top-level design module.
- 6. Refer to the following table and update the listed port names of the example design in the UniPHY-generated <variation name>_example_sim.v file.





Table 89. Example Design Port Names

Example Design Name	New Name
pll_ref_clk	Rename to clock_source.
mem_a	Rename to mem_addr.
mem_ck	Rename to mem_clk.
mem_ck_n	Rename to mem_clk_n.
mem_dqs_n	Rename to mem_dqsn.
drv_status_pass	Rename to pnf.
afi_clk	Rename to phy_clk.
afi_reset_n	Rename to reset_phy_clk_n.
drv_status_fail	This signal is not available, so comment out this output.
afi_half_clk	This signal is not exposed to the top-level design, so comment out this output.

For more information about generating example simulation files, refer to Simulating Memory IP, in volume 2 of the *External Memory Interface Handbook*.

14.8. Document Revision History

Date	Version	Changes
May 2017	2017.05.08	Rebranded as Intel.
October 2016	2016.10.31	Maintenance release.
May 2016	2016.05.02	Maintenance release.
November 2015	2015.11.02	Changed instances of <i>Quartus II</i> to <i>Quartus Prime</i> .
May 2015	2015.05.04	Maintenance release.
December 2014	2014.12.15	Maintenance release.
August 2014	2014.08.15	Maintenance release.
December 2013	2013.12.16	Removed local_wdata_req from port names table.
November 2012	2.3	Changed chapter number from 12 to 14.
June 2012	2.2	Added Feedback icon.
November 2011	2.1	Revised Simulating your Design section.

